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The revision list can be viewed directly by clicking the title page.

The revision list summarizes the locations of revisions and additions. Details should always be checked by referring to the relevant text.

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H8/36024Group, H8/36014Group

Hardware Manual

Renesas 16-Bit Single-Chip Microcomputer H8 Family/H8/300H Tiny Series

H8/36024F H8/36022F H8/36014F H8/36012F H8/36024 H8/36023 H8/36022 H8/36014 H8/36013 H8/36012 H8/36011

H8/36010 Renesas Electronics

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HD64336012, HD64336012G,

HD64336011, HD64336011G,

HD64336010, HD64336010G

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General Precautions on Handling of Product

- 1. Treatment of NC Pins
- Note: Do not connect anything to the NC pins.

The NC (not connected) pins are either not connected to any of the internal circuitry or are used as test pins or to reduce noise. If something is connected to the NC pins, the operation of the LSI is not guaranteed.

- 2. Treatment of Unused Input Pins
- Note: Fix all unused input pins to high or low level. Generally, the input pins of CMOS products are high-impedance input pins. If unused pins are in their open states, intermediate levels are induced by noise in the vicinity, a passthrough current flows internally, and a malfunction may occur.
- 3. Processing before Initialization
- Note: When power is first supplied, the product's state is undefined. The states of internal circuits are undefined until full power is supplied throughout the chip and a low level is input on the reset pin. During the period where the states are undefined, the register settings and the output state of each pin are also undefined. Design your system so that it does not malfunction because of processing while it is in this undefined state. For those products which have a reset function, reset the LSI immediately after the power supply has been turned on.
- 4. Prohibition of Access to Undefined or Reserved Addresses
- Note: Access to undefined or reserved addresses is prohibited. The undefined or reserved addresses may be used to expand functions, or test registers may have been be allocated to these addresses. Do not access these registers; the system's operation is not guaranteed if they are accessed.



Configuration of This Manual

This manual comprises the following items:

- 1. General Precautions on Handling of Product
- 2. Configuration of This Manual
- 3. Preface
- 4. Contents
- 5. Overview
- 6. Description of Functional Modules
 - CPU and System-Control Modules
 - On-Chip Peripheral Modules
 The configuration of the functional description of each module differs according to the module. However, the generic style includes the following items:
 - i) Feature
 - ii) Input/Output Pin
 - iii) Register Description
 - iv) Operation
 - v) Usage Note

When designing an application system that includes this LSI, take notes into account. Each section includes notes in relation to the descriptions given, and usage notes are given, as required, as the final part of each section.

- 7. List of Registers
- 8. Electrical Characteristics
- 9. Appendix

10. Main Revisions and Additions in this Edition (only for revised versions)

The list of revisions is a summary of points that have been revised or added to earlier versions. This does not include all of the revised contents. For details, see the actual locations in this manual.

11. Index



Preface

The H8/36024 Group and H8/36014 Group are single-chip microcomputers made up of the high-speed H8/300H CPU employing Renesas Technology original architecture as their cores, and the peripheral functions required to configure a system. The H8/300H CPU has an instruction set that is compatible with the H8/300 CPU.

- Target Users: This manual was written for users who will be using the H8/36024 Group and H8/36014 Group in the design of application systems. Target users are expected to understand the fundamentals of electrical circuits, logical circuits, and microcomputers.
- Objective: This manual was written to explain the hardware functions and electrical characteristics of the H8/36024 Group and H8/36014 Group to the target users. Refer to the H8/300H Series Software Manual for a detailed description of the instruction set.

Notes on reading this manual:

- In order to understand the overall functions of the chip Read the manual according to the contents. This manual can be roughly categorized into parts on the CPU, system control functions, peripheral functions and electrical characteristics.
- In order to understand the details of the CPU's functions Read the H8/300H Series Software Manual.
- In order to understand the details of a register when its name is known Read the index that is the final part of the manual to find the page number of the entry on the register. The addresses, bits, and initial values of the registers are summarized in section 17, List of Registers.

Example: Bit order: The MSB is on the left and the LSB is on the right.

Notes:

When using the on-chip emulator (E7, E8) for H8/36014 program development and debugging, the following restrictions must be noted.

- 1. The $\overline{\text{NMI}}$ pin is reserved for the E7 or E8, and cannot be used.
- 2. Area H'7000 to H'7FFF is used by the E7 or E8, and is not available to the user.
- 3. Area H'F780 to H'FB7F must on no account be accessed.

- 4. When the E7 or E8 is used, address breaks can be set as either available to the user or for use by the E7 or E8. If address breaks are set as being used by the E7 or E8, the address break control registers must not be accessed.
- 5. When the E7 or E8 is used, $\overline{\text{NMI}}$ is an input/output pin (open-drain in output mode).
- 6. Use channel 1 of the SCI3 (P21/RXD, P22/TXD) in on-board programming mode by boot mode.
- Related Manuals: The latest versions of all related manuals are available from our web site. Please ensure you have the latest versions of all documents you require. http://www.renesas.com/

H8/36024 Group and H8/36014 Group manuals:

Document Title	Document No.
H8/36024 Group, H8/36014 Group Hardware Manual	This manual
H8/300H Series Software Manual	REJ09B0213

User's manuals for development tools:

Document Title	Document No.
H8S, H8/300 Series C/C++ Compiler, Assembler, Optimizing Linkage Editor User's Manual	REJ10B0058
Microcomputer Development Environment System H8S, H8/300 Series Simulator/Debugger User's Manual	ADE-702-282
H8S, H8/300 Series High-Performance Embedded Workshop 3, Tutorial	REJ10B0024
H8S, H8/300 Series High-Performance Embedded Workshop 3, User's Manual	REJ10B0026

Application notes:

Document Title	Document No.
H8S, H8/300 Series C/C++ Compiler Package Application Note	REJ05B0464
Single Power Supply F-ZTAT [™] On-Board Programming	ADE-502-055



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Section 1 Overview

1.1 Features

- High-speed H8/300H central processing unit with an internal 16-bit architecture
 - Upward-compatible with H8/300 CPU on an object level
 - Sixteen 16-bit general registers
 - 62 basic instructions
- Various peripheral functions
 - Timer V (8-bit timer)
 - Timer W (16-bit timer)
 - Watchdog timer
 - SCI3 (Asynchronous or clocked synchronous serial communication interface)
 - 10-bit A/D converter
- On-chip memory

		M	lodel		
Product Classif	fication	Standard Version	On-Chip Power- On Reset and Low-Voltage Detecting Circuit Version	ROM	RAM
Flash memory	H8/36024F	HD64F36024	HD64F36024G	32 kbytes	2,048 bytes
version	H8/36022F	HD64F36022	HD64F36022G	16 kbytes	2,048 bytes
(F-ZTAT [™] version)	H8/36014F	HD64F36014	HD64F36014G	32 kbytes	2,048 bytes
	H8/36012F	HD64F36012	HD64F36012G	16 kbytes	2,048 bytes
Masked ROM	H8/36024	HD64336024	HD64336024G	32 kbytes	1,024 bytes
version	H8/36023	HD64336023	HD64336023G	24 kbytes	1,024 bytes
	H8/36022	HD64336022	HD64336022G	16 kbytes	512 bytes
	H8/36014	HD64336014	HD64336014G	32 kbytes	1,024 bytes
	H8/36013	HD64336013	HD64336013G	24 kbytes	1,024 bytes
	H8/36012	HD64336012	HD64336012G	16 kbytes	512 bytes
	H8/36011	HD64336011	HD64336011G	12 kbytes	512 bytes
	H8/36010	HD64336010	HD64336010G	8 kbytes	512 bytes

- General I/O ports
 - I/O pins: 30 I/O pins, including 5 large current ports (I_{oL} = 20 mA, @V_{oL} = 1.5 V)
 - Input-only pins: 4 input pins (also used for analog input)
- Supports various power-down modes

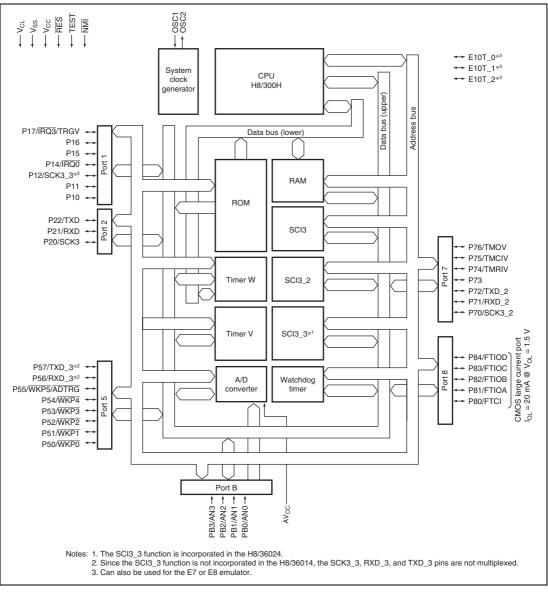
Note: F-ZTAT[™] is a trademark of Renesas Technology Corp.

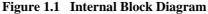
• Compact package

Package	Code	Body Size	Pin Pitch
LQFP-64	FP-64E	10.0 imes10.0 mm	0.5 mm
LQFP-48	FP-48F	10.0 imes 10.0 mm	0.65 mm
LQFP-48	FP-48B	7.0 imes 7.0 mm	0.5 mm
QFN-48	TNP-48	7.0 imes 7.0 mm	0.5 mm



1.2 Internal Block Diagram





1.3 Pin Arrangement

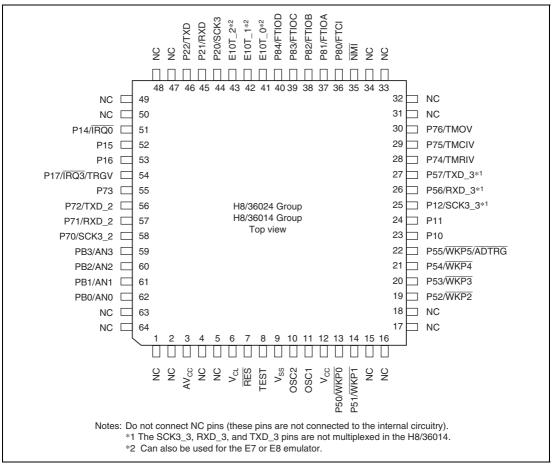


Figure 1.2 Pin Arrangement (FP-64E)

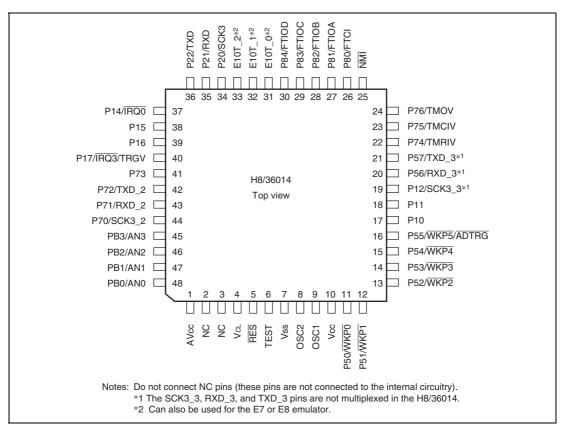


Figure 1.3 Pin Arrangement (FP-48F, FP-48B, TNP-48)



1.4 Pin Functions

Table 1.1Pin Functions

		Pin No.			
Туре	Symbol	FP-64E	FP-48F, FP-48B, TNP-48	I/O	Functions
Power source pins	V _{cc}	12	10	Input	Power supply pin. Connect this pin to the system power supply.
	V _{ss}	9	7	Input	Ground pin. Connect this pin to the system power supply (0V).
	AV _{cc}	3	1	Input	Analog power supply pin for the A/D converter. When the A/D converter is not used, connect this pin to the system power supply.
	V _{CL}	6	4	Input	Internal step-down power supply pin. Connect a capacitor of around 0.1 μ F between this pin and the Vss pin for stabilization.
Clock pins	OSC1	11	9	Input	These pins connect to a crystal or
	OSC2	10	8	Output	ceramic resonator for system clocks, or can be used to input an external clock.
					See section 5, Clock Pulse Generators, for a typical connection.
System control	RES	7	5	Input	Reset pin. The pull-up resistor (typ. 150 k Ω) is incorporated. When driven low, the chip is reset.
	TEST	8	6	Input	Test pin. Connect this pin to Vss.
Interrupt pins	NMI	35	25	Input	Non-maskable interrupt request input pin. Be sure to pull-up by a pull-up resistor.
	IRQ0, IRQ3	51, 54	37, 40	Input	External interrupt request input pins. Can select the rising or falling edge.
	WKP0 to WKP5	13, 14, 19 to 22	11 to 16	Input	External interrupt request input pins. Can select the rising or falling edge.

		Pin No.			
Туре	Symbol	FP-64E	FP-48F, FP-48B, TNP-48	- I/O	Functions
Timer V	TMOV	30	24	Output	This is an output pin for waveforms generated by the output compare function.
	TMCIV	29	23	Input	External event input pin.
	TMRIV	28	22	Input	Counter reset input pin.
	TRGV	54	40	Input	Counter start trigger input pin.
Timer W	FTCI	36	26	Input	External event input pin.
	FTIOA to FTIOD	37 to 40	27 to 30	I/O	Output compare output/ input capture input/ PWM output pin
Serial com- munication interface	TXD, TXD_2, TXD_3*	46, 56, 27	36, 42, 21	Output	Transmit data output pin
(SCI)	RXD, RXD_2, RXD_3*	45, 57, 26	35, 43, 20	Input	Receive data input pin
	SCK3, SCK3_2, SCK3_3*	44, 58, 25	34, 44, 19	I/O	Clock I/O pin
A/D	AN3 to AN0	59 to 62	45 to 48	Input	Analog input pin
converter	ADTRG	22	16	Input	A/D converter trigger input pin.
I/O ports	PB3 to PB0	59 to 62	45 to 48	Input	4-bit input port.
	P17 to P14, P12 to P10	54 to 51, 25 to 23	40 to 37, 19 to 17	I/O	7-bit I/O port.
	P22 to P20	46 to 44	36 to 34	I/O	3-bit I/O port.
	P57 to P50	27, 26, 22 to 19, 14, 13	21, 20, 16 to 11	I/O	8-bit I/O port
	P76 to P70	30 to 28, 55 to 58	24 to 22, 41 to 44	I/O	7-bit I/O port
	P84 to P80	40 to 36	30 to 26	I/O	5-bit I/O port.
E10T	E10T _0, E10T _1, E10T _2	41, 42, 43	31, 32, 33		Interface pin for the E10T, E8, or E7 emulator

Note: * The SCK3_3, RXD_3, and TXD_3 pins are not multiplexed in the H8/36014.



Section 2 CPU

This LSI has an H8/300H CPU with an internal 32-bit architecture that is upward-compatible with the H8/300CPU, and supports only normal mode, which has a 64-kbyte address space.

- Upward-compatible with H8/300 CPUs
 - Can execute H8/300 CPUs object programs
 - Additional eight 16-bit extended registers
 - 32-bit transfer and arithmetic and logic instructions are added
 - Signed multiply and divide instructions are added.
- General-register architecture
 - Sixteen 16-bit general registers also usable as sixteen 8-bit registers or eight 32-bit registers
- Sixty-two basic instructions
 - 8/16/32-bit data transfer and arithmetic and logic instructions
 - Multiply and divide instructions
 - Powerful bit-manipulation instructions
- Eight addressing modes
 - Register direct [Rn]
 - Register indirect [@ERn]
 - Register indirect with displacement [@(d:16,ERn) or @(d:24,ERn)]
 - Register indirect with post-increment or pre-decrement [@ERn+ or @-ERn]
 - Absolute address [@aa:8, @aa:16, @aa:24]
 - Immediate [#xx:8, #xx:16, or #xx:32]
 - Program-counter relative [@(d:8,PC) or @(d:16,PC)]
 - Memory indirect [@@aa:8]
- 64-kbyte address space
- High-speed operation
 - All frequently-used instructions execute in one or two states
 - 8/16/32-bit register-register add/subtract : 2 state
 - -- 8 × 8-bit register-register multiply : 14 states
 - $16 \div 8$ -bit register-register divide : 14 states
 - 16×16 -bit register-register multiply : 22 states
 - $32 \div 16$ -bit register-register divide : 22 states
- Power-down state
 - Transition to power-down state by SLEEP instruction



2.1 Address Space and Memory Map

The address space of this LSI is 64 kbytes, which includes the program area and the data area. Figures 2.1 show the memory maps.

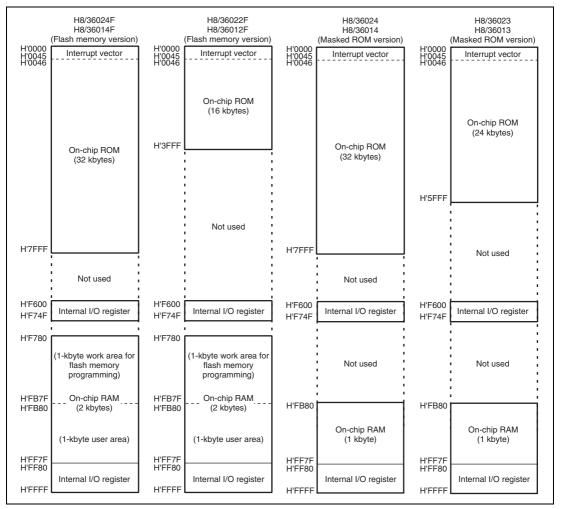


Figure 2.1 Memory Map (1)

RENESAS

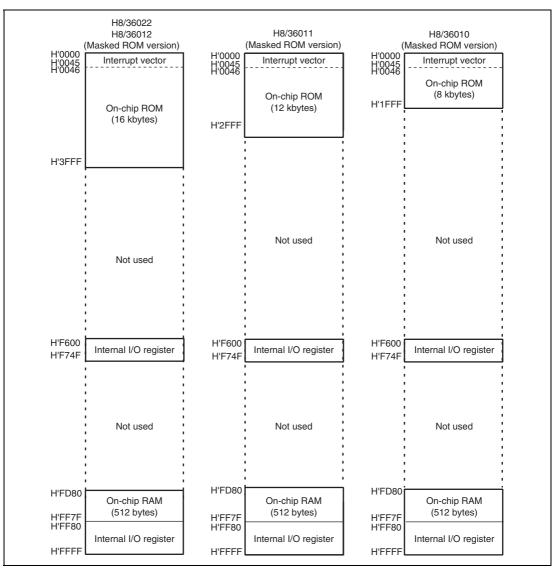


Figure 2.1 Memory Map (2)



2.2 Register Configuration

The H8/300H CPU has the internal registers shown in figure 2.2. There are two types of registers; general registers and control registers. The control registers are a 24-bit program counter (PC), and an 8-bit condition code register (CCR).

General Registers (ERn)				
	15	0 7	0 7 0	
ER0	E0	R0H	R0L	
ER1	E1	R1H	R1L	
ER2	E2	R2H	R2L	
ER3	E3	R3H	R3L	
ER4	E4	R4H	R4L	
ER5	E5	R5H	R5L	
ER6	E6	R6H	R6L	
ER7 (SP)	E7	R7H	R7L	
Control He	gisters (CR) 23	PC	0	
		СС	7 6 5 4 3 2 1 0 R I UIHUNZVC	
Legend				
SP PC CCR I UI	:Stack pointer :Program counter :Condition-code register :Interrupt mask bit :User bit	U :Use N :Neg Z :Zero V :Ove	-carry flag r bit ative flag b flag rflow flag ry flag	

Figure 2.2 CPU Registers

2.2.1 General Registers

The H8/300H CPU has eight 32-bit general registers. These general registers are all functionally identical and can be used as both address registers and data registers. When a general register is used as a data register, it can be accessed as a 32-bit, 16-bit, or 8-bit register. Figure 2.3 illustrates the usage of the general registers. When the general registers are used as 32-bit registers or address registers, they are designated by the letters ER (ER0 to ER7).

The ER registers divide into 16-bit general registers designated by the letters E (E0 to E7) and R (R0 to R7). These registers are functionally equivalent, providing a maximum of sixteen 16-bit registers. The E registers (E0 to E7) are also referred to as extended registers.

The R registers divide into 8-bit registers designated by the letters RH (R0H to R7H) and RL (R0L to R7L). These registers are functionally equivalent, providing a maximum of sixteen 8-bit registers.

The usage of each register can be selected independently.

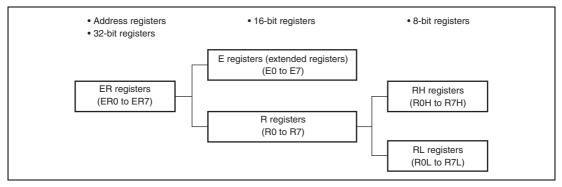


Figure 2.3 Usage of General Registers

General register ER7 has the function of stack pointer (SP) in addition to its general-register function, and is used implicitly in exception handling and subroutine calls. Figure 2.4 shows the stack.



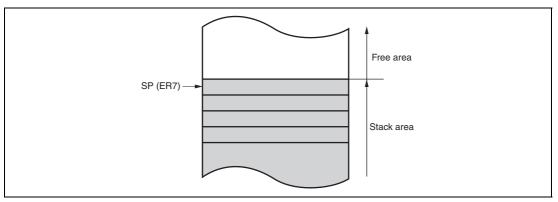


Figure 2.4 Relationship between Stack Pointer and Stack Area

2.2.2 Program Counter (PC)

This 24-bit counter indicates the address of the next instruction the CPU will execute. The length of all CPU instructions is 2 bytes (one word), so the least significant PC bit is ignored. (When an instruction is fetched, the least significant PC bit is regarded as 0). The PC is initialized when the start address is loaded by the vector address generated during reset exception-handling sequence.

2.2.3 Condition-Code Register (CCR)

This 8-bit register contains internal CPU status information, including an interrupt mask bit (I) and half-carry (H), negative (N), zero (Z), overflow (V), and carry (C) flags. The I bit is initialized to 1 by reset exception-handling sequence, but other bits are not initialized.

Some instructions leave flag bits unchanged. Operations can be performed on the CCR bits by the LDC, STC, ANDC, ORC, and XORC instructions. The N, Z, V, and C flags are used as branching conditions for conditional branch (Bcc) instructions.

For the action of each instruction on the flag bits, see Appendix A.1, Instruction List.



Bit	Bit Name	Initial Value	R/W	Description
7	I	1	R/W	Interrupt Mask Bit
				Masks interrupts other than NMI when set to 1. NMI is accepted regardless of the I bit setting. The I bit is set to 1 at the start of an exception-handling sequence.
6	UI	Undefined	R/W	User Bit
				Can be written and read by software using the LDC, STC, ANDC, ORC, and XORC instructions.
5	Н	Undefined	R/W	Half-Carry Flag
				When the ADD.B, ADDX.B, SUB.B, SUBX.B, CMP.B, or NEG.B instruction is executed, this flag is set to 1 if there is a carry or borrow at bit 3, and cleared to 0 otherwise. When the ADD.W, SUB.W, CMP.W, or NEG.W instruction is executed, the H flag is set to 1 if there is a carry or borrow at bit 11, and cleared to 0 otherwise. When the ADD.L, SUB.L, CMP.L, or NEG.L instruction is executed, the H flag is set to 1 if there is a carry or borrow at bit 27, and cleared to 0 otherwise.
4	U	Undefined	R/W	User Bit
				Can be written and read by software using the LDC, STC, ANDC, ORC, and XORC instructions.
3	Ν	Undefined	R/W	Negative Flag
				Stores the value of the most significant bit of data as a sign bit.
2	Z	Undefined	R/W	Zero Flag
				Set to 1 to indicate zero data, and cleared to 0 to indicate non-zero data.
1	V	Undefined	R/W	Overflow Flag
				Set to 1 when an arithmetic overflow occurs, and cleared to 0 at other times.
0	С	Undefined	R/W	Carry Flag
				Set to 1 when a carry occurs, and cleared to 0 otherwise. Used by:
				Add instructions, to indicate a carry
				Subtract instructions, to indicate a borrow
				Shift and rotate instructions, to indicate a carry
				The carry flag is also used as a bit accumulator by bit manipulation instructions.



2.3 Data Formats

The H8/300H CPU can process 1-bit, 4-bit (BCD), 8-bit (byte), 16-bit (word), and 32-bit (longword) data. Bit-manipulation instructions operate on 1-bit data by accessing bit n (n = 0, 1, 2, ..., 7) of byte operand data. The DAA and DAS decimal-adjust instructions treat byte data as two digits of 4-bit BCD data.

2.3.1 General Register Data Formats

Data Type General Register Data Format 7 0 **RnH** 6 5 4 3 2 1 0 Don't care 7 1-bit data Don't care RnL 7 6 5 4 3 2 1-bit data 7 4 3 0 4-bit BCD data RnH Upper Lower Don't care 4 3 0 4-bit BCD data RnL Don't care Upper Lower Byte data RnH Don't care MSB LSB Byte data RnL Don't care MSB LSB

Figure 2.5 shows the data formats in general registers.

Figure 2.5 General Register Data Formats (1)

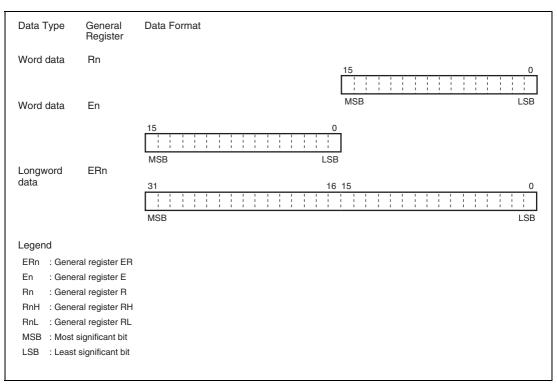


Figure 2.5 General Register Data Formats (2)



2.3.2 Memory Data Formats

Figure 2.6 shows the data formats in memory. The H8/300H CPU can access word data and longword data in memory, however word or longword data must begin at an even address. If an attempt is made to access word or longword data at an odd address, an address error does not occur, however the least significant bit of the address is regarded as 0, so access begins the preceding address. This also applies to instruction fetches.

When ER7 (SP) is used as an address register to access the stack, the operand size should be word or longword.

Data Type	Address	Data Format
		7 0
1-bit data	Address L	7 6 5 4 3 2 1 0
Byte data	Address L	MSB LLSB
Word data	Address 2M Address 2M+1	MSB'
Longword data	Address 2N Address 2N+1	MSB
	Address 2N+2 Address 2N+3	

Figure 2.6 Memory Data Formats

2.4 Instruction Set

2.4.1 Table of Instructions Classified by Function

The H8/300H CPU has 62 instructions. Tables 2.2 to 2.9 summarize the instructions in each functional category. The notation used in tables 2.2 to 2.9 is defined below.

Symbol	Description
Rd	General register (destination)*
Rs	General register (source)*
Rn	General register*
ERn	General register (32-bit register or address register)
(EAd)	Destination operand
(EAs)	Source operand
CCR	Condition-code register
Ν	N (negative) flag in CCR
Z	Z (zero) flag in CCR
V	V (overflow) flag in CCR
С	C (carry) flag in CCR
PC	Program counter
SP	Stack pointer
#IMM	Immediate data
disp	Displacement
+	Addition
_	Subtraction
×	Multiplication
÷	Division
^	Logical AND
\vee	Logical OR
\oplus	Logical XOR
\rightarrow	Move
٦	NOT (logical complement)

 Table 2.1
 Operation Notation



Symbol		Description
:3/:8/:16/:24		3-, 8-, 16-, or 24-bit length
Note: *	Gene	ral registers include 8-bit registers (R0H to R7H, R0L to R7L), 16-bit registers (R0

to R7, E0 to E7), and 32-bit registers/address registers (ER0 to ER7).

Table 2.2 Data Transfer Instructions

Instruction	Size*	Function
MOV	B/W/L	$(EAs) \rightarrow Rd, Rs \rightarrow (EAd)$ Moves data between two general registers or between a general register and memory, or moves immediate data to a general register.
MOVFPE	В	$(EAs) \rightarrow Rd$, Cannot be used in this LSI.
MOVTPE	В	$Rs \rightarrow$ (EAs) Cannot be used in this LSI.
POP	W/L	$@SP+ \rightarrow Rn$ Pops a general register from the stack. POP.W Rn is identical to MOV.W @SP+, Rn. POP.L ERn is identical to MOV.L @SP+, ERn.
PUSH	W/L	$Rn \rightarrow @-SP$ Pushes a general register onto the stack. PUSH.W Rn is identical to MOV.W Rn, @-SP. PUSH.L ERn is identical to MOV.L ERn, @-SP.
Note: * Re	efers to the	operand size.
B: Byt	e	
W: W	ord	
L: Lor	ngword	



Instruction	Size*	Function	
ADD SUB	B/W/L	$Rd \pm Rs \rightarrow Rd$, $Rd \pm \#IMM \rightarrow Rd$ Performs addition or subtraction on data in two general registers, or on immediate data and data in a general register (immediate byte data cannot be subtracted from byte data in a general register. Use the SUBX or ADD instruction.)	
ADDX SUBX	В	$Rd \pm Rs \pm C \rightarrow Rd$, $Rd \pm \#IMM \pm C \rightarrow Rd$ Performs addition or subtraction with carry on byte data in two general registers, or on immediate data and data in a general register.	
INC DEC	B/W/L	$\begin{array}{l} Rd\pm 1 \rightarrow Rd, Rd\pm 2 \rightarrow Rd \\ \mbox{Increments or decrements a general register by 1 or 2. (Byte operands \\ \mbox{can be incremented or decremented by 1 only.)} \end{array}$	
ADDS SUBS	L	$\begin{array}{ll} \mbox{Rd} \pm 1 \rightarrow \mbox{Rd}, & \mbox{Rd} \pm 2 \rightarrow \mbox{Rd}, & \mbox{Rd} \pm 4 \rightarrow \mbox{Rd} \\ \mbox{Adds or subtracts the value 1, 2, or 4 to or from data in a 32-bit register.} \end{array}$	
DAA DAS	В	Rd decimal adjust \rightarrow Rd Decimal-adjusts an addition or subtraction result in a general register by referring to the CCR to produce 4-bit BCD data.	
MULXU	B/W	$\begin{array}{l} Rd\timesRs\toRd\\ Performs \text{ unsigned multiplication on data in two general registers: either}\\ 8 \ bits\times8 \ bits\to16 \ bits \ or \ 16 \ bits\times16 \ bits\to32 \ bits. \end{array}$	
MULXS	B/W	$Rd \times Rs \rightarrow Rd$ Performs signed multiplication on data in two general registers: either 8 bits × 8 bits \rightarrow 16 bits or 16 bits × 16 bits \rightarrow 32 bits.	
DIVXU	B/W	Rd ÷ Rs → Rd Performs unsigned division on data in two general registers: either 16 bits ÷ 8 bits → 8-bit quotient and 8-bit remainder or 32 bits ÷ 16 bits → 16-bit quotient and 16-bit remainder.	
		operand size.	
B: Byte			
W: Wo	W: Word		

 Table 2.3
 Arithmetic Operations Instructions (1)

L: Longword



Instruction	Size*	Function
DIVXS	B/W	$\begin{array}{l} \text{Rd} \div \text{Rs} \rightarrow \text{Rd} \\ \text{Performs signed division on data in two general registers: either 16 bits} \\ \div 8 \text{ bits} \rightarrow 8 \text{-bit quotient and 8-bit remainder or 32 bits} \div 16 \text{ bits} \rightarrow 16 \text{-bit} \\ \text{quotient and 16-bit remainder.} \end{array}$
СМР	B/W/L	Rd – Rs, Rd – #IMM Compares data in a general register with data in another general register or with immediate data, and sets CCR bits according to the result.
NEG	B/W/L	0 – Rd \rightarrow Rd Takes the two's complement (arithmetic complement) of data in a general register.
EXTU	W/L	Rd (zero extension) \rightarrow Rd Extends the lower 8 bits of a 16-bit register to word size, or the lower 16 bits of a 32-bit register to longword size, by padding with zeros on the left.
EXTS	W/L	Rd (sign extension) \rightarrow Rd Extends the lower 8 bits of a 16-bit register to word size, or the lower 16 bits of a 32-bit register to longword size, by extending the sign bit.
Note: * Re	efers to the	operand size.
B: Byt	e	
W: W	ord	

Arithmetic Operations Instructions (2) Table 2.3

W: Word

L: Longword

Logic Operations Instructions Table 2.4

Instruction	Size*	Function
AND	B/W/L	$Rd \wedge Rs \rightarrow Rd$, $Rd \wedge #IMM \rightarrow Rd$ Performs a logical AND operation on a general register and another general register or immediate data.
OR	B/W/L	$Rd \lor Rs \rightarrow Rd$, $Rd \lor \#IMM \rightarrow Rd$ Performs a logical OR operation on a general register and another general register or immediate data.
XOR	B/W/L	$Rd \oplus Rs \rightarrow Rd$, $Rd \oplus #IMM \rightarrow Rd$ Performs a logical exclusive OR operation on a general register and another general register or immediate data.
NOT	B/W/L	\neg (Rd) \rightarrow (Rd) Takes the one's complement of general register contents.

Note: * Refers to the operand size.

- B: Byte
- W: Word

L: Longword

Table 2.5 Shift Instructions

Instructio	n Size*	Function	
SHAL SHAR	B/W/L	Rd (shift) \rightarrow Rd Performs an arithmetic shift on general register contents.	
SHLL SHLR	B/W/L	Rd (shift) \rightarrow Rd Performs a logical shift on general register contents.	
ROTL ROTR	B/W/L	Rd (rotate) \rightarrow Rd Rotates general register contents.	
ROTXL ROTXR	B/W/L	Rd (rotate) \rightarrow Rd Rotates general register contents through the carry flag.	
Note: *	Note: * Refers to the operand size.		

inote: Refers to the operand size.

B: Byte

W: Word

L: Longword



Instruction	Size*	Function
BSET	В	$1 \rightarrow$ (<bit-no.> of <ead>) Sets a specified bit in a general register or memory operand to 1. The bit number is specified by 3-bit immediate data or the lower three bits of a general register.</ead></bit-no.>
BCLR	В	$0 \rightarrow$ (<bit-no.> of <ead>) Clears a specified bit in a general register or memory operand to 0. The bit number is specified by 3-bit immediate data or the lower three bits of a general register.</ead></bit-no.>
BNOT	В	¬ (<bit-no.> of <ead>) → (<bit-no.> of <ead>) Inverts a specified bit in a general register or memory operand. The bit number is specified by 3-bit immediate data or the lower three bits of a general register.</ead></bit-no.></ead></bit-no.>
BTST	В	¬ (<bit-no.> of <ead>) → Z Tests a specified bit in a general register or memory operand and sets or clears the Z flag accordingly. The bit number is specified by 3-bit immediate data or the lower three bits of a general register.</ead></bit-no.>
BAND	В	$C \land (of) \rightarrow C$ ANDs the carry flag with a specified bit in a general register or memory operand and stores the result in the carry flag.
BIAND	В	$C \land \neg$ (<bit-no.> of <ead>) $\rightarrow C$ ANDs the carry flag with the inverse of a specified bit in a general register or memory operand and stores the result in the carry flag. The bit number is specified by 3-bit immediate data.</ead></bit-no.>
BOR	В	$C \lor (of) \rightarrow C$ ORs the carry flag with a specified bit in a general register or memory operand and stores the result in the carry flag.
BIOR	В	$C \lor \neg$ (<bit-no.> of <ead>) $\rightarrow C$ ORs the carry flag with the inverse of a specified bit in a general register or memory operand and stores the result in the carry flag. The bit number is specified by 3-bit immediate data.</ead></bit-no.>
Note: * Re	efers to the	e operand size.

Table 2.6 Bit Manipulation Instructions (1)

B: Byte

Instruction	n Size*	Function
BXOR	В	$C \oplus (\langle bit-No. \rangle of \langle EAd \rangle) \rightarrow C$ XORs the carry flag with a specified bit in a general register or memory operand and stores the result in the carry flag.
BIXOR	В	$C \oplus \neg$ (<bit-no.> of <ead>) $\rightarrow C$ XORs the carry flag with the inverse of a specified bit in a general register or memory operand and stores the result in the carry flag. The bit number is specified by 3-bit immediate data.</ead></bit-no.>
BLD	В	(kit-No.> of <ead>) \rightarrow C Transfers a specified bit in a general register or memory operand to the carry flag.</ead>
BILD	В	¬ (<bit-no.> of <ead>) → C Transfers the inverse of a specified bit in a general register or memory operand to the carry flag. The bit number is specified by 3-bit immediate data.</ead></bit-no.>
BST	В	$C \rightarrow$ (<bit-no.> of <ead>) Transfers the carry flag value to a specified bit in a general register or memory operand.</ead></bit-no.>
BIST	В	\neg C \rightarrow (<bit-no.> of <ead>) Transfers the inverse of the carry flag value to a specified bit in a general register or memory operand. The bit number is specified by 3-bit immediate data.</ead></bit-no.>
Note: *	Refers to the	operand size.

 Table 2.6
 Bit Manipulation Instructions (2)

Note: * Refers to the operand size.

B: Byte



Instruction	Size	Function							
Bcc*	—	Branches to a specified address if a specified condition is true. The branching conditions are listed below.							
		Mnemonic	Description	Condition					
		BRA(BT) Always (true)		Always					
		BRN(BF)	Never (false)	Never					
		BHI	High	$C \lor Z = 0$					
		BLS	Low or same	C ∨ Z = 1					
		BCC(BHS)	Carry clear (high or same)	C = 0					
		BCS(BLO)	Carry set (low)	C = 1					
		BNE	Not equal	Z = 0					
		BEQ	Equal	Z = 1					
		BVC	Overflow clear	V = 0					
		BVS	Overflow set	V = 1					
		BPL	Plus	N = 0					
		BMI	Minus	N = 1					
		BGE	Greater or equal	$N \oplus V = 0$					
		BLT	Less than	$N \oplus V = 1$					
		BGT	Greater than	$Z \lor (N \oplus V) = 0$					
		BLE	Less or equal	$Z \lor (N \oplus V) = 1$					
JMP		Branches unco	nditionally to a specified	address.					
BSR	—	Branches to a s	subroutine at a specified	d address.					
JSR		Branches to a s	subroutine at a specified	d address.					
RTS	_	Returns from a	subroutine						

RENESAS

Table 2.7Branch Instructions

Note: * Bcc is the general name for conditional branch instructions.

Instruction	Size*	Function
TRAPA		Starts trap-instruction exception handling.
RTE	_	Returns from an exception-handling routine.
SLEEP		Causes a transition to a power-down state.
LDC	B/W	$(EAs) \rightarrow CCR$ Moves the source operand contents to the CCR. The CCR size is one byte, but in transfer from memory, data is read by word access.
STC	B/W	$CCR \rightarrow (EAd), EXR \rightarrow (EAd)$ Transfers the CCR contents to a destination location. The condition code register size is one byte, but in transfer to memory, data is written by word access.
ANDC	В	$\label{eq:CCR} CCR \wedge \#IMM \rightarrow CCR, EXR \wedge \#IMM \rightarrow EXR \\ \mbox{Logically ANDs the CCR with immediate data.}$
ORC	В	$\label{eq:CCR} CCR \lor \#IMM \to CCR, EXR \lor \#IMM \to EXR \\ \mbox{Logically ORs the CCR with immediate data.}$
XORC	В	$\label{eq:CCR} \begin{array}{l} \oplus \mbox{ \#IMM} \rightarrow \mbox{ CCR, EXR} \oplus \mbox{ \#IMM} \rightarrow \mbox{ EXR} \\ \mbox{ Logically XORs the CCR with immediate data.} \end{array}$
NOP	—	$PC + 2 \rightarrow PC$ Only increments the program counter.
		operand size.
B: Byt	е	

Table 2.8 **System Control Instructions**

B: Byte

W: Word



Instruction	Size	Function
EEPMOV.B	_	if R4L \neq 0 then Repeat @ER5+ \rightarrow @ER6+, R4L-1 \rightarrow R4L Until R4L = 0 else next;
EEPMOV.W	_	if R4 \neq 0 then Repeat @ER5+ \rightarrow @ER6+, R4-1 \rightarrow R4 Until R4 = 0 else next;
		Transfers a data block. Starting from the address set in ER5, transfers data for the number of bytes set in R4L or R4 to the address location set in ER6.
		Execution of the next instruction begins as soon as the transfer is completed.

Table 2.9 Block Data Transfer Instructions

2.4.2 Basic Instruction Formats

H8/300H CPU instructions consist of 2-byte (1-word) units. An instruction consists of an operation field (op field), a register field (r field), an effective address extension (EA field), and a condition field (cc).

Figure 2.7 shows examples of instruction formats.

• Operation Field

Indicates the function of the instruction, the addressing mode, and the operation to be carried out on the operand. The operation field always includes the first four bits of the instruction. Some instructions have two operation fields.

• Register Field

Specifies a general register. Address registers are specified by 3 bits, and data registers by 3 bits or 4 bits. Some instructions have two register fields. Some have no register field.

Effective Address Extension

8, 16, or 32 bits specifying immediate data, an absolute address, or a displacement. A24-bit address or displacement is treated as a 32-bit data in which the first 8 bits are 0 (H'00).

• Condition Field

Specifies the branching condition of Bcc instructions.

(1) Op	peration field only			
[0	р	NOP, RTS, etc.	
(2) Op	peration field and register fiel	ds		
[ор	rn	rm	ADD.B Rn, Rm, etc.
(3) Op	eration field, register fields,	and effective a	ddress extens	ion
	ор	rn	rm	MOV.B @(d:16, Rn), Rm
	EA(d	disp)		
(4) Op	eration field, effective addre	ss extension, a	and condition f	eld
[ор сс	EA(e	disp)	BRA d:8

Figure 2.7 Instruction Formats



2.5 Addressing Modes and Effective Address Calculation

The following describes the H8/300H CPU. In this LSI, the upper eight bits are ignored in the generated 24-bit address, so the effective address is 16 bits.

2.5.1 Addressing Modes

The H8/300H CPU supports the eight addressing modes listed in table 2.10. Each instruction uses a subset of these addressing modes. Addressing modes that can be used differ depending on the instruction. For details, refer to Appendix A.4, Combinations of Instructions and Addressing Modes.

Arithmetic and logic instructions can use the register direct and immediate modes. Data transfer instructions can use all addressing modes except program-counter relative and memory indirect. Bit manipulation instructions use register direct, register indirect, or the absolute addressing mode to specify an operand, and register direct (BSET, BCLR, BNOT, and BTST instructions) or immediate (3-bit) addressing mode to specify a bit number in the operand.

No.	Addressing Mode	Symbol
1	Register direct	Rn
2	Register indirect	@ERn
3	Register indirect with displacement	@(d:16,ERn)/@(d:24,ERn)
4	Register indirect with post-increment Register indirect with pre-decrement	@ERn+ @-ERn
5	Absolute address	@aa:8/@aa:16/@aa:24
6	Immediate	#xx:8/#xx:16/#xx:32
7	Program-counter relative	@(d:8,PC)/@(d:16,PC)
8	Memory indirect	@@aa:8

Table 2.10 Addressing Modes

(1) Register Direct—Rn

The register field of the instruction specifies an 8-, 16-, or 32-bit general register containing the operand. R0H to R7H and R0L to R7L can be specified as 8-bit registers. R0 to R7 and E0 to E7 can be specified as 16-bit registers. ER0 to ER7 can be specified as 32-bit registers.

(2) Register Indirect—@ERn

The register field of the instruction code specifies an address register (ERn), the lower 24 bits of which contain the address of the operand on memory.

(3) Register Indirect with Displacement—@(d:16, ERn) or @(d:24, ERn)

A 16-bit or 24-bit displacement contained in the instruction is added to an address register (ERn) specified by the register field of the instruction, and the lower 24 bits of the sum the address of a memory operand. A 16-bit displacement is sign-extended when added.

(4) Register Indirect with Post-Increment or Pre-Decrement—@ERn+ or @-ERn

• Register indirect with post-increment—@ERn+

The register field of the instruction code specifies an address register (ERn) the lower 24 bits of which contains the address of a memory operand. After the operand is accessed, 1, 2, or 4 is added to the address register contents (32 bits) and the sum is stored in the address register. The value added is 1 for byte access, 2 for word access, or 4 for longword access. For the word or longword access, the register value should be even.

• Register indirect with pre-decrement—@-ERn

The value 1, 2, or 4 is subtracted from an address register (ERn) specified by the register field in the instruction code, and the lower 24 bits of the result is the address of a memory operand. The result is also stored in the address register. The value subtracted is 1 for byte access, 2 for word access, or 4 for longword access. For the word or longword access, the register value should be even.

(5) Absolute Address—@aa:8, @aa:16, @aa:24

The instruction code contains the absolute address of a memory operand. The absolute address may be 8 bits long (@aa:8), 16 bits long (@aa:16), 24 bits long (@aa:24)

For an 8-bit absolute address, the upper 16 bits are all assumed to be 1 (H'FFFF). For a 16-bit absolute address the upper 8 bits are a sign extension. A 24-bit absolute address can access the entire address space.



The access ranges of absolute addresses for the group of this LSI are those shown in table 2.11, because the upper 8 bits are ignored.

Absolute Address	Access Range
8 bits (@aa:8)	H'FF00 to H'FFFF
16 bits (@aa:16)	H'0000 to H'FFFF
24 bits (@aa:24)	H'0000 to H'FFFF

Table 2.11 Absolute Address Access Ranges

(6) Immediate—#xx:8, #xx:16, or #xx:32

The instruction contains 8-bit (#xx:8), 16-bit (#xx:16), or 32-bit (#xx:32) immediate data as an operand.

The ADDS, SUBS, INC, and DEC instructions contain immediate data implicitly. Some bit manipulation instructions contain 3-bit immediate data in the instruction code, specifying a bit number. The TRAPA instruction contains 2-bit immediate data in its instruction code, specifying a vector address.

(7) Program-Counter Relative—@(d:8, PC) or @(d:16, PC)

This mode is used in the BSR instruction. An 8-bit or 16-bit displacement contained in the instruction is sign-extended and added to the 24-bit PC contents to generate a branch address. The PC value to which the displacement is added is the address of the first byte of the next instruction, so the possible branching range is -126 to +128 bytes (-63 to +64 words) or -32766 to +32768 bytes (-16383 to +16384 words) from the branch instruction. The resulting value should be an even number.

(8) Memory Indirect—@@aa:8

This mode can be used by the JMP and JSR instructions. The instruction code contains an 8-bit absolute address specifying a memory operand. This memory operand contains a branch address. The memory operand is accessed by longword access. The first byte of the memory operand is ignored, generating a 24-bit branch address. Figure 2.8 shows how to specify branch address for in memory indirect mode. The upper bits of the absolute address are all assumed to be 0, so the address range is 0 to 255 (H'0000 to H'00FF).

Note that the first part of the address range is also the exception vector area.



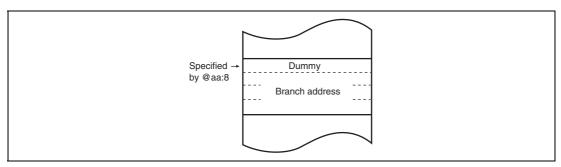
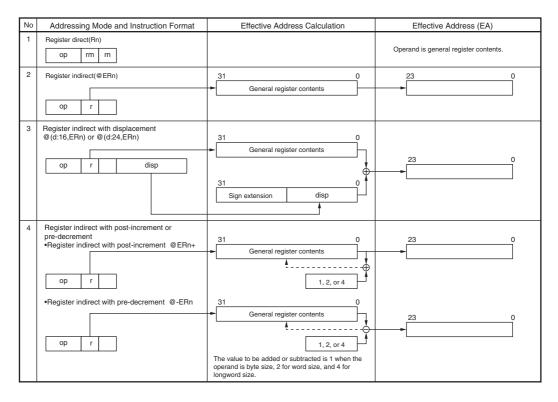


Figure 2.8 Branch Address Specification in Memory Indirect Mode

2.5.2 Effective Address Calculation

Table 2.12 indicates how effective addresses are calculated in each addressing mode. In this LSI the upper 8 bits of the effective address are ignored in order to generate a 16-bit effective address.







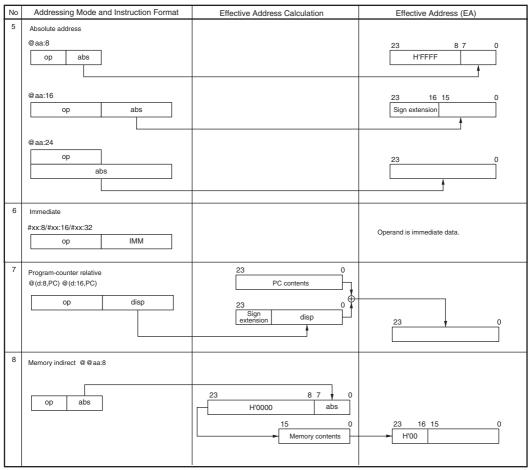


Table 2.12 Effective Address Calculation (2)

Legend

r, rm,rn: Register field

op : Operation field

disp : Displacement

IMM : Immediate data

abs : Absolute address



2.6 Basic Bus Cycle

CPU operation is synchronized by a system clock (ϕ) or a subclock (ϕ_{sub}). The period from a rising edge of ϕ or ϕ_{sub} to the next rising edge is called one state. A bus cycle consists of two states or three states. The cycle differs depending on whether access is to on-chip memory or to on-chip peripheral modules.

2.6.1 Access to On-Chip Memory (RAM, ROM)

Access to on-chip memory takes place in two states. The data bus width is 16 bits, allowing access in byte or word size. Figure 2.9 shows the on-chip memory access cycle.

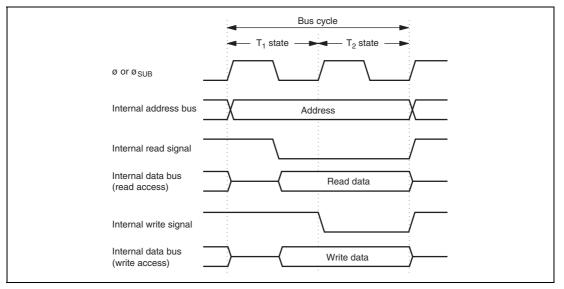


Figure 2.9 On-Chip Memory Access Cycle



2.6.2 On-Chip Peripheral Modules

On-chip peripheral modules are accessed in two states or three states. The data bus width is 8 bits or 16 bits depending on the register. For description on the data bus width and number of accessing states of each register, refer to section 17.1, Register Addresses (Address Order). Registers with 16-bit data bus width can be accessed by word size only. Registers with 8-bit data bus width can be accessed by word size. When a register with 8-bit data bus width is accessed by word size, a bus cycle occurs twice. In two-state access, the operation timing is the same as that for on-chip memory.

Figure 2.10 shows the operation timing in the case of three-state access to an on-chip peripheral module.

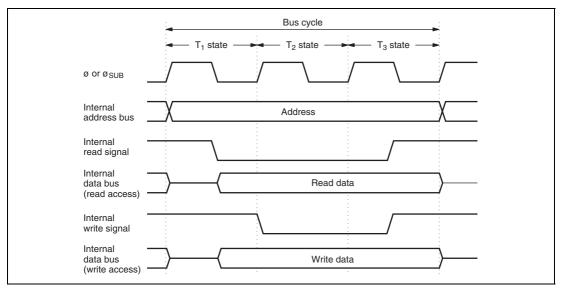


Figure 2.10 On-Chip Peripheral Module Access Cycle (3-State Access)

2.7 CPU States

There are four CPU states: the reset state, program execution state, program halt state, and exception-handling state. The program execution state includes active mode. In the program halt state there are a sleep mode, and standby mode. These states are shown in figure 2.11. Figure 2.12 shows the state transitions. For details on program execution state and program halt state, refer to section 6, Power-Down Modes. For details on exception processing, refer to section 3, Exception Handling.

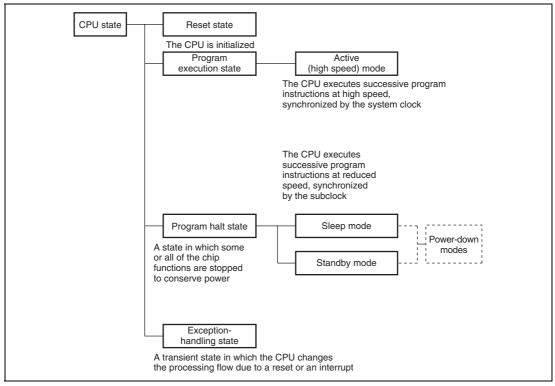


Figure 2.11 CPU Operation States



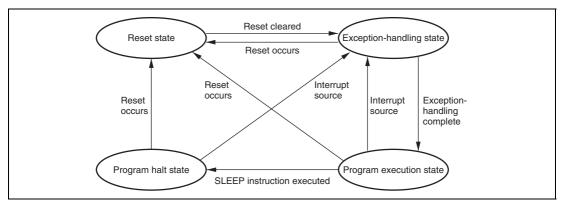


Figure 2.12 State Transitions

2.8 Usage Notes

2.8.1 Notes on Data Access to Empty Areas

The address space of this LSI includes empty areas in addition to the ROM, RAM, and on-chip I/O registers areas available to the user. When data is transferred from CPU to empty areas, the transferred data will be lost. This action may also cause the CPU to malfunction. When data is transferred from an empty area to CPU, the contents of the data cannot be guaranteed.

2.8.2 EEPMOV Instruction

EEPMOV is a block-transfer instruction and transfers the byte size of data indicated by R4L, which starts from the address indicated by R5, to the address indicated by R6. Set R4L and R6 so that the end address of the destination address (value of R6 + R4L) does not exceed H'FFFF (the value of R6 must not change from H'FFFF to H'0000 during execution).

2.8.3 Bit Manipulation Instruction

The BSET, BCLR, BNOT, BST, and BIST instructions read data from the specified address in byte units, manipulate the data of the target bit, and write data to the same address again in byte units. Special care is required when using these instructions in cases where two registers are assigned to the same address or when a bit is directly manipulated for a port, because this may rewrite data of a bit other than the bit to be manipulated.



(1) Bit manipulation for two registers assigned to the same address

Example: Bit manipulation for the timer load register and timer counter

(Applicable for timer B and timer C, not for the group of this LSI.)

Figure 2.13 shows an example of a timer in which two timer registers are assigned to the same address. When a bit manipulation instruction accesses the timer load register and timer counter of a reloadable timer, since these two registers share the same address, the following operations takes place.

- 1. Data is read in byte units.
- 2. The CPU sets or resets the bit to be manipulated with the bit manipulation instruction.
- 3. The written data is written again in byte units to the timer load register.

The timer is counting, so the value read is not necessarily the same as the value in the timer load register. As a result, bits other than the intended bit in the timer counter may be modified and the modified value may be written to the timer load register.

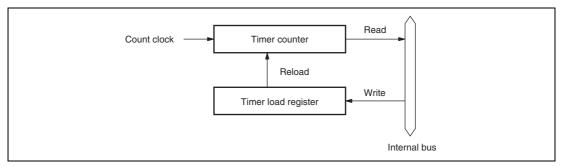


Figure 2.13 Example of Timer Configuration with Two Registers Allocated to Same Address



Example 2: The BSET instruction is executed for port 5.

P57 and P56 are input pins, with a low-level signal input at P57 and a high-level signal input at P56. P55 to P50 are output pins and output low-level signals. An example to output a high-level signal at P50 with a BSET instruction is shown below.

	P57	P56	P55	P54	P53	P52	P51	P50
Input/output	Input	Input	Output	Output	Output	Output	Output	Output
Pin state	Low level	High level	Low level	Low level	Low level	Low level	Low level	Low level
PCR5	0	0	1	1	1	1	1	1
PDR5	1	0	0	0	0	0	0	0

• Prior to executing BSET

• BSET instruction executed

BSET	#O,	@PDR5
------	-----	-------

The BSET instruction is executed for port 5.

• After executing BSET

	P57	P56	P55	P54	P53	P52	P51	P50
Input/output	Input	Input	Output	Output	Output	Output	Output	Output
Pin state	Low level	High level	Low level	Low level	Low level	Low level	Low level	High level
PCR5	0	0	1	1	1	1	1	1
PDR5	0	1	0	0	0	0	0	1

- Description on operation
- 1. When the BSET instruction is executed, first the CPU reads port 5.

Since P57 and P56 are input pins, the CPU reads the pin states (low-level and high-level input).

P55 to P50 are output pins, so the CPU reads the value in PDR5. In this example PDR5 has a value of H'80, but the value read by the CPU is H'40.

- 2. Next, the CPU sets bit 0 of the read data to 1, changing the PDR5 data to H'41.
- 3. Finally, the CPU writes H'41 to PDR5, completing execution of BSET.

As a result of the BSET instruction, bit 0 in PDR5 becomes 1, and P50 outputs a high-level signal. However, bits 7 and 6 of PDR5 end up with different values. To prevent this problem, store a copy of the PDR5 data in a work area in memory. Perform the bit manipulation on the data in the work area, then write this data to PDR5.

• Prior to executing BSET

MOV.B	#80,	ROL	
MOV.B	ROL,	@RAM0	
MOV.B	ROL,	@PDR5	

The PDR5 value (H'80) is written to a work area in memory (RAM0) as well as to PDR5.

	P57	P56	P55	P54	P53	P52	P51	P50
Input/output	Input	Input	Output	Output	Output	Output	Output	Output
Pin state	Low level	High level	Low level	Low level	Low level	Low level	Low level	Low level
PCR5	0	0	1	1	1	1	1	1
PDR5	1	0	0	0	0	0	0	0
RAM0	1	0	0	0	0	0	0	0

• BSET instruction executed

BSET #0, @RAMO

The BSET instruction is executed designating the PDR5 work area (RAM0).

• After executing BSET

MOV.B	@RAMO, ROL	
MOV.B	ROL, @PDR5	

The work area (RAM0) value is written to PDR5.

	P57	P56	P55	P54	P53	P52	P51	P50
Input/output	Input	Input	Output	Output	Output	Output	Output	Output
Pin state	Low level	High level	Low level	Low level	Low level	Low level	Low level	High level
PCR5	0	0	1	1	1	1	1	1
PDR5	1	0	0	0	0	0	0	1
RAM0	1	0	0	0	0	0	0	1



(2) Bit Manipulation in a Register Containing a Write-Only Bit

Example 3: BCLR instruction executed designating port 5 control register PCR5

P57 and P56 are input pins, with a low-level signal input at P57 and a high-level signal input at P56. P55 to P50 are output pins that output low-level signals. An example of setting the P50 pin as an input pin by the BCLR instruction is shown below. It is assumed that a high-level signal will be input to this input pin.

• Prior to executing BCLR

	P57	P56	P55	P54	P53	P52	P51	P50
Input/output	Input	Input	Output	Output	Output	Output	Output	Output
Pin state	Low level	High level	Low level	Low level	Low level	Low level	Low level	Low level
PCR5	0	0	1	1	1	1	1	1
PDR5	1	0	0	0	0	0	0	0

BCLR instruction executed

BCLR #0, @PCR5

The BCLR instruction is executed for PCR5.

• After executing BCLR

	P57	P56	P55	P54	P53	P52	P51	P50
Input/output	Output	Output	Output	Output	Output	Output	Output	Input
Pin state	Low level	High level	Low level	Low level	Low level	Low level	Low level	High level
PCR5	1	1	1	1	1	1	1	0
PDR5	1	0	0	0	0	0	0	0

- Description on operation
- 1. When the BCLR instruction is executed, first the CPU reads PCR5. Since PCR5 is a write-only register, the CPU reads a value of H'FF, even though the PCR5 value is actually H'3F.
- 2. Next, the CPU clears bit 0 in the read data to 0, changing the data to H'FE.

3. Finally, H'FE is written to PCR5 and BCLR instruction execution ends. As a result of this operation, bit 0 in PCR5 becomes 0, making P50 an input port. However, bits 7 and 6 in PCR5 change to 1, so that P57 and P56 change from input pins to output pins. To prevent this problem, store a copy of the PCR5 data in a work area in memory and manipulate data of the bit in the work area, then write this data to PCR5.



• Prior to executing BCLR

MOV.B	#3F,	ROL
MOV.B	ROL,	@RAM0
MOV.B	ROL,	@PCR5

The PCR5 value (H'3F) is written to a work area in memory (RAM0) as well as to PCR5.

	P57	P56	P55	P54	P53	P52	P51	P50
Input/output	Input	Input	Output	Output	Output	Output	Output	Output
Pin state	Low level	High level	Low level	Low level	Low level	Low level	Low level	Low level
PCR5	0	0	1	1	1	1	1	1
PDR5	1	0	0	0	0	0	0	0
RAM0	0	0	1	1	1	1	1	1

• BCLR instruction executed

BCLR #0, @RAMO

The BCLR instructions executed for the PCR5 work area (RAM0).

• After executing BCLR

MOV.B	@RAM0, ROL	
MOV.B	ROL, @PCR5	

The work area (RAM0) value is written to PCR5.

	P57	P56	P55	P54	P53	P52	P51	P50
Input/output	Input	Input	Output	Output	Output	Output	Output	Output
Pin state	Low level	High level	Low level	Low level	Low level	Low level	Low level	High level
PCR5	0	0	1	1	1	1	1	0
PDR5	1	0	0	0	0	0	0	0
RAM0	0	0	1	1	1	1	1	0



Section 3 Exception Handling

Exception handling may be caused by a reset, a trap instruction (TRAPA), or interrupts.

• Reset

A reset has the highest exception priority. Exception handling starts as soon as the reset is cleared by the $\overline{\text{RES}}$ pin. The chip is also reset when the watchdog timer overflows, and exception handling starts. Exception handling is the same as exception handling by the $\overline{\text{RES}}$ pin.

Trap Instruction

Exception handling starts when a trap instruction (TRAPA) is executed. The TRAPA instruction generates a vector address corresponding to a vector number from 0 to 3, as specified in the instruction code. Exception handling can be executed at all times in the program execution state.

• Interrupts

External interrupts other than NMI and internal interrupts other than address break are masked by the I bit in CCR, and kept masked while the I bit is set to 1. Exception handling starts when the current instruction or exception handling ends, if an interrupt request has been issued.

3.1 Exception Sources and Vector Address

Table 3.1 shows the vector addresses and priority of each exception handling. When more than one interrupt is requested, handling is performed from the interrupt with the highest priority.

Relative Module	Exception Sources	Vector Number	Vector Address	Priority
RES pin Watchdog timer	Reset	0	H'0000 to H'0001	High ▲
_	Reserved for system use	1 to 6	H'0002 to H'000D	-
External interrupt pin	NMI	7	H'000E to H'000F	-
CPU	Trap instruction (#0)	8	H'0010 to H'0011	-
	(#1)	9	H'0012 to H'0013	-
	(#2)	10	H'0014 to H'0015	-
	(#3)	11	H'0016 to H'0017	- ↓
Address break	Break conditions satisfied	12	H'0018 to H'0019	Low

Table 3.1	Exception Sources and Vector Address
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Relative Module	Exception Sources	Vector Number	Vector Address	Priority
CPU	Direct transition by executing the SLEEP instruction	13	H'001A to H'001B	High ▲
External interrupt pin	IRQ0 Low-voltage detection interrupt*1	14	H'001C to H'001D	-
	IRQ3	17	H'0022 to H'0023	-
	WKP	18	H'0024 to H'0025	-
	Reserved for system use	20	H'0028 to H'0029	-
Timer W	Timer W input capture A /compare match A Timer W input capture B /compare match B Timer W input capture C /compare match C Timer W input capture D /compare match D Timer W overflow	21	H'002A to H'002B	-
Timer V	Timer V compare match A Timer V compare match B Timer V overflow	22	H'002C to H'002D	-
SCI3	SCI3 receive data full SCI3 transmit data empty SCI3 transmit end SCI3 receive error	23	H'002E to H'002F	-
A/D converter	A/D conversion end	25	H'0032 to H'0033	-
SCI3_2	SCI3_2 receive data full SCI3_2 transmit data empty SCI3_2 transmit end SCI3_2 receive error	32	H'0040 to H'0041	-
SCI3_3* ²	SCI3_3 receive data full SCI3_3 transmit data empty SCI3_3 transmit end SCI3_3 receive error	34	H'0044 to H'0045	Low

Notes: 1. A low-voltage detection interrupt is enabled only in the product with an on-chip poweron reset and low-voltage detection circuit.

RENESAS

2. The SCI3_3 function is incorporated in the H8/36024.

3.2 Register Descriptions

Interrupts are controlled by the following registers.

- Interrupt edge select register 1 (IEGR1)
- Interrupt edge select register 2 (IEGR2)
- Interrupt enable register 1 (IENR1)
- Interrupt flag register 1 (IRR1)
- Wakeup interrupt flag register (IWPR)

3.2.1 Interrupt Edge Select Register 1 (IEGR1)

IEGR1 selects the direction of an edge that generates interrupt requests of pins and $\overline{IRQ3}$ and $\overline{IRQ0}.$

Bit	Bit Name	Initial Value	R/W	Description
7	_	0	-	Reserved
				This bit is always read as 0.
6 to 4	_	All 1		Reserved
				These bits are always read as 1.
3	IEG3	0	R/W	IRQ3 Edge Select
				0: Falling edge of IRQ3 pin input is detected
				1: Rising edge of IRQ3 pin input is detected
2, 1	_	All 0		Reserved
				These bits are always read as 0.
0	IEG0	0	R/W	IRQ0 Edge Select
				0: Falling edge of IRQ0 pin input is detected
				1: Rising edge of IRQ0 pin input is detected



3.2.2 Interrupt Edge Select Register 2 (IEGR2)

IEGR2 selects the direction of an edge that generates interrupt requests of the pins $\overline{\text{ADTRG}}$ and $\overline{\text{WKP5}}$ to $\overline{\text{WKP0}}$.

Bit	Bit Name	Initial Value	R/W	Description
7, 6		All 1		Reserved
				These bits are always read as 1.
5	WPEG5	0	R/W	WKP5 Edge Select
				0: Falling edge of $\overline{WKP5}$ (\overline{ADTRG}) pin input is detected
				1: Rising edge of $\overline{WKP5}$ (\overline{ADTRG}) pin input is detected
4	WPEG4	0	R/W	WKP4 Edge Select
				0: Falling edge of $\overline{WKP4}$ pin input is detected
				1: Rising edge of $\overline{WKP4}$ pin input is detected
3	WPEG3	0	R/W	WKP3 Edge Select
				0: Falling edge of $\overline{WKP3}$ pin input is detected
				1: Rising edge of WKP3 pin input is detected
2	WPEG2	0	R/W	WKP2 Edge Select
				0: Falling edge of $\overline{WKP2}$ pin input is detected
				1: Rising edge of WKP2 pin input is detected
1	WPEG1	0	R/W	WKP1Edge Select
				0: Falling edge of $\overline{WKP1}$ pin input is detected
				1: Rising edge of $\overline{WKP1}$ pin input is detected
0	WPEG0	0	R/W	WKP0 Edge Select
				0: Falling edge of $\overline{WKP0}$ pin input is detected
				1: Rising edge of WKP0 pin input is detected

3.2.3 Interrupt Enable Register 1 (IENR1)

D ''		Initial	D // //	
Bit	Bit Name	Value	R/W	Description
7	IENDT	0	R/W	Direct Transfer Interrupt Enable
				When this bit is set to 1, direct transition interrupt requests are enabled.
6	_	0		Reserved
				This bit is always read as 0.
5	IENWP	0	R/W	Wakeup Interrupt Enable
				This bit is an enable bit, which is common to the pins $\overline{WKP5}$ to $\overline{WKP0}$. When the bit is set to 1, interrupt requests are enabled.
4	_	1	_	Reserved
				This bit is always read as 1.
3	IEN3	0	R/W	IRQ3 Interrupt Enable
				When this bit is set to 1, interrupt requests of the $\overline{\text{IRQ3}}$ pin are enabled.
2, 1		All 0		Reserved
				These bits are always read as 0.
0	IEN0	0	R/W	IRQ0 Interrupt Enable
				When this bit is set to 1, interrupt requests of the $\overline{\text{IRQ0}}$ pin are enabled.

IENR1 enables direct transition interrupts, and external pin interrupts.

When disabling interrupts by clearing bits in an interrupt enable register, or when clearing bits in an interrupt flag register, always do so while interrupts are masked (I = 1). If the above clear operations are performed while I = 0, and as a result a conflict arises between the clear instruction and an interrupt request, exception handling for the interrupt will be executed after the clear instruction has been executed.



3.2.4 Interrupt Flag Register 1 (IRR1)

IRR1 is a status flag register for direct transition interrupts, and $\overline{IRQ3}$ and $\overline{IRQ0}$ interrupt requests.

Bit	Bit Name	Initial Value	R/W	Description
7	IRRDT	0	R/W	Direct Transfer Interrupt Request Flag
				[Setting condition]
				When a direct transfer is made by executing a SLEEP instruction while DTON in SYSCR2 is set to 1.
				[Clearing condition]
				When IRRDT is cleared by writing 0
6	_	0		Reserved
				This bit is always read as 0.
5, 4	_	All 1		Reserved
				These bits are always read as 1.
3	IRRI3	0	R/W	IRQ3 Interrupt Request Flag
				[Setting condition]
				When IRQ3 pin is designated for interrupt input and the designated signal edge is detected.
				[Clearing condition]
				When IRRI3 is cleared by writing 0
2, 1		All 0		Reserved
				These bits are always read as 0.
0	IRRI0	0	R/W	IRQ0 Interrupt Request Flag
				[Setting condition]
				When $\overline{IRQ0}$ pin is designated for interrupt input and the designated signal edge is detected.
				[Clearing condition]
				When IRRI0 is cleared by writing 0

3.2.5 Wakeup Interrupt Flag Register (IWPR)

IWPR is a status flag register for $\overline{WKP5}$ to $\overline{WKP0}$ interrupt requests.

Bit	Bit Name	Initial Value	R/W	Description
7,6		All 1		Reserved
7,0		7.01 1		These bits are always read as 1.
5	IWPF5	0	R/W	WKP5 Interrupt Request Flag
0		U		[Setting condition]
				When $\overline{WKP5}$ pin is designated for interrupt input and the designated signal edge is detected.
				[Clearing condition]
				When IWPF5 is cleared by writing 0.
4	IWPF4	0	R/W	WKP4 Interrupt Request Flag
				[Setting condition]
				When $\overline{WKP4}$ pin is designated for interrupt input and the designated signal edge is detected.
				[Clearing condition]
				When IWPF4 is cleared by writing 0.
3	IWPF3	0	R/W	WKP3 Interrupt Request Flag
				[Setting condition]
				When $\overline{WKP3}$ pin is designated for interrupt input and the designated signal edge is detected.
				[Clearing condition]
				When IWPF3 is cleared by writing 0.
2	IWPF2	0	R/W	WKP2 Interrupt Request Flag
				[Setting condition]
				When $\overline{WKP2}$ pin is designated for interrupt input and the designated signal edge is detected.
				[Clearing condition]
				When IWPF2 is cleared by writing 0.
1	IWPF1	0	R/W	WKP1 Interrupt Request Flag
				[Setting condition]
				When $\overline{WKP1}$ pin is designated for interrupt input and the designated signal edge is detected.
				[Clearing condition]
				When IWPF1 is cleared by writing 0.



Bit	Bit Name	Initial Value	R/W	Description
0	IWPF0	0	R/W	WKP0 Interrupt Request Flag
				[Setting condition]
				When $\overline{WKP0}$ pin is designated for interrupt input and the designated signal edge is detected.
				[Clearing condition]
				When IWPF0 is cleared by writing 0.

3.3 Reset Exception Handling

When the $\overline{\text{RES}}$ pin goes low, all processing halts and this LSI enters the reset. The internal state of the CPU and the registers of the on-chip peripheral modules are initialized by the reset. To ensure that this LSI is reset at power-up, hold the $\overline{\text{RES}}$ pin low until the clock pulse generator output stabilizes. To reset the chip during operation, hold the $\overline{\text{RES}}$ pin low for at least 10 system clock cycles. When the $\overline{\text{RES}}$ pin goes high after being held low for the necessary time, this LSI starts reset exception handling. The reset exception handling sequence is shown in figure 3.1.

The reset exception handling sequence is as follows. However, for the reset exception handling sequence of the product with on-chip power-on reset circuit, refer to section 15, Power-On Reset and Low-Voltage Detection Circuits (Optional).

- 1. Set the I bit in the condition code register (CCR) to 1.
- 2. The CPU generates a reset exception handling vector address (from H'0000 to H'0001), the data in that address is sent to the program counter (PC) as the start address, and program execution starts from that address.



3.4 Interrupt Exception Handling

3.4.1 External Interrupts

There are external interrupts, NMI, IRQ3, IRQ0, and WKP.

(1) NMI

NMI interrupt is requested by input falling edge to pin $\overline{\text{NMI}}$.

NMI is the highest interrupt, and can always be accepted without depending on the I bit value in CCR.

(2) IRQ3 to IRQ0 Interrupts

IRQ3 to IRQ0 interrupts are requested by input signals to pins $\overline{\text{IRQ3}}$ to $\overline{\text{IRQ0}}$. These four interrupts are given different vector addresses, and are detected individually by either rising edge sensing or falling edge sensing, depending on the settings of bits IEG3 to IEG0 in IEGR1.

When pins $\overline{IRQ3}$ to $\overline{IRQ0}$ are designated for interrupt input in PMR1 and the designated signal edge is input, the corresponding bit in IRR1 is set to 1, requesting the CPU of an interrupt. When IRQ3 to IRQ0 interrupt is accepted, the I bit is set to 1 in CCR. These interrupts can be masked by setting bits IEN3 to IEN0 in IENR1.

(3) WKP5 to WKP0 Interrupts

WKP5 to WKP0 interrupts are requested by input signals to pins $\overline{WKP5}$ to $\overline{WKP0}$. These six interrupts have the same vector addresses, and are detected individually by either rising edge sensing or falling edge sensing, depending on the settings of bits WPEG5 to WPEG0 in IEGR2.

When pins $\overline{WKP5}$ to $\overline{WKP0}$ are designated for interrupt input in PMR5 and the designated signal edge is input, the corresponding bit in IWPR is set to 1, requesting the CPU of an interrupt. These interrupts can be masked by setting bit IENWP in IENR1.



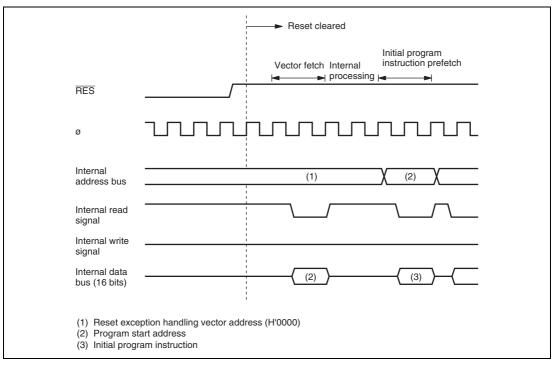


Figure 3.1 Reset Sequence

3.4.2 Internal Interrupts

Each on-chip peripheral module has a flag to show the interrupt request status and the enable bit to enable or disable the interrupt. For direct transfer interrupt requests generated by execution of a SLEEP instruction, this function is included in IRR1 and IENR1.

When an on-chip peripheral module requests an interrupt, the corresponding interrupt request status flag is set to 1, requesting the CPU of an interrupt. When this interrupt is accepted, the I bit is set to 1 in CCR. These interrupts can be masked by writing 0 to clear the corresponding enable bit.



3.4.3 Interrupt Handling Sequence

Interrupts are controlled by an interrupt controller.

Interrupt operation is described as follows.

- 1. If an interrupt occurs while the NMI or interrupt enable bit is set to 1, an interrupt request signal is sent to the interrupt controller.
- 2. When multiple interrupt requests are generated, the interrupt controller requests to the CPU for the interrupt handling with the highest priority at that time according to table 3.1. Other interrupt requests are held pending.
- 3. The CPU accepts the NMI or address break without depending on the I bit value. Other interrupt requests are accepted, if the I bit is cleared to 0 in CCR; if the I bit is set to 1, the interrupt request is held pending.
- 4. If the CPU accepts the interrupt after processing of the current instruction is completed, interrupt exception handling will begin. First, both PC and CCR are pushed onto the stack. The state of the stack at this time is shown in figure 3.2. The PC value pushed onto the stack is the address of the first instruction to be executed upon return from interrupt handling.
- 5. Then, the I bit of CCR is set to 1, masking further interrupts excluding the NMI and address break. Upon return from interrupt handling, the values of I bit and other bits in CCR will be restored and returned to the values prior to the start of interrupt exception handling.
- 6. Next, the CPU generates the vector address corresponding to the accepted interrupt, and transfers the address to PC as a start address of the interrupt handling-routine. Then a program starts executing from the address indicated in PC.

Figure 3.3 shows a typical interrupt sequence where the program area is in the on-chip ROM and the stack area is in the on-chip RAM.



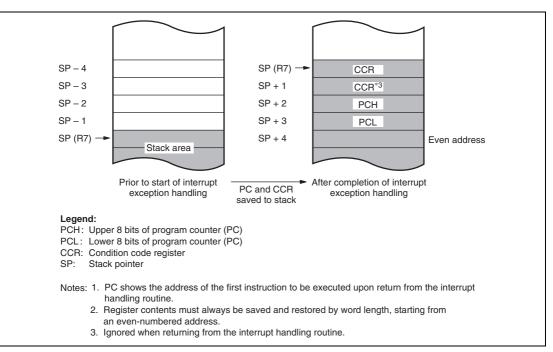


Figure 3.2 Stack Status after Exception Handling

3.4.4 Interrupt Response Time

Table 3.2 shows the number of wait states after an interrupt request flag is set until the first instruction of the interrupt handling-routine is executed.

Table 3.2Interrupt Wait States

Item	States	Total
Waiting time for completion of executing instruction*	1 to 23	15 to 37
Saving of PC and CCR to stack	4	
Vector fetch	2	
Instruction fetch	4	
Internal processing	4	
Netse W Net in shading EEDMOV/ in struction		

Note: * Not including EEPMOV instruction.

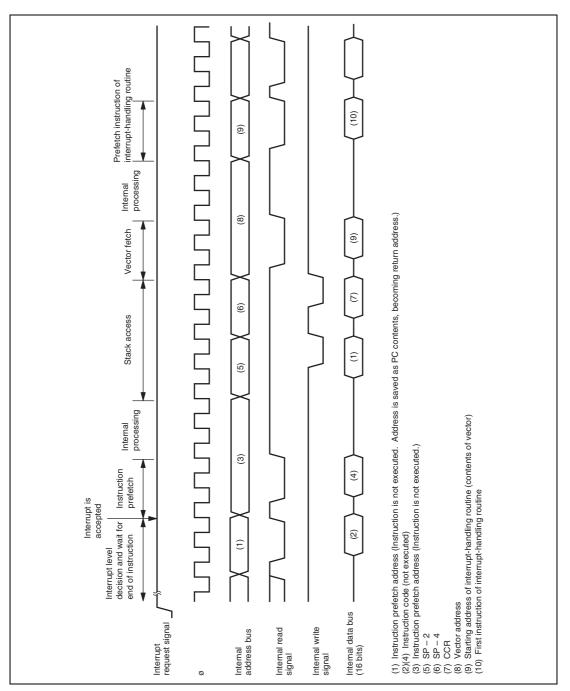


Figure 3.3 Interrupt Sequence

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3.5 Usage Notes

3.5.1 Interrupts after Reset

If an interrupt is accepted after a reset and before the stack pointer (SP) is initialized, the PC and CCR will not be saved correctly, leading to a program crash. To prevent this, all interrupt requests, including NMI, are disabled immediately after a reset. Since the first instruction of a program is always executed immediately after the reset state ends, make sure that this instruction initializes the stack pointer (example: MOV.W #xx: 16, SP).

3.5.2 Notes on Stack Area Use

When word data is accessed, the least significant bit of the address is regarded as 0. Access to the stack always takes place in word size, so the stack pointer (SP: R7) should never indicate an odd address. Use PUSH Rn (MOV.W Rn, @–SP) or POP Rn (MOV.W @SP+, Rn) to save or restore register values.

3.5.3 Notes on Rewriting Port Mode Registers

When a port mode register is rewritten to switch the functions of external interrupt pins, $\overline{\text{IRQ3}}$, $\overline{\text{IRQ0}}$, and $\overline{\text{WKP5}}$ to $\overline{\text{WKP0}}$, the interrupt request flag may be set to 1.

Figure 3.4 shows a port mode register setting and interrupt request flag clearing procedure.

When switching a pin function, mask the interrupt before setting the bit in the port mode register. After accessing the port mode register, execute at least one instruction (e.g., NOP), then clear the interrupt request flag from 1 to 0.

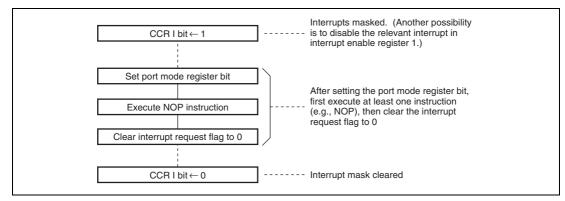


Figure 3.4 Port Mode Register Setting and Interrupt Request Flag Clearing Procedure



Section 4 Address Break

The address break simplifies on-board program debugging. It requests an address break interrupt when the set break condition is satisfied. The interrupt request is not affected by the I bit of CCR. Break conditions that can be set include instruction execution at a specific address and a combination of access and data at a specific address. With the address break function, the execution start point of a program containing a bug is detected and execution is branched to the correcting program. Figure 4.1 shows a block diagram of the address break.

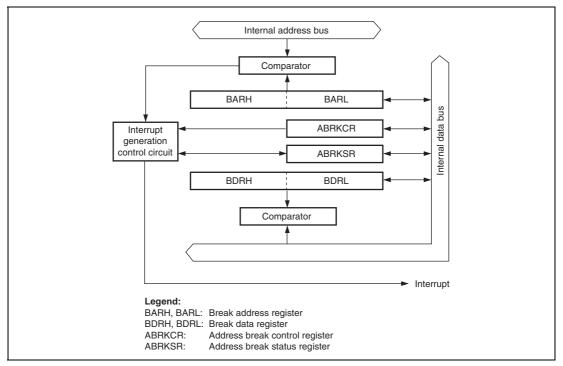


Figure 4.1 Block Diagram of Address Break

4.1 **Register Descriptions**

Address break has the following registers.

- Address break control register (ABRKCR)
- Address break status register (ABRKSR)
- Break address register (BARH, BARL)

Break data register (BDRH, BDRL) •

Address Break Control Register (ABRKCR) 4.1.1

ABRKCR sets address break conditions.

Bit	Bit Name	Initial Value	R/W	Description	
7	RTINTE	1	R/W	RTE Interrupt Enable	
				When this bit is 0, the interrupt immediately after executing RTE is masked and then one instruction must be executed. When this bit is 1, the interrupt is not masked.	
6	CSEL1	0	R/W	Condition Select 1 and 0	
5	CSEL0	0	R/W	These bits set address break conditions.	
				00: Instruction execution cycle	
				01: CPU data read cycle	
				10: CPU data write cycle	
				11: CPU data read/write cycle	
4	ACMP2	0	R/W	Address Compare Condition Select 2 to 0	
3	ACMP1	0	R/W	These bits comparison condition between the address set	
2	ACMP0	0	R/W	in BAR and the internal address bus.	
				000: Compares 16-bit addresses	
				001: Compares upper 12-bit addresses	
				010: Compares upper 8-bit addresses	
				011: Compares upper 4-bit addresses	
				1XX: Reserved (setting prohibited)	
1	DCMP1	0	R/W	Data Compare Condition Select 1 and 0	
0	DCMP0	0	R/W	These bits set the comparison condition between the data set in BDR and the internal data bus.	
				00: No data comparison	
				01: Compares lower 8-bit data between BDRL and data bus	
				10: Compares upper 8-bit data between BDRH and data bus	
				11: Compares 16-bit data between BDR and data bus	
Legend	l: X: Don't car	re.			

When an address break is set in the data read cycle or data write cycle, the data bus used will depend on the combination of the byte/word access and address. Table 4.1 shows the access and data bus used. When an I/O register space with an 8-bit data bus width is accessed in word size, a byte access is generated twice. For details on data widths of each register, see section 17.1, Register Addresses (Address Order).

Table 4.1 Access and Data Bus Used

	Word A	Access	Byte Access		
	Even Address	Odd Address	Even Address	Odd Address	
ROM space	Upper 8 bits	Lower 8 bits	Upper 8 bits	Upper 8 bits	
RAM space	Upper 8 bits	Lower 8 bits	Upper 8 bits	Upper 8 bits	
I/O register with 8-bit data bus width	Upper 8 bits	Upper 8 bits	Upper 8 bits	Upper 8 bits	
I/O register with 16-bit data bus width	Upper 8 bits	Lower 8 bits	_	—	

4.1.2 Address Break Status Register (ABRKSR)

ABRKSR consists of the address break interrupt flag and the address break interrupt enable bit.

Bit	Bit Name	Initial Value	R/W	Description
7	ABIF	0	R/W	Address Break Interrupt Flag
				[Setting condition]
				When the condition set in ABRKCR is satisfied
				[Clearing condition]
				When 0 is written after ABIF=1 is read
6	ABIE	0	R/W	Address Break Interrupt Enable
				When this bit is 1, an address break interrupt request is enabled.
5 to 0	_	All 1	_	Reserved
				These bits are always read as 1.



4.1.3 Break Address Registers (BARH, BARL)

BARH and BARL are 16-bit read/write registers that set the address for generating an address break interrupt. When setting the address break condition to the instruction execution cycle, set the first byte address of the instruction. The initial value of this register is H'FFFF.

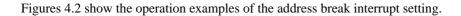
4.1.4 Break Data Registers (BDRH, BDRL)

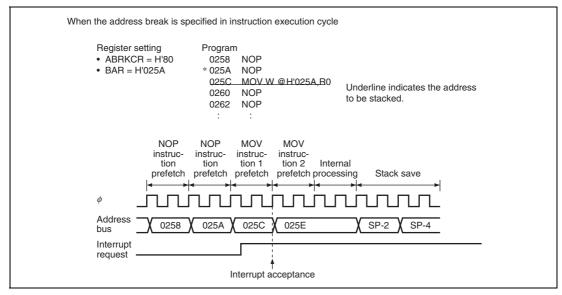
BDRH and BDRL are 16-bit read/write registers that set the data for generating an address break interrupt. BDRH is compared with the upper 8-bit data bus. BDRL is compared with the lower 8-bit data bus. When memory or registers are accessed by byte, the upper 8-bit data bus is used for even and odd addresses in the data transmission. Therefore, comparison data must be set in BDRH for byte access. For word access, the data bus used depends on the address. See section 4.1.1, Address Break Control Register (ABRKCR), for details. The initial value of this register is undefined.

4.2 Operation

When the ABIF and ABIE bits in ABRKSR are set to 1, the address break function generates an interrupt request to the CPU. The ABIF bit in ABRKSR is set to 1 by the combination of the address set in BAR, the data set in BDR, and the conditions set in ABRKCR. When the interrupt request is accepted, interrupt exception handling starts after the instruction being executed ends. The address break interrupt is not masked because of the I bit in CCR of the CPU.









When the address break is	s specified in the data read cycle
Register setting • ABRKCR = H'A0 • BAR = H'025A	Program 0258 NOP 025A NOP * 025C MOV.W @H'025A,R0 0260 NOP Underline indicates the address 0262 NOP to be stacked. : :
MOV instruc- tion 1 prefetch Address bus Interrupt request	MOV NOP MOV NOP Next instruction 2 tion tion tion tion prefetch prefetch execution prefetch prefetch processing save

Figure 4.2 Address Break Interrupt Operation Example (2)

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Section 5 Clock Pulse Generators

Clock oscillator circuitry (CPG: clock pulse generator) is provided on-chip, including a system clock pulse generator. The system clock pulse generator consists of a system clock oscillator, a duty correction circuit, and system clock dividers.

Figure 5.1 shows a block diagram of the clock pulse generators.

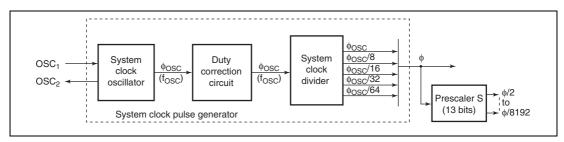


Figure 5.1 Block Diagram of Clock Pulse Generators

The basic clock signals that drive the CPU and on-chip peripheral modules are system clocks (ϕ). The system clock is divided into $\phi/8192$ to $\phi/2$ by prescaler S and they are supplied to respective peripheral modules.

5.1 System Clock Generator

Clock pulses can be supplied to the system clock divider either by connecting a crystal or ceramic resonator, or by providing external clock input. Figure 5.2 shows a block diagram of the system clock generator.

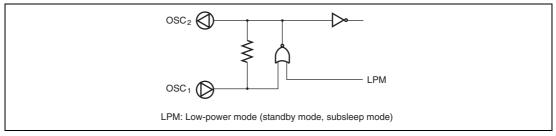
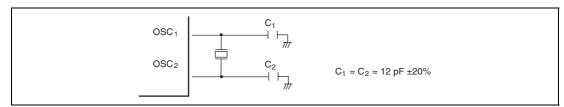


Figure 5.2 Block Diagram of System Clock Generator



5.1.1 Connecting Crystal Resonator

Figure 5.3 shows a typical method of connecting a crystal resonator. An AT-cut parallel-resonance crystal resonator should be used. Figure 5.4 shows the equivalent circuit of a crystal resonator. A resonator having the characteristics given in table 5.1 should be used.





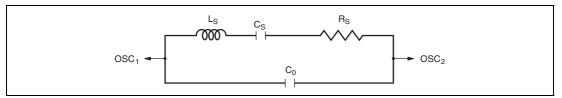


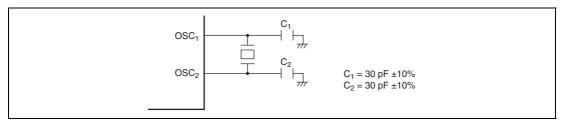
Figure 5.4 Equivalent Circuit of Crystal Resonator

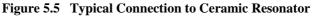
Table 5.1 Crystal Resonator Parameters

Frequency (MHz)	2	4	8	10	16	20	
R _s (max)	500 Ω	120 Ω	80 Ω	60 Ω	50 Ω	40 Ω	
C _o (max)	7 pF	7 pF	7 pF	7 pF	7 pF	7 pF	

5.1.2 Connecting Ceramic Resonator

Figure 5.5 shows a typical method of connecting a ceramic resonator.







5.1.3 External Clock Input Method

Connect an external clock signal to pin OSC_1 , and leave pin OSC_2 open. Figure 5.6 shows a typical connection. The duty cycle of the external clock signal must be 45 to 55%.

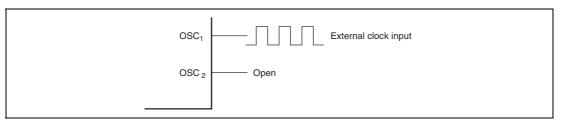


Figure 5.6 Example of External Clock Input

5.2 Prescalers

5.2.1 Prescaler S

Prescaler S is a 13-bit counter using the system clock (ϕ) as its input clock. It is incremented once per clock period. Prescaler S is initialized to H'0000 by a reset, and starts counting on exit from the reset state. In standby mode and subsleep mode, the system clock pulse generator stops. Prescaler S also stops and is initialized to H'0000. The CPU cannot read or write prescaler S.

The output from prescaler S is shared by the on-chip peripheral modules. The divider ratio can be set separately for each on-chip peripheral function. In active mode and sleep mode, the clock input to prescaler S is determined by the division factor designated by MA2 to MA0 in SYSCR2.

5.3 Usage Notes

5.3.1 Note on Resonators

Resonator characteristics are closely related to board design and should be carefully evaluated by the user, referring to the examples shown in this section. Resonator circuit constants will differ depending on the resonator element, stray capacitance in its interconnecting circuit, and other factors. Suitable constants should be determined in consultation with the resonator element manufacturer. Design the circuit so that the resonator element never receives voltages exceeding its maximum rating.



5.3.2 Notes on Board Design

When using a crystal resonator (ceramic resonator), place the resonator and its load capacitors as close as possible to the OSC_1 and OSC_2 pins. Other signal lines should be routed away from the oscillator circuit to prevent induction from interfering with correct oscillation (see figure 5.7).

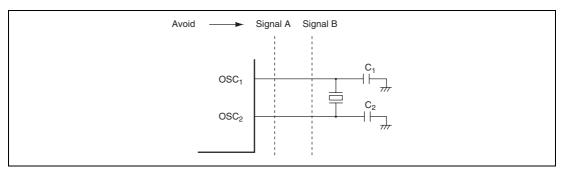


Figure 5.7 Example of Incorrect Board Design



Section 6 Power-Down Modes

This LSI has five modes of operation after a reset. These include a normal active mode and three power-down modes, in which power consumption is significantly reduced. Module standby mode reduces power consumption by selectively halting on-chip module functions.

Active mode

The CPU and all on-chip peripheral modules are operable on the system clock. The system clock frequency can be selected from ϕ osc, ϕ osc/8, ϕ osc/16, ϕ osc/32, and ϕ osc/64.

- Sleep mode The CPU halts. On-chip peripheral modules are operable on the system clock.
- Standby mode

The CPU and all on-chip peripheral modules halt.

• Subsleep mode

The CPU and all on-chip peripheral modules halt. I/O ports keep the same states as before the transition.

• Module standby mode

Independent of the above modes, power consumption can be reduced by halting on-chip peripheral modules that are not used in module units.

6.1 **Register Descriptions**

The registers related to power-down modes are listed below.

- System control register 1 (SYSCR1)
- System control register 2 (SYSCR2)
- Module standby control register 1 (MSTCR1)
- Module standby control register 2 (MSTCR2)



6.1.1 System Control Register 1 (SYSCR1)

SYSCR1 controls the power-down modes, as well as SYSCR2.

		Initial		
Bit	Bit Name	Value	R/W	Description
7	SSBY	0	R/W	Software Standby
				This bit selects the mode to transit after the execution of the SLEEP instruction.
				0: a transition is made to sleep mode
				1: a transition is made to standby mode.
				For details, see table 6.2.
6	STS2	0	R/W	Standby Timer Select 2 to 0
5	STS1	0	R/W	These bits designate the time the CPU and peripheral
4	STS0	0	R/W	modules wait for stable clock operation after exiting from standby mode, to active mode or sleep mode due to an interrupt. The designation should be made according to the clock frequency so that the waiting time is at least 6.5 ms. The relationship between the specified value and the number of wait states is shown in table 6.1. When an external clock is to be used, the minimum value (STS2 = STS1 = STS0 = 1) is recommended.
3 to 0		All 0		Reserved
				These bits are always read as 0.

Table 6.1 Operating Frequency and Waiting Time

	Bit Nam	ne		Operating Frequency							
STS2	STS1	STS0	Waiting Time	20 MHz	16 MHz	10 MHz	8 MHz	4 MHz	2 MHz	1 MHz	0.5 MHz
0	0	0	8,192 states	0.4	0.5	0.8	1.0	2.0	4.1	8.1	16.4
		1	16,384 states	0.8	1.0	1.6	2.0	4.1	8.2	16.4	32.8
	1	0	32,768 states	1.6	2.0	3.3	4.1	8.2	16.4	32.8	65.5
		1	65,536 states	3.3	4.1	6.6	8.2	16.4	32.8	65.5	131.1
1	0	0	131,072 states	6.6	8.2	13.1	16.4	32.8	65.5	131.1	262.1
		1	1,024 states	0.05	0.06	0.10	0.13	0.26	0.51	1.02	2.05
	1	0	128 states	0.00	0.00	0.01	0.02	0.03	0.06	0.13	0.26
		1	16 states	0.00	0.00	0.00	0.00	0.00	0.01	0.02	0.03

Note: Time unit is ms.

6.1.2 System Control Register 2 (SYSCR2)

SYSCR2 controls the power-down modes, as well as SYSCR1.

Bit	Bit Name	Initial Value	R/W	Description
7	SMSEL	0	R/W	Sleep Mode Selection
				This bit selects the mode to transit after the execution of a SLEEP instruction, as well as bit SSBY of SYSCR1.
				For details, see table 6.2.
6	_	0		Reserved
				This bit is always read as 0.
5	DTON	0	R/W	Direct Transfer on Flag
				This bit selects the mode to transit after the execution of a SLEEP instruction, as well as bit SSBY of SYSCR1.
				For details, see table 6.2.
4	MA2	0	R/W	Active Mode Clock Select 2 to 0
3	MA1	0	R/W	These bits select the operating clock frequency in active
2	MAO	0	R/W	and sleep modes. The operating clock frequency changes to the set frequency after the SLEEP instruction is executed.
				OXX: $\phi_{ m osc}$
				100: φ _{osc} /8
				101: φ _{osc} /16
				110:
				111:
1, 0	_	All 0		Reserved
_				These bits are always read as 0.

Legend: X : Don't care.



6.1.3 Module Standby Control Register 1 (MSTCR1)

MSTCR1 allows the on-chip peripheral modules to enter a standby state in module units.

Bit	Bit Name	Initial Value	R/W	Description
7,6		All 0	_	Reserved
				These bits are always read as 0.
5	MSTS3	0	R/W	SCI3 Module Standby
				SCI3 enters standby mode when this bit is set to 1.
4	MSTAD	0	R/W	A/D Converter Module Standby
				A/D converter enters standby mode when this bit is set to 1.
3	MSTWD	0	R/W	Watchdog Timer Module Standby
				Watchdog timer enters standby mode when this bit is set to 1. When the internal oscillator is selected for the watchdog timer clock, the watchdog timer operates regardless of the setting of this bit.
2	MSTTW	0	R/W	Timer W Module Standby
				Timer W enters standby mode when this bit is set to 1.
1	MSTTV	0	R/W	Timer V Module Standby
				Timer V enters standby mode when this bit is set to 1.
0	_	0		Reserved
				This bit is always read as 0.

6.1.4 Module Standby Control Register 2 (MSTCR2)

MSTCR2 allows the on-chip peripheral modules to enter a standby state in module units.

Bit	Bit Name	Initial Value	R/W	Description
7	MSTS3_2	0	R/W	SCI3_2 Module Standby
				SCI3_2 enters standby mode when this bit is set to1.
6 to 0	_	All 0	_	Reserved
				These bits are always read as 0.

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6.2 Mode Transitions and States of LSI

Figure 6.1 shows the possible transitions among these operating modes. A transition is made from the program execution state to the program halt state of the program by executing a SLEEP instruction. Interrupts allow for returning from the program halt state to the program execution state of the program. A direct transition from active mode to active mode changes the operating frequency. $\overline{\text{RES}}$ input enables transitions from a mode to the reset state. Table 6.2 shows the transition conditions of each mode after the SLEEP instruction is executed and a mode to return by an interrupt. Table 6.3 shows the internal states of the LSI in each mode.

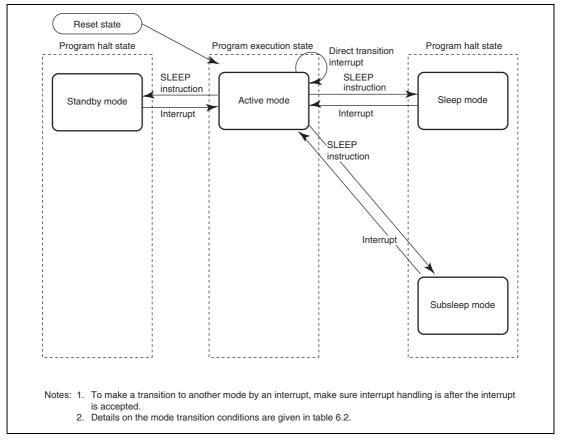


Figure 6.1 Mode Transition Diagram

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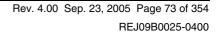


Table 6.2	Transition Mode after SLEEP Instruction Execution and Interrupt Handling
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DTON	SSBY	SMSEL	Transition Mode after SLEEP Instruction Execution	Transition Mode due to Interrupt
0	0	0	Sleep mode	Active mode
	0	1	Subsleep mode	Active mode
	1	Х	Standby mode	Active mode
1	Х	0*	Active mode (direct transition)	_

Legend: X: Don't care.

* When a state transition is performed while SMSEL is 1, timer V, SCI3, SCI3_2, SCI3_3 (only for the H8/36024) and the A/D converter are reset, and all registers are set to their initial values. To use these functions after entering active mode, reset the registers.

Table 6.3 Internal State in Each Operating Mode

Function		Active Mode	Sleep Mode	Subsleep Mode	Standby Mode
System cloo	ck oscillator	Functioning	Functioning	Halted	Halted
CPU	Instructions	Functioning	Halted	Halted	Halted
operations	Registers	Functioning	Retained	Retained	Retained
RAM		Functioning	Retained	Retained	Retained
IO ports		Functioning	Retained	Retained	Register contents are retained, but output is the high-impedance state.
External	IRQ3, IRQ0	Functioning	Functioning	Functioning	Functioning
interrupts	WKP5 to WKP0	Functioning	Functioning	Functioning	Functioning
Peripheral	Timer V	Functioning	Functioning	Reset	Reset
functions	Timer W	Functioning	Functioning	Retained	Retained (if internal clock \$\ophi\$ is selected as a count clock, the counter is incremented by a subclock)
	Watchdog timer	Functioning	Functioning	Retained	Retained (functioning if the internal oscillator is selected as a count clock)
	SCI3	Functioning	Functioning	Reset	Reset
	A/D converter	Functioning	Functioning	Reset	Reset



6.2.1 Sleep Mode

In sleep mode, CPU operation is halted but the on-chip peripheral modules function at the clock frequency set by the MA2 to MA0 bits in SYSCR2. CPU register contents are retained. When an interrupt is requested, sleep mode is cleared and interrupt exception handling starts. Sleep mode is not cleared if the I bit of the condition code register (CCR) is set to 1 or the requested interrupt is disabled in the interrupt enable register. a transition is made to subactive mode when the bit is 1.

When the $\overline{\text{RES}}$ pin goes low, the CPU goes into the reset state and sleep mode is cleared.

6.2.2 Standby Mode

In standby mode, the clock pulse generator stops, so the CPU and on-chip peripheral modules stop functioning. However, as long as the rated voltage is supplied, the contents of CPU registers, on-chip RAM, and some on-chip peripheral module registers are retained. On-chip RAM contents will be retained as long as the voltage set by the RAM data retention voltage is provided. The I/O ports go to the high-impedance state.

Standby mode is cleared by an interrupt. When an interrupt is requested, the system clock pulse generator starts. After the time set in bits STS2–STS0 in SYSCR1 has elapsed, and interrupt exception handling starts. Standby mode is not cleared if the I bit of CCR is set to 1 or the requested interrupt is disabled in the interrupt enable register.

When the $\overline{\text{RES}}$ pin goes low, the system clock pulse generator starts. Since system clock signals are supplied to the entire chip as soon as the system clock pulse generator starts functioning, the $\overline{\text{RES}}$ pin must be kept low until the pulse generator output stabilizes. After the pulse generator output has stabilized, the CPU starts reset exception handling if the $\overline{\text{RES}}$ pin is driven high.

6.2.3 Subsleep Mode

In subsleep mode, the system clock oscillator is halted, and operation of the CPU and on-chip peripheral modules is halted. As long as a required voltage is applied, the contents of CPU registers, the on-chip RAM, and some registers of the on-chip peripheral modules are retained. I/O ports keep the same states as before the transition.

Subsleep mode is cleared by an interrupt. When an interrupt is requested, the system clock oscillator starts to oscillate. Subsleep mode is cleared and an interrupt exception handling starts when the time set in bits STS2 to STS0 in SYSCR1 elapses. Subsleep mode is not cleared if the I bit of CCR is 1 or the interrupt is disabled in the interrupt enable bit.



6.3 Operating Frequency in Active Mode

Operation in active mode is clocked at the frequency designated by the MA2 to MA0 bits in SYSCR2. The operating frequency changes to the set frequency after SLEEP instruction execution.

6.4 Direct Transition

The CPU can execute programs in active mode. The operating frequency can be changed by making a transition directly from active mode to active mode. A direct transition can be made by executing a SLEEP instruction while the DTON bit in SYSCR2 is set to 1. The direct transition also enables operating frequency modification in active mode. After the mode transition, direct transition interrupt exception handling starts.

If the direct transition interrupt is disabled in interrupt enable register 1, a transition is made instead to sleep mode. Note that if a direct transition is attempted while the I bit in CCR is set to 1, sleep mode will be entered, and the resulting mode cannot be cleared by means of an interrupt.

6.5 Module Standby Function

The module-standby function can be set to any peripheral module. In module standby mode, the clock supply to modules stops to enter the power-down mode. Module standby mode enables each on-chip peripheral module to enter the standby state by setting a bit that corresponds to each module in MSTCR1 and MSTCR2 to 1 and cancels the mode by clearing the bit to 0.



Section 7 ROM

The features of the 32-kbyte (4 kbytes of them are the control program area for E7 or E8) flash memory built into the HD64F36024 and HD64F36014 are summarized below.

- Programming/erase methods
 - The flash memory is programmed 128 bytes at a time. Erase is performed in single-block units. The flash memory is configured as follows: 1 kbyte × 4 blocks and 28 kbytes × 1 block. To erase the entire flash memory, each block must be erased in turn.
- Reprogramming capability
 - The flash memory can be reprogrammed up to 1,000 times.
- On-board programming
 - On-board programming/erasing can be done in boot mode, in which the boot program built into the chip is started to erase or program of the entire flash memory. In normal user program mode, individual blocks can be erased or programmed.
- Automatic bit rate adjustment
 - For data transfer in boot mode, this LSI's bit rate can be automatically adjusted to match the transfer bit rate of the host.
- Programming/erasing protection
 - Sets software protection against flash memory programming/erasing.



7.1 Block Configuration

Figure 7.1 shows the block configuration of 32-kbyte flash memory. The thick lines indicate erasing units, the narrow lines indicate programming units, and the values are addresses. The flash memory is divided into 1 kbyte \times 4 blocks and 28 kbytes \times 1 block. Erasing is performed in these units. Programming is performed in 128-byte units starting from an address with lower eight bits H'00 or H'80.

Г	1.1100000	1.1100.01	1110000		
	H'0000	H'0001	H'0002	← Programming unit: 128 bytes →	H'007F
Erase unit	H'0080	H'0081	H'0082		H'00FF
1kbyte			 		1 1 1
-	H'0380	H'0381	H'0382		H'03FF
ŀ	H'0400	H'0401	H'0402	← Programming unit: 128 bytes →	H'047F
Erase unit	H'0480	H'0481	H'0481		H'04FF
1kbyte					
-	H'0780	H'0781	H'0782		H'07FF
ſ	H'0800	H'0801	H'0802	- Programming unit: 128 bytes -	H'087F
Erase unit	H'0880	H'0881	H'0882		H'08FF
1kbyte					
ŀ	H'0B80	H'0B81	H'0B82		H'0BFF
ľ	H'0C00	H'0C01	H'0C02	← Programming unit: 128 bytes →	H'0C7F
Erase unit	H'0C80	H'0C81	H'0C82		H'0CFF
1kbyte					
-	H'0F80	H'0F81	H'0F82		H'0FFF
ľ	H'1000	H'1001	H'1002	← Programming unit: 128 bytes →	H'107F
Erase unit	H'1080	H'1081	H'1082		H'10FF
28 kbytes					
					1 1 1 1
	H'7F80	H'7F81	H'7F82		H'7FFF

Figure 7.1 Flash Memory Block Configuration

7.2 **Register Descriptions**

The flash memory has the following registers.

- Flash memory control register 1 (FLMCR1)
- Flash memory control register 2 (FLMCR2)
- Erase block register 1 (EBR1)
- Flash memory enable register (FENR)

7.2.1 Flash Memory Control Register 1 (FLMCR1)

FLMCR1 is a register that makes the flash memory change to program mode, program-verify mode, erase mode, or erase-verify mode. For details on register setting, refer to section 7.4, Flash Memory Programming/Erasing.

Bit	Bit Name	Initial Value	R/W	Description
7	—	0	—	Reserved
				This bit is always read as 0.
6	SWE	0	R/W	Software Write Enable
				When this bit is set to 1, flash memory programming/erasing is enabled. When this bit is cleared to 0, other FLMCR1 register bits and all EBR1 bits cannot be set.
5	ESU	0	R/W	Erase Setup
				When this bit is set to 1, the flash memory changes to the erase setup state. When it is cleared to 0, the erase setup state is cancelled. Set this bit to 1 before setting the E bit to 1 in FLMCR1.
4	PSU	0	R/W	Program Setup
				When this bit is set to 1, the flash memory changes to the program setup state. When it is cleared to 0, the program setup state is cancelled. Set this bit to 1 before setting the P bit in FLMCR1.
3	EV	0	R/W	Erase-Verify
				When this bit is set to 1, the flash memory changes to erase-verify mode. When it is cleared to 0, erase-verify mode is cancelled.



Bit	Bit Name	Initial Value	R/W	Description
2	PV	0	R/W	Program-Verify
				When this bit is set to 1, the flash memory changes to program-verify mode. When it is cleared to 0, program-verify mode is cancelled.
1	E	0	R/W	Erase
				When this bit is set to 1, and while the SWE = 1 and ESU = 1 bits are 1, the flash memory changes to erase mode. When it is cleared to 0, erase mode is cancelled.
0	Р	0	R/W	Program
				When this bit is set to 1, and while the SWE = 1 and PSU = 1 bits are 1, the flash memory changes to program mode. When it is cleared to 0, program mode is cancelled.

7.2.2 Flash Memory Control Register 2 (FLMCR2)

FLMCR2 is a register that displays the state of flash memory programming/erasing. FLMCR2 is a read-only register, and should not be written to.

Bit	Bit Name	Initial Value	R/W	Description
7	FLER	0	R	Flash Memory Error
				Indicates that an error has occurred during an operation on flash memory (programming or erasing). When FLER is set to 1, flash memory goes to the error-protection state.
				See 7.5.3, Error Protection, for details.
6 to 0	_	All 0	_	Reserved
				These bits are always read as 0.

7.2.3 Erase Block Register 1 (EBR1)

EBR1 specifies the flash memory erase area block. EBR1 is initialized to H'00 when the SWE bit in FLMCR1 is 0. Do not set more than one bit at a time, as this will cause all the bits in EBR1 to be automatically cleared to 0.

Bit	Bit Name	Initial Value	R/W	Description
7 to 5	_	All 0	_	Reserved
				These bits are always read as 0.
4	EB4	0	R/W	When this bit is set to 1, 28 kbytes of H'1000 to H'7FFF will be erased.
3	EB3	0	R/W	When this bit is set to 1, 1 kbyte of H'0C00 to H'0FFF will be erased.
2	EB2	0	R/W	When this bit is set to 1, 1 kbyte of H'0800 to H'0BFF will be erased.
1	EB1	0	R/W	When this bit is set to 1, 1 kbyte of H'0400 to H'07FF will be erased.
0	EB0	0	R/W	When this bit is set to 1, 1 kbyte of H'0000 to H'03FF will be erased.

7.2.4 Flash Memory Enable Register (FENR)

Bit 7 (FLSHE) in FENR enables or disables the CPU access to the flash memory control registers, FLMCR1, FLMCR2, and EBR1.

Bit	Bit Name	Initial Value	R/W	Description
7	FLSHE	0	R/W	Flash Memory Control Register Enable
				Flash memory control registers can be accessed when this bit is set to 1. Flash memory control registers cannot be accessed when this bit is set to 0.
6 to 0		All 0	_	Reserved
				These bits are always read as 0.



7.3 On-Board Programming Modes

There is a mode for programming/erasing of the flash memory; boot mode, which enables onboard programming/erasing. On-board programming/erasing can also be performed in user program mode. At reset-start in reset mode, this LSI changes to a mode depending on the TEST pin settings, $\overline{\text{NMI}}$ pin settings, and input level of each port, as shown in table 7.1. The input level of each pin must be defined four states before the reset ends.

When changing to boot mode, the boot program built into this LSI is initiated. The boot program transfers the programming control program from the externally-connected host to on-chip RAM via SCI3. After erasing the entire flash memory, the programming control program is executed. This can be used for programming initial values in the on-board state or for a forcible return when programming/erasing can no longer be done in user program mode. In user program mode, individual blocks can be erased and programmed by branching to the user program/erase control program prepared by the user.

TEST	NMI	E10T_0	PB0	PB1	PB2	LSI State after Reset End
0	1	Х	Х	Х	Х	User Mode
0	0	1	Х	Х	Х	Boot Mode

Legend: X: Don't care.

7.3.1 Boot Mode

Table 7.2 shows the boot mode operations between reset end and branching to the programming control program.

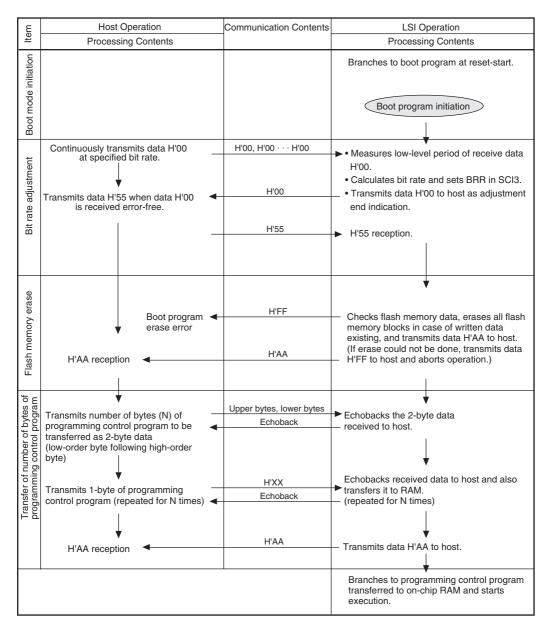
- 1. When boot mode is used, the flash memory programming control program must be prepared in the host beforehand. Prepare a programming control program in accordance with the description in section 7.4, Flash Memory Programming/Erasing.
- 2. SCI3 should be set to asynchronous mode, and the transfer format as follows: 8-bit data, 1 stop bit, and no parity.
- 3. When the boot program is initiated, the chip measures the low-level period of asynchronous SCI communication data (H'00) transmitted continuously from the host. The chip then calculates the bit rate of transmission from the host, and adjusts the SCI3 bit rate to match that of the host. The reset should end with the RxD pin high. The RxD and TxD pins should be pulled up on the board if necessary. After the reset is complete, it takes approximately 100 states before the chip is ready to measure the low-level period.

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- 4. After matching the bit rates, the chip transmits one H'00 byte to the host to indicate the completion of bit rate adjustment. The host should confirm that this adjustment end indication (H'00) has been received normally, and transmit one H'55 byte to the chip. If reception could not be performed normally, initiate boot mode again by a reset. Depending on the host's transfer bit rate and system clock frequency of this LSI, there will be a discrepancy between the bit rates of the host and the chip. To operate the SCI properly, set the host's transfer bit rate and system clock frequency of this LSI within the ranges listed in table 7.3.
- 5. In boot mode, a part of the on-chip RAM area is used by the boot program. The area H'F780 to H'FEEF is the area to which the programming control program is transferred from the host. The boot program area cannot be used until the execution state in boot mode switches to the programming control program.
- 6. Before branching to the programming control program, the chip terminates transfer operations by SCI3 (by clearing the RE and TE bits in SCR3 to 0), however the adjusted bit rate value remains set in BRR. Therefore, the programming control program can still use it for transfer of write data or verify data with the host. The TxD pin is high (PCR22 = 1, P22 = 1). The contents of the CPU general registers are undefined immediately after branching to the programming control program. These registers must be initialized at the beginning of the programming control program, as the stack pointer (SP), in particular, is used implicitly in subroutine calls, etc.
- 7. Boot mode can be cleared by a reset. End the reset after driving the reset pin low, waiting at least 20 states, and then setting the $\overline{\text{NMI}}$ pin. Boot mode is also cleared when a WDT overflow occurs.
- 8. Do not change the TEST pin and $\overline{\text{NMI}}$ pin input levels in boot mode.



Table 7.2 Boot Mode Operation





Host Bit Rate	System Clock Frequency Range of LSI
19,200 bps	16 to 20 MHz
9,600 bps	8 to 16 MHz
4,800 bps	4 to 16 MHz
2,400 bps	2 to 16 MHz

Table 7.3 System Clock Frequencies for which Automatic Adjustment of LSI Bit Rate is Possible

7.3.2 Programming/Erasing in User Program Mode

On-board programming/erasing of an individual flash memory block can also be performed in user program mode by branching to a user program/erase control program. The user must set branching conditions and provide on-board means of supplying programming data. The flash memory must contain the user program/erase control program or a program that provides the user program/erase control program from external memory. As the flash memory itself cannot be read during programming/erasing, transfer the user program/erase control program to on-chip RAM, as in boot mode. Figure 7.2 shows a sample procedure for programming/erasing in user program mode. Prepare a user program/erase control program in accordance with the description in section 7.4, Flash Memory Programming/Erasing.

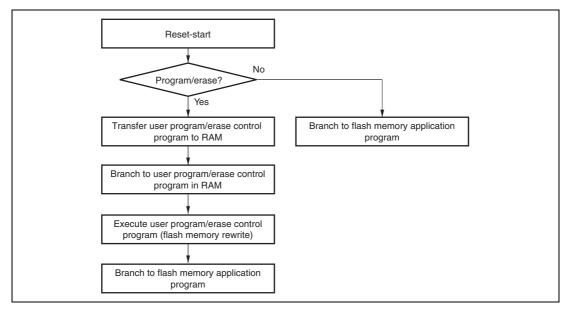


Figure 7.2 Programming/Erasing Flowchart Example in User Program Mode



7.4 Flash Memory Programming/Erasing

A software method using the CPU is employed to program and erase flash memory in the onboard programming modes. Depending on the FLMCR1 setting, the flash memory operates in one of the following four modes: Program mode, program-verify mode, erase mode, and erase-verify mode. The programming control program in boot mode and the user program/erase control program in user program mode use these operating modes in combination to perform programming/erasing. Flash memory programming and erasing should be performed in accordance with the descriptions in section 7.4.1, Program/Program-Verify and section 7.4.2, Erase/Erase-Verify, respectively.

7.4.1 Program/Program-Verify

When writing data or programs to the flash memory, the program/program-verify flowchart shown in figure 7.3 should be followed. Performing programming operations according to this flowchart will enable data or programs to be written to the flash memory without subjecting the chip to voltage stress or sacrificing program data reliability.

- 1. Programming must be done to an empty address. Do not reprogram an address to which programming has already been performed.
- 2. Programming should be carried out 128 bytes at a time. A 128-byte data transfer must be performed even if writing fewer than 128 bytes. In this case, H'FF data must be written to the extra addresses.
- 3. Prepare the following data storage areas in RAM: A 128-byte programming data area, a 128byte reprogramming data area, and a 128-byte additional-programming data area. Perform reprogramming data computation according to table 7.4, and additional programming data computation according to table 7.5.
- 4. Consecutively transfer 128 bytes of data in byte units from the reprogramming data area or additional-programming data area to the flash memory. The program address and 128-byte data are latched in the flash memory. The lower 8 bits of the start address in the flash memory destination area must be H'00 or H'80.
- 5. The time during which the P bit is set to 1 is the programming time. Table 7.6 shows the allowable programming times.
- 6. The watchdog timer (WDT) is set to prevent overprogramming due to program runaway, etc. An overflow cycle of approximately 6.6 ms is allowed.
- 7. For a dummy write to a verify address, write 1-byte data H'FF to an address whose lower 2 bits are B'00. Verify data can be read in words or in longwords from the address to which a dummy write was performed.

8. The maximum number of repetitions of the program/program-verify sequence of the same bit is 1,000.

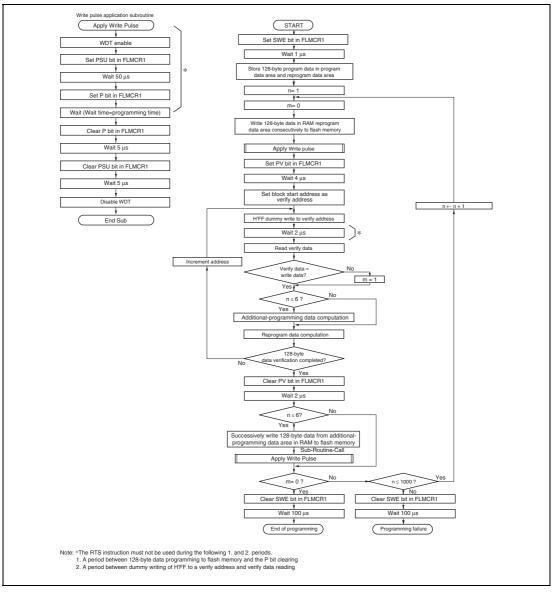


Figure 7.3 Program/Program-Verify Flowchart

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Program Data	Verify Data	Reprogram Data	Comments
0	0	1	Programming completed
0	1	0	Reprogram bit
1	0	1	_
1	1	1	Remains in erased state

Table 7.4 Reprogram Data Computation Table

Table 7.5 Additional-Program Data Computation Table

Reprogram Data	Verify Data	Additional-Program Data	Comments
0	0	0	Additional-program bit
0	1	1	No additional programming
1	0	1	No additional programming
1	1	1	No additional programming

Table 7.6Programming Time

n (Number of Writes)	Programming Time	In Additional Programming	Comments
1 to 6	30	10	
7 to 1,000	200	—	

Note: Time shown in μ s.

7.4.2 Erase/Erase-Verify

When erasing flash memory, the erase/erase-verify flowchart shown in figure 7.4 should be followed.

- 1. Prewriting (setting erase block data to all 0s) is not necessary.
- 2. Erasing is performed in block units. Make only a single-bit specification in the erase block register (EBR1). To erase multiple blocks, each block must be erased in turn.
- 3. The time during which the E bit is set to 1 is the flash memory erase time.
- 4. The watchdog timer (WDT) is set to prevent overerasing due to program runaway, etc. An overflow cycle of approximately 19.8 ms is allowed.

- 5. For a dummy write to a verify address, write 1-byte data H'FF to an address whose lower two bits are B'00. Verify data can be read in longwords from the address to which a dummy write was performed.
- 6. If the read data is not erased successfully, set erase mode again, and repeat the erase/erase-verify sequence as before. The maximum number of repetitions of the erase/erase-verify sequence is 100.

7.4.3 Interrupt Handling when Programming/Erasing Flash Memory

All interrupts, including the $\overline{\text{NMI}}$ interrupt, are disabled while flash memory is being programmed or erased, or while the boot program is executing, for the following three reasons:

- 1. Interrupt during programming/erasing may cause a violation of the programming or erasing algorithm, with the result that normal operation cannot be assured.
- 2. If interrupt exception handling starts before the vector address is written or during programming/erasing, a correct vector cannot be fetched and the CPU malfunctions.
- 3. If an interrupt occurs during boot program execution, normal boot mode sequence cannot be carried out.



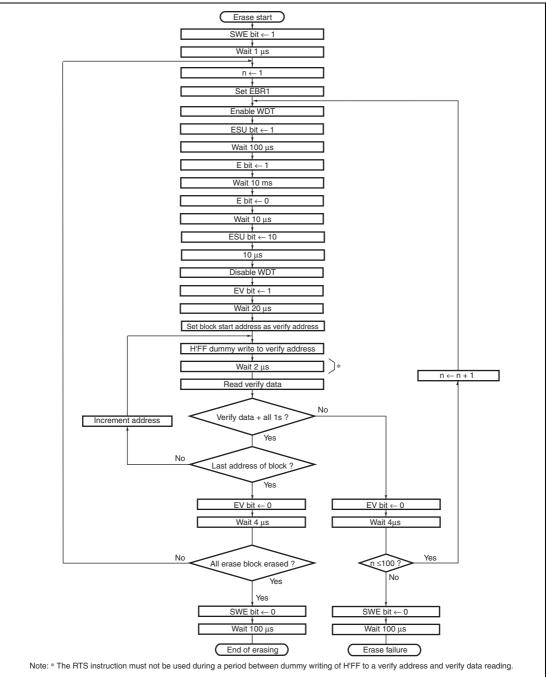


Figure 7.4 Erase/Erase-Verify Flowchart



7.5 Program/Erase Protection

There are three kinds of flash memory program/erase protection; hardware protection, software protection, and error protection.

7.5.1 Hardware Protection

Hardware protection refers to a state in which programming/erasing of flash memory is forcibly disabled or aborted because of a transition to reset, subsleep mode or standby mode. Flash memory control register 1 (FLMCR1), flash memory control register 2 (FLMCR2), and erase block register 1 (EBR1) are initialized. In a reset via the $\overline{\text{RES}}$ pin, the reset state is not entered unless the $\overline{\text{RES}}$ pin is held low until oscillation stabilizes after powering on. In the case of a reset during operation, hold the $\overline{\text{RES}}$ pin low for the $\overline{\text{RES}}$ pulse width specified in the AC Characteristics section.

7.5.2 Software Protection

Software protection can be implemented against programming/erasing of all flash memory blocks by clearing the SWE bit in FLMCR1. When software protection is in effect, setting the P or E bit in FLMCR1 does not cause a transition to program mode or erase mode. By setting the erase block register 1 (EBR1), erase protection can be set for individual blocks. When EBR1 is set to H'00, erase protection is set for all blocks.

7.5.3 Error Protection

In error protection, an error is detected when CPU runaway occurs during flash memory programming/erasing, or operation is not performed in accordance with the program/erase algorithm, and the program/erase operation is aborted. Aborting the program/erase operation prevents damage to the flash memory due to overprogramming or overerasing.

When the following errors are detected during programming/erasing of flash memory, the FLER bit in FLMCR2 is set to 1, and the error protection state is entered.

- When the flash memory of the relevant address area is read during programming/erasing (including vector read and instruction fetch)
- Immediately after exception handling excluding a reset during programming/erasing
- When a SLEEP instruction is executed during programming/erasing



The FLMCR1, FLMCR2, and EBR1 settings are retained, however program mode or erase mode is aborted at the point at which the error occurred. Program mode or erase mode cannot be reentered by re-setting the P or E bit. However, PV and EV bit setting is enabled, and a transition can be made to verify mode. Error protection can be cleared only by a reset.

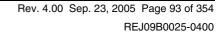


Section 8 RAM

This LSI has 2 kbytes of on-chip high-speed static RAM. The RAM is connected to the CPU by a 16-bit data bus, enabling two-state access by the CPU to both byte data and word data.

Product Classification		RAM Size	RAM Address
Flash memory version	H8/36024F, H8/36014F	2 kbytes	H'F780 to H'FF7F*
	H8/36022F, H8/36012F	2 kbytes	H'F780 to H'FF7F*
Masked ROM version	H8/36024, H8/36014	1 kbyte	H'FB80 to H'FF7F
	H8/36023, H8/36013	1 kbyte	H'FB80 to H'FF7F
	H8/36022, H8/36012	512 bytes	H'FD80 to H'FF7F
	H8/36011	512 bytes	H'FD80 to H'FF7F
	H8/36010	512 bytes	H'FD80 to H'FF7F

Note: * When the E7 or E8 is used, area H'F780 to H'FB7F must not be accessed.





Section 9 I/O Ports

The group of this LSI has thirty general I/O ports and four general input-only ports. Port 8 is a large current port, which can drive 20 mA ($@V_{ot} = 1.5$ V) when a low level signal is output. Any of these ports can become an input port immediately after a reset. They can also be used as I/O pins of the on-chip peripheral modules or external interrupt input pins, and these functions can be switched depending on the register settings. The registers for selecting these functions can be divided into two types: those included in I/O ports and those included in each on-chip peripheral module. General I/O ports are comprised of the port control register for controlling inputs/outputs and the port data register for storing output data and can select inputs/outputs in bit units. For functions in each port, see Appendix B.1, I/O Port Block Diagrams. For the execution of bit manipulation instructions to the port control register and port data register, see section 2.8.3, Bit Manipulation Instruction.

9.1 Port 1

Port 1 is a general I/O port also functioning as IRQ interrupt input pins, timer V input pin, and SCI3 I/O pin. Figure 9.1 shows its pin configuration.

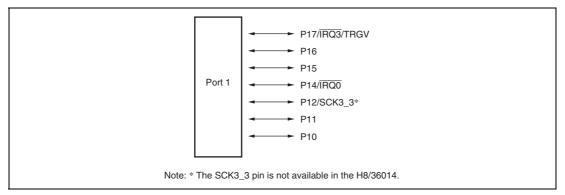


Figure 9.1 Port 1 Pin Configuration

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Port 1 has the following registers.

- Port mode register 1 (PMR1)
- Port control register 1 (PCR1)
- Port data register 1 (PDR1)
- Port pull-up control register 1 (PUCR1)

9.1.1 Port Mode Register 1 (PMR1)

PMR1 switches the functions of pins in port 1, port 2, and port 7.

Bit	Bit Name	Initial Value	R/W	Description
7	IRQ3	0	R/W	P17/IRQ3/TRGV Pin Function Switch
				This bit selects whether pin P17/IRQ3/TRGV is used as P17 or as IRQ3/TRGV.
				0: General I/O port
				1: IRQ3/TRGV input pin
6, 5		All 0		Reserved
				These bits are always read as 0.
4	IRQ0	0	R/W	P14/IRQ0 Pin Function Switch
				This bit selects whether pin P14/ $\overline{IRQ0}$ is used as P14 or as $\overline{IRQ0}$.
				0: General I/O port
				1: IRQ0 input pin
3	TXD2	0	R/W	P72/TXD_2 Pin Function Switch
				This bit selects whether pin P72/TXD_2 is used as P72 or as TXD_2.
				0: General I/O port
				1: TXD_2 output pin
2		0	R/W	Reserved
				This bit must always be cleared to 0 (setting to 1 is disabled).
1	TXD	0	R/W	P22/TXD Pin Function Switch
				This bit selects whether pin P22/TXD is used as P22 or as TXD.
				0: General I/O port
				1: TXD output pin
0		0	_	Reserved
				This bit is always read as 0.

9.1.2 Port Control Register 1 (PCR1)

Bit	Bit Name	Initial Value	R/W	Description
7	PCR17	0	W	When the corresponding pin is designated in PMR1 as a
6	PCR16	0	W	general I/O pin, setting a PCR1 bit to 1 makes the corresponding pin an output port, while clearing the bit to
5	PCR15	0	W	0 makes the pin an input port.
4	PCR14	0	W	Bit 3 is a reserved bit.
3	—	—		
2	PCR12	0	W	
1	PCR11	0	W	
0	PCR10	0	W	

PCR1 selects inputs/outputs in bit units for pins to be used as general I/O ports of port 1.

9.1.3 Port Data Register 1 (PDR1)

PDR1 is a general I/O port data register of port 1.

Bit	Bit Name	Initial Value	R/W	Description
7	P17	0	R/W	PDR1 stores output data for port 1 pins.
6	P16	0	R/W	If PDR1 is read while PCR1 bits are set to 1, the value
5	P15	0	R/W	stored in PDR1 are read. If PDR1 is read while PCR1 bits are cleared to 0, the pin states are read regardless of the
4	P14	0	R/W	value stored in PDR1.
3	—	1		Bit 3 is a reserved bit. This bit is always read as 1.
2	P12	0	R/W	
1	P11	0	R/W	
0	P10	0	R/W	



9.1.4 Port Pull-Up Control Register 1 (PUCR1)

Bit	Bit Name	Initial Value	R/W	Description
7	PUCR17	0	R/W	Only bits for which PCR1 is cleared are valid. The pull-up
6	PUCR16	0	R/W	MOS of P17 to P14 and P12 to P10 pins enter the on-
5	PUCR15	0	R/W	state when these bits are set to 1, while they enter the off-state when these bits are cleared to 0.
4	PUCR14	0	R/W	Bit 3 is a reserved bit. This bit is always read as 1.
3	—	1	—	
2	PUCR12	0	R/W	
1	PUCR11	0	R/W	
0	PUCR10	0	R/W	

PUCR1 controls the pull-up MOS in bit units of the pins set as the input ports.

9.1.5 Pin Functions

The correspondence between the register specification and the port functions is shown below.

• P17/IRQ3/TRGV pin

Register	PMR1	PCR1	
Bit Name	IRQ3	PCR17	Pin Function
Setting value	9 0	0	P17 input pin
		1	P17 output pin
	1	Х	IRQ3 input/TRGV input pin

Legend X: Don't care.

• P16 pin

Register	PCR1	
Bit Name	PCR16	Pin Function
Setting value	0	P16 input pin
	1	P16 output pin

• P15 pin

Register	PCR1	
Bit Name	PCR15	Pin Function
Setting value	0	P15 input pin
	1	P15 output pin

• P14/IRQ0 pin

PMR1	PCR1	
IRQ0	PCR14	Pin Function
0	0	P14 input pin
	1	P14 output pin
1	Х	IRQ0 input pin
		IRQ0 PCR14 0 0 1

Legend X: Don't care.

• P12/SCK3_3* pin

Register	SCR3_3*		SMR_3	* PCR1	
Bit Name	CKE1	CKE0	COM	PCR12	Pin Function
Setting value	0	0	0	0	P12 input pin
				1	P12 output pin
			1	Х	SCK3_3 output pin*
	0	1	Х	Х	SCK3_3 output pin*
	1	Х	Х	Х	SCK3_3 input pin*

Legend X: Don't care.

Note: * Not available in the H8/36014.

• P11 pin

Register	PCR1	
Bit Name	PCR11	Pin Function
Setting value	0	P11 input pin
	1	P11 output pin

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P10 pin

Register	PCR1	
Bit Name	PCR10	Pin Function
Setting value	0	P10 input pin
	1	P10 output pin

9.2 Port 2

Port 2 is a general I/O port also functioning as a SCI3 I/O pin. Each pin of the port 2 is shown in figure 9.2. The register settings of PMR1 and SCI3 have priority for functions of the pins for both uses.

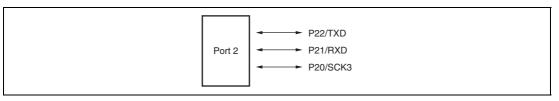


Figure 9.2 Port 2 Pin Configuration

Port 2 has the following registers.

- Port control register 2 (PCR2)
- Port data register 2 (PDR2)

9.2.1 Port Control Register 2 (PCR2)

PCR2 selects inputs/outputs in bit units for pins to be used as general I/O ports of port 2.

Bit	Bit Name	Initial Value	R/W	Description
7 to 3	_	_	_	Reserved
2	PCR22	0	W	When each of the port 2 pins P22 to P20 functions as a general I/O port, setting a PCR2 bit to 1 makes the corresponding pin an output port, while clearing the bit
1	PCR21	0	W	
0	PCR20	0	W	0 makes the pin an input port.

9.2.2 Port Data Register 2 (PDR2)

Bit	Bit Name	Initial Value	R/W	Description
7 to 3		All 1	—	Reserved
				These bits are always read as 1.
2	P22	0	R/W	PDR2 stores output data for port 2 pins.
1	P21	0	R/W	If PDR2 is read while PCR2 bits are set to 1, the value
0	P20	0	R/W	stored in PDR2 is read. If PDR2 is read while PCR2 bits are cleared to 0, the pin states are read regardless of the value stored in PDR2.

PDR2 is a general I/O port data register of port 2.

9.2.3 Pin Functions

The correspondence between the register specification and the port functions is shown below.

• P22/TXD pin

Register	PMR1	PCR2	
Bit Name	TXD	PCR22	Pin Function
Setting Value	0	0	P22 input pin
		1	P22 output pin
	1	Х	TXD output pin

Legend X: Don't care.

• P21/RXD pin

Register	SCR3	PCR2	
Bit Name	RE	PCR21	Pin Function
Setting Value	0	0	P21 input pin
		1	P21 output pin
	1	Х	RXD input pin

Legend X: Don't care.



• P20/SCK3 pin

Register	SCR3		SMR	PCR2	
Bit Name	CKE1	CKE0	COM	PCR20	Pin Function
Setting Value	0	0	0	0	P20 input pin
				1	P20 output pin
	0	0	1	Х	SCK3 output pin
	0	1	Х	Х	SCK3 output pin
	1	Х	Х	Х	SCK3 input pin

Legend X: Don't care.

9.3 Port 5

Port 5 is a general I/O port also functioning as an SCI3 I/O pins, A/D trigger input pin, and wakeup interrupt input pins. Each pin of the port 5 is shown in figure 9.3.

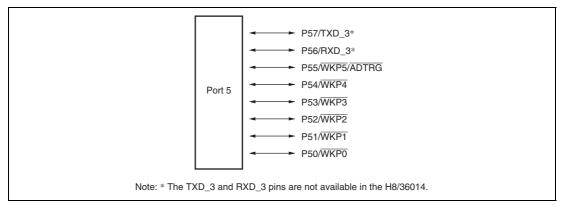


Figure 9.3 Port 5 Pin Configuration

Port 5 has the following registers.

- Port mode register 5 (PMR5)
- Port control register 5 (PCR5)
- Port data register 5 (PDR5)
- Port pull-up control register 5 (PUCR5)

9.3.1 Port Mode Register 5 (PMR5)

PMR5 switches the functions of pins in port 5.

Bit	Bit Name	Initial Value	R/W	Description
7	POF57	0	R/W	P57 Pin Function Switch
				0: General I/O port
				1: NMOS open-drain output
6	POF56	0	R/W	P56 Pin Function Switch
				0: General I/O port
				1: NMOS open-drain output
5	WKP5	0	R/W	P55/WKP5/ADTRG Pin Function Switch
				Selects whether pin P55/WKP5/ADTRG is used as P55 or as WKP5/ADTRG input.
				0: General I/O port
				1: WKP5/ADTRG input pin
4	WKP4	0	R/W	P54/WKP4 Pin Function Switch
				Selects whether pin P54/ $\overline{WKP4}$ is used as P54 or as $\overline{WKP4}$.
				0: General I/O port
				1: WKP4 input pin
3	WKP3	0	R/W	P53/WKP3 Pin Function Switch
				Selects whether pin P53/WKP3 is used as P53 or as WKP3.
				0: General I/O port
				1: WKP3 input pin
2	WKP2	0	R/W	P52/WKP2 Pin Function Switch
				Selects whether pin P52/WKP2 is used as P52 or as WKP2.
				0: General I/O port
				1: WKP2 input pin
1	WKP1	0	R/W	P51/WKP1 Pin Function Switch
				Selects whether pin P51/WKP1 is used as P51 or as $WKP1$.
				0: General I/O port
				1: WKP1 input pin



Bit	Bit Name	Initial Value	R/W	Description
0	WKP0	0	R/W	P50/WKP0 Pin Function Switch
			Selects whether pin P50/ $\overline{WKP0}$ is used as P50 or as $\overline{WKP0}$.	
				0: General I/O port
				1: WKP0 input pin

9.3.2 Port Control Register 5 (PCR5)

PCR5 selects inputs/outputs in bit units for pins to be used as general I/O ports of port 5.

			R/W	Description
7	PCR57	0	W	When each of the port 5 pins P57 to P50 functions as an
6	PCR56	0	W	general I/O port, setting a PCR5 bit to 1 makes the corresponding pin an output port, while clearing the bit to 0
5	PCR55	0	W	makes the pin an input port.
4	PCR54	0	W	
3	PCR53	0	W	
2	PCR52	0	W	
1	PCR51	0	W	
0	PCR50	0	W	

9.3.3 Port Data Register 5 (PDR5)

Bit	Bit Name	Initial Value	R/W	Description
7	P57	0	R/W	Stores output data for port 5 pins.
6	P56	0	R/W	If PDR5 is read while PCR5 bits are set to 1, the value
5	P55	0	R/W	stored in PDR5 are read. If PDR5 is read while PCR5 bits
4	P54	0	R/W	are cleared to 0, the pin states are read regardless of the value stored in PDR5.
3	P53	0	R/W	
2	P52	0	R/W	
1	P51	0	R/W	
0	P50	0	R/W	

PDR5 is a general I/O port data register of port 5.

9.3.4 Port Pull-Up Control Register 5 (PUCR5)

PUCR5 controls the pull-up MOS in bit units of the pins set as the input ports.

Bit	Bit Name	Initial Value	R/W	Description
7, 6	—	All 0	_	Reserved
				These bits are always read as 0.
5	PUCR55	0	R/W	Only bits for which PCR5 is cleared are valid. The pull-up
4	PUCR54	0	R/W	MOS of the corresponding pins enter the on-state when these bits are set to 1, while they enter the off-state when
3	PUCR53	0	R/W	these bits are cleared to 0.
2	PUCR52	0	R/W	
1	PUCR51	0	R/W	
0	PUCR50	0	R/W	



9.3.5 Pin Functions

The correspondence between the register specification and the port functions is shown below.

• P57/TXD_3* pin

Register	SMCR*	PCR5	
Bit Name	TXD_3	PCR57	Pin Function
Setting Value	0	0	P57 input pin
		1	P57 output pin
	1	Х	TXD_3 output pin*

Legend X: Don't care.

Note: * Not available in the H8/36014.

• P56/RXD_3* pin

Register SCR3_3* PCR5

Bit Name	RE	PCR56	Pin Function
Setting Value	0	0	P56 input pin
		1	P56 output pin
	1	Х	RXD_3 input pin*

Legend X: Don't care.

Note: * Not available in the H8/36014.

• P55/WKP5/ADTRG pin

Register	PMR5	PCR5	
Bit Name	WKP5	PCR55	Pin Function
Setting Value	0	0	P55 input pin
		1	P55 output pin
	1	Х	WKP5/ADTRG input pin

Legend X: Don't care.

• P54/WKP4 pin

Register	PMR5	PCR5	
Bit Name	WKP4	PCR54	Pin Function
Setting Value	0	0	P54 input pin
		1	P54 output pin
	1	Х	WKP4 input pin

Legend X: Don't care.

• P53/WKP3 pin

Register	PMR5	PCR5	
Bit Name	WKP3	PCR53	Pin Function
Setting Value	0	0	P53 input pin
		1	P53 output pin
	1	Х	WKP3 input pin

Legend X: Don't care.

• P52/WKP2 pin

Register	PMR5	PCR5	
Bit Name	WKP2	PCR52	Pin Function
Setting Value	0	0	P52 input pin
		1	P52 output pin
	1	Х	WKP2 input pin

Legend X: Don't care.

• P51/WKP1 pin

Register	PMR5	PCR5	
Bit Name	WKP1	PCR51	Pin Function
Setting Value	0	0	P51 input pin
		1	P51 output pin
	1	Х	WKP1 input pin

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Legend X: Don't care.

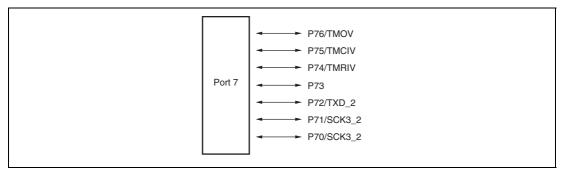
• P50/WKP0 pin

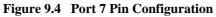
Register	PMR5	PCR5	
Bit Name	WKP0	PCR50	Pin Function
Setting Value	0	0	P50 input pin
		1	P50 output pin
	1	Х	WKP0 input pin

Legend X: Don't care.

9.4 Port 7

Port 7 is a general I/O port also functioning as a timer V I/O pin. Each pin of the port 7 is shown in figure 9.4. The register setting of TCSRV in timer V has priority for functions of pin P76/TMOV. The pins, P75/TMCIV and P74/TMRIV, are also functioning as timer V input ports that are connected to the timer V regardless of the register setting of port 7.





Port 7 has the following registers.

- Port control register 7 (PCR7)
- Port data register 7 (PDR7)

9.4.1 Port Control Register 7 (PCR7)

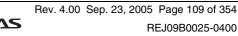
Bit	Bit Name	Initial Value	R/W	Description
7	_	_		Reserved
6	PCR76	0	W	Setting a PCR7 bit to 1 makes the corresponding pin an
5	PCR75	0	W	output port, while clearing the bit to 0 makes the pin an
4	PCR74	0	W	input port. Note that the TCSRV setting of the timer V has priority for deciding input/output direction of the
3	PCR73	0	W	P76/TMOV pin.
2	PCR72	0	W	
1	PCR71	0	W	
0	PCR70	0	W	

PCR7 selects inputs/outputs in bit units for pins to be used as general I/O ports of port 7.

Port Data Register 7 (PDR7) 9.4.2

PDR7 is a general I/O port data register of port 7.

Bit	Bit Name	Initial Value	R/W	Description
7	_	1	_	Reserved
				This bit is always read as 1.
6	P76	0	R/W	PDR7 stores output data for port 7 pins.
5	P75	0	R/W	If PDR7 is read while PCR7 bits are set to 1, the value
4	P74	0	R/W	stored in PDR7 is read. If PDR7 is read while PCR7 bits are cleared to 0, the pin states are read regardless of the
3	P73	0	R/W	value stored in PDR7.
2	P72	0	R/W	
1	P71	0	R/W	
0	P70	0	R/W	



9.4.3 Pin Functions

The correspondence between the register specification and the port functions is shown below.

• P76/TMOV pin

Register	TCSRV	PCR7	
Bit Name	Bit Name OS3 to OS0 PCR76		Pin Function
Setting Value	0000	0	P76 input pin
		1	P76 output pin
	Other than the above values	Х	TMOV output pin

Legend X: Don't care.

• P75/TMCIV pin

Register	PCR7	
Bit Name	PCR75	Pin Function
Setting Value 0		P75 input/TMCIV input pin
	1	P75 output/TMCIV input pin

• P74/TMRIV pin

Register	PCR7	
Bit Name	PCR74	Pin Function
Setting Value	0	P74 input/TMRIV input pin
	1	P74 output/TMRIV input pin

• P73 pin

Register	PCR7	
Bit Name	PCR73	Pin Function
Setting Value	0	P73 input pin
	1	P73 output pin

• P72/TXD_2 pin

Register	PMR1	PCR7	
Bit Name	TXD2	PCR72	Pin Function
Setting Value	0	0	P72 input pin
		1	P72 output pin
	1	Х	TXD_2 output pin

Legend X: Don't care.

• P71/RXD_2 pin

SCR3_2	PCR7	
RE	PCR71	Pin Function
0	0	P71 input pin
	1	P71 output pin
1	Х	RXD_2 input pin
	RE	RE PCR71 0 0 1

Legend X: Don't care.

• P70/SCK3_2 pin

Register	SCR3_2		SMR_2	PCR7	
Bit Name	CKE1	CKE0	СОМ	PCR70	Pin Function
Setting Value	0	0	0	0	P70 input pin
				1	P70 output pin
			1	Х	SCK3_2 output pin
	0	1	Х	Х	SCK3_2 output pin
	1	Х	Х	Х	SCK3_2 input pin

Legend X: Don't care.



9.5 Port 8

Port 8 is a general I/O port also functioning as a timer W I/O pin. Each pin of the port 8 is shown in figure 9.5. The register setting of the timer W has priority for functions of the pins P84/FTIOD, P83/FTIOC, P82/FTIOB, and P81/FTIOA. The P80/FTCI pin also functions as a timer W input port that is connected to the timer W regardless of the register setting of port 8.

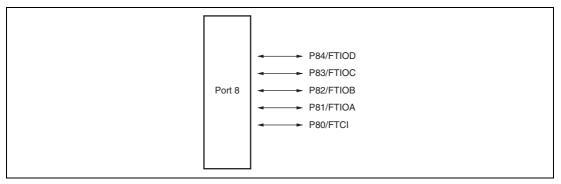


Figure 9.5 Port 8 Pin Configuration

Port 8 has the following registers.

- Port control register 8 (PCR8)
- Port data register 8 (PDR8)

9.5.1 Port Control Register 8 (PCR8)

PCR8 selects inputs/outputs in bit units for pins to be used as general I/O ports of port 8.

D '/		Initial	5.44	
Bit	Bit Name	Value	R/W	Description
7 to 5				Reserved
4	PCR84	0	W	When each of the port 8 pins P84 to P80 functions as an
3	PCR83	0	W	general I/O port, setting a PCR8 bit to 1 makes the corresponding pin an output port, while clearing the bit to
2	PCR82	0	W	0 makes the pin an input port.
1	PCR81	0	W	
0	PCR80	0	W	

9.5.2 Port Data Register 8 (PDR8)

Bit	Bit Name	Initial Value	R/W	Description
7 to 5	_	All 0	_	Reserved
4	P84	0	R/W	PDR8 stores output data for port 8 pins.
3	P83	0	R/W	If PDR8 is read while PCR8 bits are set to 1, the value
2	P82	0	R/W	stored in PDR8 is read. If PDR8 is read while PCR8 bits are cleared to 0, the pin states are read regardless of the
1	P81	0	R/W	value stored in PDR8.
0	P80	0	R/W	

PDR8 is a general I/O port data register of port 8.

9.5.3 Pin Functions

The correspondence between the register specification and the port functions is shown below.

• P84/FTIOD pin

Register	TIOR1			PCR8	
Bit Name	IOD2	IOD1	IOD0	PCR84	Pin Function
Setting Value	0	0	0	0	P84 input/FTIOD input pin
				1	P84 output/FTIOD input pin
	0	0	1	Х	FTIOD output pin
	0	1	Х	Х	FTIOD output pin
	1	Х	Х	0	P84 input/FTIOD input pin
				1	P84 output/FTIOD input pin

Legend X: Don't care.



• P83/FTIOC pin

Register	TIOR1			PCR8	
Bit Name	IOC2	IOC1	IOC0	PCR83	Pin Function
Setting Value	0	0	0	0	P83 input/FTIOC input pin
				1	P83 output/FTIOC input pin
	0	0	1	Х	FTIOC output pin
	0	1	Х	Х	FTIOC output pin
	1	Х	Х	0	P83 input/FTIOC input pin
				1	P83 output/FTIOC input pin

Legend X: Don't care.

• P82/FTIOB pin

Register	TIOR0			PCR8	
Bit Name	IOB2	IOB1	IOB0	PCR82	Pin Function
Setting Value	0	0	0	0	P82 input/FTIOB input pin
				1	P82 output/FTIOB input pin
	0	0	1	Х	FTIOB output pin
	0	1	Х	Х	FTIOB output pin
	1	Х	Х	0	P82 input/FTIOB input pin
				1	P82 output/FTIOB input pin

Legend X: Don't care.

• P81/FTIOA pin

Register	TIOR0			PCR8	
Bit Name	IOA2	IOA1	IOA0	PCR81	Pin Function
Setting Value	0	0	0	0	P81 input/FTIOA input pin
				1	P81 output/FTIOA input pin
	0	0	1	Х	FTIOA output pin
	0	1	Х	Х	FTIOA output pin
	1	Х	Х	0	P81 input/FTIOA input pin
				1	P81 output/FTIOA input pin

Legend X: Don't care.

P80/FTCI pin

Register	PCR8	
Bit Name	PCR80	Pin Function
Setting Value 0		P80 input/FTCI input pin
	1	P80 output/FTCI input pin

9.6 Port B

Port B is an input port also functioning as an A/D converter analog input pin. Each pin of the port B is shown in figure 9.6.

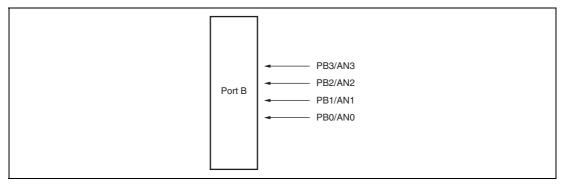


Figure 9.6 Port B Pin Configuration

Port B has the following register.

• Port data register B (PDRB)



9.6.1 Port Data Register B (PDRB)

PDRB is a general input-only port data register of port B.

Bit	Bit Name	Initial Value	R/W	Description
7 to 4	_	_	_	Reserved
3	PB3	_	R	The input value of each pin is read by reading this
2	PB2	_	R	register.
1	PB1	_	R	However, if a port B pin is designated as an analog input channel by ADCSR in A/D converter, 0 is read.
0	PB0		R	channel by ADCSh in A/D converter, 0 is read.

Section 10 Timer V

Timer V is an 8-bit timer based on an 8-bit counter. Timer V counts external events. Comparematch signals with two registers can also be used to reset the counter, request an interrupt, or output a pulse signal with an arbitrary duty cycle. Counting can be initiated by a trigger input at the TRGV pin, enabling pulse output control to be synchronized to the trigger, with an arbitrary delay from the trigger input. Figure 10.1 shows a block diagram of timer V.

10.1 Features

- Choice of seven clock signals is available.
 Choice of six internal clock sources (φ/128, φ/64, φ/32, φ/16, φ/8, φ/4) or an external clock.
- Counter can be cleared by compare match A or B, or by an external reset signal. If the count stop function is selected, the counter can be halted when cleared.
- Timer output is controlled by two independent compare match signals, enabling pulse output with an arbitrary duty cycle, PWM output, and other applications.
- Three interrupt sources: compare match A, compare match B, timer overflow
- Counting can be initiated by trigger input at the TRGV pin. The rising edge, falling edge, or both edges of the TRGV input can be selected.



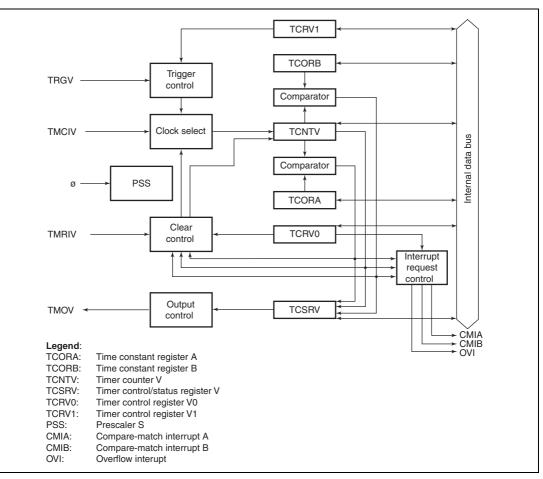


Figure 10.1 Block Diagram of Timer V

10.2 Input/Output Pins

Table 10.1 shows the timer V pin configuration.

Table 10.1 Pin Configuration

Name	Abbreviation	n I/O	Function
Timer V output	TMOV	Output	Timer V waveform output
Timer V clock input	TMCIV	Input	Clock input to TCNTV
Timer V reset input	TMRIV	Input	External input to reset TCNTV
Trigger input	TRGV	Input	Trigger input to initiate counting

10.3 Register Descriptions

Time V has the following registers.

- Timer counter V (TCNTV)
- Timer constant register A (TCORA)
- Timer constant register B (TCORB)
- Timer control register V0 (TCRV0)
- Timer control/status register V (TCSRV)
- Timer control register V1 (TCRV1)

10.3.1 Timer Counter V (TCNTV)

TCNTV is an 8-bit up-counter. The clock source is selected by bits CKS2 to CKS0 in timer control register V0 (TCRV0). The TCNTV value can be read and written by the CPU at any time. TCNTV can be cleared by an external reset input signal, or by compare match A or B. The clearing signal is selected by bits CCLR1 and CCLR0 in TCRV0.

When TCNTV overflows, OVF is set to 1 in timer control/status register V (TCSRV).

TCNTV is initialized to H'00.



10.3.2 Time Constant Registers A and B (TCORA, TCORB)

TCORA and TCORB have the same function.

TCORA and TCORB are 8-bit read/write registers.

TCORA and TCNTV are compared at all times. When the TCORA and TCNTV contents match, CMFA is set to 1 in TCSRV. If CMIEA is also set to 1 in TCRV0, a CPU interrupt is requested. Note that they must not be compared during the T3 state of a TCORA write cycle.

Timer output from the TMOV pin can be controlled by the identifying signal (compare match A) and the settings of bits OS3 to OS0 in TCSRV.

TCORA and TCORB are initialized to H'FF.



10.3.3 Timer Control Register V0 (TCRV0)

TCRV0 selects the input clock signals of TCNTV, specifies the clearing conditions of TCNTV, and controls each interrupt request.

Bit	Bit Name	Initial Value	R/W	Description
7	CMIEB	0	R/W	Compare Match Interrupt Enable B
				When this bit is set to 1, interrupt request from the CMFB bit in TCSRV is enabled.
6	CMIEA	0	R/W	Compare Match Interrupt Enable A
				When this bit is set to 1, interrupt request from the CMFA bit in TCSRV is enabled.
5	OVIE	0	R/W	Timer Overflow Interrupt Enable
				When this bit is set to 1, interrupt request from the OVF bit in TCSRV is enabled.
4	CCLR1	0	R/W	Counter Clear 1 and 0
3	CCLR0	0	R/W	These bits specify the clearing conditions of TCNTV.
				00: Clearing is disabled
				01: Cleared by compare match A
				10: Cleared by compare match B
				 Cleared on the rising edge of the TMRIV pin. The operation of TCNTV after clearing depends on TRGE in TCRV1.
2	CKS2	0	R/W	Clock Select 2 to 0
1	CKS1	0	R/W	These bits select clock signals to input to TCNTV and the
0	CKS0	0	R/W	counting condition in combination with ICKS0 in TCRV1.
				Refer to table 10.2.



TCRV0		TCRV1		
Bit 2	Bit 1	Bit 0	Bit 0	
CKS2	CKS1	CKS0	ICKS0	Description
0	0	0	_	Clock input prohibited
		1	0	Internal clock: counts on $\phi/4$, falling edge
			1	Internal clock: counts on $\phi/8$, falling edge
	1	0	0	Internal clock: counts on $\phi/16$, falling edge
			1	Internal clock: counts on $\phi/32$, falling edge
		1	0	Internal clock: counts on $\phi/64$, falling edge
			1	Internal clock: counts on $\phi/128$, falling edge
1	0	0		Clock input prohibited
		1		External clock: counts on rising edge
	1	0		External clock: counts on falling edge
		1		External clock: counts on rising and falling edge

Table 10.2 Clock Signals to Input to TCNTV and Counting Conditions

10.3.4 Timer Control/Status Register V (TCSRV)

TCSRV indicates the status flag and controls outputs by using a compare match.

		Initial		
Bit	Bit Name	Value	R/W	Description
7	CMFB	0	R/W	Compare Match Flag B
				Setting condition:
				When the TCNTV value matches the TCORB value
				Clearing condition:
				After reading CMFB = 1, cleared by writing 0 to CMFB
6	CMFA	0	R/W	Compare Match Flag A
				Setting condition:
				When the TCNTV value matches the TCORA value
				Clearing condition:
				After reading CMFA = 1, cleared by writing 0 to CMFA
5	OVF	0	R/W	Timer Overflow Flag
				Setting condition:
				When TCNTV overflows from H'FF to H'00
				Clearing condition:
				After reading OVF = 1, cleared by writing 0 to OVF
4		1		Reserved
				This bit is always read as 1.
3	OS3	0	R/W	Output Select 3 and 2
2	OS2	0	R/W	These bits select an output method for the TMOV pin by the compare match of TCORB and TCNTV.
				00: No change
				01: 0 output
				10: 1 output
				11: Output toggles



Bit	Bit Name	Initial Value	R/W	Description
1	OS1	0	R/W	Output Select 1 and 0
0	OS0	0	R/W	These bits select an output method for the TMOV pin by the compare match of TCORA and TCNTV.
				00: No change
				01: 0 output
				10: 1 output
				11: Output toggles

OS3 and OS2 select the output level for compare match B. OS1 and OS0 select the output level for compare match A. The two output levels can be controlled independently. After a reset, the timer output is 0 until the first compare match.

10.3.5 Timer Control Register V1 (TCRV1)

TCRV1 selects the edge at the TRGV pin, enables TRGV input, and selects the clock input to TCNTV.

Bit	Bit Name	Initial Value	R/W	Description
7 to 5		All 1		Reserved
				These bits are always read as 1.
4	TVEG1	0	R/W	TRGV Input Edge Select
3	TVEG0	0	R/W	These bits select the TRGV input edge.
				00: TRGV trigger input is prohibited
				01: Rising edge is selected
				10: Falling edge is selected
				11: Rising and falling edges are both selected
2	TRGE	0	R/W	TCNT starts counting up by the input of the edge which is selected by TVEG1 and TVEG0.
				0: Disables starting counting-up TCNTV by the input of the TRGV pin and halting counting-up TCNTV when TCNTV is cleared by a compare match.
				 Enables starting counting-up TCNTV by the input of the TRGV pin and halting counting-up TCNTV when TCNTV is cleared by a compare match.
1		1		Reserved
				This bit is always read as 1.
0	ICKS0	0	R/W	Internal Clock Select 0
				This bit selects clock signals to input to TCNTV in combination with CKS2 to CKS0 in TCRV0.
				Refer to table 10.2.



10.4 Operation

10.4.1 Timer V Operation

- According to table 10.2, six internal/external clock signals output by prescaler S can be selected as the timer V operating clock signals. When the operating clock signal is selected, TCNTV starts counting-up. Figure 10.2 shows the count timing with an internal clock signal selected, and figure 10.3 shows the count timing with both edges of an external clock signal selected.
- 2. When TCNTV overflows (changes from H'FF to H'00), the overflow flag (OVF) in TCRV0 will be set. The timing at this time is shown in figure 10.4. An interrupt request is sent to the CPU when OVIE in TCRV0 is 1.
- 3. TCNTV is constantly compared with TCORA and TCORB. Compare match flag A or B (CMFA or CMFB) is set to 1 when TCNTV matches TCORA or TCORB, respectively. The compare-match signal is generated in the last state in which the values match. Figure 10.5 shows the timing. An interrupt request is generated for the CPU when CMIEA or CMIEB in TCRV0 is 1.
- 4. When a compare match A or B is generated, the TMOV responds with the output value selected by bits OS3 to OS0 in TCSRV. Figure 10.6 shows the timing when the output is toggled by compare match A.
- 5. When CCLR1 or CCLR0 in TCRV0 is 01 or 10, TCNTV can be cleared by the corresponding compare match. Figure 10.7 shows the timing.
- 6. When CCLR1 or CCLR0 in TCRV0 is 11, TCNTV can be cleared by the rising edge of the input of TMRIV pin. A TMRIV input pulse-width of at least 1.5 system clocks is necessary. Figure 10.8 shows the timing.
- 7. When a counter-clearing source is generated with TRGE in TCRV1 set to 1, the counting-up is halted as soon as TCNTV is cleared. TCNTV resumes counting-up when the edge selected by TVEG1 or TVEG0 in TCRV1 is input from the TGRV pin.

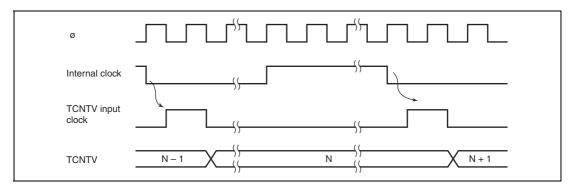


Figure 10.2 Increment Timing with Internal Clock

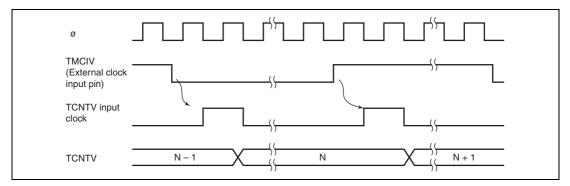


Figure 10.3 Increment Timing with External Clock

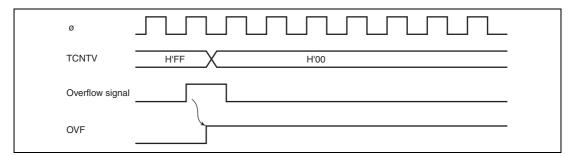
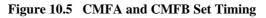


Figure 10.4 OVF Set Timing



ø				
TCNTV	Ν	_X	N+1	
TCORA or TCORB	Ν			
Compare match signal				
CMFA or				



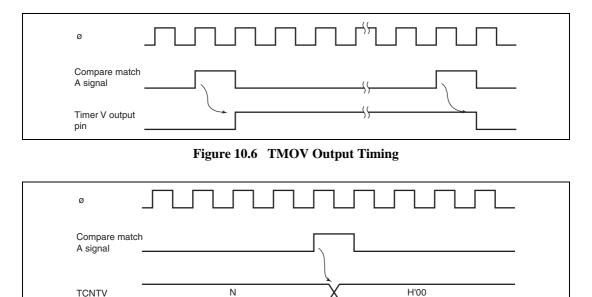


Figure 10.7 Clear Timing by Compare Match

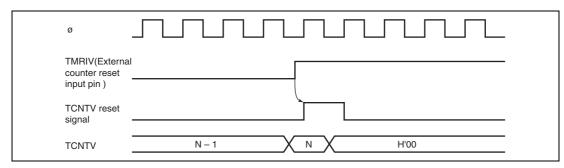


Figure 10.8 Clear Timing by TMRIV Input



10.5 Timer V Application Examples

10.5.1 Pulse Output with Arbitrary Duty Cycle

Figure 10.9 shows an example of output of pulses with an arbitrary duty cycle.

- 1. Set bits CCLR1 and CCLR0 in TCRV0 so that TCNTV will be cleared by compare match with TCORA.
- 2. Set bits OS3 to OS0 in TCSRV so that the output will go to 1 at compare match with TCORA and to 0 at compare match with TCORB.
- 3. Set bits CKS2 to CKS0 in TCRV0 and bit ICKS0 in TCRV1 to select the desired clock source.
- 4. With these settings, a waveform is output without further software intervention, with a period determined by TCORA and a pulse width determined by TCORB.

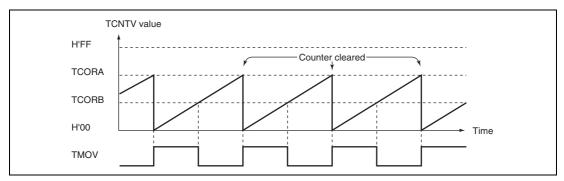


Figure 10.9 Pulse Output Example



10.5.2 Pulse Output with Arbitrary Pulse Width and Delay from TRGV Input

The trigger function can be used to output a pulse with an arbitrary pulse width at an arbitrary delay from the TRGV input, as shown in figure 10.10. To set up this output:

- 1. Set bits CCLR1 and CCLR0 in TCRV0 so that TCNTV will be cleared by compare match with TCORB.
- 2. Set bits OS3 to OS0 in TCSRV so that the output will go to 1 at compare match with TCORA and to 0 at compare match with TCORB.
- 3. Set bits TVEG1 and TVEG0 in TCRV1 and set TRGE to select the falling edge of the TRGV input.
- 4. Set bits CKS2 to CKS0 in TCRV0 and bit ICKS0 in TCRV1 to select the desired clock source.
- 5. After these settings, a pulse waveform will be output without further software intervention, with a delay determined by TCORA from the TRGV input, and a pulse width determined by (TCORB TCORA).

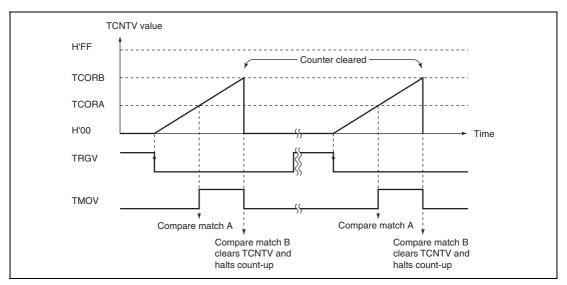


Figure 10.10 Example of Pulse Output Synchronized to TRGV Input



10.6 Usage Notes

The following types of contention or operation can occur in timer V operation.

- 1. Writing to registers is performed in the T3 state of a TCNTV write cycle. If a TCNTV clear signal is generated in the T3 state of a TCNTV write cycle, as shown in figure 10.11, clearing takes precedence and the write to the counter is not carried out. If counting-up is generated in the T3 state of a TCNTV write cycle, writing takes precedence.
- 2. If a compare match is generated in the T3 state of a TCORA or TCORB write cycle, the write to TCORA or TCORB takes precedence and the compare match signal is inhibited. Figure 10.12 shows the timing.
- 3. If compare matches A and B occur simultaneously, any conflict between the output selections for compare match A and compare match B is resolved by the following priority: toggle output > output 1 > output 0.
- 4. Depending on the timing, TCNTV may be incremented by a switch between different internal clock sources. When TCNTV is internally clocked, an increment pulse is generated from the falling edge of an internal clock signal, that is divided system clock (φ). Therefore, as shown in figure 10.3 the switch is from a high clock signal to a low clock signal, the switchover is seen as a falling edge, causing TCNTV to increment. TCNTV can also be incremented by a switch between internal and external clocks.

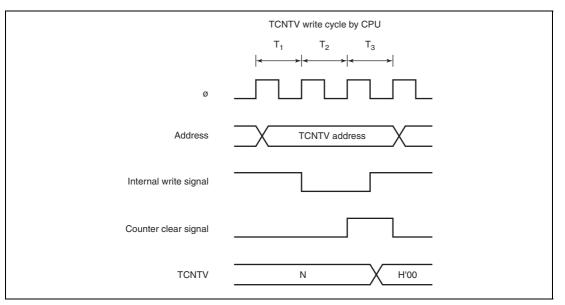


Figure 10.11 Contention between TCNTV Write and Clear

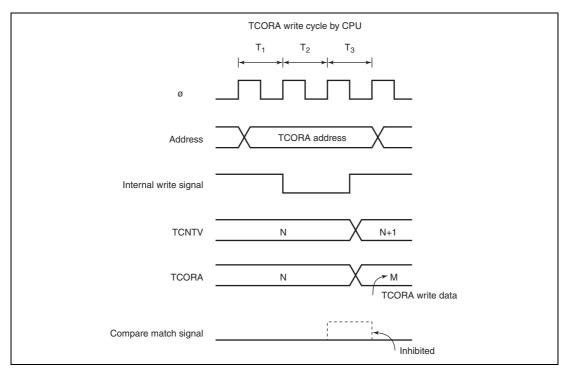


Figure 10.12 Contention between TCORA Write and Compare Match

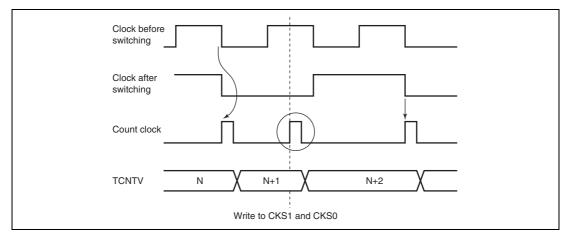
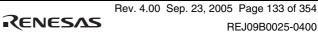


Figure 10.13 Internal Clock Switching and TCNTV Operation





Section 11 Timer W

The timer W has a 16-bit timer having output compare and input capture functions. The timer W can count external events and output pulses with an arbitrary duty cycle by compare match between the timer counter and four general registers. Thus, it can be applied to various systems.

11.1 Features

- Selection of five counter clock sources: four internal clocks (ϕ , $\phi/2$, $\phi/4$, and $\phi/8$) and an external clock (external events can be counted)
- Capability to process up to four pulse outputs or four pulse inputs
- Four general registers:
 - Independently assignable output compare or input capture functions
 - Usable as two pairs of registers; one register of each pair operates as a buffer for the output compare or input capture register
- Four selectable operating modes :
 - Waveform output by compare match
 - Selection of 0 output, 1 output, or toggle output
 - Input capture function
 - Rising edge, falling edge, or both edges
 - Counter clearing function
 - Counters can be cleared by compare match
 - PWM mode
 - Up to three-phase PWM output can be provided with desired duty ratio.
- Any initial timer output value can be set
- Five interrupt sources

Four compare match/input capture interrupts and an overflow interrupt.

Table 11.1 summarizes the timer W functions, and figure 11.1 shows a block diagram of the timer W.



Table 11.1 Timer W Functions

				Input/O	utput Pins		
ltem		Counter	FTIOA	FTIOB	FTIOC	FTIOD	
Count clock			Internal clocks: φ, φ/2, φ/4, φ/8 External clock: FTCI				
General registers (output compare/input capture registers)		Period specified in GRA	GRA	GRB	GRC (buffer register for GRA in buffer mode)	GRD (buffer register for GRB in buffer mode)	
Counter clearing function		GRA compare match	GRA compare match	_	_	_	
Initial output value setting function		_	Yes	Yes	Yes	Yes	
Buffer function		—	Yes	Yes	—	_	
Compare	0	_	Yes	Yes	Yes	Yes	
match output	1	_	Yes	Yes	Yes	Yes	
	Toggle	—	Yes	Yes	Yes	Yes	
Input capture function		_	Yes	Yes	Yes	Yes	
PWM mode		_	_	Yes	Yes	Yes	
Interrupt sources		Overflow	Compare match/input capture	Compare match/input capture	Compare match/input capture	Compare match/input capture	

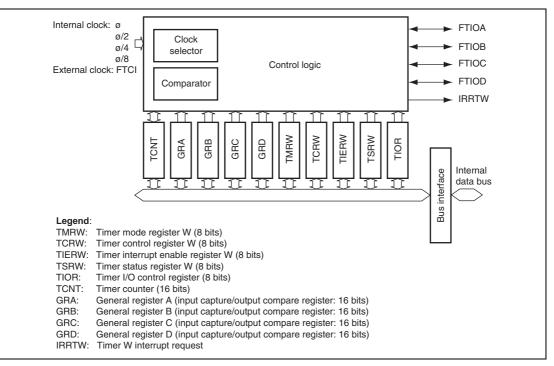


Figure 11.1 Timer W Block Diagram



11.2 Input/Output Pins

Table 11.2 summarizes the timer W pins.

Table 11.2 Pin Configuration

Name	Abbreviation	Input/Output	Function
External clock input	FTCI	Input	External clock input pin
Input capture/output compare A	FTIOA	Input/output	Output pin for GRA output compare or input pin for GRA input capture
Input capture/output compare B	FTIOB	Input/output	Output pin for GRB output compare, input pin for GRB input capture, or PWM output pin in PWM mode
Input capture/output compare C	FTIOC	Input/output	Output pin for GRC output compare, input pin for GRC input capture, or PWM output pin in PWM mode
Input capture/output compare D	FTIOD	Input/output	Output pin for GRD output compare, input pin for GRD input capture, or PWM output pin in PWM mode

11.3 Register Descriptions

The timer W has the following registers.

- Timer mode register W (TMRW)
- Timer control register W (TCRW)
- Timer interrupt enable register W (TIERW)
- Timer status register W (TSRW)
- Timer I/O control register 0 (TIOR0)
- Timer I/O control register 1 (TIOR1)
- Timer counter (TCNT)
- General register A (GRA)
- General register B (GRB)
- General register C (GRC)
- General register D (GRD)

11.3.1 Timer Mode Register W (TMRW)

TMRW selects the general register functions and the timer output mode.

Bit	Bit Name	Initial Value	R/W	Description
7	CTS	0	R/W	Counter Start
				The counter operation is halted when this bit is 0, while it can be performed when this bit is 1.
6	_	1	_	Reserved
				This bit is always read as 1.
5	BUFEB	0	R/W	Buffer Operation B
				Selects the GRD function.
				0: GRD operates as an input capture/output compare register
				1: GRD operates as the buffer register for GRB
4	BUFEA	0	R/W	Buffer Operation A
				Selects the GRC function.
				0: GRC operates as an input capture/output compare register
				1: GRC operates as the buffer register for GRA
3	_	1	_	Reserved
				This bit is always read as 1.
2	PWMD	0	R/W	PWM Mode D
				Selects the output mode of the FTIOD pin.
				0: FTIOD operates normally (output compare output)
				1: PWM output
1	PWMC	0	R/W	PWM Mode C
				Selects the output mode of the FTIOC pin.
				0: FTIOC operates normally (output compare output)
				1: PWM output
0	PWMB	0	R/W	PWM Mode B
				Selects the output mode of the FTIOB pin.
				0: FTIOB operates normally (output compare output)
				1: PWM output



11.3.2 Timer Control Register W (TCRW)

TCRW selects the timer counter clock source, selects a clearing condition, and specifies the timer output levels.

7 CCLR 0 R/W Counter Clear The TCNT value is cleared by compare match A when this bit is 1. When it is 0, TCNT operates as a free-running counter. 6 6 CKS2 0 R/W Clock Select 2 to 0 5 CKS1 0 R/W Select the TCNT clock source. 4 CKS0 0 R/W Select the TCNT clock source. 4 CKS0 0 R/W 000: Internal clock: counts on $\phi/2$ 010: Internal clock: counts on $\phi/4$ 011: Internal clock: counts on $\phi/4$ 011: Internal clock: counts on $\phi/8$ 1XX: Counts on rising edges of the external event (FTCI) When the internal clock source (ϕ) is selected, subclock sources are counted in subactive and subsleep modes. 3 TOD 0 R/W Timer Output Level Setting D Sets the output value of the FTIOD pin until the first compare match D is generated. 0: Output value is 0* 1 TOB 0 R/W Timer Output Level Setting B Sets the output value is 0* 1: Output value is 0* 1: Output value is 0* 1 TOB R/W Timer Output Level Setting B Sets the output value is 0* 1: Output value is 0* 1: Output value is 0* <th>Bit</th> <th>Bit Name</th> <th>Initial Value</th> <th>R/W</th> <th>Description</th>	Bit	Bit Name	Initial Value	R/W	Description
 this bit is 1. When it is 0, TCNT operates as a free- running counter. CKS2 0 R/W Clock Select 2 to 0 CKS1 0 R/W Select the TCNT clock source. CKS0 0 R/W 000: Internal clock: counts on φ 001: Internal clock: counts on φ/2 010: Internal clock: counts on φ/4 011: Internal clock: counts on φ/8 1 TOB 0 R/W Timer Output Level Setting B Sets the output value is 1* TOB 0 R/W Timer Output Level Setting B Sets the output value is 0* 1 TOB 0 R/W Timer Output Level Setting B Sets the output value is 1* COULPUT value is 0* OUTPUT value is 0* 	7	CCLR	0	R/W	Counter Clear
5 CKS1 0 R/W Select the TCNT clock source. 4 CKS0 0 R/W 000: Internal clock: counts on \$\u00e9 4 CKS0 0 R/W 000: Internal clock: counts on \$\u00e9 011: Internal clock: counts on \$\u00e9/2 010: Internal clock: counts on \$\u00e9/2 010: Internal clock: counts on \$\u00e9/2 1 TOD 0 R/W Timer Output Level Setting D Sets the output value is 0* 1: Output value is 0* 1: Output value is 1* 2 TOC 0 R/W Timer Output Level Setting C Sets the output value is 0* 1: Output value is 0* 1: Output value is 0* 1 TOB 0 R/W Timer Output Level Setting B Sets the output value is 0* 1: Output value is 0* 1: Output value is 0* 1 TOB 0 R/W Timer Output Level Setting B Sets the output value is 0* 1: Output value is 0* 1: Output value is 0* 1 TOB R/W Timer Output Level Setting B Sets the output value of the FTIOB pin until the first compare match B is generated. 0: Output value is 0*					this bit is 1. When it is 0, TCNT operates as a free-
4 CKS0 0 R/W 000: Internal clock: counts on \$ 001: Internal clock: counts on \$ 001: Internal clock: counts on \$ 011: Internal clock: counts on \$ 011: Internal clock: counts on \$ 011: Internal clock: counts on \$ 011: Internal clock: counts on \$ 1 TOB 0 R/W Timer Output Level Setting B 2 TOB 0 R/W Timer Output Level Setting C 2 TOC 0 R/W Timer Output Level Setting C 2 TOC 0 R/W Timer Output Level Setting C 3 TOD R/W Timer Output Level Setting C 3 TOC 0 R/W Timer Output Level Setting C 3 Sets the output value is 1* 1 OUTC 0 2 TOC 0 R/W Timer Output Level Setting C 3 Sets the output value of the FTIOC pin until the first compare match C is generated. 0: Output value is 0* 1 TOB 0 R/W Timer Output Level Setting B Sets the output value is 1* 1 TOB R/W Timer Output Level Setting B Sets the output val	6	CKS2	0	R/W	Clock Select 2 to 0
001: Internal clock: counts on \$\u03c6/2 001: Internal clock: counts on \$\u03c6/2 010: Internal clock: counts on \$\u03c6/2 011: Internal clock: counts on \$\u03c6/2 01: Internal clock: counts on \$\u03c6/2 01: Internal clock: counts on \$\u03c6/2 02: Output value is 0* 1 TOB 0 R/W	5	CKS1	0	R/W	Select the TCNT clock source.
010: Internal clock: counts on \$\u03c6/4 011: Internal clock: counts on \$\u03c6/8 1XX: Counts on rising edges of the external event (FTCI) When the internal clock source (\$\u03c6) is selected, subclock sources are counted in subactive and subsleep modes. 3 TOD 0 R/W Timer Output Level Setting D Sets the output value of the FTIOD pin until the first compare match D is generated. 0: Output value is 0* 1: Output value is 1* 2 TOC 0 R/W Timer Output Level Setting C Sets the output value of the FTIOC pin until the first compare match C is generated. 0: Output value is 0* 1 TOB 0 R/W Timer Output Level Setting B Sets the output value is 1* 1 TOB 0 R/W 1 TOB 0 R/W Timer Output Level Setting B Sets the output value is 1* 1 COB Timer Output Level Setting B Sets the output value is 0* 1: Output value is 1* 1	4	CKS0	0	R/W	000: Internal clock: counts on ϕ
011: Internal clock: counts on \$\u03c6/8 1XX: Counts on rising edges of the external event (FTCI) When the internal clock source (\$\u03c6) is selected, subclock sources are counted in subactive and subsleep modes. 3 TOD 0 R/W Timer Output Level Setting D Sets the output value of the FTIOD pin until the first compare match D is generated. 0: Output value is 0* 1: Output value is 1* 2 TOC 0 R/W Timer Output Level Setting C Sets the output value of the FTIOC pin until the first compare match C is generated. 0: Output value is 0* 1 TOB 0 R/W 1 TOB 0 R/W 1 TOB 0 R/W 2 O R/W Timer Output Level Setting C Sets the output value is 1* 0 Output value is 0* 1: Output value is 0* 1: Output value is 1* 0 1 TOB 0 R/W Timer Output Level Setting B Sets the output value of the FTIOB pin until the first compare match B is generated. 0: Output value is 0*					001: Internal clock: counts on \phi/2
1XX: Counts on rising edges of the external event (FTCI) When the internal clock source (\$\phi\$) is selected, subclock sources are counted in subactive and subsleep modes. 3 TOD 0 R/W Timer Output Level Setting D Sets the output value of the FTIOD pin until the first compare match D is generated. 0: Output value is 0* 1: Output value is 1* 2 TOC 0 R/W Timer Output Level Setting C Sets the output value of the FTIOC pin until the first compare match C is generated. 0: Output value is 0* 1 TOB 0 R/W 1 TOB 0 R/W 1 TOB 0 R/W 1 OB R/W Timer Output Level Setting B Sets the output value is 0* 1: Output value is 1* 1 TOB 0 R/W 1 OB R/W Timer Output Level Setting B Sets the output value is 1* Sets the output value of the FTIOB pin until the first compare match B is generated. 0: Output value is 0* 0: Output value is 0*					010: Internal clock: counts on
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3 TOD 0 R/W Timer Output Level Setting D 3 TOD 0 R/W Timer Output Level Setting D Sets the output value of the FTIOD pin until the first compare match D is generated. 0: Output value is 0* 1: Output value is 1* 2 TOC 0 R/W Timer Output Level Setting C Sets the output value of the FTIOC pin until the first compare match C is generated. 0: Output value is 0* 1: Output value is 0* 1: Output value is 1* 1 TOB 0 R/W 1 TOB 0 R/W 1 TOB 0 R/W 2 OUtput value is 1* Sets the output value of the FTIOC pin until the first compare match C is generated. 0: Output value is 1* 1 1 TOB 0 R/W Timer Output Level Setting B Sets the output value of the FTIOB pin until the first compare match B is generated. 0: Output value is 0*					1XX: Counts on rising edges of the external event (FTCI)
Sets the output value of the FTIOD pin until the first compare match D is generated. 0: Output value is 0* 1: Output value is 1* 1: Output value is 1* 2 TOC 0 R/W Timer Output Level Setting C Sets the output value of the FTIOC pin until the first compare match C is generated. 0: Output value is 0* 1: Output value is 0* 1 TOB 0 R/W Timer Output Level Setting B Sets the output value is 1* Sets the output value is 1*					
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1: Output value is 1* 2 TOC 0 R/W Timer Output Level Setting C Sets the output value of the FTIOC pin until the first compare match C is generated. 0: Output value is 0* 1: Output value is 0* 1: Output value is 1* 1 TOB 0 R/W Timer Output Level Setting B Sets the output value of the FTIOB pin until the first compare match B is generated. 0: Output value is 0* 0: Output value is 0*					•
2 TOC 0 R/W Timer Output Level Setting C Sets the output value of the FTIOC pin until the first compare match C is generated. 0: Output value is 0* 1: Output value is 1* 1: Output value is 1* 1 TOB 0 R/W Sets the output value of the FTIOB pin until the first compare match B is generated. 0: Output value is 0* 0: Output value is 0* 0: Output value of the FTIOB pin until the first compare match B is generated. 0: Output value is 0* 0: Output value is 0*					0: Output value is 0*
Sets the output value of the FTIOC pin until the first compare match C is generated. 0: Output value is 0* 1: Output value is 1* 1: Output value is 1* 1 TOB 0 R/W Sets the output Level Setting B Sets the output value of the FTIOB pin until the first compare match B is generated. 0: Output value is 0* 0: Output value is 0*					1: Output value is 1*
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1 TOB 0 R/W Timer Output Level Setting B Sets the output value of the FTIOB pin until the first compare match B is generated. 0: Output value is 0*					
1 TOB 0 R/W Timer Output Level Setting B Sets the output value of the FTIOB pin until the first compare match B is generated. 0: Output value is 0*					0: Output value is 0*
Sets the output value of the FTIOB pin until the first compare match B is generated. 0: Output value is 0*					1: Output value is 1*
compare match B is generated. 0: Output value is 0*	1	ТОВ	0	R/W	Timer Output Level Setting B
· · · · · · · · · · · · · · · · · · ·					
1: Output value is 1*					0: Output value is 0*
					1: Output value is 1*

Bit	Bit Name	Initial Value	R/W	Description
0	TOA	0	R/W	Timer Output Level Setting A
				Sets the output value of the FTIOA pin until the first compare match A is generated.
				0: Output value is 0*
				1: Output value is 1*

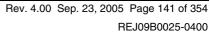
Legend X: Don't care.

Note: * The change of the setting is immediately reflected in the output value.

11.3.3 Timer Interrupt Enable Register W (TIERW)

TIERW controls the timer W interrupt request.

		Initial		
Bit	Bit Name	Value	R/W	Description
7	OVIE	0	R/W	Timer Overflow Interrupt Enable
				When this bit is set to 1, FOVI interrupt requested by OVF flag in TSRW is enabled.
6 to 4	_	All 1	—	Reserved
				These bits are always read as 1.
3	IMIED	0	R/W	Input Capture/Compare Match Interrupt Enable D
				When this bit is set to 1, IMID interrupt requested by IMFD flag in TSRW is enabled.
2	IMIEC	0	R/W	Input Capture/Compare Match Interrupt Enable C
				When this bit is set to 1, IMIC interrupt requested by IMFC flag in TSRW is enabled.
1	IMIEB	0	R/W	Input Capture/Compare Match Interrupt Enable B
				When this bit is set to 1, IMIB interrupt requested by IMFB flag in TSRW is enabled.
0	IMIEA	0	R/W	Input Capture/Compare Match Interrupt Enable A
				When this bit is set to 1, IMIA interrupt requested by IMFA flag in TSRW is enabled.



11.3.4 Timer Status Register W (TSRW)

TSRW shows the status of interrupt requests.

Bit	Bit Name	Initial Value	R/W	Description
7	OVF	0	R/W	Timer Overflow Flag
				[Setting condition]
				When TCNT overflows from H'FFFF to H'0000
				[Clearing condition]
				Read OVF when OVF = 1, then write 0 in OVF
6 to 4	_	All 1		Reserved
				These bits are always read as 1.
3	IMFD	0	R/W	Input Capture/Compare Match Flag D
				[Setting conditions]
				 TCNT = GRD when GRD functions as an output
				compare register
				• The TCNT value is transferred to GRD by an input
				capture signal when GRD functions as an input capture register
				[Clearing condition]
				Read IMFD when IMFD = 1, then write 0 in IMFD
2	IMFC	0	R/W	Input Capture/Compare Match Flag C
-		U		[Setting conditions]
				 TCNT = GRC when GRC functions as an output
				compare register
				The TCNT value is transferred to GRC by an input
				capture signal when GRC functions as an input
				capture register
				[Clearing condition]
				Read IMFC when IMFC = 1, then write 0 in IMFC

Bit	Bit Name	Initial Value	R/W	Description
1	IMFB	0	R/W	 Input Capture/Compare Match Flag B [Setting conditions] TCNT = GRB when GRB functions as an output compare register The TCNT value is transferred to GRB by an input capture signal when GRB functions as an input capture register
				[Clearing condition] Read IMFB when IMFB = 1, then write 0 in IMFB
0	IMFA	0	R/W	 Input Capture/Compare Match Flag A [Setting conditions] TCNT = GRA when GRA functions as an output compare register The TCNT value is transferred to GRA by an input capture signal when GRA functions as an input capture register [Clearing condition] Read IMFA when IMFA = 1, then write 0 in IMFA



11.3.5 Timer I/O Control Register 0 (TIOR0)

TIOR0 selects the functions of GRA and GRB, and specifies the functions of the FTIOA and FTIOB pins.

Bit	Bit Name	Initial Value	R/W	Description
7		1		Reserved
				This bit is always read as 1.
6	IOB2	0	R/W	I/O Control B2
				Selects the GRB function.
				0: GRB functions as an output compare register
				1: GRB functions as an input capture register
5	IOB1	0	R/W	I/O Control B1 and B0
4	IOB0	0	R/W	When IOB2 = 0,
				00: No output at compare match
				01: 0 output to the FTIOB pin at GRB compare match
				10: 1 output to the FTIOB pin at GRB compare match
				11: Output toggles to the FTIOB pin at GRB compare match
				When IOB2 = 1,
				00: Input capture at rising edge at the FTIOB pin
				01: Input capture at falling edge at the FTIOB pin
				1X: Input capture at rising and falling edges of the FTIOB pin
3		1		Reserved
				This bit is always read as 1.
2	IOA2	0	R/W	I/O Control A2
				Selects the GRA function.
				0: GRA functions as an output compare register
				1: GRA functions as an input capture register

Bit	Bit Name	Initial Value	R/W	Description
1	IOA1	0	R/W	I/O Control A1 and A0
0	IOA0	0	R/W	When $IOA2 = 0$,
				00: No output at compare match
				01: 0 output to the FTIOA pin at GRA compare match
				10: 1 output to the FTIOA pin at GRA compare match
				11: Output toggles to the FTIOA pin at GRA compare match
				When IOA2 = 1,
				00: Input capture at rising edge of the FTIOA pin
				01: Input capture at falling edge of the FTIOA pin
				1X: Input capture at rising and falling edges of the FTIOA pin

Legend X: Don't care.

11.3.6 Timer I/O Control Register 1 (TIOR1)

TIOR1 selects the functions of GRC and GRD, and specifies the functions of the FTIOC and FTIOD pins.

Bit	Bit Name	Initial Value	R/W	Description
7	—	1	_	Reserved
				This bit is always read as 1.
6	IOD2	0	R/W	I/O Control D2
				Selects the GRD function.
				0: GRD functions as an output compare register
				1: GRD functions as an input capture register



Bit	Bit Name	Initial Value	R/W	Description
5	IOD1	0	R/W	I/O Control D1 and D0
4	IOD0	0	R/W	When IOD2 = 0,
				00: No output at compare match
				01: 0 output to the FTIOD pin at GRD compare match
				10: 1 output to the FTIOD pin at GRD compare match
				11: Output toggles to the FTIOD pin at GRD compare match
				When IOD2 = 1,
				00: Input capture at rising edge at the FTIOD pin
				01: Input capture at falling edge at the FTIOD pin
				1X: Input capture at rising and falling edges at the FTIOD pin
3		1		Reserved
				This bit is always read as 1.
2	IOC2	0	R/W	I/O Control C2
				Selects the GRC function.
				0: GRC functions as an output compare register
				1: GRC functions as an input capture register
1	IOC1	0	R/W	I/O Control C1 and C0
0	IOC0	0	R/W	When IOC2 = 0,
				00: No output at compare match
				01: 0 output to the FTIOC pin at GRC compare match
				10: 1 output to the FTIOC pin at GRC compare match
				 Output toggles to the FTIOC pin at GRC compare match
				When IOC2 = 1,
				00: Input capture to GRC at rising edge of the FTIOC pin
				01: Input capture to GRC at falling edge of the FTIOC pin
				1X: Input capture to GRC at rising and falling edges of the FTIOC pin

Legend X: Don't care.

11.3.7 Timer Counter (TCNT)

TCNT is a 16-bit readable/writable up-counter. The clock source is selected by bits CKS2 to CKS0 in TCRW. TCNT can be cleared to H'0000 through a compare match with GRA by setting the CCLR in TCRW to 1. When TCNT overflows (changes from H'FFFF to H'0000), the OVF flag in TSRW is set to 1. If OVIE in TIERW is set to 1 at this time, an interrupt request is generated. TCNT must always be read or written in 16-bit units; 8-bit access is not allowed. TCNT is initialized to H'0000 by a reset.

11.3.8 General Registers A to D (GRA to GRD)

Each general register is a 16-bit readable/writable register that can function as either an outputcompare register or an input-capture register. The function is selected by settings in TIOR0 and TIOR1.

When a general register is used as an input-compare register, its value is constantly compared with the TCNT value. When the two values match (a compare match), the corresponding flag (IMFA, IMFB, IMFC, or IMFD) in TSRW is set to 1. An interrupt request is generated at this time, when IMIEA, IMIEB, IMIEC, or IMIED is set to 1. Compare match output can be selected in TIOR.

When a general register is used as an input-capture register, an external input-capture signal is detected and the current TCNT value is stored in the general register. The corresponding flag (IMFA, IMFB, IMFC, or IMFD) in TSRW is set to 1. If the corresponding interrupt-enable bit (IMIEA, IMIEB, IMIEC, or IMIED) in TSRW is set to 1 at this time, an interrupt request is generated. The edge of the input-capture signal is selected in TIOR.

GRC and GRD can be used as buffer registers of GRA and GRB, respectively, by setting BUFEA and BUFEB in TMRW.

For example, when GRA is set as an output-compare register and GRC is set as the buffer register for GRA, the value in the buffer register GRC is sent to GRA whenever compare match A is generated.

When GRA is set as an input-capture register and GRC is set as the buffer register for GRA, the value in TCNT is transferred to GRA and the value in the buffer register GRC is transferred to GRA whenever an input capture is generated.

GRA to GRD must be written or read in 16-bit units; 8-bit access is not allowed. GRA to GRD are initialized to H'FFFF by a reset.



11.4 Operation

The timer W has the following operating modes.

- Normal Operation
- PWM Operation

11.4.1 Normal Operation

TCNT performs free-running or periodic counting operations. After a reset, TCNT is set as a freerunning counter. When the CTS bit in TMRW is set to 1, TCNT starts incrementing the count. When the count overflows from H'FFFF to H'0000, the OVF flag in TSRW is set to 1. If the OVIE in TIERW is set to 1, an interrupt request is generated. Figure 11.2 shows free-running counting.

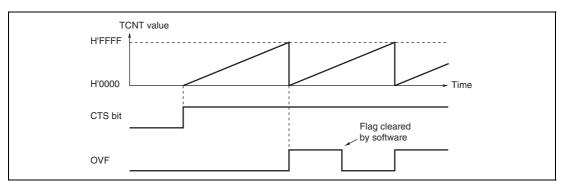
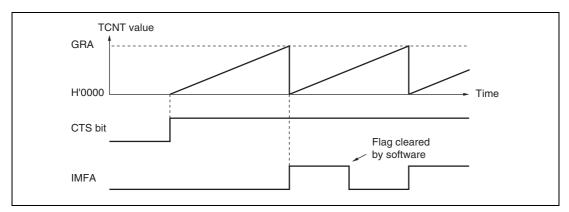


Figure 11.2 Free-Running Counter Operation



Periodic counting operation can be performed when GRA is set as an output compare register and bit CCLR in TCRW is set to 1. When the count matches GRA, TCNT is cleared to H'0000, the IMFA flag in TSRW is set to 1. If the corresponding IMIEA bit in TIERW is set to 1, an interrupt request is generated. TCNT continues counting from H'0000. Figure 11.3 shows periodic counting.





By setting a general register as an output compare register, compare match A, B, C, or D can cause the output at the FTIOA, FTIOB, FTIOC, or FTIOD pin to output 0, output 1, or toggle. Figure 11.4 shows an example of 0 and 1 output when TCNT operates as a free-running counter, 1 output is selected for compare match A, and 0 output is selected for compare match B. When signal is already at the selected output level, the signal level does not change at compare match.

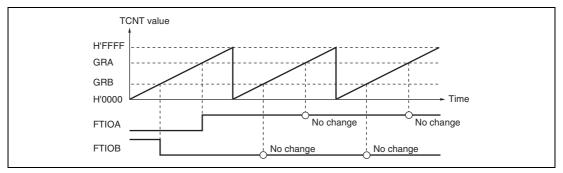


Figure 11.4 0 and 1 Output Example (TOA = 0, TOB = 1)

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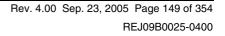


Figure 11.5 shows an example of toggle output when TCNT operates as a free-running counter, and toggle output is selected for both compare match A and B.

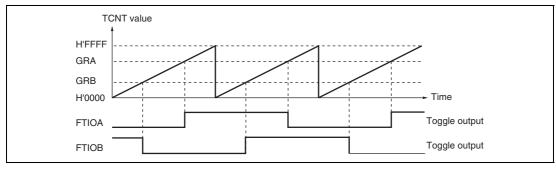


Figure 11.5 Toggle Output Example (TOA = 0, TOB = 1)

Figure 11.6 shows another example of toggle output when TCNT operates as a periodic counter, cleared by compare match A. Toggle output is selected for both compare match A and B.

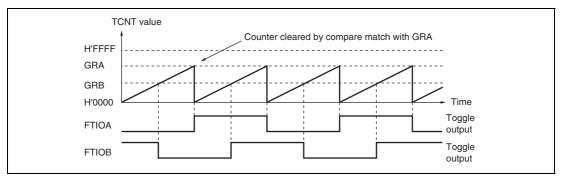


Figure 11.6 Toggle Output Example (TOA = 0, TOB = 1)

The TCNT value can be captured into a general register (GRA, GRB, GRC, or GRD) when a signal level changes at an input-capture pin (FTIOA, FTIOB, FTIOC, or FTIOD). Capture can take place on the rising edge, falling edge, or both edges. By using the input-capture function, the pulse width and periods can be measured. Figure 11.7 shows an example of input capture when both edges of FTIOA and the falling edge of FTIOB are selected as capture edges. TCNT operates as a free-running counter.

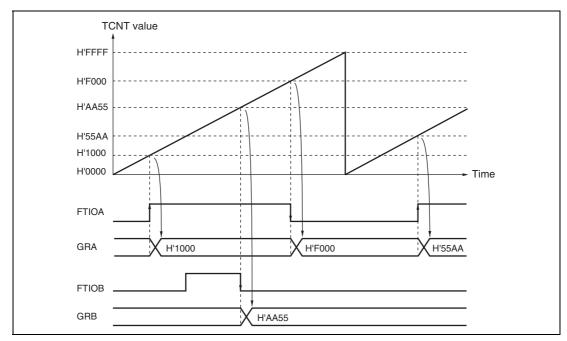


Figure 11.7 Input Capture Operating Example



Figure 11.8 shows an example of buffer operation when the GRA is set as an input-capture register and GRC is set as the buffer register for GRA. TCNT operates as a free-running counter, and FTIOA captures both rising and falling edge of the input signal. Due to the buffer operation, the GRA value is transferred to GRC by input-capture A and the TCNT value is stored in GRA.

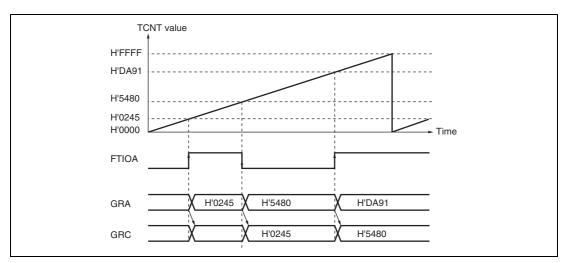


Figure 11.8 Buffer Operation Example (Input Capture)



11.4.2 PWM Operation

In PWM mode, PWM waveforms are generated by using GRA as the period register and GRB, GRC, and GRD as duty registers. PWM waveforms are output from the FTIOB, FTIOC, and FTIOD pins. Up to three-phase PWM waveforms can be output. In PWM mode, a general register functions as an output compare register automatically. The output level of each pin depends on the corresponding timer output level set bit (TOB, TOC, and TOD) in TCRW. When TOB is 1, the FTIOB output goes to 1 at compare match A and to 0 at compare match B. When TOB is 0, the FTIOB output goes to 0 at compare match A and to 1 at compare match B. Thus the compare match output level settings in TIOR0 and TIOR1 are ignored for the output pin set to PWM mode. If the same value is set in the cycle register and the duty register, the output does not change when a compare match occurs.

Figure 11.9 shows an example of operation in PWM mode. The output signals go to 1 and TCNT is cleared at compare match A, and the output signals go to 0 at compare match B, C, and D (TOB, TOC, and TOD = 1: initial output values are set to 1).

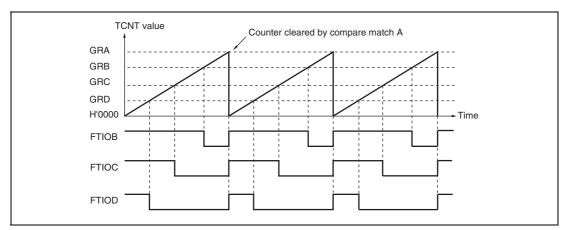


Figure 11.9 PWM Mode Example (1)



Figure 11.10 shows another example of operation in PWM mode. The output signals go to 0 and TCNT is cleared at compare match A, and the output signals go to 1 at compare match B, C, and D (TOB, TOC, and TOD = 0: initial output values are set to 1).

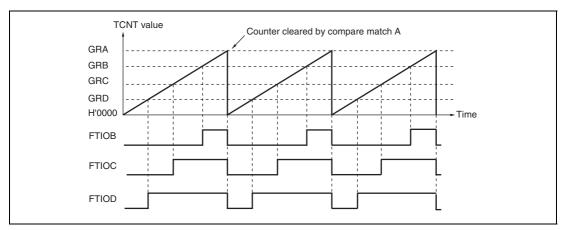


Figure 11.10 PWM Mode Example (2)



Figure 11.11 shows an example of buffer operation when the FTIOB pin is set to PWM mode and GRD is set as the buffer register for GRB. TCNT is cleared by compare match A, and FTIOB outputs 1 at compare match B and 0 at compare match A.

Due to the buffer operation, the FTIOB output level changes and the value of buffer register GRD is transferred to GRB whenever compare match B occurs. This procedure is repeated every time compare match B occurs.

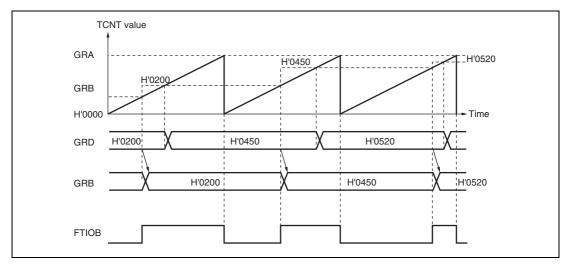
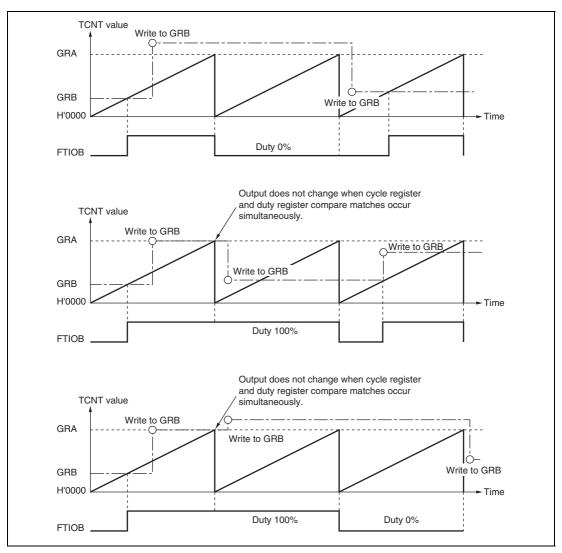


Figure 11.11 Buffer Operation Example (Output Compare)





Figures 11.12 and 11.13 show examples of the output of PWM waveforms with duty cycles of 0% and 100%.

Figure 11.12 PWM Mode Example (TOB, TOC, and TOD = 0: initial output values are set to 0)

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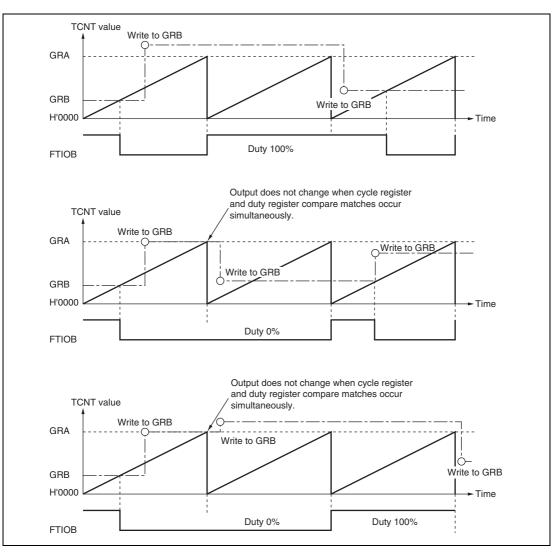


Figure 11.13 PWM Mode Example (TOB, TOC, and TOD = 1: initial output values are set to 1)



11.5 Operation Timing

11.5.1 TCNT Count Timing

Figure 11.14 shows the TCNT count timing when the internal clock source is selected. Figure 11.15 shows the timing when the external clock source is selected. The pulse width of the external clock signal must be at least two system clock (ϕ) cycles; shorter pulses will not be counted correctly.

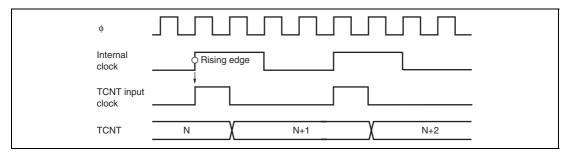


Figure 11.14 Count Timing for Internal Clock Source

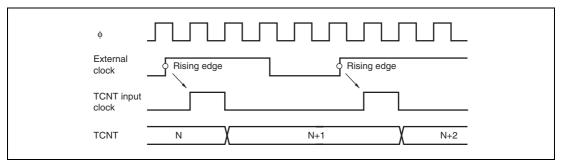


Figure 11.15 Count Timing for External Clock Source

11.5.2 Output Compare Output Timing

The compare match signal is generated in the last state in which TCNT and GR match (when TCNT changes from the matching value to the next value). When the compare match signal is generated, the output value selected in TIOR is output at the compare match output pin (FTIOA, FTIOB, FTIOC, or FTIOD).

When TCNT matches GR, the compare match signal is generated only after the next counter clock pulse is input.

Figure 11.16 shows the output compare timing.

φ		
TCNT input clock		
TCNT	N X N+1	
GRA to GRD	Ν	
Compare match signal		
FTIOA to FTIOD	χ	

Figure 11.16 Output Compare Output Timing



11.5.3 Input Capture Timing

Input capture on the rising edge, falling edge, or both edges can be selected through settings in TIOR0 and TIOR1. Figure 11.17 shows the timing when the falling edge is selected. The pulse width of the input capture signal must be at least two system clock (ϕ) cycles; shorter pulses will not be detected correctly.

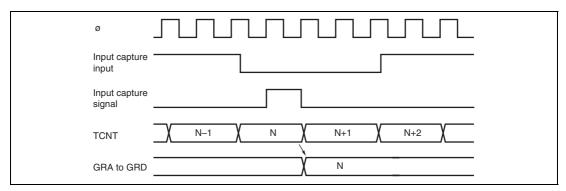


Figure 11.17 Input Capture Input Signal Timing

11.5.4 Timing of Counter Clearing by Compare Match

Figure 11.18 shows the timing when the counter is cleared by compare match A. When the GRA value is N, the counter counts from 0 to N, and its cycle is N + 1.

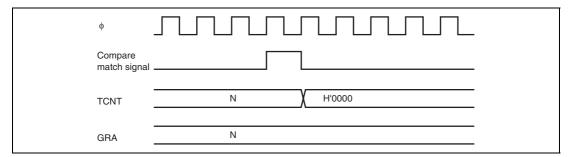
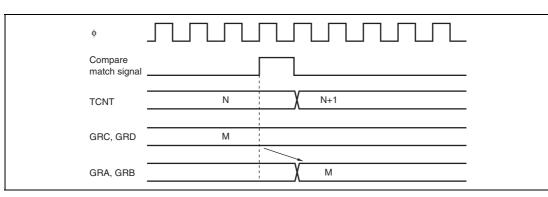


Figure 11.18 Timing of Counter Clearing by Compare Match

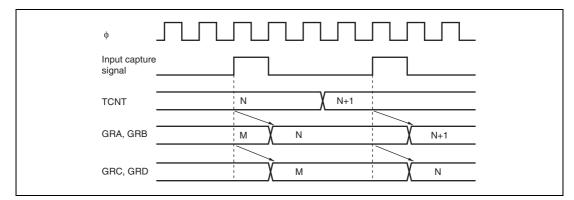
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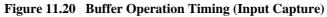
11.5.5 Buffer Operation Timing



Figures 11.19 and 11.20 show the buffer operation timing.







11.5.6 Timing of IMFA to IMFD Flag Setting at Compare Match

If a general register (GRA, GRB, GRC, or GRD) is used as an output compare register, the corresponding IMFA, IMFB, IMFC, or IMFD flag is set to 1 when TCNT matches the general register.

The compare match signal is generated in the last state in which the values match (when TCNT is updated from the matching count to the next count). Therefore, when TCNT matches a general register, the compare match signal is generated only after the next TCNT clock pulse is input.

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Figure 11.21 shows the timing of the IMFA to IMFD flag setting at compare match.

Figure 11.21 Timing of IMFA to IMFD Flag Setting at Compare Match

11.5.7 Timing of IMFA to IMFD Setting at Input Capture

If a general register (GRA, GRB, GRC, or GRD) is used as an input capture register, the corresponding IMFA, IMFB, IMFC, or IMFD flag is set to 1 when an input capture occurs. Figure 11.22 shows the timing of the IMFA to IMFD flag setting at input capture.

φ		
Input capture signal		
TCNT	Ν	
GRA to GRD	N	
IMFA to IMFD		
IRRTW		

Figure 11.22 Timing of IMFA to IMFD Flag Setting at Input Capture

11.5.8 Timing of Status Flag Clearing

When the CPU reads a status flag while it is set to 1, then writes 0 in the status flag, the status flag is cleared. Figure 11.23 shows the status flag clearing timing.

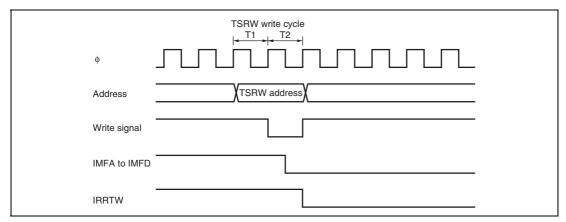


Figure 11.23 Timing of Status Flag Clearing by CPU

11.6 Usage Notes

The following types of contention or operation can occur in timer W operation.

- 1. The pulse width of the input clock signal and the input capture signal must be at least two system clock (ϕ) cycles; shorter pulses will not be detected correctly.
- 2. Writing to registers is performed in the T2 state of a TCNT write cycle.

If counter clear signal occurs in the T2 state of a TCNT write cycle, clearing of the counter takes priority and the write is not performed, as shown in figure 11.24. If counting-up is generated in the TCNT write cycle to contend with the TCNT counting-up, writing takes precedence.

- 3. Depending on the timing, TCNT may be incremented by a switch between different internal clock sources. When TCNT is internally clocked, an increment pulse is generated from the rising edge of an internal clock signal, that is divided system clock (φ). Therefore, as shown in figure 11.25 the switch is from a low clock signal to a high clock signal, the switchover is seen as a rising edge, causing TCNT to increment.
- 4. If timer W enters module standby mode while an interrupt request is generated, the interrupt request cannot be cleared. Before entering module standby mode, disable interrupt requests.



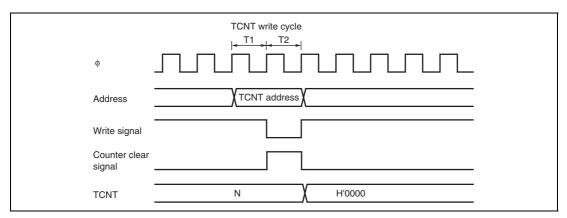


Figure 11.24 Contention between TCNT Write and Clear

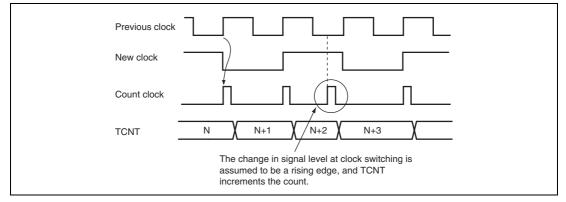


Figure 11.25 Internal Clock Switching and TCNT Operation

5. The TOA to TOD bits in TCRW decide the value of the FTIO pin, which is output until the first compare match occurs. Once a compare match occurs and this compare match changes the values of FTIOA to FTIOD output, the values of the FTIOA to FTIOD pin output and the values read from the TOA to TOD bits may differ. Moreover, when the writing to TCRW and the generation of the compare match A to D occur at the same timing, the writing to TCRW has the priority. Thus, output change due to the compare match is not reflected to the FTIOA to FTIOD pins. Therefore, when bit manipulation instruction is used to write to TCRW, the values of the FTIOA to FTIOD pin output may result in an unexpected result. When TCRW is to be written to while compare match is operating, stop the counter once before accessing to TCRW, read the port 8 state to reflect the values of FTIOA to FTIOD output, to TOA to TOD, and then restart the counter. Figure 11.26 shows an example when the compare match and the bit manipulation instruction to TCRW occur at the same timing.

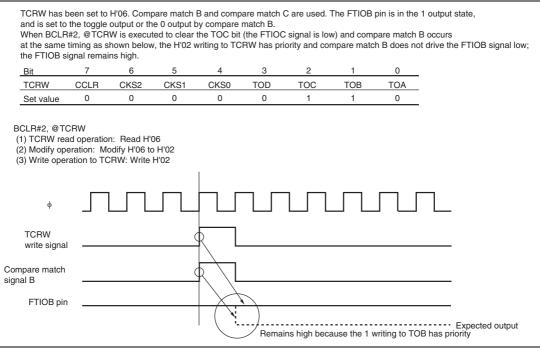


Figure 11.26 When Compare Match and Bit Manipulation Instruction to TCRW Occur at the Same Timing





Section 12 Watchdog Timer

The watchdog timer is an 8-bit timer that can generate an internal reset signal for this LSI if a system crash prevents the CPU from writing to the timer counter, thus allowing it to overflow.

The block diagram of the watchdog timer is shown in figure 12.1.

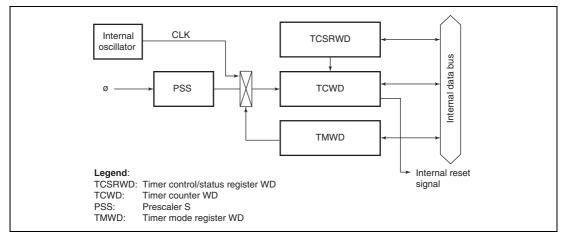


Figure 12.1 Block Diagram of Watchdog Timer

12.1 Features

• Selectable from nine counter input clocks.

Eight clock sources ($\phi/64$, $\phi/128$, $\phi/256$, $\phi/512$, $\phi/1024$, $\phi/2048$, $\phi/4096$, and $\phi/8192$) or the internal oscillator can be selected as the timer-counter clock. When the internal oscillator is selected, it can operate as the watchdog timer in any operating mode.

Reset signal generated on counter overflow
 An overflow period of 1 to 256 times the selected clock can be set.



12.2 Register Descriptions

The watchdog timer has the following registers.

- Timer control/status register WD (TCSRWD)
- Timer counter WD (TCWD)
- Timer mode register WD (TMWD)

12.2.1 Timer Control/Status Register WD (TCSRWD)

TCSRWD performs the TCSRWD and TCWD write control. TCSRWD also controls the watchdog timer operation and indicates the operating state. TCSRWD must be rewritten by using the MOV instruction. The bit manipulation instruction cannot be used to change the setting value.

Bit	Bit Name	Initial Value	R/W	Description
7	B6WI	1	R/W	Bit 6 Write Inhibit
				The TCWE bit can be written only when the write value of the B6WI bit is 0.
				This bit is always read as 1.
6	TCWE	0	R/W	Timer Counter WD Write Enable
				TCWD can be written when the TCWE bit is set to 1.
				When writing data to this bit, the value for bit 7 must be 0.
5	B4WI	1	R/W	Bit 4 Write Inhibit
				The TCSRWE bit can be written only when the write value of the B4WI bit is 0. This bit is always read as 1.
4	TCSRWE	0	R/W	Timer Control/Status Register WD Write Enable
				The WDON and WRST bits can be written when the TCSRWE bit is set to 1.
				When writing data to this bit, the value for bit 5 must be 0.
3	B2WI	1	R/W	Bit 2 Write Inhibit
				This bit can be written to the WDON bit only when the write value of the B2WI bit is 0.
				This bit is always read as 1.

Bit	Bit Name	Initial Value	R/W	Description
2	WDON	0	R/W	Watchdog Timer On
				TCWD starts counting up when WDON is set to 1 and halts when WDON is cleared to 0.
				[Setting condition]
				When 1 is written to the WDON bit while writing 0 to the B2WI bit when the TCSRWE bit=1
				[Clearing condition]
				Reset by RES pin
				 When 0 is written to the WDON bit while writing 0 to the B2WI when the TCSRWE bit=1
1	B0WI	1	R/W	Bit 0 Write Inhibit
				This bit can be written to the WRST bit only when the write value of the B0WI bit is 0. This bit is always read as 1.
0	WRST	0	R/W	Watchdog Timer Reset
				[Setting condition]
				When TCWD overflows and an internal reset signal is generated
				[Clearing condition]
				Reset by RES pin
				 When 0 is written to the WRST bit while writing 0 to the B0WI bit when the TCSRWE bit=1

12.2.2 Timer Counter WD (TCWD)

TCWD is an 8-bit readable/writable up-counter. When TCWD overflows from H'FF to H'00, the internal reset signal is generated and the WRST bit in TCSRWD is set to 1. TCWD is initialized to H'00.

12.2.3 Timer Mode Register WD (TMWD)

TMWD selects the input clock.

Bit	Bit Name	Initial Value	R/W	Description
7 to 4	_	All 1		Reserved
				These bits are always read as 1.
3	CKS3	1	R/W	Clock Select 3 to 0
2	CKS2	1	R/W	Select the clock to be input to TCWD.
1	CKS1	1	R/W	1000: Internal clock: counts on $\phi/64$
0	CKS0	1	R/W	1001: Internal clock: counts on $\phi/128$
				1010: Internal clock: counts on $\phi/256$
				1011: Internal clock: counts on $\phi/512$
				1100: Internal clock: counts on $\phi/1024$
				1101: Internal clock: counts on $\phi/2048$
				1110: Internal clock: counts on $\phi/4096$
				1111: Internal clock: counts on ϕ 8192
				0XXX: Internal oscillator
				For the internal oscillator overflow periods, see section 18, Electrical Characteristics.

Legend X: Don't care.

12.3 Operation

The watchdog timer is provided with an 8-bit counter. If 1 is written to WDON while writing 0 to B2WI when the TCSRWE bit in TCSRWD is set to 1, TCWD begins counting up. (To operate the watchdog timer, two write accesses to TCSRWD are required.) When a clock pulse is input after the TCWD count value has reached H'FF, the watchdog timer overflows and an internal reset signal is generated. The internal reset signal is output for a period of 256 ϕ_{osc} clock cycles. TCWD is a writable counter, and when a value is set in TCWD, the count-up starts from that value. An overflow period in the range of 1 to 256 input clock cycles can therefore be set, according to the TCWD set value.

Figure 12.2 shows an example of watchdog timer operation.

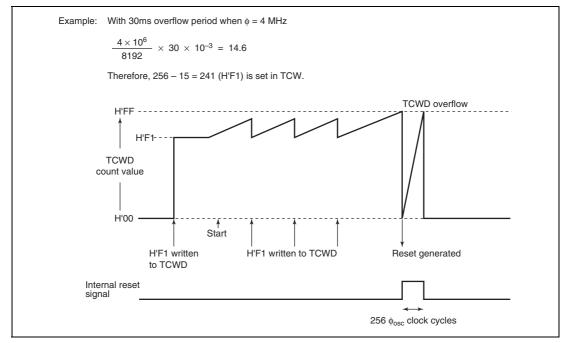


Figure 12.2 Watchdog Timer Operation Example





Section 13 Serial Communication Interface 3 (SCI3)

This LSI includes a serial communication interface 3 (SCI3). The SCI3 can handle both asynchronous and clocked synchronous serial communication. In asynchronous mode, serial data communication can be carried out using standard asynchronous communication chips such as a Universal Asynchronous Receiver/Transmitter (UART) or an Asynchronous Communication Interface Adapter (ACIA). A function is also provided for serial communication between processors (multiprocessor communication function).

Table 13.1 shows the SCI3 channel configuration and figure 13.1 shows a block diagram of the SCI3. Since pin functions are identical for each of the two channels (SCI3 and SCI3_2), separate explanations are not given in this section.

13.1 Features

- Choice of asynchronous or clocked synchronous serial communication mode
- Full-duplex communication capability

The transmitter and receiver are mutually independent, enabling transmission and reception to be executed simultaneously.

Double-buffering is used in both the transmitter and the receiver, enabling continuous transmission and continuous reception of serial data.

- On-chip baud rate generator allows any bit rate to be selected
- External clock or on-chip baud rate generator can be selected as a transfer clock source.
- Six interrupt sources

Transmit-end, transmit-data-empty, receive-data-full, overrun error, framing error, and parity error.

Asynchronous mode

- Data length: 7 or 8 bits
- Stop bit length: 1 or 2 bits
- Parity: Even, odd, or none
- Receive error detection: Parity, overrun, and framing errors
- Break detection: Break can be detected by reading the RXD pin level directly in the case of a framing error



Clocked synchronous mode

- Data length: 8 bits
- Receive error detection: Overrun errors



Channel	Abbreviation	Pin	Register	Register Address
Channel 1*1	SCI3	SCK3	SMR	H'FFA8
		RXD TXD	BRR	H'FFA9
		IXD	SCR3	H'FFAA
			TDR	H'FFAB
			SSR	H'FFAC
			RDR	H'FFAD
			RSR	_
			TSR	_
Channel 2	SCI3_2	SCK3_2	SMR_2	H'F740
		RXD_2 TXD_2	BRR_2	H'F741
		TXD_2	SCR3_2	H'F742
			TDR_2	H'F743
			SSR_2	H'F744
			RDR_2	H'F745
			RSR_2	_
			TSR_2	_
Channel 3* ²	SCI3_3	SCK3_3*3	SMR_3	H'F600
		RXD_3 TXD_3	BRR_3	H'F601
		TXD_0	SCR3_3	H'F602
			TDR_3	H'F603
			SSR_3	H'F604
			RDR_3	H'F605
			RSR_3	_
			TSR_3	_
			SMCR	H'F608

Table 13.1 Channel Configuration

Notes: 1. The channel 1 of the SCI3 is used in on-board programming mode by boot mode.

2. The SCI3_3 function is incorporated in the H8/36024.

3. When this pin is used as the SCI3_3 function with the emulator used, the corresponding PCR value must be cleared to 0.



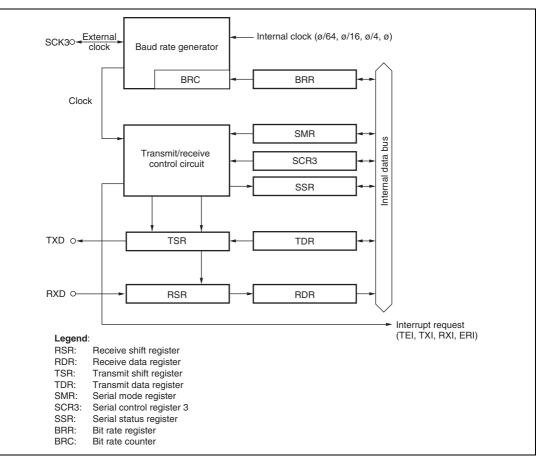


Figure 13.1 Block Diagram of SCI3

13.2 Input/Output Pins

Table 13.2 shows the SCI3 pin configuration.

Table 13.2 Pin Configuration

Pin Name	Abbreviation	I/O	Function
SCI3 clock	SCK3	I/O	SCI3 clock input/output
SCI3 receive data input	RXD	Input	SCI3 receive data input
SCI3 transmit data output	TXD	Output	SCI3 transmit data output

13.3 Register Descriptions

The SCI3 has the following registers for each channel.

- Receive Shift Register (RSR)
- Receive Data Register (RDR)
- Transmit Shift Register (TSR)
- Transmit Data Register (TDR)
- Serial Mode Register (SMR)
- Serial Control Register 3 (SCR3)
- Serial Status Register (SSR)
- Bit Rate Register (BRR)
- SCI3_3 Module Control Register (SMCR)



13.3.1 Receive Shift Register (RSR)

RSR is a shift register that is used to receive serial data input from the RXD pin and convert it into parallel data. When one frame of data has been received, it is transferred to RDR automatically. RSR cannot be directly accessed by the CPU.

13.3.2 Receive Data Register (RDR)

RDR is an 8-bit register that stores received data. When the SCI3 has received one frame of serial data, it transfers the received serial data from RSR to RDR, where it is stored. After this, RSR is receive-enabled. As RSR and RDR function as a double buffer in this way, continuous receive operations are possible. After confirming that the RDRF bit in SSR is set to 1, read RDR only once. RDR cannot be written to by the CPU. RDR is initialized to H'00.

13.3.3 Transmit Shift Register (TSR)

TSR is a shift register that transmits serial data. To perform serial data transmission, the SCI3 first transfers transmit data from TDR to TSR automatically, then sends the data that starts from the LSB to the TXD pin. TSR cannot be directly accessed by the CPU.

13.3.4 Transmit Data Register (TDR)

TDR is an 8-bit register that stores data for transmission. When the SCI3 detects that TSR is empty, it transfers the transmit data written in TDR to TSR and starts transmission. The doublebuffered structure of TDR and TSR enables continuous serial transmission. If the next transmit data has already been written to TDR during transmission of one-frame data, the SCI3 transfers the written data to TSR to continue transmission. To achieve reliable serial transmission, write transmit data to TDR only once after confirming that the TDRE bit in SSR is set to 1. TDR is initialized to H'FF.



13.3.5 Serial Mode Register (SMR)

SMR is used to set the SCI3's serial transfer format and select the baud rate generator clock source.

Bit	Bit Name	Initial Value	R/W	Description
7	COM	0	R/W	Communication Mode
				0: Asynchronous mode
				1: Clocked synchronous mode
6	CHR	0	R/W	Character Length (enabled only in asynchronous mode)
				0: Selects 8 bits as the data length.
				1: Selects 7 bits as the data length.
5	PE	0	R/W	Parity Enable (enabled only in asynchronous mode)
				When this bit is set to 1, the parity bit is added to transmit data before transmission, and the parity bit is checked in reception.
4	РМ	0	R/W	Parity Mode (enabled only when the PE bit is 1 in asynchronous mode)
				0: Selects even parity.
				1: Selects odd parity.
3	STOP	0	R/W	Stop Bit Length (enabled only in asynchronous mode)
				Selects the stop bit length in transmission.
				0: 1 stop bit
				1: 2 stop bits
				For reception, only the first stop bit is checked, regardless of the value in the bit. If the second stop bit is 0, it is treated as the start bit of the next transmit character.
2	MP	0	R/W	Multiprocessor Mode
				When this bit is set to 1, the multiprocessor communication function is enabled. The PE bit and PM bit settings are invalid in multiprocessor mode. In clocked synchronous mode, clear this bit to 0.



Bit	Bit Name	Initial Value	R/W	Description
1	CKS1	0	R/W	Clock Select 0 and 1
0	CKS0	0	R/W	These bits select the clock source for the baud rate generator.
				00: φ clock (n = 0)
				01:
				10: φ/16 clock (n = 2)
				11: φ/64 clock (n = 3)
				For the relationship between the bit rate register setting and the baud rate, see section 13.3.8, Bit Rate Register (BRR). n is the decimal representation of the value of n in BRR (see section 13.3.8, Bit Rate Register (BRR)).

13.3.6 Serial Control Register 3 (SCR3)

SCR3 is a register that enables or disables SCI3 transfer operations and interrupt requests, and is also used to select the transfer clock source. For details on interrupt requests, refer to section 13.7, Interrupts.

Bit	Bit Name	Initial Value	R/W	Description
7	TIE	0	R/W	Transmit Interrupt Enable
				When this bit is set to 1, the TXI interrupt request is enabled.
6	RIE	0	R/W	Receive Interrupt Enable
				When this bit is set to 1, RXI and ERI interrupt requests are enabled.
5	TE	0	R/W	Transmit Enable
				When this bit s set to 1, transmission is enabled.
4	RE	0	R/W	Receive Enable
				When this bit is set to 1, reception is enabled.

Bit	Bit Name	Initial Value	R/W	Description
3	MPIE	0	R/W	Multiprocessor Interrupt Enable (enabled only when the MP bit in SMR is 1 in asynchronous mode)
				When this bit is set to 1, receive data in which the multiprocessor bit is 0 is skipped, and setting of the RDRF, FER, and OER status flags in SSR is disabled. On receiving data in which the multiprocessor bit is 1, this bit is automatically cleared and normal reception is resumed. For details, refer to section 13.6, Multiprocessor Communication Function.
2	TEIE	0	R/W	Transmit End Interrupt Enable
				When this bit is set to 1, TEI interrupt request is enabled.
1	CKE1	0	R/W	Clock Enable 0 and 1
0	CKE0	0	R/W	Selects the clock source.
				Asynchronous mode
				00: On-chip baud rate generator
				01: On-chip baud rate generator
				Outputs a clock of the same frequency as the bit rate from the SCK3 pin.
				10: External clock
				Inputs a clock with a frequency 16 times the bit rate from the SCK3 pin.
				11:Reserved
				Clocked synchronous mode
				00: On-chip clock (SCK3 pin functions as clock output)
				01:Reserved
				10: External clock (SCK3 pin functions as clock input)
				11:Reserved



13.3.7 Serial Status Register (SSR)

SSR is a register containing status flags of the SCI3 and multiprocessor bits for transfer. 1 cannot be written to flags TDRE, RDRF, OER, PER, and FER; they can only be cleared.

Bit	Bit Name	Initial Value	R/W	Description
7	TDRE	1	R/W	Transmit Data Register Empty
				Indicates whether TDR contains transmit data.
				[Setting conditions]
				When the TE bit in SCR3 is 0
				When data is transferred from TDR to TSR
				[Clearing conditions]
				• When 0 is written to TDRE after reading TDRE = 1
				When the transmit data is written to TDR
6	RDRF	0	R/W	Receive Data Register Full
				Indicates that the received data is stored in RDR.
				[Setting condition]
				 When serial reception ends normally and receive data is transferred from RSR to RDR
				[Clearing conditions]
				• When 0 is written to RDRF after reading RDRF = 1
				When data is read from RDR
5	OER	0	R/W	Overrun Error
				[Setting condition]
				When an overrun error occurs in reception
				[Clearing condition]
				 When 0 is written to OER after reading OER = 1
4	FER	0	R/W	Framing Error
				[Setting condition]
				When a framing error occurs in reception
				[Clearing condition]
				• When 0 is written to FER after reading FER = 1

Bit	Bit Name	Initial Value	R/W	Description
3	PER	0	R/W	Parity Error
				[Setting condition]
				When a parity error is detected during reception [Clearing condition]
				• When 0 is written to PER after reading PER = 1
2	TEND	1	R	 Transmit End [Setting conditions] When the TE bit in SCR3 is 0 When TDRE = 1 at transmission of the last bit of a 1-frame serial transmit character [Clearing conditions] When 0 is written to TDRE after reading TDRE = 1 When the transmit data is written to TDR
1	MPBR	0	R	Multiprocessor Bit Receive MPBR stores the multiprocessor bit in the receive character data. When the RE bit in SCR3 is cleared to 0, its state is retained.
0	MPBT	0	R/W	Multiprocessor Bit Transfer
				MPBT stores the multiprocessor bit to be added to the transmit character data.



13.3.8 Bit Rate Register (BRR)

BRR is an 8-bit register that adjusts the bit rate. The initial value of BRR is H'FF. Table 13.3 shows the relationship between the N setting in BRR and the n setting in bits CKS1 and CKS0 of SMR in asynchronous mode. Table 13.4 shows the maximum bit rate for each frequency in asynchronous mode. The values shown in both tables 13.3 and 13.4 are values in active (high-speed) mode. Table 13.5 shows the relationship between the N setting in BRR and the n setting in bits CKS1 and CKS0 of SMR in clocked synchronous mode. The values shown in table 13.5 are values in active (high-speed) mode. The N setting in BRR and error for other operating frequencies and bit rates can be obtained by the following formulas:

[Asynchronous Mode]

$$N = \frac{\varphi}{64 \times 2^{2n-1} \times B} \times 10^6 - 1$$

Error (%) =
$$\left\{\frac{\phi \times 10^{6}}{(N+1) \times B \times 64 \times 2^{2n-1}} - 1\right\} \times 100$$

[Clocked Synchronous Mode]

$$N = \frac{\phi}{8 \times 2^{2n-1} \times B} \times 10^6 - 1$$

[Legend]

B: Bit rate (bit/s)

N: BRR setting for baud rate generator ($0 \le N \le 255$)

φ: Operating frequency (MHz)

n: CSK1 and CSK0 settings in SMR (0 \leq n \leq 3)

		Operating Frequency ϕ (MHz)												
	2			2.097152			2.4576			3				
Bit Rate (bits/s)	n	N	Error (%)	n	N	Error (%)	n	N	Error (%)	n	N	Error (%)		
110	1	141	0.03	1	148	-0.04	1	174	-0.26	1	212	0.03		
150	1	103	0.16	1	108	0.21	1	127	0.00	1	155	0.16		
300	0	207	0.16	0	217	0.21	0	255	0.00	1	77	0.16		
600	0	103	0.16	0	108	0.21	0	127	0.00	0	155	0.16		
1200	0	51	0.16	0	54	-0.70	0	63	0.00	0	77	0.16		
2400	0	25	0.16	0	26	1.14	0	31	0.00	0	38	0.16		
4800	0	12	0.16	0	13	-2.48	0	15	0.00	0	19	-2.34		
9600	0	6	-6.99	0	6	-2.48	0	7	0.00	0	9	-2.34		
19200	0	2	8.51	0	2	13.78	0	3	0.00	0	4	-2.34		
31250	0	1	0.00	0	1	4.86	0	1	22.88	0	2	0.00		
38400	0	1	-18.62	0	1	-14.67	0	1	0.00			_		

Table 13.3 Examples of BRR Settings for Various Bit Rates (Asynchronous Mode) (1)

Operating Frequency φ (MHz)

	3.6864				4			4.9152			5		
Bit Rate (bits/s)	n	N	Error (%)	n	N	Error (%)	n	N	Error (%)	n	N	Error (%)	
110	2	64	0.70	2	70	0.03	2	86	0.31	2	88	-0.25	
150	1	191	0.00	1	207	0.16	1	255	0.00	2	64	0.16	
300	1	95	0.00	1	103	0.16	1	127	0.00	1	129	0.16	
600	0	191	0.00	0	207	0.16	0	255	0.00	1	64	0.16	
1200	0	95	0.00	0	103	0.16	0	127	0.00	0	129	0.16	
2400	0	47	0.00	0	51	0.16	0	63	0.00	0	64	0.16	
4800	0	23	0.00	0	25	0.16	0	31	0.00	0	32	-1.36	
9600	0	11	0.00	0	12	0.16	0	15	0.00	0	15	1.73	
19200	0	5	0.00	0	6	-6.99	0	7	0.00	0	7	1.73	
31250	_	—	_	0	3	0.00	0	4	-1.70	0	4	0.00	
38400	0	2	0.00	0	2	8.51	0	3	0.00	0	3	1.73	

Legend

---: A setting is available but error occurs



		Operating Frequency (MHZ)													
		6			6.144	Ļ	7.3728								
Bit Rate (bit/s)	n	N	Error (%)	n	N	Error (%)	n	N	Error (%)						
110	2	106	-0.44	2	108	0.08	2	130	-0.07						
150	2	77	0.16	2	79	0.00	2	95	0.00						
300	1	155	0.16	1	159	0.00	1	191	0.00						
600	1	77	0.16	1	79	0.00	1	95	0.00						
1200	0	155	0.16	0	159	0.00	0	191	0.00						
2400	0	77	0.16	0	79	0.00	0	95	0.00						
4800	0	38	0.16	0	39	0.00	0	47	0.00						
9600	0	19	-2.34	0	19	0.00	0	23	0.00						
19200	0	9	-2.34	0	9	0.00	0	11	0.00						
31250	0	5	0.00	0	5	2.40	0	6	5.33						
38400	0	4	-2.34	0	4	0.00	0	5	0.00						

Table 13.3 Examples of BRR Settings for Various Bit Rates (Asynchronous Mode) (2)

Operating Frequency & (MHz)

Operating Frequency φ (MHz)

	8				9.8304			10			12		
Bit Rate (bit/s)	n	N	Error (%)	n	N	Error (%)	n	N	Error (%)	n	N	Error (%)	
110	2	141	0.03	2	174	-0.26	2	177	-0.25	2	212	0.03	
150	2	103	0.16	2	127	0.00	2	129	0.16	2	155	0.16	
300	1	207	0.16	1	255	0.00	2	64	0.16	2	77	0.16	
600	1	103	0.16	1	127	0.00	1	129	0.16	1	155	0.16	
1200	0	207	0.16	0	255	0.00	1	64	0.16	1	77	0.16	
2400	0	103	0.16	0	127	0.00	0	129	0.16	0	155	0.16	
4800	0	51	0.16	0	63	0.00	0	64	0.16	0	77	0.16	
9600	0	25	0.16	0	31	0.00	0	32	-1.36	0	38	0.16	
19200	0	12	0.16	0	15	0.00	0	15	1.73	0	19	-2.34	
31250	0	7	0.00	0	9	-1.70	0	9	0.00	0	11	0.00	
38400	0	6	-6.99	0	7	0.00	0	7	1.73	0	9	-2.34	

Legend

--: A setting is available but error occurs.

	Operating Frequency φ (MHz)												
	12.888				14			14.7456			16		
Bit Rate (bit/s)	n	N	Error (%)	n	N	Error (%)	n	N	Error (%)	n	N	Error (%)	
110	2	217	0.08	2	248	-0.17	3	64	0.70	3	70	0.03	
150	2	159	0.00	2	181	0.16	2	191	0.00	2	207	0.16	
300	2	79	0.00	2	90	0.16	2	95	0.00	2	103	0.16	
600	1	159	0.00	1	181	0.16	1	191	0.00	1	207	0.16	
1200	1	79	0.00	1	90	0.16	1	95	0.00	1	103	0.16	
2400	0	159	0.00	0	181	0.16	0	191	0.00	0	207	0.16	
4800	0	79	0.00	0	90	0.16	0	95	0.00	0	103	0.16	
9600	0	39	0.00	0	45	-0.93	0	47	0.00	0	51	0.16	
19200	0	19	0.00	0	22	-0.93	0	23	0.00	0	25	0.16	
31250	0	11	2.40	0	13	0.00	0	14	-1.70	0	15	0.00	
38400	0	9	0.00		—	—	0	11	0.00	0	12	0.16	

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 Table 13.3
 Examples of BRR Settings for Various Bit Rates (Asynchronous Mode) (3)

Operating Frequency φ (MHz)

		18		20					
Bit Rate (bit/s)	n	N	Error (%)	n	N	Error (%)			
110	3	79	-0.12	3	88	-0.25			
150	2	233	0.16	3	64	0.16			
300	2	116	0.16	2	129	0.16			
600	1	233	0.16	2	64	0.16			
1200	1	116	0.16	1	129	0.16			
2400	0	233	0.16	1	64	0.16			
4800	0	116	0.16	0	129	0.16			
9600	0	58	-0.96	0	64	0.16			
19200	0	28	1.02	0	32	-1.36			
31250	0	17	0.00	0	19	0.00			
38400	0	14	-2.34	0	15	1.73			

Legend

-: A setting is available but error occurs.

φ (MHz)	Maximum Bit Rate (bit/s)	n	N	φ (MHz)	Maximum Bit Rate (bit/s)	n	N
2	62500	0	0	8	250000	0	0
2.097152	65536	0	0	9.8304	307200	0	0
2.4576	76800	0	0	10	312500	0	0
3	93750	0	0	12	375000	0	0
3.6864	115200	0	0	12.288	384000	0	0
4	125000	0	0	14	437500	0	0
4.9152	153600	0	0	14.7456	460800	0	0
5	156250	0	0	16	500000	0	0
6	187500	0	0	17.2032	537600	0	0
6.144	192000	0	0	18	562500	0	0
7.3728	230400	0	0	20	625000	0	0

Table 13.4 Maximum Bit Rate for Each Frequency (Asynchronous Mode)



Table 13.5	Examples of BRR Settings for Various Bit Rates (Clocked Synchronous Mode)
	(1)

	Operating Frequency φ (MHz)											
Bit Rate	2		4			8		10		16		
(bit/s)	n	Ν	n	Ν	n	Ν	n	Ν	n	Ν		
110	3	70		—			_	_				
250	2	124	2	249	3	124		_	3	249		
500	1	249	2	124	2	249	_	—	3	124		
1k	1	124	1	249	2	124		_	2	249		
2.5k	0	199	1	99	1	199	1	249	2	99		
5k	0	99	0	199	1	99	1	124	1	199		
10k	0	49	0	99	0	199	0	249	1	99		
25k	0	19	0	39	0	79	0	99	0	159		
50k	0	9	0	19	0	39	0	49	0	79		
100k	0	4	0	9	0	19	0	24	0	39		
250k	0	1	0	3	0	7	0	9	0	15		
500k	0	0*	0	1	0	3	0	4	0	7		
1M			0	0*	0	1		_	0	3		
2M					0	0*			0	1		
2.5M							0	0*	—	—		
4M									0	0*		

Operating Frequency ϕ (MHz)

Legend

Blank : No setting is available.

- : A setting is available but error occurs.

* : Continuous transfer is not possible.



Table 13.5 Examples of BRR Settings for Various Bit Rates (Clocked Synchronous Mode) (2)

	Operating Frequency φ (MI				
Bit Rate		18	20		
(bit/s)	n	Ν	n	Ν	
110	_	_	_	_	
250	_	_	_	_	
500	3	140	3	155	
1k	3	69	3	77	
2.5k	2	112	2	124	
5k	1	224	1	249	
10k	1	112	1	124	
25k	0	179	0	199	
50k	0	89	0	99	
100k	0	44	0	49	
250k	0	17	0	19	
500k	0	8	0	9	
1M	0	4	0	4	
2M	_		_	_	
2.5M	_	_	0	1	
4M	—	—	_	—	

Legend

Blank : No setting is available.

- : A setting is available but error occurs. ____
- : Continuous transfer is not possible. *

13.3.9 SCI3_3 Module Control Register (SMCR)

SMCR controls the SCI3_3 and module standby function.

Bit	Bit Name	Initial Value	R/W	Description
7 to 4		All 1	_	Reserved
				These bits are always read as 1.
3, 2	_	All 1		Reserved
				These bits are always read as 1. When the emulator is used, these bits must be cleared to 0.
1	TXD_3	0	R/W	TXD_3 Output Select
				Selects the function of the P57/TXD_3 pin.
				0: General I/O port
				1: TXD_3 output pin
0	MSTS3_3	0	R/W	SCI3_3 Module Standby
				When this bit is set to 1, the SCI3_3 enters the standby state.



13.4 Operation in Asynchronous Mode

Figure 13.2 shows the general format for asynchronous serial communication. One character (or frame) consists of a start bit (low level), followed by data (in LSB-first order), a parity bit (high or low level), and finally stop bits (high level). Inside the SCI3, the transmitter and receiver are independent units, enabling full-duplex. Both the transmitter and the receiver also have a double-buffered structure, so data can be read or written during transmission or reception, enabling continuous data transfer.

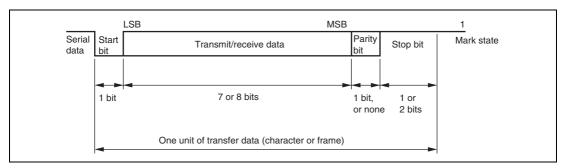


Figure 13.2 Data Format in Asynchronous Communication

13.4.1 Clock

Either an internal clock generated by the on-chip baud rate generator or an external clock input at the SCK3 pin can be selected as the SCI3's serial clock, according to the setting of the COM bit in SMR and the CKE0 and CKE1 bits in SCR3. When an external clock is input at the SCK3 pin, the clock frequency should be 16 times the bit rate used.

When the SCI3 is operated on an internal clock, the clock can be output from the SCK3 pin. The frequency of the clock output in this case is equal to the bit rate, and the phase is such that the rising edge of the clock is in the middle of the transmit data, as shown in figure 13.3.

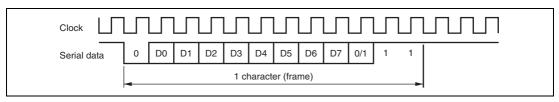


Figure 13.3 Relationship between Output Clock and Transfer Data Phase (Asynchronous Mode)(Example with 8-Bit Data, Parity, Two Stop Bits)

13.4.2 SCI3 Initialization

Before transmitting and receiving data, you should first clear the TE and RE bits in SCR3 to 0, then initialize the SCI3 as described below. When the operating mode, or transfer format, is changed for example, the TE and RE bits must be cleared to 0 before making the change using the following procedure. When the TE bit is cleared to 0, the TDRE flag is set to 1. Note that clearing the RE bit to 0 does not initialize the contents of the RDRF, PER, FER, and OER flags, or the contents of RDR. When the external clock is used in asynchronous mode, the clock must be supplied even during initialization.

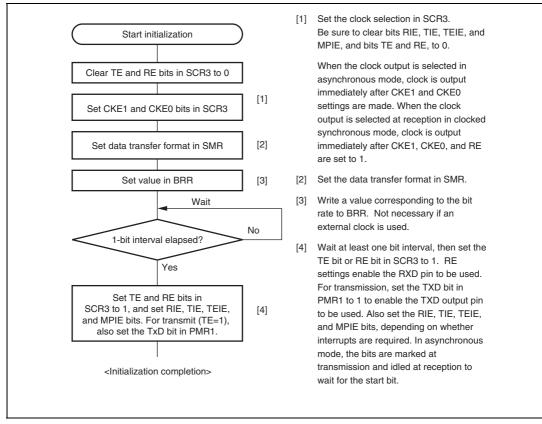


Figure 13.4 Sample SCI3 Initialization Flowchart



13.4.3 Data Transmission

Figure 13.5 shows an example of operation for transmission in asynchronous mode. In transmission, the SCI3 operates as described below.

- 1. The SCI3 monitors the TDRE flag in SSR. If the flag is cleared to 0, the SCI3 recognizes that data has been written to TDR, and transfers the data from TDR to TSR.
- 2. After transferring data from TDR to TSR, the SCI3 sets the TDRE flag to 1 and starts transmission. If the TIE bit is set to 1 at this time, a TXI interrupt request is generated. Continuous transmission is possible because the TXI interrupt routine writes next transmit data to TDR before transmission of the current transmit data has been completed.
- 3. The SCI3 checks the TDRE flag at the timing for sending the stop bit.
- 4. If the TDRE flag is 0, the data is transferred from TDR to TSR, the stop bit is sent, and then serial transmission of the next frame is started.
- 5. If the TDRE flag is 1, the TEND flag in SSR is set to 1, the stop bit is sent, and then the "mark state" is entered, in which 1 is output. If the TEIE bit in SCR3 is set to 1 at this time, a TEI interrupt request is generated.
- 6. Figure 13.6 shows a sample flowchart for transmission in asynchronous mode.

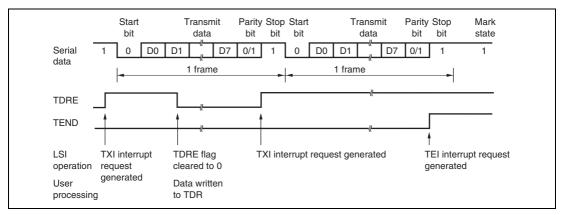
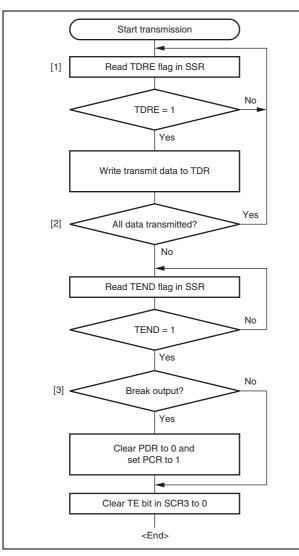


Figure 13.5 Example of SCI3 Transmission in Asynchronous Mode (8-Bit Data, Parity, One Stop Bit)



- [1] Read SSR and check that the TDRE flag is set to 1, then write transmit data to TDR. When data is written to TDR, the TDRE flag is automaticaly cleared to 0.
- [2] To continue serial transmission, read 1 from the TDRE flag to confirm that writing is possible, then write data to TDR. When data is written to TDR, the TDRE flag is automaticaly cleared to 0.
- [3] To output a break in serial transmission, after setting PCR to 1 and PDR to 0, clear TxD in PMR1 to 0, then clear the TE bit in SCR3 to 0.

Figure 13.6 Sample Serial Transmission Data Flowchart (Asynchronous Mode)



13.4.4 Serial Data Reception

Figure 13.7 shows an example of operation for reception in asynchronous mode. In serial reception, the SCI3 operates as described below.

- 1. The SCI3 monitors the communication line. If a start bit is detected, the SCI3 performs internal synchronization, receives receive data in RSR, and checks the parity bit and stop bit.
- 2. If an overrun error occurs (when reception of the next data is completed while the RDRF flag is still set to 1), the OER bit in SSR is set to 1. If the RIE bit in SCR3 is set to 1 at this time, an ERI interrupt request is generated. Receive data is not transferred to RDR.
- 3. If a parity error is detected, the PER bit in SSR is set to 1 and receive data is transferred to RDR. If the RIE bit in SCR3 is set to 1 at this time, an ERI interrupt request is generated.
- 4. If a framing error is detected (when the stop bit is 0), the FER bit in SSR is set to 1 and receive data is transferred to RDR. If the RIE bit in SCR3 is set to 1 at this time, an ERI interrupt request is generated.
- 5. If reception is completed successfully, the RDRF bit in SSR is set to 1, and receive data is transferred to RDR. If the RIE bit in SCR3 is set to 1 at this time, an RXI interrupt request is generated. Continuous reception is possible because the RXI interrupt routine reads the receive data transferred to RDR before reception of the next receive data has been completed.

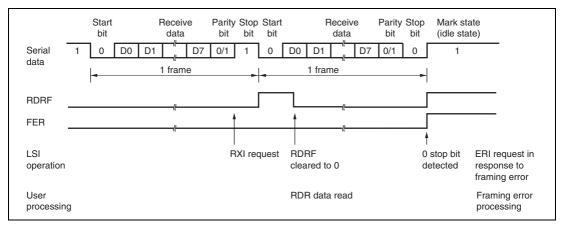


Figure 13.7 Example of SCI3 Reception in Asynchronous Mode (8-Bit Data, Parity, One Stop Bit)

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Table 13.6 shows the states of the SSR status flags and receive data handling when a receive error is detected. If a receive error is detected, the RDRF flag retains its state before receiving data. Reception cannot be resumed while a receive error flag is set to 1. Accordingly, clear the OER, FER, PER, and RDRF bits to 0 before resuming reception. Figure 13.8 shows a sample flow chart for serial data reception.

	SSR	Status Flag	3		
RDRF*	OER	FER	PER	Receive Data	Receive Error Type
1	1	0	0	Lost	Overrun error
0	0	1	0	Transferred to RDR	Framing error
0	0	0	1	Transferred to RDR	Parity error
1	1	1	0	Lost	Overrun error + framing error
1	1	0	1	Lost	Overrun error + parity error
0	0	1	1	Transferred to RDR	Framing error + parity error
1	1	1	1	Lost	Overrun error + framing error + parity error

Table 13.6 SSR Status Flags and Receive Data Handling

Note: * The RDRF flag retains the state it had before data reception.



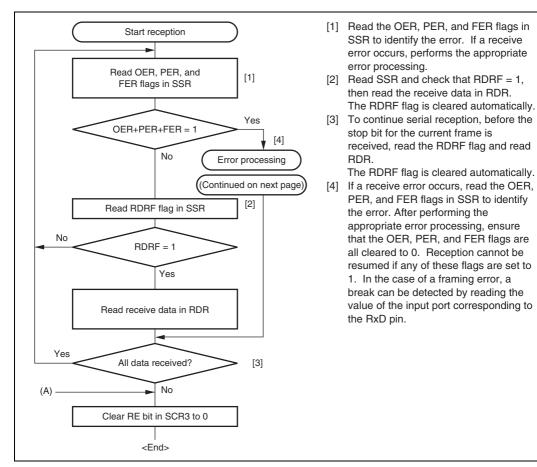


Figure 13.8 Sample Serial Reception Data Flowchart (Asynchronous Mode)(1)

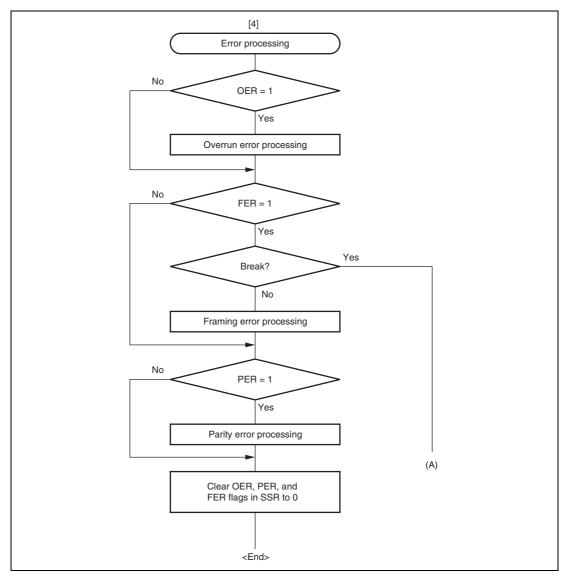


Figure 13.8 Sample Serial Reception Data Flowchart (Asynchronous Mode)(2)



13.5 Operation in Clocked Synchronous Mode

Figure 13.9 shows the general format for clocked synchronous communication. In clocked synchronous mode, data is transmitted or received synchronous with clock pulses. A single character in the transmit data consists of the 8-bit data starting from the LSB. In clocked synchronous serial communication, data on the transmission line is output from one falling edge of the synchronization clock to the next. In clocked synchronous mode, the SCI3 receives data in synchronous with the rising edge of the synchronization clock. After 8-bit data is output, the transmission line holds the MSB state. In clocked synchronous mode, no parity or multiprocessor bit is added. Inside the SCI3, the transmitter and receiver are independent units, enabling full-duplex communication through the use of a common clock. Both the transmitter and the receiver also have a double-buffered structure, so data can be read or written during transmission or reception, enabling continuous data transfer.

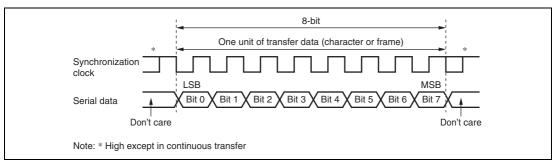


Figure 13.9 Data Format in Clocked Synchronous Communication

13.5.1 Clock

Either an internal clock generated by the on-chip baud rate generator or an external synchronization clock input at the SCK3 pin can be selected, according to the setting of the COM bit in SMR and CKE0 and CKE1 bits in SCR3. When the SCI3 is operated on an internal clock, the synchronization clock is output from the SCK3 pin. Eight synchronization clock pulses are output in the transfer of one character, and when no transfer is performed the clock is fixed high.



13.5.2 SCI3 Initialization

Before transmitting and receiving data, the SCI3 should be initialized as described in a sample flowchart in figure 13.4.

13.5.3 Serial Data Transmission

Figure 13.10 shows an example of SCI3 operation for transmission in clocked synchronous mode. In serial transmission, the SCI3 operates as described below.

- 1. The SCI3 monitors the TDRE flag in SSR, and if the flag is 0, the SCI3 recognizes that data has been written to TDR, and transfers the data from TDR to TSR.
- 2. The SCI3 sets the TDRE flag to 1 and starts transmission. If the TIE bit in SCR3 is set to 1 at this time, a transmit data empty interrupt (TXI) is generated.
- 3. 8-bit data is sent from the TXD pin synchronized with the output clock when output clock mode has been specified, and synchronized with the input clock when use of an external clock has been specified. Serial data is transmitted sequentially from the LSB (bit 0), from the TXD pin.
- 4. The SCI3 checks the TDRE flag at the timing for sending the MSB (bit 7).
- 5. If the TDRE flag is cleared to 0, data is transferred from TDR to TSR, and serial transmission of the next frame is started.
- 6. If the TDRE flag is set to 1, the TEND flag in SSR is set to 1, and the TDRE flag maintains the output state of the last bit. If the TEIE bit in SCR3 is set to 1 at this time, a TEI interrupt request is generated.
- 7. The SCK3 pin is fixed high at the end of transmission.

Figure 13.11 shows a sample flow chart for serial data transmission. Even if the TDRE flag is cleared to 0, transmission will not start while a receive error flag (OER, FER, or PER) is set to 1. Make sure that the receive error flags are cleared to 0 before starting transmission.

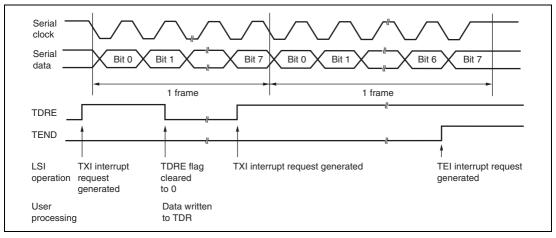


Figure 13.10 Example of SCI3 Transmission in Clocked Synchronous Mode

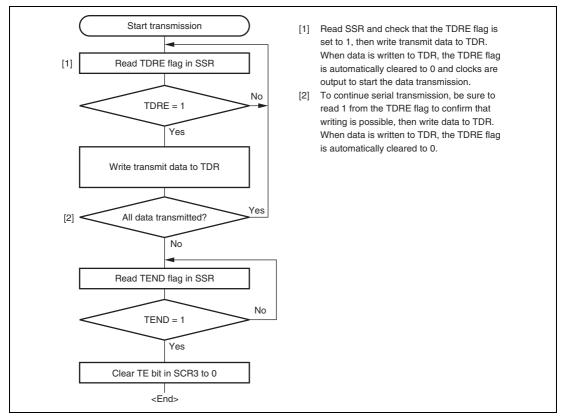


Figure 13.11 Sample Serial Transmission Flowchart (Clocked Synchronous Mode)



13.5.4 Serial Data Reception (Clocked Synchronous Mode)

Figure 13.12 shows an example of SCI3 operation for reception in clocked synchronous mode. In serial reception, the SCI3 operates as described below.

- 1. The SCI3 performs internal initialization synchronous with a synchronization clock input or output, starts receiving data.
- 2. The SCI3 stores the receive data in RSR.
- 3. If an overrun error occurs (when reception of the next data is completed while the RDRF flag in SSR is still set to 1), the OER bit in SSR is set to 1. If the RIE bit in SCR3 is set to 1 at this time, an ERI interrupt request is generated, receive data is not transferred to RDR, and the RDRF flag remains to be set to 1.
- 4. If reception is completed successfully, the RDRF bit in SSR is set to 1, and receive data is transferred to RDR. If the RIE bit in SCR3 is set to 1 at this time, an RXI interrupt request is generated.

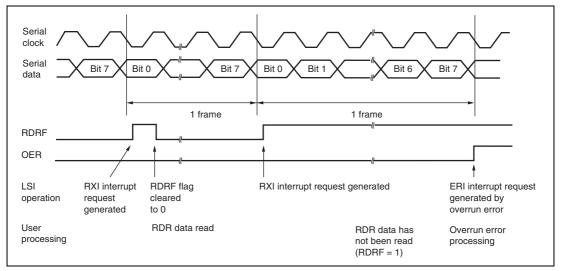
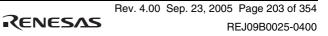
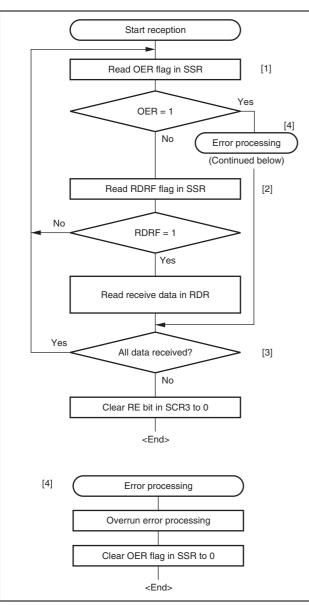


Figure 13.12 Example of SCI3 Reception in Clocked Synchronous Mode

Reception cannot be resumed while a receive error flag is set to 1. Accordingly, clear the OER, FER, PER, and RDRF bits to 0 before resuming reception. Figure 13.13 shows a sample flow chart for serial data reception.





- Read the OER flag in SSR to determine if there is an error. If an overrun error has occurred, execute overrun error processing.
- [2] Read SSR and check that the RDRF flag is set to 1, then read the receive data in RDR. When data is read from RDR, the RDRF flag is automatically cleared to 0.
- [3] To continue serial reception, before the MSB (bit 7) of the current frame is received, reading the RDRF flag and reading RDR should be finished. When data is read from RDR, the RDRF flag is automatically cleared to 0.
- [4] If an overrun error occurs, read the OER flag in SSR, and after performing the appropriate error processing, clear the OER flag to 0. Reception cannot be resumed if the OER flag is set to 1.

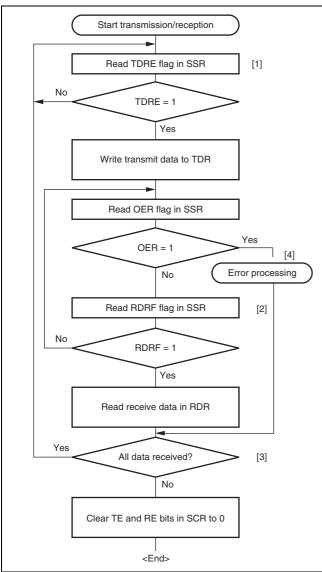
Figure 13.13 Sample Serial Reception Flowchart (Clocked Synchronous Mode)

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13.5.5 Simultaneous Serial Data Transmission and Reception

Figure 13.14 shows a sample flowchart for simultaneous serial transmit and receive operations. The following procedure should be used for simultaneous serial data transmit and receive operations. To switch from transmit mode to simultaneous transmit and receive mode, after checking that the SCI3 has finished transmission and the TDRE and TEND flags are set to 1, clear TE to 0. Then simultaneously set TE and RE to 1 with a single instruction. To switch from receive mode to simultaneous transmit and receive mode, after checking that the SCI3 has finished receive mode, after checking that the SCI3 has finished receive mode, after checking that the SCI3 has finished receive mode to simultaneous transmit and receive mode, after checking that the SCI3 has finished reception, clear RE to 0. Then after checking that the RDRF and receive error flags (OER, FER, and PER) are cleared to 0, simultaneously set TE and RE to 1 with a single instruction.





- Read SSR and check that the TDRE flag is set to 1, then write transmit data to TDR.
 When data is written to TDR, the TDRE flag is automatically cleared to 0.
- Read SSR and check that the RDRF flag is set to 1, then read the receive data in RDR.
 When data is read from RDR, the RDRF flag is automatically cleared to 0.
- [3] To continue serial transmission/ reception, before the MSB (bit 7) of the current frame is received, finish reading the RDRF flag, reading RDR. Also, before the MSB (bit 7) of the current frame is transmitted, read 1 from the TDRE flag to confirm that writing is possible. Then write data to TDR.

When data is written to TDR, the TDRE flag is automatically cleared to 0. When data is read from RDR, the RDRF flag is automatically cleared to 0.

[4] If an overrun error occurs, read the OER flag in SSR, and after performing the appropriate error processing, clear the OER flag to 0. Transmission/reception cannot be resumed if the OER flag is set to 1. For overrun error processing, see figure 13.13.

Figure 13.14 Sample Flowchart of Simultaneous Serial Transmit and Receive Operations (Clocked Synchronous Mode)

13.6 Multiprocessor Communication Function

Use of the multiprocessor communication function enables data transfer between a number of processors sharing communication lines by asynchronous serial communication using the multiprocessor format, in which a multiprocessor bit is added to the transfer data. When multiprocessor communication is performed, each receiving station is addressed by a unique ID code. The serial communication cycle consists of two component cycles; an ID transmission cycle that specifies the receiving station, and a data transmission cycle. The multiprocessor bit is used to differentiate between the ID transmission cycle and the data transmission cycle. If the multiprocessor bit is 1, the cycle is an ID transmission cycle; if the multiprocessor bit is 0, the cycle is a data transmission cycle. Figure 13.15 shows an example of inter-processor communication using the multiprocessor format. The transmitting station first sends the ID code of the receiving station with which it wants to perform serial communication as data with a 1 multiprocessor bit added. It then sends transmit data as data with a 0 multiprocessor bit added. When data with a 1 multiprocessor bit is received, the receiving station compares that data with its own ID. The station whose ID matches then receives the data sent next. Stations whose IDs do not match continue to skip data until data with a 1 multiprocessor bit is again received.

The SCI3 uses the MPIE bit in SCR3 to implement this function. When the MPIE bit is set to 1, transfer of receive data from RSR to RDR, error flag detection, and setting the SSR status flags, RDRF, FER, and OER, to 1, are inhibited until data with a 1 multiprocessor bit is received. On reception of a receive character with a 1 multiprocessor bit, the MPBR bit in SSR is set to 1 and the MPIE bit is automatically cleared, thus normal reception is resumed. If the RIE bit in SCR3 is set to 1 at this time, an RXI interrupt is generated.

When the multiprocessor format is selected, the parity bit setting is rendered invalid. All other bit settings are the same as those in normal asynchronous mode. The clock used for multiprocessor communication is the same as that in normal asynchronous mode.



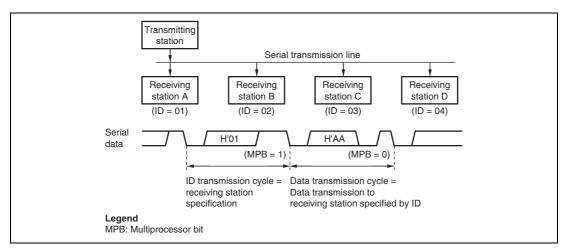
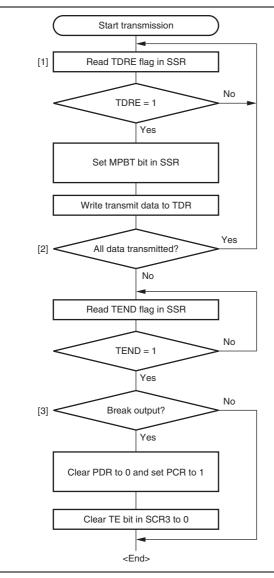


Figure 13.15 Example of Inter-Processor Communication Using Multiprocessor Format (Transmission of Data H'AA to Receiving Station A)

13.6.1 Multiprocessor Serial Data Transmission

Figure 13.16 shows a sample flowchart for multiprocessor serial data transmission. For an ID transmission cycle, set the MPBT bit in SSR to 1 before transmission. For a data transmission cycle, clear the MPBT bit in SSR to 0 before transmission. All other SCI3 operations are the same as those in asynchronous mode.





- Read SSR and check that the TDRE flag is set to 1, set the MPBT bit in SSR to 0 or 1, then write transmit data to TDR. When data is written to TDR, the TDRE flag is automatically cleared to 0.
- [2] To continue serial transmission, be sure to read 1 from the TDRE flag to confirm that writing is possible, then write data to TDR. When data is written to TDR, the TDRE flag is automatically cleared to 0.
- [3] To output a break in serial transmission, set the port PCR to 1, clear PDR to 0, then clear the TE bit in SCR3 to 0.

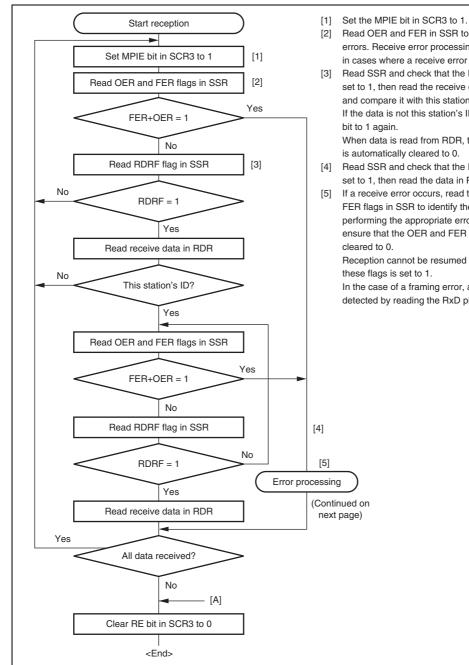
Figure 13.16 Sample Multiprocessor Serial Transmission Flowchart



13.6.2 Multiprocessor Serial Data Reception

Figure 13.17 shows a sample flowchart for multiprocessor serial data reception. If the MPIE bit in SCR3 is set to 1, data is skipped until data with a 1 multiprocessor bit is sent. On receiving data with a 1 multiprocessor bit, the receive data is transferred to RDR. An RXI interrupt request is generated at this time. All other SCI3 operations are the same as those in asynchronous mode. Figure 13.18 shows an example of SCI3 operation for multiprocessor format reception.





[2] Read OER and FER in SSR to check for errors. Receive error processing is performed in cases where a receive error occurs.

[3] Read SSR and check that the RDRF flag is set to 1, then read the receive data in RDR and compare it with this station's ID. If the data is not this station's ID, set the MPIE

When data is read from RDR, the RDRF flag is automatically cleared to 0.

[4] Read SSR and check that the RDRF flag is set to 1, then read the data in RDR.

[5] If a receive error occurs, read the OER and FER flags in SSR to identify the error. After performing the appropriate error processing, ensure that the OER and FER flags are all

Reception cannot be resumed if either of

In the case of a framing error, a break can be detected by reading the RxD pin value.

Figure 13.17 Sample Multiprocessor Serial Reception Flowchart (1)

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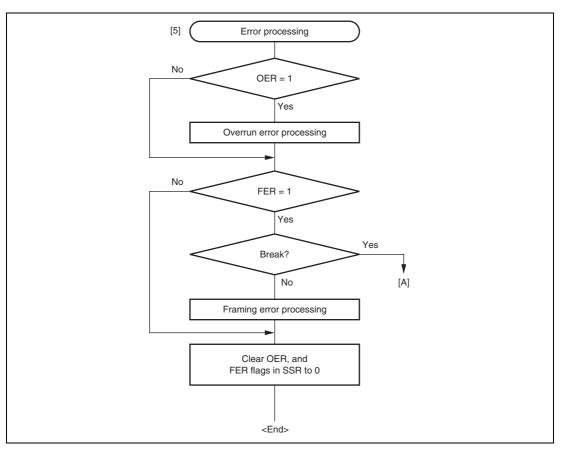
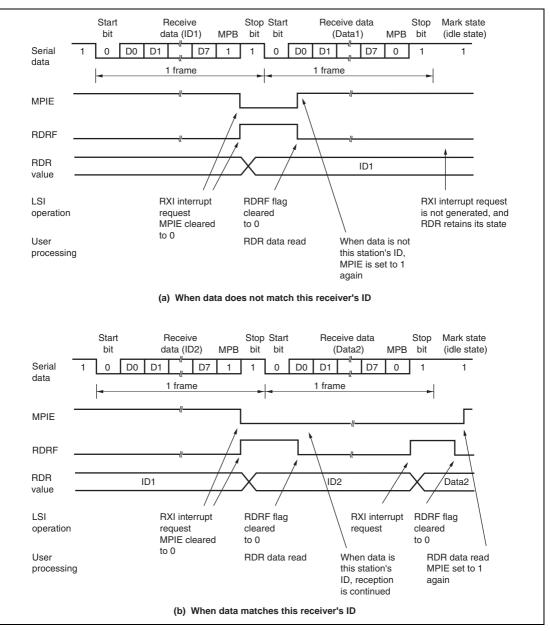
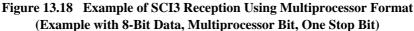


Figure 13.17 Sample Multiprocessor Serial Reception Flowchart (2)





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13.7 Interrupts

SCI3 creates the following six interrupt requests: transmission end, transmit data empty, receive data full, and receive errors (overrun error, framing error, and parity error). Table 13.7 shows the interrupt sources.

Interrupt Requests	Abbreviation	Interrupt Sources
Receive Data Full	RXI	Setting RDRF in SSR
Transmit Data Empty	ТХІ	Setting TDRE in SSR
Transmission End	TEI	Setting TEND in SSR
Receive Error	ERI	Setting OER, FER, and PER in SSR

The initial value of the TDRE flag in SSR is 1. Thus, when the TIE bit in SCR3 is set to 1 before transferring the transmit data to TDR, a TXI interrupt request is generated even if the transmit data is not ready. The initial value of the TEND flag in SSR is 1. Thus, when the TEIE bit in SCR3 is set to 1 before transferring the transmit data to TDR, a TEI interrupt request is generated even if the transmit data has not been sent. It is possible to make use of the most of these interrupt requests efficiently by transferring the transmit data to TDR in the interrupt routine. To prevent the generation of these interrupt requests (TXI and TEI), set the enable bits (TIE and TEIE) that correspond to these interrupt requests to 1, after transferring the transmit data to TDR.



13.8 Usage Notes

13.8.1 Break Detection and Processing

When framing error detection is performed, a break can be detected by reading the RXD pin value directly. In a break, the input from the RXD pin becomes all 0s, setting the FER flag, and possibly the PER flag. Note that as the SCI3 continues the receive operation after receiving a break, even if the FER flag is cleared to 0, it will be set to 1 again.

13.8.2 Mark State and Break Sending

When TE is 0, the TXD pin is used as an I/O port whose direction (input or output) and level are determined by PCR and PDR. This can be used to set the TXD pin to mark state (high level) or send a break during serial data transmission. To maintain the communication line at mark state until TE is set to 1, set both PCR and PDR to 1. As TE is cleared to 0 at this point, the TXD pin becomes an I/O port, and 1 is output from the TXD pin. To send a break during serial transmission, first set PCR to 1 and clear PDR to 0, and then clear TE to 0. When TE is cleared to 0, the transmitter is initialized regardless of the current transmission state, the TXD pin becomes an I/O port, and 0 is output from the TXD pin.

13.8.3 Receive Error Flags and Transmit Operations (Clocked Synchronous Mode Only)

Transmission cannot be started when a receive error flag (OER, PER, or FER) is set to 1, even if the TDRE flag is cleared to 0. Be sure to clear the receive error flags to 0 before starting transmission. Note also that receive error flags cannot be cleared to 0 even if the RE bit is cleared to 0.



13.8.4 Receive Data Sampling Timing and Reception Margin in Asynchronous Mode

In asynchronous mode, the SCI3 operates on a basic clock with a frequency of 16 times the transfer rate. In reception, the SCI3 samples the falling edge of the start bit using the basic clock, and performs internal synchronization. Receive data is latched internally at the rising edge of the 8th pulse of the basic clock as shown in figure 13.19. Thus, the reception margin in asynchronous mode is given by formula (1) below.

$$M = \left\{ (0.5 - \frac{1}{2N}) - \frac{D - 0.5}{N} - (L - 0.5) F \right\} \times 100(\%)$$

... Formula (1)

[Legend\

N: Ratio of bit rate to clock (N = 16)

D: Clock duty (D = 0.5 to 1.0)

L: Frame length (L = 9 to 12)

F: Absolute value of clock rate deviation

Assuming values of F (absolute value of clock rate deviation) = 0 and D (clock duty) = 0.5 in formula (1), the reception margin can be given by the formula.

 $M = \{0.5 - 1/(2 \times 16)\} \times 100 \ [\%] = 46.875\%$

However, this is only the computed value, and a margin of 20% to 30% should be allowed for in system design.

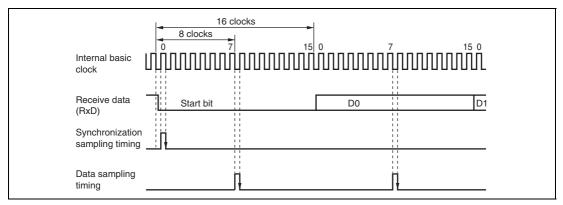


Figure 13.19 Receive Data Sampling Timing in Asynchronous Mode



Section 14 A/D Converter

This LSI includes a successive approximation type 10-bit A/D converter that allows up to four analog input channels to be selected. The block diagram of the A/D converter is shown in figure 14.1.

14.1 Features

- 10-bit resolution
- Four input channels
- Conversion time: at least 3.5 µs per channel (at 20 MHz operation)
- Two operating modes
 - Single mode: Single-channel A/D conversion
 - Scan mode: Continuous A/D conversion on 1 to 4 channels
- Four data registers
 - Conversion results are held in a 16-bit data register for each channel
- Sample and hold function
- Two conversion start methods
 - Software
 - External trigger signal
- Interrupt request
 - An A/D conversion end interrupt request (ADI) can be generated





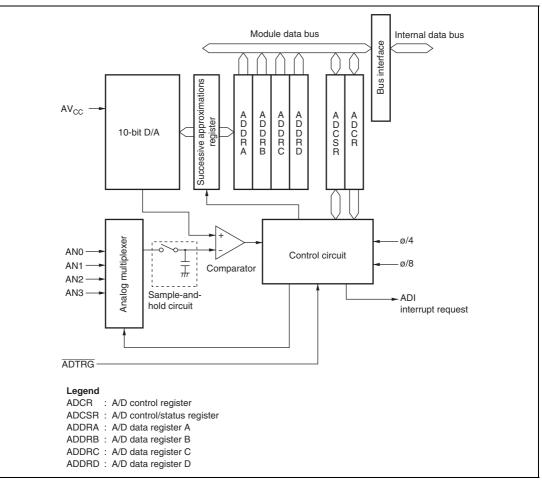


Figure 14.1 Block Diagram of A/D Converter



14.2 Input/Output Pins

Table 14.1 summarizes the input pins used by the A/D converter.

Table 14.1 Pin Configuration

Pin Name	Symbol	I/O	Function
Analog power supply pin	AV_{cc}	Input	Analog block power supply pin
Analog input pin 0	AN0	Input	Analog input pins
Analog input pin 1	AN1	Input	
Analog input pin 2	AN2	Input	
Analog input pin 3	AN3	Input	
A/D external trigger input pin	ADTRG	Input	External trigger input pin for starting A/D conversion



14.3 Register Description

The A/D converter has the following registers.

- A/D data register A (ADDRA)
- A/D data register B (ADDRB)
- A/D data register C (ADDRC)
- A/D data register D (ADDRD)
- A/D control/status register (ADCSR)
- A/D control register (ADCR)

14.3.1 A/D Data Registers A to D (ADDRA to ADDRD)

There are four 16-bit read-only ADDR registers; ADDRA to ADDRD, used to store the results of A/D conversion. The ADDR registers, which store a conversion result for each channel, are shown in table 14.2.

The converted 10-bit data is stored in bits 6 to 15. The lower 6 bits are always read as 0.

The data bus between the CPU and the A/D converter is 8 bits wide. The upper byte can be read directly from the CPU, however the lower byte should be read via a temporary register. The temporary register contents are transferred from the ADDR when the upper byte data is read. Therefore byte access to ADDR should be done by reading the upper byte first then the lower one. Word access is also possible. ADDR is initialized to H'0000.

Analog Input Channel	A/D Data Register to Be Stored Results of A/D Conversion
AN0	ADDRA
AN1	ADDRB
AN2	ADDRC
AN3	ADDRD

Table 14.2 Analog Input Channels and Corresponding ADDR Regist
--

14.3.2 A/D Control/Status Register (ADCSR)

ADCSR consists of the control bits and conversion end status bits of the A/D converter.

Bit	Bit Name	Initial Value	R/W	Description
7	ADF	0	R/W	A/D End Flag
				[Setting conditions]
				When A/D conversion ends in single mode
				 When A/D conversion ends on all the channels selected in scan mode
				[Clearing conditions]
				• When 0 is written after reading ADF = 1
6	ADIE	0	R/W	A/D Interrupt Enable
				A/D conversion end interrupt (ADI) request enabled by ADF when 1 is set
5	ADST	0	R/W	A/D Start
				Setting this bit to 1 starts A/D conversion. In single mode, this bit is cleared to 0 automatically when conversion on the specified channel is complete. In scan mode, conversion continues sequentially on the specified channels until this bit is cleared to 0 by software, a reset, or a transition to standby mode.
4	SCAN	0	R/W	Scan Mode
				Selects single mode or scan mode as the A/D conversion operating mode.
				0: Single mode
				1: Scan mode
3	CKS	0	R/W	Clock Select
				Selects the A/D conversions time
				0: Conversion time = 134 states (max.)
				1: Conversion time = 70 states (max.)
				Clear the ADST bit to 0 before switching the conversion time.



		Initial			
Bit	Bit Name	Value	R/W	Description	
2	CH2	0	R/W	Channel Select 0 to 2	
1	CH1	0	R/W	Select analog input chan	nels.
0	CH0	0	R/W	When SCAN = 0	When SCAN = 1
				X00: AN0	X00: AN0
				X01: AN1	X01: AN0 to AN1
				X10: AN2	X10: AN0 to AN2
				X11: AN3	X11: AN0 to AN3

Legend X: Don't care.

14.3.3 A/D Control Register (ADCR)

ADCR enables A/D conversion started by an external trigger signal.

Bit	Bit Name	Initial Value	R/W	Description
7	TRGE	0	R/W	Trigger Enable
				A/D conversion is started at the falling edge and the rising edge of the external trigger signal (ADTRG) when this bit is set to 1.
				The selection between the falling edge and rising edge of the external trigger pin (ADTRG) conforms to the WPEG5 bit in the interrupt edge select register 2 (IEGR2)
6 to 1	_	All 1	_	Reserved
				These bits are always read as 1.
0	_	0	R/W	Reserved
				Do not set this bit to 1, though the bit is readable/writable.

14.4 Operation

The A/D converter operates by successive approximation with 10-bit resolution. It has two operating modes; single mode and scan mode. When changing the operating mode or analog input channel, in order to prevent incorrect operation, first clear the bit ADST to 0 in ADCSR. The ADST bit can be set at the same time as the operating mode or analog input channel is changed.

14.4.1 Single Mode

In single mode, A/D conversion is performed once for the analog input on the specified single channel as follows:

- 1. A/D conversion is started from the first channel when the ADST bit in ADCSR is set to 1, according to software or external trigger input.
- 2. When A/D conversion is completed, the result is transferred to the corresponding A/D data register to the channel.
- 3. On completion of conversion, the ADF bit in ADCSR is set to 1. If the ADIE bit is set to 1 at this time, an ADI interrupt request is generated.
- 4. The ADST bit remains set to 1 during A/D conversion. When A/D conversion ends, the ADST bit is automatically cleared to 0 and the A/D converter enters the wait state.

14.4.2 Scan Mode

In scan mode, A/D conversion is performed sequentially for the analog input on the specified channels (four channels maximum) as follows:

- 1. When the ADST bit is set to 1 by software, or external trigger input, A/D conversion starts on the first channel in the group.
- 2. When A/D conversion for each channel is completed, the result is sequentially transferred to the A/D data register corresponding to each channel.
- 3. When conversion of all the selected channels is completed, the ADF flag in ADCSR is set to 1. If the ADIE bit is set to 1 at this time, an ADI interrupt is requested. Conversion of the first channel in the group starts again.
- 4. The ADST bit is not automatically cleared to 0. Steps [2] to [3] are repeated as long as the ADST bit remains set to 1. When the ADST bit is cleared to 0, A/D conversion stops.



14.4.3 Input Sampling and A/D Conversion Time

The A/D converter has a built-in sample-and-hold circuit. The A/D converter samples the analog input when the A/D conversion start delay time (t_D) has passed after the ADST bit is set to 1, then starts conversion. Figure 14.2 shows the A/D conversion timing. Table 14.3 shows the A/D conversion time.

As indicated in figure 14.2, the A/D conversion time includes t_D and the input sampling time. The length of t_D varies depending on the timing of the write access to ADCSR. The total conversion time therefore varies within the ranges indicated in table 14.3.

In scan mode, the values given in table 14.3 apply to the first conversion time. In the second and subsequent conversions, the conversion time is 128 states (fixed) when CKS = 0 and 66 states (fixed) when CKS = 1.

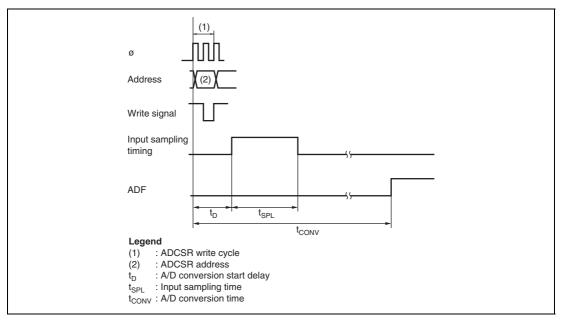


Figure 14.2 A/D Conversion Timing

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		CKS = 0			CKS = 1		
Item	Symbol	Min	Тур	Max	Min	Тур	Max
A/D conversion start delay	t _D	6		9	4	—	5
Input sampling time	t _{spl}	_	31			15	_
A/D conversion time	t _{conv}	131		134	69	_	70

Table 14.3 A/D Conversion Time (Single Mode)

Note: All values represent the number of states.

14.4.4 External Trigger Input Timing

A/D conversion can also be started by an external trigger input. When the TRGE bit is set to 1 in ADCR, external trigger input is enabled at the $\overline{\text{ADTRG}}$ pin. A falling edge at the $\overline{\text{ADTRG}}$ input pin sets the ADST bit to 1 in ADCSR, starting A/D conversion. Other operations, in both single and scan modes, are the same as when the bit ADST has been set to 1 by software. Figure 14.3 shows the timing.

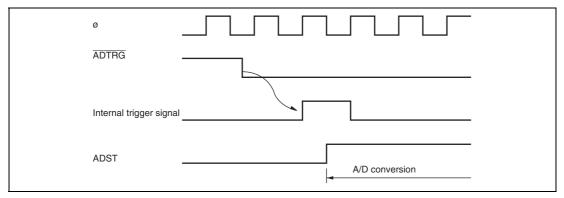


Figure 14.3 External Trigger Input Timing



14.5 A/D Conversion Accuracy Definitions

This LSI's A/D conversion accuracy definitions are given below.

Resolution

The number of A/D converter digital output codes

• Quantization error

The deviation inherent in the A/D converter, given by 1/2 LSB (see figure 14.4).

Offset error

The deviation of the analog input voltage value from the ideal A/D conversion characteristic when the digital output changes from the minimum voltage value 0000000000 to 0000000001 (see figure 14.5).

• Full-scale error

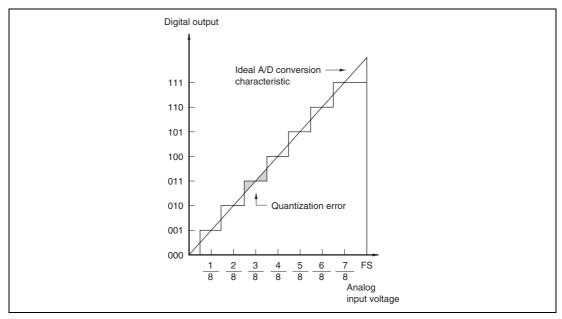
The deviation of the analog input voltage value from the ideal A/D conversion characteristic when the digital output changes from 1111111110 to 111111111 (see figure 14.5).

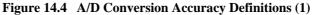
• Nonlinearity error

The error with respect to the ideal A/D conversion characteristics between zero voltage and full-scale voltage. Does not include offset error, full-scale error, or quantization error.

• Absolute accuracy

The deviation between the digital value and the analog input value. Includes offset error, full-scale error, quantization error, and nonlinearity error.





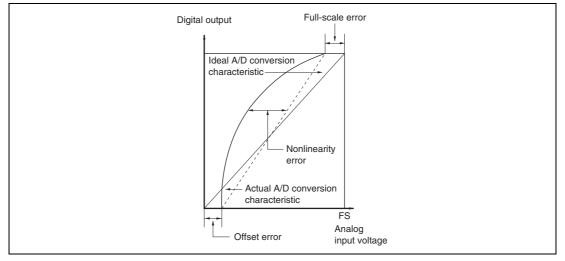


Figure 14.5 A/D Conversion Accuracy Definitions (2)



14.6 Usage Notes

14.6.1 Permissible Signal Source Impedance

This LSI's analog input is designed such that conversion accuracy is guaranteed for an input signal for which the signal source impedance is 5 k Ω or less. This specification is provided to enable the A/D converter's sample-and-hold circuit input capacitance to be charged within the sampling time; if the sensor output impedance exceeds 5 k Ω , charging may be insufficient and it may not be possible to guarantee A/D conversion accuracy. However, for A/D conversion in single mode with a large capacitance provided externally, the input load will essentially comprise only the internal input resistance of 10 k Ω , and the signal source impedance is ignored. However, as a low-pass filter effect is obtained in this case, it may not be possible to follow an analog signal with a large differential coefficient (e.g., 5 mV/µs or greater) (see figure 14.6). When converting a high-speed analog signal or converting in scan mode, a low-impedance buffer should be inserted.

14.6.2 Influences on Absolute Accuracy

Adding capacitance results in coupling with GND, and therefore noise in GND may adversely affect absolute accuracy. Be sure to make the connection to an electrically stable GND.

Care is also required to ensure that filter circuits do not interfere with digital signals or act as antennas on the mounting board.

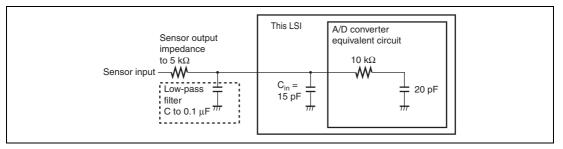


Figure 14.6 Analog Input Circuit Example

Section 15 Power-On Reset and Low-Voltage Detection Circuits (Optional)

This LSI can include a power-on reset circuit and low-voltage detection circuit as optional circuits.

The low-voltage detection circuit consists of two circuits: LVDI (interrupt by low voltage detect) and LVDR (reset by low voltage detect) circuits.

This circuit is used to prevent abnormal operation (runaway execution) from occurring due to the power supply voltage fall and to recreate the state before the power supply voltage fall when the power supply voltage rises again.

Even if the power supply voltage falls, the unstable state when the power supply voltage falls below the guaranteed operating voltage can be removed by entering standby mode when exceeding the guaranteed operating voltage and during normal operation. Thus, system stability can be improved. If the power supply voltage falls more, the reset state is automatically entered. If the power supply voltage rises again, the reset state is held for a specified period, then active mode is automatically entered.

Figure 15.1 is a block diagram of the power-on reset circuit and the low-voltage detection circuit.

15.1 Features

• Power-on reset circuit

Uses an external capacitor to generate an internal reset signal when power is first supplied.

• Low-voltage detection circuit

LVDR: Monitors the power-supply voltage, and generates an internal reset signal when the voltage falls below a specified value.

LVDI: Monitors the power-supply voltage, and generates an interrupt when the voltage falls below or rises above respective specified values.

Two pairs of detection levels for reset generation voltage are available: when only the LVDR circuit is used, or when the LVDI and LVDR circuits are both used.

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LVI0000A_000020030300
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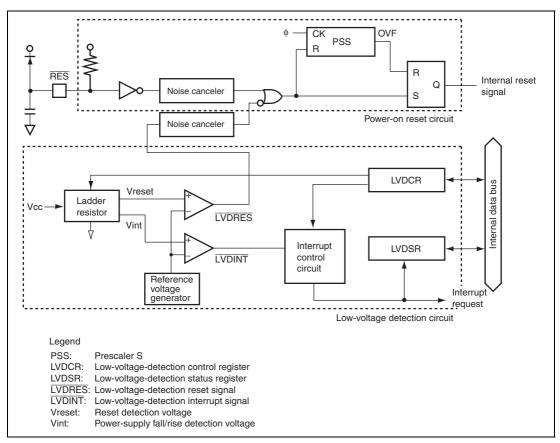


Figure 15.1 Block Diagram of Power-On Reset Circuit and Low-Voltage Detection Circuit

15.2 Register Descriptions

The low-voltage detection circuit has the following registers.

- Low-voltage-detection control register (LVDCR)
- Low-voltage-detection status register (LVDSR)

15.2.1 Low-Voltage-Detection Control Register (LVDCR)

LVDCR is used to enable or disable the low-voltage detection circuit, set the detection levels for the LVDR function, enable or disable the LVDR function, and enable or disable generation of an interrupt when the power-supply voltage rises above or falls below the respective levels.

Table 15.1 shows the relationship between the LVDCR settings and select functions. LVDCR should be set according to table 15.1.

Bit	Bit Name	Initial Value	R/W	Description
7	LVDE	0*	R/W	LVD Enable
				0: The low-voltage detection circuit is not used (In standby mode)
				1: The low-voltage detection circuit is used
6 to 4	_	All 1		Reserved
				These bits are always read as 1, and cannot be modified.
3	LVDSEL	0*	R/W	LVDR Detection Level Select
				0: Reset detection voltage is 2.3 V (typ.)
				1: Reset detection voltage is 3.6 V (typ.)
				When the falling or rising voltage detection interrupt is used, reset detection voltage of 2.3 V (typ.) should be used. When only a reset detection interrupt is used, reset detection voltage of 3.6 V (typ.) should be used.
2	LVDRE	0*	R/W	LVDR Enable
				0: Disables the LVDR function
				1: Enables the LVDR function
1	LVDDE	0	R/W	Voltage-Fall-Interrupt Enable
				0: Interrupt on the power-supply voltage falling below the selected detection level disabled
				1: Interrupt on the power-supply voltage falling below the selected detection level enabled
0	LVDUE	0	R/W	Voltage-Rise-Interrupt Enable
				0: Interrupt on the power-supply voltage rising above the selected detection level disabled
				1: Interrupt on the power-supply voltage rising above the selected detection level enabled
Note:	* Not initia	lized by LV	'DR but i	nitialized by a power-on reset or WDT reset.



	L١	/DCR Se	ttings		Select Functions				
LVDE	LVDSEL	LVDRE	LVDDE	LVDUE	Power-On Reset	LVDR	Low-Voltage- Detection Falling Interrupt	Low-Voltage- Detection Rising Interrupt	
0	*	*	*	*	0	_	_	_	
1	1	1	0	0	0	0	_	_	
1	0	0	1	0	0	_	0	_	
1	0	0	1	1	0	—	0	0	
1	0	1	1	1	0	0	0	0	

Table 15.1 LVDCR Settings and Select Functions

Legend * means invalid.

15.2.2 Low-Voltage-Detection Status Register (LVDSR)

LVDSR indicates whether the power-supply voltage falls below or rises above the respective specified values.

Bit	Bit Name	Initial Value	R/W	Description
7 to 2		All 1	_	Reserved
				These bits are always read as 1, and cannot be modified.
1	LVDDF	0*	R/W	LVD Power-Supply Voltage Fall Flag
				[Setting condition]
				When the power-supply voltage falls below Vint (D) (typ. = 3.7 V)
				[Clearing condition]
				Writing 0 to this bit after reading it as 1
0	LVDUF	0*	R/W	LVD Power-Supply Voltage Rise Flag
				[Setting condition]
				When the power supply voltage falls below Vint (D) while the LVDUE bit in LVDCR is set to 1, then rises above Vint (U) (typ. = 4.0 V) before falling below Vreset1 (typ. = 2.3 V)
				[Clearing condition]
				Writing 0 to this bit after reading it as 1
Note:	* Initialized	d by LVDI	٦.	

15.3 Operation

15.3.1 Power-On Reset Circuit

Figure 15.2 shows the timing of the operation of the power-on reset circuit. As the power-supply voltage rises, the capacitor which is externally connected to the $\overline{\text{RES}}$ pin is gradually charged via the on-chip pull-up resistor (typ. 150 k Ω). Since the state of the $\overline{\text{RES}}$ pin is transmitted within the chip, the prescaler S and the entire chip are in their reset states. When the level on the $\overline{\text{RES}}$ pin reaches the specified value, the prescaler S is released from its reset state and it starts counting. The OVF signal is generated to release the internal reset signal after the prescaler S has counted 131,072 clock (ϕ) cycles. The noise cancellation circuit of approximately 100 ns is incorporated to prevent the incorrect operation of the chip by noise on the $\overline{\text{RES}}$ pin.

To achieve stable operation of this LSI, the power supply needs to rise to its full level and settles within the specified time. The maximum time required for the power supply to rise and settle after power has been supplied (t_{PWON}) is determined by the oscillation frequency (f_{osc}) and capacitance which is connected to $\overline{\text{RES}}$ pin ($C_{\overline{\text{RES}}}$). If t_{PWON} means the time required to reach 90 % of power supply voltage, the power supply circuit should be designed to satisfy the following formula.

 $t_{_{PWON}} \text{ (ms)} \le 90 \times C_{\overline{\text{RES}}} \text{ (}\mu\text{F}\text{)} + 162/f_{_{OSC}} \text{ (MHz)}$

(t_{_{PWON}} \leq 3000 ms, $C_{\overline{RES}} \geq 0.22~\mu F,$ and $f_{_{OSC}}$ = 10 in 2-MHz to 10-MHz operation)

Note that the power supply voltage (Vcc) must fall below Vpor = 100 mV and rise after charge on the $\overline{\text{RES}}$ pin is removed. To remove charge on the $\overline{\text{RES}}$ pin, it is recommended that the diode should be placed near Vcc. If the power supply voltage (Vcc) rises from the point above Vpor, a power-on reset may not occur.

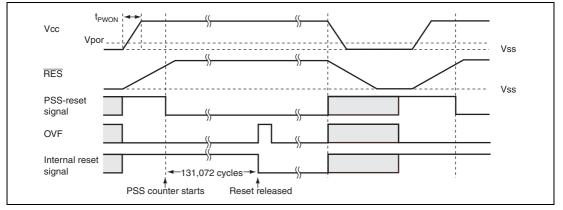


Figure 15.2 Operational Timing of Power-On Reset Circuit



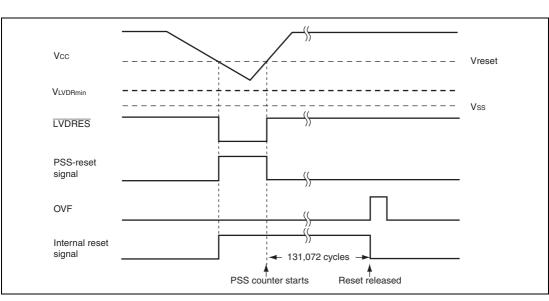
15.3.2 Low-Voltage Detection Circuit

(1) LVDR (Reset by Low Voltage Detect) Circuit

Figure 15.3 shows the timing of the LVDR function. The LVDR enters the module-standby state after a power-on reset is canceled. To operate the LVDR, set the LVDE bit in LVDCR to 1, wait for 50 μ s (t_{LVDON}) until the reference voltage and the low-voltage-detection power supply have stabilized by a software timer, etc., then set the LVDRE bit in LVDCR to 1. After that, the output settings of ports must be made. To cancel the low-voltage detection circuit, first the LVDRE bit should be cleared to 0 and then the LVDE bit should be cleared to 0. The LVDE and LVDRE bits must not be cleared to 0 simultaneously because incorrect operation may occur.

When the power-supply voltage falls below the Vreset voltage (typ. = 2.3 V or 3.6 V), the LVDR clears the \overline{LVDRES} signal to 0, and resets the prescaler S. The low-voltage detection reset state remains in place until a power-on reset is generated. When the power-supply voltage rises above the Vreset voltage again, the prescaler S starts counting. It counts 131,072 clock (ϕ) cycles, and then releases the internal reset signal. In this case, the LVDE, LVDSEL, and LVDRE bits in LVDCR are not initialized.

Note that if the power supply voltage (Vcc) falls below $V_{LVDRmin} = 1.0$ V and then rises from that point, the low-voltage detection reset may not occur.



If the power supply voltage (Vcc) falls below Vpor = 100 mV, a power-on reset occurs.

Figure 15.3 Operational Timing of LVDR Circuit



(2) LVDI (Interrupt by Low Voltage Detect) Circuit

Figure 15.4 shows the timing of LVDI functions. The LVDI enters the module-standby state after a power-on reset is canceled. To operate the LVDI, set the LVDE bit in LVDCR to 1, wait for 50 μ s (t_{LVDON}) until the reference voltage and the low-voltage-detection power supply have stabilized by a software timer, etc., then set the LVDDE and LVDUE bits in LVDCR to 1. After that, the output settings of ports must be made. To cancel the low-voltage detection circuit, first the LVDDE and LVDUE bits should all be cleared to 0 and then the LVDDE bit should be cleared to 0. The LVDE bit must not be cleared to 0 at the same timing as the LVDDE and LVDUE bits because incorrect operation may occur.

When the power-supply voltage falls below Vint (D) (typ. = 3.7 V) voltage, the LVDI clears the $\overline{\text{LVDINT}}$ signal to 0 and the LVDDF bit in LVDSR is set to 1. If the LVDDE bit is 1 at this time, an IRQ0 interrupt request is simultaneously generated. In this case, the necessary data must be saved in the external EEPROM, etc, and a transition must be made to standby mode or subsleep mode. Until this processing is completed, the power supply voltage must be higher than the lower limit of the guaranteed operating voltage.

When the power-supply voltage does not fall below Vreset1 (typ. = 2.3 V) voltage but rises above Vint (U) (typ. = 4.0 V) voltage, the LVDI sets the $\overline{\text{LVDINT}}$ signal to 1. If the LVDUE bit is 1 at this time, the LVDUF bit in LVDSR is set to 1 and an IRQ0 interrupt request is simultaneously generated.

If the power supply voltage (Vcc) falls below Vreset1 (typ. = 2.3 V) voltage, the LVDR function is performed.

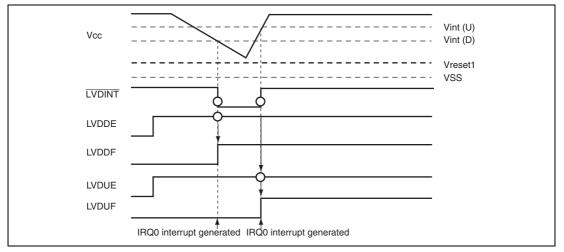


Figure 15.4 Operational Timing of LVDI Circuit



(3) Procedures for Clearing Settings when Using LVDR and LVDI

To operate or release the low-voltage detection circuit normally, follow the procedure described below. Figure 15.5 shows the timing for the operation and release of the low-voltage detection circuit.

- 1. To operate the low-voltage detection circuit, set the LVDE bit in LVDCR to 1.
- 2. Wait for 50 μ s (t_{LVDON}) until the reference voltage and the low-voltage-detection power supply have stabilized by a software timer, etc. Then, clear the LVDDF and LVDUF bits in LVDSR to 0 and set the LVDRE, LVDDE, and LVDUE bits in LVDCR to 1, as required.
- 3. To release the low-voltage detection circuit, start by clearing all of the LVDRE, LVDDE, and LVDUE bits to 0. Then clear the LVDE bit to 0. The LVDE bit must not be cleared to 0 at the same timing as the LVDRE, LVDDE, and LVDUE bits because incorrect operation may occur.

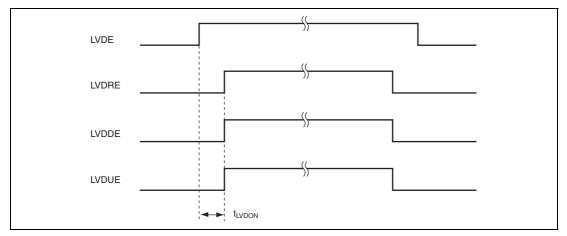


Figure 15.5 Timing for Operation/Release of Low-Voltage Detection Circuit

Section 16 Power Supply Circuit

This LSI incorporates an internal power supply step-down circuit. Use of this circuit enables the internal power supply to be fixed at a constant level of approximately 3.0 V, independently of the voltage of the power supply connected to the external V_{cc} pin. As a result, the current consumed when an external power supply is used at 3.0 V or above can be held down to virtually the same low level as when used at approximately 3.0 V. If the external power supply is 3.0 V or below, the internal voltage will be practically the same as the external voltage. It is, of course, also possible to use the same level of external power supply voltage and internal power supply voltage without using the internal power supply step-down circuit.

16.1 When Using Internal Power Supply Step-Down Circuit

Connect the external power supply to the V_{cc} pin, and connect a capacitance of approximately 0.1 μ F between V_{cc} and V_{ss} , as shown in figure 16.1. The internal step-down circuit is made effective simply by adding this external circuit. In the external circuit interface, the external power supply voltage connected to V_{cc} and the GND potential connected to V_{ss} are the reference levels. For example, for port input/output levels, the V_{cc} level is the reference for the high level, and the V_{ss} level is that for the low level. The A/D converter analog power supply is not affected by the internal step-down circuit.

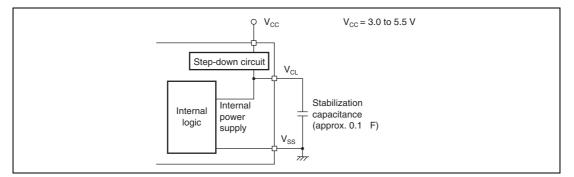


Figure 16.1 Power Supply Connection when Internal Step-Down Circuit is Used

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16.2 When Not Using Internal Power Supply Step-Down Circuit

When the internal power supply step-down circuit is not used, connect the external power supply to the V_{cL} pin and V_{cc} pin, as shown in figure 16.2. The external power supply is then input directly to the internal power supply. The permissible range for the power supply voltage is 3.0 V to 3.6 V. Operation cannot be guaranteed if a voltage outside this range (less than 3.0 V or more than 3.6 V) is input.

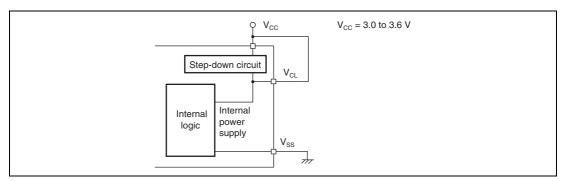


Figure 16.2 Power Supply Connection when Internal Step-Down Circuit is Not Used



Section 17 List of Registers

The register list gives information on the on-chip I/O register addresses, how the register bits are configured, and the register states in each operating mode. The information is given as shown below.

- 1. Register addresses (address order)
- Registers are listed from the lower allocation addresses.
- Registers are classified by functional modules.
- The data bus width is indicated.
- The number of access states is indicated.
- 2. Register bits
- Bit configurations of the registers are described in the same order as the register addresses.
- Reserved bits are indicated by in the bit name column.
- When registers consist of 16 bits, bits are described from the MSB side.
- 3. Register states in each operating mode
- Register states are described in the same order as the register addresses.
- The register states described here are for the basic operating modes. If there is a specific reset for an on-chip peripheral module, refer to the section on that on-chip peripheral module.



17.1 Register Addresses (Address Order)

The data bus width indicates the numbers of bits by which the register is accessed.

The number of access states indicates the number of states based on the specified reference clock.

Register Name	Abbre- viation	Bit No	Address	Module Name	Data Bus Width	Access State
Serial mode register_3	SMR_3	8	H'F600	SCI3_3	8	3
Bit rate register_3	BRR_3	8	H'F601	SCI3_3	8	3
Serial control register 3_3	SCR3_3	8	H'F602	SCI3_3	8	3
Transmit data register_3	TDR_3	8	H'F603	SCI3_3	8	3
Serial status register_3	SSR_3	8	H'F604	SCI3_3	8	3
Receive data register_3	RDR_3	8	H'F605	SCI3_3	8	3
_		_	H'F606, H'F607	SCI3_3		
SCI3_3 module control register	SMCR	8	H'F608	SCI3_3	8	3
Low-voltage-detection control register	LVDCR	8	H'F730	LVDC*1	8	2
Low-voltage-detection status register	LVDSR	8	H'F731	LVDC*1	8	2
Serial mode register_2	SMR_2	8	H'F740	SCI3_2	8	3
Bit rate register_2	BRR_2	8	H'F741	SCI3_2	8	3
Serial control register 3_2	SCR3_2	8	H'F742	SCI3_2	8	3
Transmit data register_2	TDR_2	8	H'F743	SCI3_2	8	3
Serial status register_2	SSR_2	8	H'F744	SCI3_2	8	3
Receive data register_2	RDR_2	8	H'F745	SCI3_2	8	3
Timer mode register W	TMRW	8	H'FF80	Timer W	8	2
Timer control register W	TCRW	8	H'FF81	Timer W	8	2
Timer interrupt enable register W	TIERW	8	H'FF82	Timer W	8	2
Timer status register W	TSRW	8	H'FF83	Timer W	8	2
Timer I/O control register 0	TIOR0	8	H'FF84	Timer W	8	2
Timer I/O control register 1	TIOR1	8	H'FF85	Timer W	8	2
Timer counter	TCNT	16	H'FF86	Timer W	16* ²	2
General register A	GRA	16	H'FF88	Timer W	16* ²	2

Register Name	Abbre- viation	Bit No	Address	Module Name	Data Bus Width	Access State
General register B	GRB	16	H'FF8A	Timer W	16* ²	2
General register C	GRC	16	H'FF8C	Timer W	16* ²	2
General register D	GRD	16	H'FF8E	Timer W	16* ²	2
Flash memory control register 1	FLMCR1	8	H'FF90	ROM	8	2
Flash memory control register 2	FLMCR2	8	H'FF91	ROM	8	2
Erase block register 1	EBR1	8	H'FF93	ROM	8	2
Flash memory enable register	FENR	8	H'FF9B	ROM	8	2
Timer control register V0	TCRV0	8	H'FFA0	Timer V	8	3
Timer control/status register V	TCSRV	8	H'FFA1	Timer V	8	3
Timer constant register A	TCORA	8	H'FFA2	Timer V	8	3
Timer constant register B	TCORB	8	H'FFA3	Timer V	8	3
Timer counter V	TCNTV	8	H'FFA4	Timer V	8	3
Timer control register V1	TCRV1	8	H'FFA5	Timer V	8	3
Serial mode register	SMR	8	H'FFA8	SCI3	8	3
Bit rate register	BRR	8	H'FFA9	SCI3	8	3
Serial control register 3	SCR3	8	H'FFAA	SCI3	8	3
Transmit data register	TDR	8	H'FFAB	SCI3	8	3
Serial status register	SSR	8	H'FFAC	SCI3	8	3
Receive data register	RDR	8	H'FFAD	SCI3	8	3
A/D data register A	ADDRA	16	H'FFB0	A/D converter	8	3
A/D data register B	ADDRB	16	H'FFB2	A/D converter	8	3
A/D data register C	ADDRC	16	H'FFB4	A/D converter	8	3
A/D data register D	ADDRD	16	H'FFB6	A/D converter	8	3
A/D control/status register	ADCSR	8	H'FFB8	A/D converter	8	3
A/D control register	ADCR	8	H'FFB9	A/D converter	8	3
Timer control/status register WD	TCSRWD	8	H'FFC0	WDT* ³	8	2
Timer counter WD	TCWD	8	H'FFC1	WDT* ³	8	2



Register Name	Abbre- viation	Bit No	Address	Module Name	Data Bus Width	Access State
Timer mode register WD	TMWD	8	H'FFC2	WDT* ³	8	2
Address break control register	ABRKCR	8	H'FFC8	Address break	8	2
Address break status register	ABRKSR	8	H'FFC9	Address break	8	2
Break address register H	BARH	8	H'FFCA	Address break	8	2
Break address register L	BARL	8	H'FFCB	Address break	8	2
Break data register H	BDRH	8	H'FFCC	Address break	8	2
Break data register L	BDRL	8	H'FFCD	Address break	8	2
Port pull-up control register 1	PUCR1	8	H'FFD0	I/O port	8	2
Port pull-up control register 5	PUCR5	8	H'FFD1	I/O port	8	2
Port data register 1	PDR1	8	H'FFD4	I/O port	8	2
Port data register 2	PDR2	8	H'FFD5	I/O port	8	2
Port data register 5	PDR5	8	H'FFD8	I/O port	8	2
Port data register 7	PDR7	8	H'FFDA	I/O port	8	2
Port data register 8	PDR8	8	H'FFDB	I/O port	8	2
Port data register B	PDRB	8	H'FFDD	I/O port	8	2
Port mode register 1	PMR1	8	H'FFE0	I/O port	8	2
Port mode register 5	PMR5	8	H'FFE1	I/O port	8	2
Port control register 1	PCR1	8	H'FFE4	I/O port	8	2
Port control register 2	PCR2	8	H'FFE5	I/O port	8	2
Port control register 5	PCR5	8	H'FFE8	I/O port	8	2
Port control register 7	PCR7	8	H'FFEA	I/O port	8	2
Port control register 8	PCR8	8	H'FFEB	I/O port	8	2
System control register 1	SYSCR1	8	H'FFF0	Power- down	8	2
System control register 2	SYSCR2	8	H'FFF1	Power- down	8	2
Interrupt edge select register 1	IEGR1	8	H'FFF2	Interrupts	8	2

Register Name	Abbre- viation	Bit No	Address	Module Name	Data Bus Width	Access State
Interrupt edge select register 2	IEGR2	8	H'FFF3	Interrupts	8	2
Interrupt enable register 1	IENR1	8	H'FFF4	Interrupts	8	2
Interrupt flag register 1	IRR1	8	H'FFF6	Interrupts	8	2
Wake-up interrupt flag register	IWPR	8	H'FFF8	Interrupts	8	2
Module standby control register 1	MSTCR1	8	H'FFF9	Power- down	8	2
Module standby control register 2	MSTCR2	8	H'FFFA	Power- down	8	2

Notes: 1. LVDC: Low-voltage detection circuits (optional)

2. Only word access can be used.

3. WDT: Watchdog timer



17.2 Register Bits

Register bit names of the on-chip peripheral modules are described below.

Each line covers eight bits, and 16-bit registers are shown as 2 lines.

Register Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Module Name
SMR_3	COM	CHR	PE	PM	STOP	MP	CKS1	CKS0	SCI3_3
BRR_3	BRR7	BRR6	BRR5	BRR4	BRR3	BRR2	BRR1	BRR0	
SCR3_3	TIE	RIE	TE	RE	MPIE	TEIE	CKE1	CKE0	-
TDR_3	TDR7	TDR6	TDR5	TDR4	TDR3	TDR2	TDR1	TDR0	
SSR_3	TDRE	RDRF	OER	FER	PER	TEND	MPBR	MPBT	-
RDR_3	RDR7	RDR6	RDR5	RDR4	RDR3	RDR2	RDR1	RDR0	-
SMCR	_	_	_	_	_	_	TXD_3	MSTS3_3	-
LVDCR	LVDE	_	_	_	LVDSEL	LVDRE	LVDDE	LVDUE	LVDC
LVDSR	_	_	_	_	_	_	LVDDF	LVDUF	(optional)
SMR_2	COM	CHR	PE	PM	STOP	MP	CKS1	CKS0	SCI3_2
BRR_2	BRR7	BRR6	BRR5	BRR4	BRR3	BRR2	BRR1	BRR0	
SCR3_2	TIE	RIE	TE	RE	MPIE	TEIE	CKE1	CKE0	-
TDR_2	TDR7	TDR6	TDR5	TDR4	TDR3	TDR2	TDR1	TDR0	-
SSR_2	TDRE	RDRF	OER	FER	PER	TEND	MPBR	MPBT	-
RDR_2	RDR7	RDR6	RDR5	RDR4	RDR3	RDR2	RDR1	RDR0	
TMRW	CTS	_	BUFEB	BUFEA	_	PWMD	PWMC	PWMB	Timer W
TCRW	CCLR	CKS2	CKS1	CKS0	TOD	TOC	ТОВ	TOA	
TIERW	OVIE	_	_	_	IMIED	IMIEC	IMIEB	IMIEA	
TSRW	OVF	_	_	_	IMFD	IMFC	IMFB	IMFA	
TIOR0	—	IOB2	IOB1	IOB0	—	IOA2	IOA1	IOA0	
TIOR1	_	IOD2	IOD1	IOD0	_	IOC2	IOC1	IOC0	
TCNT	TCNT15	TCNT14	TCNT13	TCNT12	TCNT11	TCNT10	TCNT9	TCNT8	
	TCNT7	TCNT6	TCNT5	TCNT4	TCNT3	TCNT2	TCNT1	TCNT0	
GRA	GRA15	GRA14	GRA13	GRA12	GRA11	GRA10	GRA9	GRA8	<u>.</u>
	GRA7	GRA6	GRA5	GRA4	GRA3	GRA2	GRA1	GRA0	
GRB	GRB15	GRB14	GRB13	GRB12	GRB11	GRB10	GRB9	GRB8	
	GRB7	GRB6	GRB5	GRB4	GRB3	GRB2	GRB1	GRB0	

Register Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Module Name
GRC	GRC15	GRC14	GRC13	GRC12	GRC11	GRC10	GRC9	GRC8	Timer W
	GRC7	GRC6	GRC5	GRC4	GRC3	GRC2	GRC1	GRC0	
GRD	GRD15	GRD14	GRD13	GRD12	GRD11	GRD10	GRD9	GRD8	
	GRD7	GRD6	GRD5	GRD4	GRD3	GRD2	GRD1	GRD0	
FLMCR1	_	SWE	ESU	PSU	EV	PV	E	Р	ROM
FLMCR2	FLER	_	_	_	_	_	_	_	
EBR1	_		_	EB4	EB3	EB2	EB1	EB0	
FENR	FLSHE		_	_	_	_		_	
TCRV0	CMIEB	CMIEA	OVIE	CCLR1	CCLR0	CKS2	CKS1	CKS0	Timer V
TCSRV	CMFB	CMFA	OVF	_	OS3	OS2	OS1	OS0	
TCORA	TCORA7	TCORA6	TCORA5	TCORA4	TCORA3	TCORA2	TCORA1	TCORA0	
TCORB	TCORB7	TCORB6	TCORB5	TCORB4	TCORB3	TCORB2	TCORB1	TCORB0	
TCNTV	TCNTV7	TCNTV6	TCNTV5	TCNTV4	TCNTV3	TCNTV2	TCNTV1	TCNTV0	
TCRV1	_	_	_	TVEG1	TVEG0	TRGE	_	ICKS0	
SMR	COM	CHR	PE	PM	STOP	MP	CKS1	CKS0	SCI3
BRR	BRR7	BRR6	BRR5	BRR4	BRR3	BRR2	BRR1	BRR0	
SCR3	TIE	RIE	TE	RE	MPIE	TEIE	CKE1	CKE0	
TDR	TDR7	TDR6	TDR5	TDR4	TDR3	TDR2	TDR1	TDR0	
SSR	TDRE	RDRF	OER	FER	PER	TEND	MPBR	MPBT	
RDR	RDR7	RDR6	RDR5	RDR4	RDR3	RDR2	RDR1	RDR0	
ADDRA	AD9	AD8	AD7	AD6	AD5	AD4	AD3	AD2	A/D converter
	AD1	AD0	_	_	_		_	_	
ADDRB	AD9	AD8	AD7	AD6	AD5	AD4	AD3	AD2	
	AD1	AD0	_	_	_	_	_	_	
ADDRC	AD9	AD8	AD7	AD6	AD5	AD4	AD3	AD2	
	AD1	AD0	_	_	_		_	_	
ADDRD	AD9	AD8	AD7	AD6	AD5	AD4	AD3	AD2	
	AD1	AD0	_	_	_	_	_	_	
ADCSR	ADF	ADIE	ADST	SCAN	CKS	CH2	CH1	CH0	
ADCR	TRGE		_	_	—	_	_	—	
TCSRWD	B6WI	TCWE	B4WI	TCSRWE	B2WI	WDON	B0WI	WRST	WDT*
TCWD	TCWD7	TCWD6	TCWD5	TCWD4	TCWD3	TCWD2	TCWD1	TCWD0	
TMWD	_	—	_	_	CKS3	CKS2	CKS1	CKS0	



Register Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Module Name
ABRKCR	RTINTE	CSEL1	CSEL0	ACMP2	ACMP1	ACMP0	DCMP1	DCMP0	Address
ABRKSR	ABIF	ABIE	_	_	_	_	_	_	break
BARH	BARH7	BARH6	BARH5	BARH4	BARH3	BARH2	BARH1	BARH0	-
BARL	BARL7	BARL6	BARL5	BARL4	BARL3	BARL2	BARL1	BARL0	-
BDRH	BDRH7	BDRH6	BDRH5	BDRH4	BDRH3	BDRH2	BDRH1	BDRH0	-
BDRL	BDRL7	BDRL6	BDRL5	BDRL4	BDRL3	BDRL2	BDRL1	BDRL0	•
PUCR1	PUCR17	PUCR16	PUCR15	PUCR14	_	PUCR12	PUCR11	PUCR10	I/O port
PUCR5	_	_	PUCR55	PUCR54	PUCR53	PUCR52	PUCR51	PUCR50	-
PDR1	P17	P16	P15	P14	_	P12	P11	P10	-
PDR2	_	_	_	_	_	P22	P21	P20	-
PDR5	P57	P56	P55	P54	P53	P52	P51	P50	-
PDR7	_	P76	P75	P74	P73	P72	P71	P70	-
PDR8	_	_	_	P84	P83	P82	P81	P80	-
PDRB	_	_	_	_	PB3	PB2	PB1	PB0	-
PMR1	IRQ3	_	_	IRQ0	TXD2	_	TXD	_	-
PMR5	POF57	POF56	WKP5	WKP4	WKP3	WKP2	WKP1	WKP0	-
PCR1	PCR17	PCR16	PCR15	PCR14	_	PCR12	PCR11	PCR10	-
PCR2	_	_	_	_	_	PCR22	PCR21	PCR20	-
PCR5	PCR57	PCR56	PCR55	PCR54	PCR53	PCR52	PCR51	PCR50	-
PCR7	_	PCR76	PCR75	PCR74	PCR73	PCR72	PCR71	PCR70	-
PCR8	_	_	_	PCR84	PCR83	PCR82	PCR81	PCR80	
SYSCR1	SSBY	STS2	STS1	STS0	_	_	_	_	Power-down
SYSCR2	SMSEL	_	DTON	MA2	MA1	MA0	_	_	-
IEGR1	_	_	_	_	IEG3	_	_	IEG0	Interrupts
IEGR2	_	_	WPEG5	WPEG4	WPEG3	WPEG2	WPEG1	WPEG0	-
IENR1	IENDT	_	IENWP	_	IEN3	_	_	IEN0	-
IRR1	IRRDT	_	_	_	IRRI3	_	_	IRRI0	-
IWPR	_	_	IWPF5	IWPF4	IWPF3	IWPF2	IWPF1	IWPF0	-
MSTCR1	_	_	MSTS3	MSTAD	MSTWD	MSTTW	MSTTV	_	Power-down
MSTCR2	MSTS3_2	_	_	_	_	_	_	_	

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Note: * WDT: Watchdog timer

17.3 Register States in Each Operating Mode

Register Name	Reset	Active	Sleep	Subsleep	Standby	Module
SMR_3	Initialized	_	_	Initialized	Initialized	SCI3_3
BRR_3	Initialized	_	_	Initialized	Initialized	_
SCR3_3	Initialized	—	—	Initialized	Initialized	_
TDR_3	Initialized	_	_	Initialized	Initialized	-
SSR_3	Initialized	_	_	Initialized	Initialized	_
RDR_3	Initialized	_	_	Initialized	Initialized	_
SMCR	Initialized	_	_	Initialized	Initialized	_
LVDCR	Initialized	_	_	_	_	LVDC (optional)
LVDSR	Initialized	—	_	_	_	-
SMR_2	Initialized	_	_	Initialized	Initialized	SCI3_2
BRR_2	Initialized	_	_	Initialized	Initialized	-
SCR3_2	Initialized	_	_	Initialized	Initialized	-
TDR_2	Initialized	_	_	Initialized	Initialized	_
SSR_2	Initialized	_	_	Initialized	Initialized	_
RDR_2	Initialized	_	_	Initialized	Initialized	_
TMRW	Initialized	_	_	_	_	Timer W
TCRW	Initialized	_	_	_	_	_
TIERW	Initialized	_	_	_	_	_
TSRW	Initialized	_	_	_	_	_
TIOR0	Initialized	_	_	_	_	_
TIOR1	Initialized	_	_	_	_	_
TCNT	Initialized	_	_	_	_	_
GRA	Initialized	_	_	_	_	_
GRB	Initialized	_	_	_	_	_
GRC	Initialized	_	—	_	_	_
GRD	Initialized	_	_	_	_	_
FLMCR1	Initialized	_	_	Initialized	Initialized	ROM
FLMCR2	Initialized	_	_	_	_	_
EBR1	Initialized	_	_	Initialized	Initialized	_
FENR	Initialized	_	—	_		_



Register Name	Reset	Active	Sleep	Subsleep	Standby	Module
TCRV0	Initialized		_	Initialized	Initialized	Timer V
TCSRV	Initialized	_	_	Initialized	Initialized	_
TCORA	Initialized	_	_	Initialized	Initialized	_
TCORB	Initialized	—	_	Initialized	Initialized	_
TCNTV	Initialized	—	_	Initialized	Initialized	_
TCRV1	Initialized	_	_	Initialized	Initialized	_
SMR	Initialized		_	Initialized	Initialized	SCI3
BRR	Initialized	—	_	Initialized	Initialized	_
SCR3	Initialized	_	_	Initialized	Initialized	-
TDR	Initialized		_	Initialized	Initialized	-
SSR	Initialized	—	_	Initialized	Initialized	_
RDR	Initialized		_	Initialized	Initialized	-
ADDRA	Initialized	—	_	Initialized	Initialized	A/D converter
ADDRB	Initialized	—	_	Initialized	Initialized	_
ADDRC	Initialized	_	_	Initialized	Initialized	_
ADDRD	Initialized	—	_	Initialized	Initialized	_
ADCSR	Initialized	—	_	Initialized	Initialized	_
ADCR	Initialized	_	_	Initialized	Initialized	-
TCSRWD	Initialized		_	_	—	WDT*
TCWD	Initialized		_	_	—	-
TMWD	Initialized		_	_	_	_
ABRKCR	Initialized		—	_	_	Address Break
ABRKSR	Initialized		_	_	—	-
BARH	Initialized		_	_	_	_
BARL	Initialized		_	_	—	-
BDRH	Initialized		_	_	_	-
BDRL	Initialized	_	_	_	_	_
PUCR1	Initialized	_	_	_	_	I/O port
PUCR5	Initialized	_	_	_	_	_
PDR1	Initialized	_	_	_	_	_
PDR2	Initialized	_	_	_	_	_
PDR5	Initialized	_	_	_	_	_
PDR7	Initialized	_	_	_	_	_

Register Name	Reset	Active	Sleep	Subsleep	Standby	Module
PDR8	Initialized	—	—	_	—	I/O port
PDRB	Initialized	_	_	_		_
PMR1	Initialized	_	_	_	_	_
PMR5	Initialized	_	_	_	_	_
PCR1	Initialized	_	_	_	_	_
PCR2	Initialized	_	_	_	_	_
PCR5	Initialized	_	_	_	_	_
PCR7	Initialized	_	_	_	_	_
PCR8	Initialized	_	_	_	_	_
SYSCR1	Initialized	_	_	_	_	Power-down
SYSCR2	Initialized	_	_	_	_	_
IEGR1	Initialized	_	_	_	_	Interrupts
IEGR2	Initialized	_	_	_	_	_
IENR1	Initialized	_	_	_	_	_
IRR1	Initialized	_	_	_	_	_
IWPR	Initialized	_	_	_	_	_
MSTCR1	Initialized	_	_	_	_	Power-down
MSTCR2	Initialized	_	_	_	_	_

Note: — is not initialized

* WDT: Watchdog timer





Section 18 Electrical Characteristics

18.1 Absolute Maximum Ratings

Table 18.1 Absolute Maximum Ratings

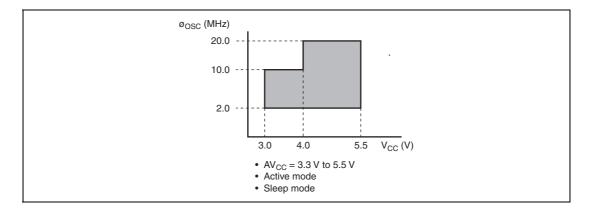
Item		Symbol	Value	Unit	Note
Power supply voltage	9	V _{cc}	–0.3 to +7.0	V	*
Analog power supply	voltage	AV_{cc}	-0.3 to +7.0	V	_
Input voltage	Ports other than Port B		–0.3 to V $_{\rm cc}$ +0.3	V	_
	Port B	_	–0.3 to AV $_{\rm cc}$ +0.3	V	_
Operating temperatu	re	$T_{_{opr}}$	-20 to +75	°C	_
Storage temperature		T_{stg}	–55 to +125	°C	

Note: * Permanent damage may result if maximum ratings are exceeded. Normal operation should be under the conditions specified in Electrical Characteristics. Exceeding these values can result in incorrect operation and reduced reliability.

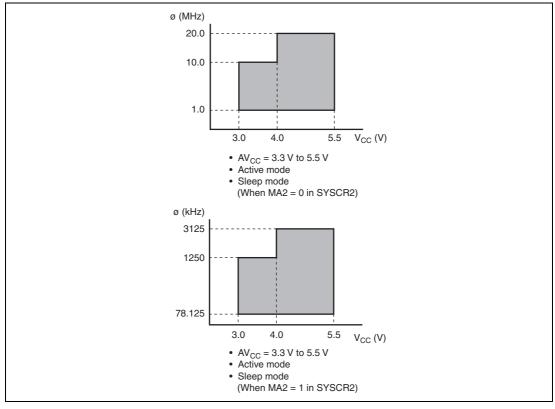
18.2 Electrical Characteristics (F-ZTATTM Version)

18.2.1 Power Supply Voltage and Operating Ranges

(1) Power Supply Voltage and Oscillation Frequency Range

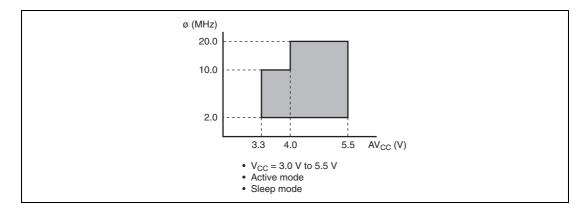


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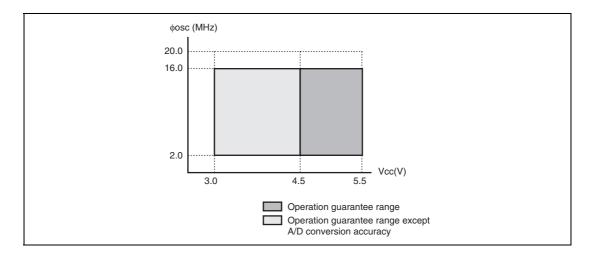
(2) Power Supply Voltage and Operating Frequency Range

(3) Analog Power Supply Voltage and A/D Converter Accuracy Guarantee Range



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(4) Range of Power Supply Voltage and Oscillation Frequency when Low-Voltage Detection Circuit is Used





18.2.2 DC Characteristics

Table 18.2 DC Characteristics (1)

 $V_{\rm cc}$ = 3.0 V to 5.5 V, V_{ss} = 0.0 V, $T_{\rm a}$ = –20°C to +75°C unless otherwise indicated.

				Values				
Item	Symbol	Applicable Pins	Test Condition	Min	Тур	Max	Unit	Notes
Input high voltage	V _{IH}	RES, NMI WKP0 to WKP5, IRQ0, IRQ3, ADTRG,TMRIV,	V_{cc} = 4.0 V to 5.5 V				V	
		TMCIV, FTCI, FTIOA to FTIOD, SCK3, SCK3_2, SCK3_3* ¹ , TRGV		$V_{cc} \times 0.9$	_	V _{cc} + 0.3		_
		RXD, RXD_2, RXD_3* ¹ , P12 to P10, P17 to P14, P22 to P20,	$V_{cc} = 4.0 \text{ V to } 5.5 \text{ V}$				V	_
		P57 to P50, P76 to P70, P84 to P80		$V_{cc} imes 0.8$	—	V _{cc} + 0.3		
		PB3 to PB0	$V_{\rm cc}$ = 4.0 V to 5.5 V	$V_{cc} imes 0.7$	—	$AV_{cc} + 0.3$	V	_
				$V_{cc} imes 0.8$		$AV_{cc} + 0.3$	-	
		OSC1	$V_{\rm cc}$ = 4.0 V to 5.5 V	$V_{\rm cc}-0.5$	_	V _{cc} + 0.3	V	_
				$V_{\rm cc} - 0.3$	_	V _{cc} + 0.3	-	
Input low voltage	V _{IL}	RES, NMI WKP0 to WKP5, IRQ0, IRQ3, ADTRG,TMRIV,	V_{cc} = 4.0 V to 5.5 V	-0.3	_	$V_{cc} \times 0.2$	V	
		TMCIV, FTCI, FTIOA to FTIOD, SCK3, SCK3_2, SCK3_3* ¹ , TRGV		-0.3	_	$V_{cc} \times 0.1$	_	
		RXD, RXD_2, RXD_3* ¹ , P12 to P10, P17 to P14, P22 to P20,	$V_{cc} = 4.0 \text{ V to } 5.5 \text{ V}$	-0.3		$V_{cc} \times 0.3$	V	_
		P57 to P50, P76 to P70, P84 to P80 PB3 to PB0		-0.3		$V_{cc} \times 0.2$	-	_
		OSC1	$V_{\rm cc}$ = 4.0 V to 5.5 V	-0.3	_	0.5	V	
				-0.3		0.3		

RENESAS

					Value	S		
ltem	Symbol	Applicable Pins	Test Condition	Min	Тур	Max	Unit	Notes
Output high voltage	V _{oh}	P12 to P10, P17 to P14, P22 to P20,	$V_{cc} = 4.0 \text{ V to } 5.5 \text{ V}$ $-I_{OH} = 1.5 \text{ mA}$	V _{cc} - 1.0	_	_	V	
J	P57 to P50, P76 to P70, P84 to P80	-Ι _{OH} = 0.1 mA	V _{cc} – 0.5	_	_			
Output low voltage	V _{ol}	P12 to P10, P17 to P14, P22 to P20,	$V_{cc} = 4.0 \text{ V to } 5.5 \text{ V}$ $I_{oL} = 1.6 \text{ mA}$	_	_	0.6	V	_
lonago		P57 to P50, P76 to P70	I _{oL} = 0.4 mA	_	-	0.4		
		P84 to P80	$V_{cc} = 4.0 \text{ V to } 5.5 \text{ V}$ $I_{oL} = 20.0 \text{ mA}$	_	—	1.5	V	-
			$V_{cc} = 4.0 \text{ V to } 5.5 \text{ V}$ $I_{oL} = 10.0 \text{ mA}$	_	_	1.0	_	
			$V_{cc} = 4.0 \text{ V to } 5.5 \text{ V}$ $I_{ol} = 1.6 \text{ mA}$	_	_	0.4		
			$I_{oL} = 0.4 \text{ mA}$		_	0.4		
Input/ output leakage current	I _L	OSC1, RES, NMI WKP0, WKP5, IRQ0, IRQ3, ADTRG, TRGV, TMRIV, TMCIV, FTCI, FTIOA to FTIOD, RXD, RXD_2, RXD_3* ¹ , SCK3, SCK3_2, SCK3_3* ¹	$V_{IN} = 0.5 V to$ ($V_{CC} - 0.5 V$)	_	_	1.0	μA	_
		P12 to P10, P17 to P14, P22 to P20, P57 to P50, P76 to P70, P84 to P80	$V_{IN} = 0.5 V \text{ to}$ ($V_{CC} - 0.5 V$)	_		1.0	μA	-
		PB3 to PB0	$V_{IN} = 0.5 \text{ V to}$ (AV _{cc} - 0.5 V)	_	_	1.0	μA	_
Pull-up MOS	$-I_{p}$	P12 to P10, P17 to P14,	V _{cc} = 5.0 V, V _{IN} = 0.0 V	50.0	—	300.0	μA	
current		P55 to P50	V _{cc} = 3.0 V, V _{IN} = 0.0 V		60.0	_	_	Reference value

RENESAS

					Valu	es		
ltem	Symbol	Applicable Pins	Test Condition	Min	Тур	Max	Unit	Notes
Input capaci- tance	C _{in}	All input pins except power supply pins	f = 1 MHz, $V_{IN} = 0.0 \text{ V},$ $T_a = 25^{\circ}\text{C}$	_	_	15.0	pF	
Active mode current	I _{OPE1}	V _{cc}	Active mode 1 $V_{cc} = 5.0 V$, $f_{osc} = 20 MHz$	_	15.0	30.0	mA	*2
consump- tion			Active mode 1 $V_{cc} = 3.0 V$, $f_{osc} = 10 MHz$	_	8.0	—		* ² Reference value
	I _{OPE2}	V _{cc}	Active mode 2 $V_{cc} = 5.0 V$, $f_{osc} = 20 MHz$	_	1.8	3.0	mA	*2
			Active mode 2 $V_{cc} = 3.0 V$, $f_{osc} = 10 MHz$	_	1.2	—		* ² Reference value
Sleep mode current	I _{SLEEP1}	V _{cc}	Sleep mode 1 $V_{cc} = 5.0 V$, $f_{osc} = 20 MHz$	_	11.5	22.5	mA	*2
consump- tion			Sleep mode 1 $V_{cc} = 3.0 V$, $f_{osc} = 10 MHz$	_	6.5	—		* ² Reference value
	I _{SLEEP2}	V _{cc}	Sleep mode 2 $V_{cc} = 5.0 V$, $f_{osc} = 20 MHz$	_	1.7	2.7	mA	*2
			Sleep mode 2 $V_{cc} = 3.0 V$, $f_{osc} = 10 MHz$	_	1.1	_		* ² Reference value
Standby mode current consump- tion	I _{STBY}	V _{cc}			_	5.0	μΑ	*2

					Valu			
Item	Symbol	Applicable Pins	Test Condition	Min	Тур	Max	Unit	Notes
RAM data retaining voltage	V_{RAM}	V _{cc}		2.0	—	_	V	

Notes: 1. The SCK3_3 and RXD_3 pins are not available in the H8/36014.

2. Pin states during current consumption measurement are given below (excluding current in the pull-up MOS transistors and output buffers).

Mode	RES Pin	Internal State	Other Pins	Oscillator Pins		
Active mode 1	V _{cc}	Operates	V _{cc}	Main clock:		
Active mode 2		Operates (¢OSC/64)		ceramic or crystal resonator		
Sleep mode 1 V _{cc}		Only timers operate	V _{cc}			
Sleep mode 2		Only timers operate (¢OSC/64)				
Standby mode	V _{cc}	CPU and timers both stop	V _{cc}	Main clock: ceramic or crystal resonator		



Table 18.2 DC Characteristics (2)

 V_{cc} = 3.0 V to 5.5 V, V_{ss} = 0.0 V, T_{a} = –20°C to +75°C, unless otherwise indicated.

		Applicable			Value	s	
Item	Symbol	Pins	Test Condition	Min	Тур	Max	Unit
Allowable output low current (per pin)	I _{ol}	Output pins except port 8	V _{cc} = 4.0 V to 5.5 V	—	—	2.0	mA
		Port 8	—	_	_	20.0	mA
		Port 8		—	_	10.0	mA
		Output pins except port 8	_	_	—	0.5	mA
Allowable output low current (total)	$\Sigma I_{\rm OL}$	Output pins except port 8	V _{cc} = 4.0 V to 5.5 V	_		40.0	mA
		Port 8	—		—	80.0	mA
		Output pins except port 8		_	—	20.0	mA
		Port 8	—		—	40.0	mA
Allowable output high current (per pin)	I –I _{OH} I	All output pins	V _{cc} = 4.0 V to 5.5 V	_	—	2.0	mA
					—	0.2	mA
Allowable output high current (total)	I –∑I _{OH} I	All output pins	V _{cc} = 4.0 V to 5.5 V	_	_	30.0	mA
				_	_	8.0	mA



18.2.3 AC Characteristics

Table 18.3 AC Characteristics

 $V_{cc} = 3.0 \text{ V}$ to 5.5 V, $V_{ss} = 0.0 \text{ V}$, $T_a = -20^{\circ}\text{C}$ to +75°C, unless otherwise specified.

		Applicable			Value	s		Reference
Item	Symbol	Pins	Test Condition	Min	Тур	Max	Unit	Figure
System clock oscillation	f _{osc}	OSC1, OSC2	$V_{cc} = 4.0 \text{ V to } 5.5 \text{ V}$	2.0	—	20.0	MHz	*1
frequency				2.0	_	10.0	MHz	_
System clock (t _{cyc}			1	_	64	t _{osc}	*2
cycle time				—	—	12.8	μs	_
Instruction cycle time				2	_	_	t _{cyc}	
Oscillation stabilization time (crystal resonator)	t _{rc}	OSC1, OSC2		_		10.0	ms	
Oscillation stabilization time (ceramic resonator)	t _{rc}	OSC1, OSC2		_	_	5.0	ms	
External clock	t _{CPH}	OSC1	$V_{\rm CC}$ = 4.0 V to 5.5 V	20.0	—	—	ns	Figure 18.1
high width				40.0	_	—	ns	_
External clock	t _{cpl}	OSC1	$V_{\rm CC}$ = 4.0 V to 5.5 V	20.0	_	_	ns	-
low width				40.0	_	—	ns	_
External clock	t _{CPr}	OSC1	$V_{\rm cc}$ = 4.0 V to 5.5 V	—	_	10.0	ns	_
rise time				—	—	15.0	ns	_
External clock	t _{CPf}	OSC1	$V_{cc} = 4.0 \text{ V to } 5.5 \text{ V}$	—	—	10.0	ns	_
fall time						15.0	ns	-



		Applicable			Value	S		Reference
Item	Symbol	Pins	Test Condition	Min	Тур	Max	Unit	Figure
RES pin low width	t _{REL}	RES	At power-on and in modes other than those below	t _{rc}	—	_	ms	Figure 18.2
			In active mode and sleep mode operation	200	_	_	ns	_
Input pin high width	t _{in}	NMI, IRQ0, IRQ3, WKP0 to WKP5, TMCIV, TMRIV, TRGV, ADTRG, FTCI, FTIOA to FTIOD		2			t _{cyc}	Figure 18.3
Input pin low width	t _{iL}	NMI, IRQ0, IRQ3, WKP0 to WKP5, TMCIV, TMRIV, TRGV, ADTRG, FTIOA to FTIOD		2	_		t _{cyc}	-

Notes: 1. When an external clock is input, the minimum system clock oscillator frequency is 1.0 MHz.

2. Determined by MA2 to MA0 in system control register 2 (SYSCR2).

Table 18.4 Serial Interface (SCI3) Timing

 $V_{cc} = 3.0 \text{ V}$ to 5.5 V, $V_{ss} = 0.0 \text{ V}$, $T_a = -20^{\circ}\text{C}$ to +75°C, unless otherwise specified.

			Applicable		١	Values	5		Reference
ltem		Symbol	Pins	Test Condition	Min	Тур	Max	Unit	Figure
Input clock	Asynchro- nous	t _{Scyc}	SCK3, SCK3_2,		4	_	_	t _{cyc}	Figure 18.4
cycle	Clocked synchro- nous	_	SCK3_3*		6	_	—	t _{cyc}	_
Input clo width	ock pulse	t _{sскw}	SCK3, SCK3_2, SCK3_3*		0.4	_	0.6	t _{Scyc}	_
	it data delay	t _{TXD}	TXD,	V_{cc} = 4.0 V to 5.5 V	—	—	1	t _{cyc}	Figure 18.5
time (clo synchro			TXD_2, TXD_3*		_	_	1	t _{cyc}	
	data setup	t _{RXS}	RXD,	V_{cc} = 4.0 V to 5.5 V	50.0	_	_	ns	
time (clo synchro			RXD_2, RXD_3*		100.0	_	_	ns	_
	data hold	t _{RXH}	RXD,	$V_{\rm cc}$ = 4.0 V to 5.5 V	50.0		_	ns	
time (clo synchro			RXD_2, RXD_3*		100.0	_	_	ns	_

Note: * The SCK3_3, RXD_3, and TXD_3 pins are not available in the H8/36014.



18.2.4 A/D Converter Characteristics

Table 18.5 A/D Converter Characteristics

 V_{cc} = 3.0 V to 5.5 V, V_{ss} = 0.0 V, T_a = -20°C to +75°C, unless otherwise specified.

		Applicable	Test		Value	S		
Item	Symbol	Pins	Condition	Min	Тур	Max	Unit	Notes
Analog power supply voltage	AV_{cc}	AV_{cc}		3.3	V_{cc}	5.5	V	*1
Analog input voltage	AV_{IN}	AN3 to AN0		$V_{_{\rm SS}}-0.3$	_	AV _{cc} + 0.3	V	
Analog power supply current	Al _{ope}	AV _{cc}	AV _{cc} = 5.0 V f _{osc} = 20 MHz	_	_	2.0	mA	
	AI _{STOP1}	AV_{cc}		_	50	_	μA	* ² Reference value
	$AI_{_{STOP2}}$	AV_{cc}		_	—	5.0	μA	*3
Analog input capacitance	C _{AIN}	AN3 to AN0		_	_	30.0	pF	
Allowable signal source impedance	R _{AIN}	AN3 to AN0		_	—	5.0	kΩ	
Resolution (data length)				10	10	10	bit	
Conversion time (single mode)			AV _{cc} = 3.3 V to 5.5 V	134	_	_	t _{cyc}	
Nonlinearity error			_	_	—	±7.5	LSB	_
Offset error			_	_		±7.5	LSB	_
Full-scale error			_	_	—	±7.5	LSB	_
Quantization error			_	—	—	±0.5	LSB	_
Absolute accuracy			_	_	—	±8.0	LSB	_
Conversion time (single mode)			AV _{cc} = 4.0 V to 5.5 V	70	-	_	$t_{_{\mathrm{cyc}}}$	
Nonlinearity error			_	_	—	±7.5	LSB	_
Offset error			_	_	_	±7.5	LSB	_
Full-scale error			_	_		±7.5	LSB	_
Quantization error			_	_	_	±0.5	LSB	_
Absolute accuracy			_	_	—	±8.0	LSB	_

		Applicable ymbol Pins	Test	Values				
Item	Symbol		Condition	Min	Тур	Max	Unit	Notes
Conversion time (single mode)			AV _{cc} = 4.0 V to 5.5 V	134	_	_	$t_{_{cyc}}$	
Nonlinearity error			_	_	_	±3.5	LSB	_
Offset error			—	_		±3.5	LSB	_
Full-scale error			—	_	_	±3.5	LSB	_
Quantization error			_	_	—	±0.5	LSB	_
Absolute accuracy			_	_	_	±4.0	LSB	_

Notes: 1. Set $AV_{cc} = V_{cc}$ when the A/D converter is not used.

2. AI_{STOP1} is the current in active and sleep modes while the A/D converter is idle.

AI_{STOP2} is the current at reset and in standby and subsleep modes while the A/D converter is idle.

18.2.5 Watchdog Timer Characteristics

Table 18.6 Watchdog Timer Characteristics

 $V_{cc} = 3.0 \text{ V}$ to 5.5 V, $V_{ss} = 0.0 \text{ V}$, $T_a = -20^{\circ}\text{C}$ to +75°C, unless otherwise specified.

		Applicable Pins			Value			
ltem	Symbol			Min	Тур	Max	Unit	Notes
On-chip oscillator overflow time	t _{ove}			0.2	0.4		S	*
Note: *	Shows the	time to count fr	om 0 to 255, a	it which r	point an ir	nternal re	set is ae	nerated.

Note: * Shows the time to count from 0 to 255, at which point an internal reset is generated, when the internal oscillator is selected.

18.2.6 Flash Memory Characteristics

Table 18.7 Flash Memory Characteristics

 V_{cc} = 3.0 V to 5.5 V, V_{ss} = 0.0 V, T_a = -20°C to +75°C, unless otherwise specified.

			Test		Values	;	
Item		Symbol	Condition	Min	Тур	Max	Unit
Programming t	time (per 128 bytes)* ¹ * ² * ⁴	t _P		_	7	200	ms
Erase time (pe	r block) * ¹ * ³ * ⁶	t _e		_	100	1200	ms
Reprogrammin	ng count	N_{wec}		1000	10000	—	Times
Programming	Wait time after SWE bit setting*1	x		1	_	_	μs
-	Wait time after PSU bit setting*1	у		50	_	_	μs
	Wait time after P bit setting	z1	$1 \le n \le 6$	28	30	32	μs
	*1*4	z2	$7 \le n \le 1000$	198	200	202	μs
		z3	Additional- programming	8	10	12	μs
	Wait time after P bit clear*1	α		5	—	_	μs
	Wait time after PSU bit clear*1	β		5	—	—	μs
	Wait time after PV bit setting*1	γ		4	—	—	μs
	Wait time after dummy write* ¹	ε		2	_	_	μs
	Wait time after PV bit clear*1	η		2	—	—	μs
	Wait time after SWE bit clear*1	θ		100	_	_	μs
	Maximum programming count*1*4*5	Ν		_		1000	Times

			Test		Value	s	
ltem		Symbol	Condition	Min	Тур	Max	Unit
Erase	Wait time after SWE bit setting*1	x		1	_	_	μs
	Wait time after ESU bit setting* ¹	У		100	_	_	μs
	Wait time after E bit setting* ¹ * ⁶	Z		10	_	100	ms
	Wait time after E bit clear*1	α		10	—	_	μs
	Wait time after ESU bit clear*1	β		10	_	—	μs
	Wait time after EV bit setting* ¹	γ		20	_	_	μs
	Wait time after dummy write*1	ε		2	_	—	μs
	Wait time after EV bit clear*1	η		4	_	_	μs
	Wait time after SWE bit clear*1	θ		100	_	—	μs
	Maximum erase count*1*6*7	Ν		_		120	Times

Notes: 1. Make the time settings in accordance with the program/erase algorithms.

- 2. The programming time for 128 bytes. (Indicates the total time for which the P bit in flash memory control register 1 (FLMCR1) is set. The program-verify time is not included.)
- 3. The time required to erase one block. (Indicates the time for which the E bit in flash memory control register 1 (FLMCR1) is set. The erase-verify time is not included.)
- 4. Programming time maximum value (t_{_P} (max.)) = wait time after P bit setting (z) \times maximum programming count (N)
- 5. Set the maximum programming count (N) according to the actual set values of z1, z2, and z3, so that it does not exceed the programming time maximum value (t_p (max.)). The wait time after P bit setting (z1, z2) should be changed as follows according to the value of the programming count (n).

Programming count (n)

 $1 \leq n \leq 6 \qquad \qquad z1 = 30 \ \mu s$

$$7 \le n \le 1000$$
 $z2 = 200 \ \mu s$

- 6. Erase time maximum value (t_e (max.)) = wait time after E bit setting (z) \times maximum erase count (N)
- 7. Set the maximum erase count (N) according to the actual set value of (z), so that it does not exceed the erase time maximum value (t_{e} (max.)).



18.2.7 Power-Supply-Voltage Detection Circuit Characteristics (Optional)

Table 18.8 Power-Supply-Voltage Detection Circuit Characteristics

 $V_{ss} = 0.0 \text{ V}, T_a = -20 \text{ to } +75^{\circ}\text{C}$, unless otherwise indicated.

		Test		Value	s	
Item	Symbol	Condition	Min	Тур	Max	Unit
Power-supply falling detection voltage	Vint (D)	LVDSEL = 0	3.3	3.7	_	V
Power-supply rising detection voltage	Vint (U)	LVDSEL = 0	—	4.0	4.5	V
Reset detection voltage 1*1	Vreset1	LVDSEL = 0	_	2.3	2.7	V
Reset detection voltage 2* ²	Vreset2	LVDSEL = 1	3.0	3.6	4.2	V
Lower-limit voltage of LVDR operation* ³	$V_{\scriptscriptstyle LVDRmin}$		1.0	_	_	V
LVD stabilization time	t _{lvdon}		50	_	_	μs
Current consumption in standby mode	I _{STBY}	LVDE = 1, Vcc = 5.0 V, When a 32- kHz crystal resonator is not used		_	350	μA

Notes: 1. This voltage should be used when the falling and rising voltage detection function is used.

2. Select the low-voltage reset 2 when only the low-voltage detection reset is used.

3. When the power-supply voltage (Vcc) falls below V_{LVDRmin} = 1.0 V and then rises, a reset may not occur. Therefore sufficient evaluation is required.

18.2.8 Power-On Reset Circuit Characteristics (Optional)

Table 18.9 Power-On Reset Circuit Characteristics

 $V_{ss} = 0.0 \text{ V}, T_a = -20 \text{ to } +75^{\circ}\text{C}$, unless otherwise indicated.

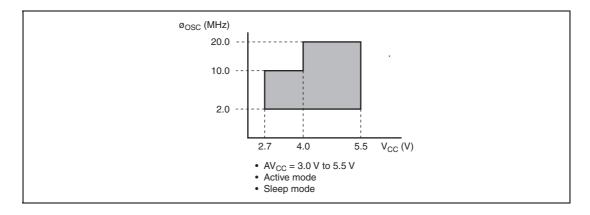
		Test				
Item	Symbol	Condition	Min	Тур	Max	Unit
Pull-up resistance of RES pin	$R_{\scriptscriptstyleRES}$		100	150	_	kΩ
Power-on reset start voltage*	V_{por}		—		100	mV

Note: * The power-supply voltage (Vcc) must fall below Vpor = 100 mV and then rise after charge of the RES pin is removed completely. In order to remove charge of the RES pin, it is recommended that the diode be placed in the Vcc side. If the power-supply voltage (Vcc) rises from the point over 100 mV, a power-on reset may not occur.

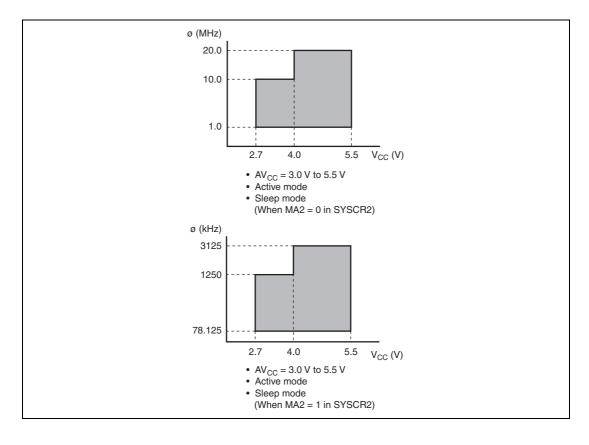
18.3 Electrical Characteristics (Masked ROM Version)

18.3.1 Power Supply Voltage and Operating Ranges

(1) Power Supply Voltage and Oscillation Frequency Range

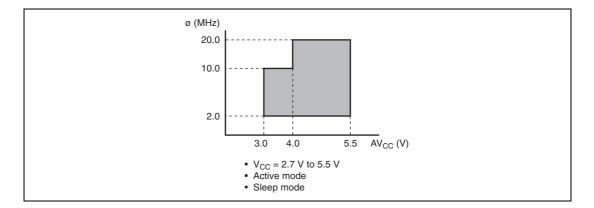




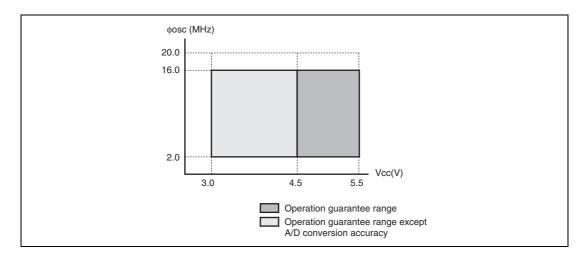


(2) Power Supply Voltage and Operating Frequency Range

(3) Analog Power Supply Voltage and A/D Converter Accuracy Guarantee Range



(4) Range of Power Supply Voltage and Oscillation Frequency when Low-Voltage Detection Circuit is Used





18.3.2 DC Characteristics

Table 18.10 DC Characteristics (1)

 $V_{cc} = 2.7$ V to 5.5 V, $V_{ss} = 0.0$ V, $T_a = -20^{\circ}$ C to +75°C, unless otherwise specified.

					Value	s		
Item	Symbol	Applicable Pins	Test Condition	Min	Тур	Max	Unit	Notes
Input high voltage	V _{IH}	RES, NMI WKP0 to WKP5, IRQ0, IRQ3, ADTRG, TMRIV,	$V_{\rm cc}$ = 4.0 V to 5.5 V	$V_{cc} \times 0.8$	—	V _{cc} + 0.3	V	
		TMCIV, FTCI, FTIOA to FTIOD, SCK3, SCK3_2, SCK3_3* ¹ , TRGV		$V_{cc} \times 0.9$		V _{cc} + 0.3	-	
		RXD, RXD_2, RXD_3* ¹ , P12 to P10, P17 to P14, P22 to P20,	$V_{\rm cc}$ = 4.0 V to 5.5 V	$V_{cc} \times 0.7$		V _{cc} + 0.3	V	_
		P57 to P50, P76 to P70, P84 to P80		$V_{cc} \times 0.8$	_	V _{cc} + 0.3	-	
		PB3 to PB0	$V_{\rm cc}$ = 4.0 V to 5.5 V	$V_{cc} \times 0.7$	—	$AV_{cc} + 0.3$	V	_
				$V_{cc} \times 0.8$		$AV_{cc} + 0.3$	-	
		OSC1	V_{cc} = 4.0 V to 5.5 V	$V_{cc} - 0.5$	_	V _{cc} + 0.3	V	_
				$V_{cc} - 0.3$	_	V _{cc} + 0.3	-	
Input low voltage	V _{IL}	RES, NMI WKP0 to WKP5, IRQ0, IRQ3, ADTRG,TMRIV,	$V_{\rm cc}$ = 4.0 V to 5.5 V	-0.3	_	$V_{cc} \times 0.2$	V	
		TMCIV, FTCI, FTIOA to FTIOD, SCK3, SCK3_2, SCK3_3* ¹ , TRGV		-0.3	—	V _{cc} ×0.1	_	
		RXD, RXD_2, RXD_3* ¹ , P12 to P10, P17 to P14, P22 to P20,	V_{cc} = 4.0 V to 5.5 V	-0.3		$V_{cc} \times 0.3$	V	_
		P57 to P50, P76 to P70, P84 to P80 PB3 to PB0		-0.3		$V_{cc} \times 0.2$		
		OSC1	$V_{\rm cc}$ = 4.0 V to 5.5 V	-0.3	_	0.5	V	
				-0.3	_	0.3		

					Value	s		
Item	Symbol	Applicable Pins	Test Condition	Min	Тур	Max	Unit	Notes
Output high voltage	V _{oH}	P12 to P10, P17 to P14, P22 to P20,	$V_{cc} = 4.0 \text{ V to } 5.5 \text{ V}$ $-I_{OH} = 1.5 \text{ mA}$			—	V	
		P57 to P50, P76 to P70, P84 to P80	-I _{OH} = 0.1 mA	V _{cc} – 0.5	_	_		
Output low voltage	V _{ol}	P12 to P10, P17 to P14, P22 to P20,	$V_{cc} = 4.0 \text{ V}$ to 5.5 V $I_{oL} = 1.6 \text{ mA}$	_	_	0.6	V	
		P57 to P50, P76 to P70	I _{oL} = 0.4 mA	_	_	0.4		
		P84 to P80	$V_{cc} = 4.0 \text{ V to } 5.5 \text{ V}$ $I_{oL} = 20.0 \text{ mA}$	_	_	1.5	V	_
			$V_{cc} = 4.0 \text{ V to } 5.5 \text{ V}$ $I_{oL} = 10.0 \text{ mA}$	_	_	1.0		
			$V_{cc} = 4.0 \text{ V to } 5.5 \text{ V}$ $I_{oL} = 1.6 \text{ mA}$	_	_	0.4		
			I _{oL} = 0.4 mA	—	—	0.4		
Input/ output leakage current	I _{IL}	OSC1, RES, NMI, WKP0 to WKP5, IRQ0, IRQ3, ADTRG, TRGV, TMRIV, TMCIV, FTCI, FTIOA to FTIOD, RXD, RXD_2, RXD_3* ¹ , SCK3, SCK3_2, SCK3_3* ¹	$V_{\rm IN} = 0.5 \text{ V to}$ ($V_{\rm cc} - 0.5 \text{ V}$)	_	-	1.0	μΑ	_
		P12 to P10, P17 to P14, P22 to P20, P57 to P50, P76 to P70, P84 to P80	$V_{IN} = 0.5 V to$ ($V_{CC} - 0.5 V$)	_	_	1.0	μΑ	_
		PB3 to PB0	$V_{IN} = 0.5 \text{ V to}$ (AV _{cc} - 0.5 V)	_	—	1.0	μA	

					Value	s		
Item	Symbol	Applicable Pins	Test Condition	Min	Тур	Max	Unit	Notes
Pull-up MOS	−I _p	P12 to P10, P17 to P14,	$V_{cc} = 5.0 \text{ V},$ $V_{IN} = 0.0 \text{ V}$	50.0		300.0	μΑ	
current		P55 to P50	$V_{cc} = 3.0 \text{ V},$ $V_{IN} = 0.0 \text{ V}$	_	60.0	—		Reference value
Input capaci- tance	C _{in}	All input pins except power supply pins	f = 1 MHz, V _{IN} = 0.0 V, T _a = 25°C	—	_	15.0	pF	
Active mode current	I _{OPE1}	V _{cc}	Active mode 1 $V_{cc} = 5.0 V$, $f_{osc} = 20 MHz$	—	15.0	30.0	mA	*2
consump- tion			Active mode 1 $V_{cc} = 3.0 V$, $f_{osc} = 10 MHz$	_	8.0	_		* ² Reference value
	I _{OPE2}	V _{cc}	Active mode 2 $V_{cc} = 5.0 V$, $f_{osc} = 20 MHz$	—	1.8	3.0	mA	* ²
			Active mode 2 $V_{cc} = 3.0 V$, $f_{osc} = 10 MHz$	—	1.2	_		* ² Reference value
Sleep mode current	I _{SLEEP1}	V _{cc}	Sleep mode 1 $V_{cc} = 5.0 V$, $f_{osc} = 20 MHz$	—	11.5	22.5	mA	*2
consump- tion			Sleep mode 1 $V_{cc} = 3.0 V$, $f_{osc} = 10 MHz$	_	6.5	_		* ² Reference value
	I _{SLEEP2}	V _{cc}	Sleep mode 2 $V_{cc} = 5.0 V$, $f_{osc} = 20 MHz$	_	1.7	2.7	mA	*2
			Sleep mode 2 $V_{cc} = 3.0 V$, $f_{osc} = 10 MHz$	_	1.1	_		* ² Reference value
Standby mode current consump- tion	I _{stby}	V _{cc}		_	_	5.0	μΑ	*2

					Value			
Item	Symbol	Applicable Pins	Test Condition	Min	Тур	Max	Unit	Notes
RAM data retaining voltage	$V_{_{RAM}}$	V _{cc}		2.0	_	—	V	

Notes: 1. The SCK3_3 and RXD_3 pins are not available in the H8/36014.

2. Pin states during current consumption measurement are given below (excluding current in the pull-up MOS transistors and output buffers).

Mode	RES Pin	Internal State	Other Pins	Oscillator Pins
Active mode 1	V _{cc}	Operates	V _{cc}	Main clock:
Active mode 2		Operates (¢OSC/64)		ceramic or crystal resonator
Sleep mode 1	V _{cc}	Only timers operate	V _{cc}	
Sleep mode 2		Only timers operate (¢OSC/64)		
Standby mode	V _{cc}	CPU and timers both stop	V _{cc}	Main clock: ceramic or crystal resonator



Table 18.10 DC Characteristics (2)

 V_{cc} = 2.7 V to 5.5 V, V_{ss} = 0.0 V, T_{a} = –20°C to +75°C, unless otherwise specified.

		Applicable		s			
Item	Symbol	Pins	Test Condition	Min	Тур	Max	Unit
Allowable output low current (per pin)	I _{ol}	Output pins except port 8	V _{cc} = 4.0 V to 5.5 V	—	—	2.0	mA
		Port 8		_	—	20.0	mA
		Output pins except port 8		_	—	0.5	mA
		Port 8		_	_	10.0	mA
Allowable output low current (total)	$\Sigma I_{\rm OL}$	Output pins except port 8	V _{cc} = 4.0 V to 5.5 V	_		40.0	mA
		Port 8	_	_	_	80.0	mA
		Output pins except port 8		_		20.0	mA
		Port 8		_	_	40.0	mA
Allowable output high current (per pin)	I –I _{OH} I	All output pins	V _{cc} = 4.0 V to 5.5 V	_	_	2.0	mA
				_	_	0.2	mA
Allowable output high current (total)	I –∑I _{OH} I	All output pins	V _{cc} = 4.0 V to 5.5 V	_	_	30.0	mA
					_	8.0	mA

18.3.3 AC Characteristics

Table 18.11 AC Characteristics

 $V_{cc} = 2.7$ V to 5.5 V, $V_{ss} = 0.0$ V, $T_a = -20^{\circ}$ C to +75°C, unless otherwise specified.

		Applicable			Value	S		Reference
Item	Symbol	Pins	Test Condition	Min	Тур	Max	Unit	Figure
System clock oscillation	f _{osc}	OSC1, OSC2	$V_{cc} = 4.0 \text{ V to } 5.5 \text{ V}$	2.0	—	20.0	MHz	* ¹
frequency				2.0	—	10.0	MHz	
System clock (ø)	t _{cyc}			1		64	t _{osc}	*2
cycle time				—	—	12.8	μs	
Instruction cycle time				2	_	_	t _{cyc}	
Oscillation stabilization time (crystal resonator)	t _{rc}	OSC1, OSC2		_	_	10.0	ms	
Oscillation stabilization time (ceramic resonator)	t _{rc}	OSC1, OSC2		_	_	5.0	ms	
External clock	t _{CPH}	OSC1	$V_{cc} = 4.0 \text{ V to } 5.5 \text{ V}$	20.0	_	_	ns	Figure 18.1
high width				40.0	—		ns	_
External clock	t _{CPL}	OSC1	$V_{cc} = 4.0 \text{ V to } 5.5 \text{ V}$	20.0	—	—	ns	-
low width				40.0	_	_	ns	_
External clock	t _{CPr}	OSC1	$V_{cc} = 4.0 \text{ V to } 5.5 \text{ V}$	—		10.0	ns	-
rise time				_	_	15.0	ns	-
External clock	t _{cPf}	OSC1	$V_{cc} = 4.0 \text{ V to } 5.5 \text{ V}$	_	_	10.0	ns	_
fall time				—	—	15.0	ns	_
RES pin low width	t _{REL}	RES	At power-on and in modes other than those below	t _{rc}	—	_	ms	Figure 18.2
			In active mode and sleep mode operation	200			ns	_



		Applicable			Value	s		Reference	
Item	Symbol	Pins	Test Condition	Min	Тур Мах		Unit	Figure	
Input pin high width	t _{iH}	NMI, IRQ0, IRQ3, WKP0 to WKP5, TMCIV, TMRIV, TRGV, ADTRG, FTCI, FTIOA to FTIOD		2	_		t _{cyc}	Figure 18.3	
Input pin low width	t _{iL}	NMI, IRQ0, IRQ3, WKP0 to WKP5, TMCIV, TMRIV, TRGV, ADTRG, FTCI, FTIOA to FTIOD		2	_		t _{cyc}	_	

Notes: 1. When an external clock is input, the minimum system clock oscillator frequency is 1.0 MHz.

2. Determined by the MA2 to MA0 bits in the system control register 2 (SYSCR2).

Table 18.12 Serial Interface (SCI3) Timing

 $V_{cc} = 2.7 \text{ V}$ to 5.5 V, $V_{ss} = 0.0 \text{ V}$, $T_a = -20^{\circ}\text{C}$ to +75°C, unless otherwise specified.

			Applicable		Values				Reference
ltem		Symbol	Pins	Test Condition	Min	Тур	Max	Unit	Figure
Input clock	Asynchro- nous	t _{Scyc}	SCK3, SCK3_2,		4	_	_	t _{cyc}	Figure 18.4
cycle	Clocked synchro- nous	_	SCK3_3*		6	_	—	t _{cyc}	_
Input clo width	ock pulse	t _{sскw}	SCK3, SCK3_2, SCK3_3*		0.4	_	0.6	t _{Scyc}	_
	it data delay	t _{TXD}	TXD,	V_{cc} = 4.0 V to 5.5 V	—	—	1	t _{cyc}	Figure 18.5
time (clo synchro			TXD_2, TXD_3*		_	_	1	t _{cyc}	
	data setup	t _{RXS}	RXD,	V_{cc} = 4.0 V to 5.5 V	50.0	_	_	ns	
time (clo synchro			RXD_2, RXD_3*		100.0	_	_	ns	_
	data hold	t _{RXH}	RXD,	V_{cc} = 4.0 V to 5.5 V	50.0		_	ns	
time (clo synchro			RXD_2, RXD_3*		100.0	_	_	ns	_

Note: * The SCK3_3, RXD_3, and TXD_3 pins are not available in the H8/36014.



18.3.4 A/D Converter Characteristics

Table 18.13 A/D Converter Characteristics

 V_{cc} = 2.7 V to 5.5 V, V_{ss} = 0.0 V, T_a = -20°C to +75°C, unless otherwise specified.

		Applicable	Test	Values				
Item	Symbol	Pins	Condition	Min	Тур	Max	Unit	Notes
Analog power supply voltage	AV_{cc}	AV_{cc}		3.0	V_{cc}	5.5	V	*1
Analog input voltage	AV_{IN}	AN3 to AN0		$V_{_{\rm SS}}-0.3$	_	AV _{cc} + 0.3	V	
Analog power supply current	Al _{ope}	AV _{cc}	$AV_{cc} = 5.0 V$ $f_{osc} =$ 20 MHz	_	_	2.0	mA	
	AI _{STOP1}	AV_{cc}		_	50	_	μA	* ² Reference value
	$AI_{_{STOP2}}$	AV_{cc}		_	—	5.0	μA	*3
Analog input capacitance	C _{AIN}	AN3 to AN0		_	_	30.0	pF	
Allowable signal source impedance	R _{AIN}	AN3 to AN0		_	—	5.0	kΩ	
Resolution (data length)				10	10	10	bit	
Conversion time (single mode)			AV _{cc} = 3.0 V to 5.5 V	134	_	_	t _{cyc}	
Nonlinearity error			_	_		±7.5	LSB	_
Offset error			_	_		±7.5	LSB	_
Full-scale error			_	_	—	±7.5	LSB	_
Quantization error			_	—	—	±0.5	LSB	_
Absolute accuracy			_	_	—	±8.0	LSB	_
Conversion time (single mode)			AV _{cc} = 4.0 V to 5.5 V	70	-	_	$t_{_{\mathrm{cyc}}}$	
Nonlinearity error			_	_	—	±7.5	LSB	_
Offset error			_	_	_	±7.5	LSB	_
Full-scale error			_	_		±7.5	LSB	_
Quantization error			_	_	_	±0.5	LSB	_
Absolute accuracy			_	_	—	±8.0	LSB	_

		Applicable Pins	Test Condition	Values				Reference
Item	Symbol			Min	Тур	Max	Unit	Figure
Conversion time (single mode)			AV _{cc} = 4.0 V to 5.5 V	134	_	_	$t_{\rm cyc}$	
Nonlinearity error			_	_	—	±3.5	LSB	_
Offset error				_		±3.5	LSB	_
Full-scale error				_	—	±3.5	LSB	_
Quantization error				_	—	±0.5	LSB	_
Absolute accuracy					_	±4.0	LSB	_

Notes: 1. Set $AV_{cc} = V_{cc}$ when the A/D converter is not used.

2. Al_{STOP1} is the current in active and sleep modes while the A/D converter is idle.

3. Al_{STOP2} is the current at reset and in standby and subsleep modes while the A/D converter is idle.

18.3.5 Watchdog Timer Characteristics

Table 18.14 Watchdog Timer Characteristics

 $V_{cc} = 2.7 \text{ V}$ to 5.5 V, $V_{ss} = 0.0 \text{ V}$, $T_a = -20^{\circ}\text{C}$ to +75°C, unless otherwise specified.

		Applicable	Test	Values				
ltem	Symbol	Pins	Condition	Min	Тур	Max	Unit	Notes
On-chip oscillator overflow time	t _{ovf}			0.2	0.4	_	S	*

Note: * Shows the time to count from 0 to 255, at which point an internal reset is generated, when the internal oscillator is selected.

18.3.6 Power-Supply-Voltage Detection Circuit Characteristics (Optional)

Table 18.15 Power-Supply-Voltage Detection Circuit Characteristics

 $V_{ss} = 0.0 \text{ V}, T_a = -20 \text{ to } +75^{\circ}\text{C}$, unless otherwise indicated.

	Test			Value	S		
Item	Symbol	Condition	Min	Тур	Max	Unit	
Power-supply falling detection voltage	Vint (D)	LVDSEL = 0	3.3	3.7	_	V	
Power-supply rising detection voltage	Vint (U)	LVDSEL = 0	—	4.0	4.5	V	
Reset detection voltage 1*1	Vreset1	LVDSEL = 0	—	2.3	2.7	V	
Reset detection voltage 2* ²	Vreset2	LVDSEL = 1	3.0	3.6	4.2	V	
Lower-limit voltage of LVDR operation* ³	$V_{_{\rm LVDRmin}}$		1.0	—	—	V	
LVD stabilization time	t _{lvdon}		50	_	_	μs	
Current consumption in standby mode	I	LVDE = 1, Vcc = 5.0 V, When a 32- kHz crystal resonator is not used		_	350	μΑ	

Notes: 1. This voltage should be used when the falling and rising voltage detection function is used.

2. Select the low-voltage reset 2 when only the low-voltage detection reset is used.

 When the power-supply voltage (Vcc) falls below V_{LVDRmin} = 1.0 V and then rises, a reset may not occur. Therefore sufficient evaluation is required.

18.3.7 Power-On Reset Circuit Characteristics (Optional)

Table 18.16 Power-On Reset Circuit Characteristics

 $V_{ss} = 0.0 \text{ V}, T_a = -20 \text{ to } +75^{\circ}\text{C}$, unless otherwise indicated.

		Test				
Item	Symbol	Condition	Min	Тур	Max	Unit
Pull-up resistance of R	ES pin R _{RES}		100	150		kΩ
Power-on reset start vo	Itage* V _{por}		_	_	100	mV
	supply voltage (Vcc) m	ust fall below Vn	or - 100	mV and	thon	rico

Note: * The power-supply voltage (Vcc) must fall below Vpor = 100 mV and then rise after charge of the RES pin is removed completely. In order to remove charge of the RES pin, it is recommended that the diode be placed in the Vcc side. If the power-supply voltage (Vcc) rises from the point over 100 mV, a power-on reset may not occur.

18.4 Operation Timing

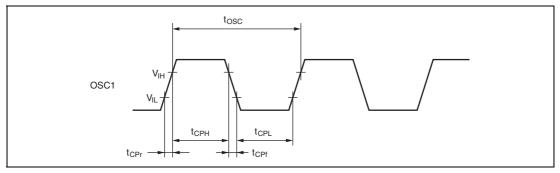


Figure 18.1 System Clock Input Timing

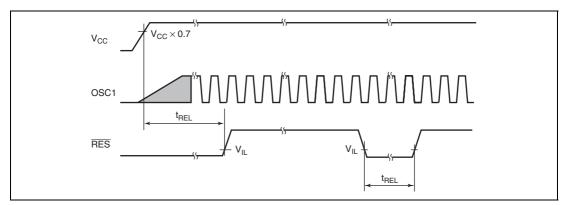


Figure 18.2 RES Low Width Timing

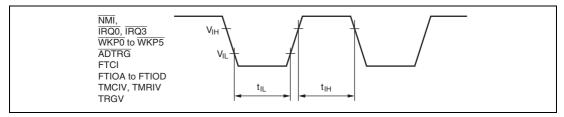


Figure 18.3 Input Timing

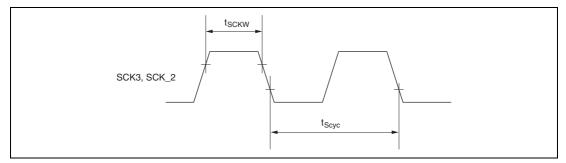
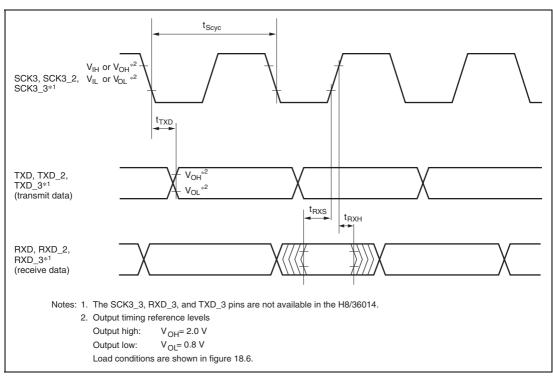
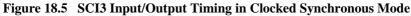
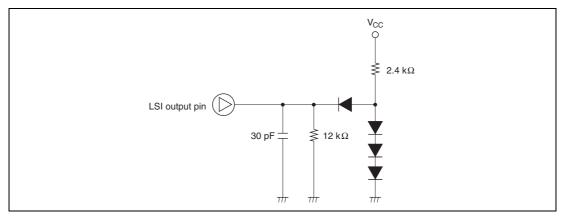


Figure 18.4 SCK3 Input Clock Timing





18.5 Output Load Condition







Appendix A Instruction Set

A.1 Instruction List

Operand Notation

Symbol	Description
Rd	General (destination*) register
Rs	General (source*) register
Rn	General register*
ERd	General destination register (address register or 32-bit register)
ERs	General source register (address register or 32-bit register)
ERn	General register (32-bit register)
(EAd)	Destination operand
(EAs)	Source operand
PC	Program counter
SP	Stack pointer
CCR	Condition-code register
Ν	N (negative) flag in CCR
Z	Z (zero) flag in CCR
V	V (overflow) flag in CCR
С	C (carry) flag in CCR
disp	Displacement
\rightarrow	Transfer from the operand on the left to the operand on the right, or transition from the state on the left to the state on the right
+	Addition of the operands on both sides
-	Subtraction of the operand on the right from the operand on the left
×	Multiplication of the operands on both sides
÷	Division of the operand on the left by the operand on the right
^	Logical AND of the operands on both sides
\vee	Logical OR of the operands on both sides
\oplus	Logical exclusive OR of the operands on both sides
7	NOT (logical complement)

Symbol	Description
(), <>	Contents of operand
	eral registers include 8-bit registers (R0H to R7H and R0L to R7L) and 16-bit registers to R7 and E0 to E7).

Condition Code Notation

Symbol	Description
\updownarrow	Changed according to execution result
*	Undetermined (no guaranteed value)
0	Cleared to 0
1	Set to 1
_	Not affected by execution of the instruction
Δ	Varies depending on conditions, described in notes



Table A.1 Instruction Set

1. Data transfer instructions

				A Inst					le a 1 (by)								No. Stat	
	Mnemonic	Operand Size	#xx	Rn	@ERn	@(d, ERn)	@-ERn/@ERn+	@aa	@(d, PC)	@ @aa	1	Operation	1	Con H	ditio	n Co	ode	с	Normal	Advanced
MOV	MOV.B #xx:8, Rd	в	2	-	-	-	-	-		-		#xx:8 → Rd8	-		1	1	0	_	- 2	
	MOV.B Rs, Rd	В		2								$Rs8 \rightarrow Rd8$	_	_	1	1	0	_	2	2
	MOV.B @ERs, Rd	В			2							@ERs \rightarrow Rd8	_	_	1	1	0	—	4	1
	MOV.B @(d:16, ERs), Rd	В				4						@(d:16, ERs) → Rd8	_	_	\$	\$	0	_	6	; ;
	MOV.B @(d:24, ERs), Rd	В				8						@(d:24, ERs) → Rd8	_	_	\$	\$	0	_	1	0
	MOV.B @ERs+, Rd	В					2					@ERs → Rd8 ERs32+1 → ERs32	—	-	\$	\$	0	-	6	3
	MOV.B @aa:8, Rd	В						2				@aa:8 \rightarrow Rd8	—	-	\$	\$	0	—	4	1
	MOV.B @aa:16, Rd	В						4				@aa:16 \rightarrow Rd8	—	_	\$	\$	0	—	6	3
	MOV.B @aa:24, Rd	В						6				@aa:24 \rightarrow Rd8	—	-	\$	\$	0	—	8	3
	MOV.B Rs, @ERd	В			2							$Rs8 \rightarrow @ERd$	—	-	\$	\$	0	—	4	ł
	MOV.B Rs, @(d:16, ERd)	В				4						$Rs8 \rightarrow @(d:16, ERd)$	—	—	\$	\$	0	—	6	3
	MOV.B Rs, @(d:24, ERd)	В				8						$Rs8 \rightarrow @(d:24, ERd)$	—	—	\$	\$	0	—	1	0
	MOV.B Rs, @-ERd	В					2					$\begin{array}{l} ERd32-1 \rightarrow ERd32 \\ Rs8 \rightarrow @ ERd \end{array}$	—	-	\$	\$	0	-	6	\$
	MOV.B Rs, @aa:8	В						2				Rs8 \rightarrow @aa:8	—	—	\$	\$	0	—	4	ł
	MOV.B Rs, @aa:16	В						4				Rs8 \rightarrow @aa:16	—	—	\$	\$	0	—	6	3
	MOV.B Rs, @aa:24	В						6				$Rs8 \rightarrow @aa:24$	—	-	\$	\$	0	—	8	3
	MOV.W #xx:16, Rd	W	4									#xx:16 → Rd16	—	—	\$	\$	0	—	4	1
	MOV.W Rs, Rd	W		2								$Rs16 \rightarrow Rd16$	—	—	\$	\$	0	—	2	2
	MOV.W @ERs, Rd	W			2							$@ERs \rightarrow Rd16$	—	-	\$	\$	0	-	4	1
	MOV.W @(d:16, ERs), Rd	W				4						@(d:16, ERs) → Rd16	—	-	\$	\$	0	-	6	;
	MOV.W @(d:24, ERs), Rd	W				8						@(d:24, ERs) → Rd16	—	-	\$	\$	0	—	1	0
	MOV.W @ERs+, Rd	W					2					@ERs → Rd16 ERs32+2 → @ERd32	—	_	\$	\$	0	-	6	;
	MOV.W @aa:16, Rd	W						4				@aa:16 → Rd16	-	-	\$	\$	0	—	6	3
	MOV.W @aa:24, Rd	W						6				@aa:24 → Rd16	-	-	\$	\$	0	-	8	3
	MOV.W Rs, @ERd	W			2							$Rs16 \rightarrow @ERd$	—	-	\$	\$	0	-	4	1
	MOV.W Rs, @(d:16, ERd)	W				4						$Rs16 \rightarrow @(d:16, ERd)$	—	—	€	€	0	_	6	}
	MOV.W Rs, @(d:24, ERd)	W				8						$Rs16 \rightarrow @(d:24, ERd)$	—	-	\$	\$	0	—	1	0



									le a 1 (by)								No Stat	. of es ^{*1}
	Mnemonic	Operand Size	#xx	Rn	@ERn	@(d, ERn)	@-ERn/@ERn+	@aa	@(d, PC)	@ @ aa	I	Operation	1	Con	ditio	n Co	v	с	Normal	Advanced
MOV	MOV.W Rs, @-ERd	w					2					ERd32–2 \rightarrow ERd32 Rs16 \rightarrow @ERd	-	-	\$	\$	0	-	6	6
	MOV.W Rs, @aa:16	w						4				Rs16 \rightarrow @aa:16	_	-	\$	\$	0	-	6	6
	MOV.W Rs, @aa:24	w						6				Rs16 \rightarrow @aa:24	_	-	\$	\$	0	-	8	8
	MOV.L #xx:32, Rd	L	6									#xx:32 → Rd32	_	-	\$	\$	0	-	e	6
	MOV.L ERs, ERd	L		2								ERs32 \rightarrow ERd32	_	-	\$	\$	0	-	2	2
	MOV.L @ERs, ERd	L			4							@ERs \rightarrow ERd32	_	-	\$	\$	0	-	8	8
	MOV.L @(d:16, ERs), ERd	L				6						@(d:16, ERs) → ERd32	_	-	\$	\$	0	-	1	0
	MOV.L @(d:24, ERs), ERd	L				10						@(d:24, ERs) → ERd32	_	-	\$	\$	0	-	1	4
	MOV.L @ERs+, ERd	L					4					@ERs → ERd32 ERs32+4 → ERs32	-	-	\$	\$	0	-	1	0
	MOV.L @aa:16, ERd	L						6				@aa:16 \rightarrow ERd32	_	—	\$	\$	0	-	1	0
	MOV.L @aa:24, ERd	L						8				@aa:24 \rightarrow ERd32	_	-	\$	\$	0	-	1	2
	MOV.L ERs, @ERd	L			4							$ERs32 \rightarrow @ERd$	_	-	\$	\$	0	—	8	В
	MOV.L ERs, @(d:16, ERd)	L				6						ERs32 \rightarrow @(d:16, ERd)	_	-	\$	\$	0	-	1	0
	MOV.L ERs, @(d:24, ERd)	L				10						ERs32 \rightarrow @(d:24, ERd)	_	-	\$	\$	0	—	1	4
	MOV.L ERs, @-ERd	L					4					$\begin{array}{l} ERd32-4 \to ERd32 \\ ERs32 \to @ ERd \end{array}$	-	-	\$	\$	0	-	1	0
	MOV.L ERs, @aa:16	L						6				ERs32 \rightarrow @aa:16	_	-	\$	\$	0	-	1	0
	MOV.L ERs, @aa:24	L						8				ERs32 \rightarrow @aa:24	_	-	\$	\$	0	—	1	2
POP	POP.W Rn	W									2	$\begin{array}{l} @ SP \to Rn16 \\ \\ SP+2 \to SP \end{array}$	-	-	\$	\$	0	-	e	6
	POP.L ERn	L									4	$\begin{array}{l} @SP \to ERn32 \\ SP+4 \to SP \end{array}$	-	-	\$	\$	0	-	1	0
PUSH	PUSH.W Rn	W									2	$SP-2 \rightarrow SP$ Rn16 $\rightarrow @SP$	-	-	\$	\$	0	-	6	6
	PUSH.L ERn	L									4	$SP-4 \rightarrow SP$ ERn32 $\rightarrow @SP$	-	-	\$	\$	0	-	1	0
MOVFPE	MOVFPE @aa:16, Rd	В						4				Cannot be used in this LSI		annc is LS		use	ed ir	1		
MOVTPE	MOVTPE Rs, @aa:16	В						4				Cannot be used in this LSI		annc is LS	ı					

2. Arithmetic instructions

									le ai i (by)								No Stat	. of es ^{*1}
	Mnemonic	Operand Size	XX#	Rn	@ERn	@(d, ERn)	@-ERn/@ERn+	@aa	@(d, PC)	@ @ aa	1	Operation	1	Con	ditio	n Co	v	с	Normal	Advanced
ADD	ADD.B #xx:8, Rd	В	2									$Rd8+#xx:8 \rightarrow Rd8$	_	\$	\$	\$	\$	1	2	2
	ADD.B Rs, Rd	В		2								$Rd8+Rs8 \rightarrow Rd8$	-	\$	\$	1	\$	\$	2	2
	ADD.W #xx:16, Rd	w	4									Rd16+#xx:16 \rightarrow Rd16	_	(1)	\$	1	\$	\$	4	1
	ADD.W Rs, Rd	w		2								Rd16+Rs16 \rightarrow Rd16	-	(1)	\$	\$	\$	\$	2	2
	ADD.L #xx:32, ERd	L	6									ERd32+#xx:32 → ERd32	-	(2)	\$	\$	\$	\$	6	6
	ADD.L ERs, ERd	L		2								ERd32+ERs32 → ERd32	-	(2)	\$	\$	\$	\$	2	2
ADDX	ADDX.B #xx:8, Rd	в	2									$Rd8+#xx:8 + C \rightarrow Rd8$	—	\$	€	(3)	\$	\$	2	2
	ADDX.B Rs, Rd	В		2								Rd8+Rs8 +C \rightarrow Rd8	-	\$	\$	(3)	\$	\$	2	2
ADDS	ADDS.L #1, ERd	L		2								ERd32+1 \rightarrow ERd32	—	—	_	—	—	—	2	2
	ADDS.L #2, ERd	L		2								$ERd32+2 \rightarrow ERd32$	—	—	_	—	—	—	2	2
	ADDS.L #4, ERd	L		2								$ERd32+4 \rightarrow ERd32$	—	—	_	—	—	—	ć	2
INC	INC.B Rd	В		2								$Rd8+1 \rightarrow Rd8$	—	—	\$	\$	\$	-	2	2
	INC.W #1, Rd	w		2								Rd16+1 → Rd16	—	—	\$	\$	\$	—	2	2
	INC.W #2, Rd	W		2								Rd16+2 → Rd16	—	—	€	\$	\$	—	2	2
	INC.L #1, ERd	L		2								ERd32+1 \rightarrow ERd32	—	—	€	\$	\$	—	2	2
	INC.L #2, ERd	L		2								$ERd32+2 \rightarrow ERd32$	—	—	€	\$	\$	—	2	2
DAA	DAA Rd	В		2								Rd8 decimal adjust → Rd8	—	*	\$	\$	*	—	2	2
SUB	SUB.B Rs, Rd	В		2								$Rd8-Rs8 \rightarrow Rd8$	—	\$	\$	\$	\$	\$	2	2
	SUB.W #xx:16, Rd	W	4									Rd16–#xx:16 \rightarrow Rd16	—	(1)	€	\$	\$	\$	4	1
	SUB.W Rs, Rd	W		2								Rd16–Rs16 \rightarrow Rd16	—	(1)	↕	\$	\$	\$	2	2
	SUB.L #xx:32, ERd	L	6									$ERd32\text{-}\#xx:32 \rightarrow ERd32$	—	(2)	↕	\$	↕	\uparrow	6	6
	SUB.L ERs, ERd	L		2								$ERd32{-}ERs32 \rightarrow ERd32$	—	(2)	€	\$	\$	\$	2	2
SUBX	SUBX.B #xx:8, Rd	В	2									Rd8–#xx:8–C \rightarrow Rd8	—	\$	\$	(3)	\$	\$	2	2
	SUBX.B Rs, Rd	В		2								Rd8–Rs8–C \rightarrow Rd8	—	\$	\$	(3)	\$	\$	2	2
SUBS	SUBS.L #1, ERd	L		2								ERd32–1 \rightarrow ERd32	-	-	—	-	_	-	2	2
	SUBS.L #2, ERd	L		2								$ERd32-2 \rightarrow ERd32$	—	_	—	-	—	—	2	2
	SUBS.L #4, ERd	L		2								$ERd324 \to ERd32$	—	—	—	—	—	—	2	2
DEC	DEC.B Rd	В		2								$Rd8-1 \rightarrow Rd8$	-	—	€	€	↕	—	2	2
	DEC.W #1, Rd	W		2								$Rd16-1 \rightarrow Rd16$	—	—	\updownarrow	¢	\updownarrow	—	2	2
	DEC.W #2, Rd	W		2								Rd16–2 \rightarrow Rd16	_	-	€	\$	\uparrow	_	2	2



									le a n (by)								No Stat	. of es ^{*1}
	Mnemonic	Operand Size	#xx	Rn	@ERn	@(d, ERn)	@-ERn/@ERn+	@aa	@(d, PC)	@ @ aa		Operation		Con	ditio	n Co	v	с	Normal	Advanced
DEC	DEC.L #1, ERd	L	-145	2			-				-	ERd32–1 \rightarrow ERd32	-	п —	№	2	▼		_	2
220	DEC.L #2, ERd	L		2			-	-				ERd32–2 \rightarrow ERd32	_	_	\$	↓	↓ ↓	_		2
DAS	DAS.Rd	В		2								Rd8 decimal adjust \rightarrow Rd8	-	*	\$	\$	*	-	2	2
MULXU	MULXU. B Rs, Rd	В		2								$Rd8 \times Rs8 \rightarrow Rd16$ (unsigned multiplication)	-	-	-	-	-	-	1	4
	MULXU. W Rs, ERd	W		2								$Rd16 \times Rs16 \rightarrow ERd32$ (unsigned multiplication)	—	—	—	—	—	-	2	2
MULXS	MULXS. B Rs, Rd	В		4								$Rd8 \times Rs8 \rightarrow Rd16$ (signed multiplication)	-	-	\$	\$	—	-	1	6
	MULXS. W Rs, ERd	W		4								$Rd16 \times Rs16 \rightarrow ERd32$ (signed multiplication)	-	—	\$	\$	—	-	2	4
DIVXU	DIVXU. B Rs, Rd	В		2								Rd16 \div Rs8 \rightarrow Rd16 (RdH: remainder, RdL: quotient) (unsigned division)	_		(6)	(7)	—	_	1	4
	DIVXU. W Rs, ERd	W		2								$ERd32 \div Rs16 \rightarrow ERd32$ (Ed: remainder, Rd: quotient) (unsigned division)	-	_	(6)	(7)	-	-	2	2
DIVXS	DIVXS. B Rs, Rd	В		4								$\begin{array}{l} Rd16 \div Rs8 \rightarrow Rd16 \\ (RdH: remainder, \\ RdL: quotient) \\ (signed division) \end{array}$	-	—	(8)	(7)	_	-	1	6
	DIVXS. W Rs, ERd	W		4								$\label{eq:result} \begin{array}{l} ERd32 \div Rs16 \rightarrow ERd32 \\ (Ed: remainder, \\ Rd: quotient) \\ (signed division) \end{array}$	-	—	(8)	(7)	_	-	2	4
CMP	CMP.B #xx:8, Rd	В	2									Rd8–#xx:8	—	\$	\$	\$	\$	\$	1	2
	CMP.B Rs, Rd	В		2								Rd8–Rs8	—	\updownarrow	\$	\$	↕	\$	1	2
	CMP.W #xx:16, Rd	W	4									Rd16-#xx:16	—	(1)	\$	\$	↕	\$	4	4
	CMP.W Rs, Rd	W		2								Rd16–Rs16	—	(1)	\$	\$	↕	\$	1	2
	CMP.L #xx:32, ERd	L	6									ERd32-#xx:32	_	(2)	\$	\$	↕	\$	4	1
	CMP.L ERs, ERd	L		2								ERd32–ERs32		(2)	\$	\$	\$	\$	2	2

								ng Lei			nd /tes)							No Stat	
	Mnemonic	Operand Size	Operation	×		@ERn	@(d, ERn)	@-ERn/@ERn+	@aa	@(d, PC)	@aa			Con	ditio	n Co	ode		Normal	Advanced
		ő		XX#	Rn	0	0	ġ	0	0	0	Ι	Т	н	Ν	z	v	С	Ŷ	Ad
NEG	NEG.B Rd	В	$0-Rd8 \rightarrow Rd8$		2								—	\updownarrow	\updownarrow	\uparrow	\updownarrow	\updownarrow	2	2
	NEG.W Rd	W	$0-Rd16 \rightarrow Rd16$		2								—	\updownarrow	\updownarrow	€	\updownarrow	\updownarrow	2	2
	NEG.L ERd	L	$0-ERd32 \rightarrow ERd32$		2								-	\$	\$	\$	\updownarrow	\updownarrow	2	2
EXTU	EXTU.W Rd	W	$0 \rightarrow (\text{} \text{ of Rd16})$		2								-	—	0	€	0	—	2	2
	EXTU.L ERd	L	$0 \rightarrow (< bits 31 to 16 > of ERd32)$		2								-	—	0	\$	0	—	2	2
EXTS	EXTS.W Rd	w	(<bit 7=""> of Rd16) \rightarrow (<bits 15="" 8="" to=""> of Rd16)</bits></bit>		2								—	—	\$	\$	0	—	2	2
	EXTS.L ERd	L	(<bit 15=""> of ERd32) \rightarrow (<bits 16="" 31="" to=""> of ERd32)</bits></bit>		2										\$	\$	0		2	2



3. Logic instructions

							ng I Ler)								No. Stat	. of es ^{*1}
	Mnemonic	Operand Size	#xx	Rn	@ERn	@(d, ERn)	@-ERn/@ERn+	@ aa	@(d, PC)	@ @ aa		Operation		Con	ditio	n Co	v	с	Normal	Advanced
AND	AND.B #xx:8, Rd	В	2	-	-	-	-	-	-	-	· ·	Rd8∧#xx:8 → Rd8		-	1	1	0	Ē	_	2
/	AND.B Rs, Rd	В	-	2								$Rd8 \land Rs8 \rightarrow Rd8$	_	-	↓	↓	0	-	2	2
	AND.W #xx:16, Rd	w	4									Rd16∧#xx:16 → Rd16	_	_	\$	\$	0	_	4	4
	AND.W Rs, Rd	w		2								Rd16∧Rs16 \rightarrow Rd16	_	_	\$	\$	0	_	2	2
	AND.L #xx:32, ERd	L	6									ERd32 \wedge #xx:32 \rightarrow ERd32	_	_	\$	\$	0	-	e	6
	AND.L ERs, ERd	L		4								$ERd32 \land ERs32 \rightarrow ERd32$	_	—	\$	\$	0	—	4	4
OR	OR.B #xx:8, Rd	В	2									$Rd8/#xx:8 \rightarrow Rd8$	_	—	\$	\$	0	-	2	2
	OR.B Rs, Rd	В		2								Rd8/Rs8 \rightarrow Rd8	_	—	\$	\$	0	—	2	2
	OR.W #xx:16, Rd	W	4									Rd16/#xx:16 → Rd16	—	-	\$	\$	0	-	4	4
	OR.W Rs, Rd	W		2								$Rd16/Rs16 \rightarrow Rd16$	-	-	\$	\$	0	-	2	2
	OR.L #xx:32, ERd	L	6									$ERd32/#xx:32 \rightarrow ERd32$	-	—	\updownarrow	\uparrow	0	—	6	6
	OR.L ERs, ERd	L		4								$ERd32/ERs32 \rightarrow ERd32$	—	—	\updownarrow	\$	0	—	4	4
XOR	XOR.B #xx:8, Rd	В	2									$Rd8 \oplus \#xx: 8 \rightarrow Rd8$	—	—	\updownarrow	\$	0	-	2	2
	XOR.B Rs, Rd	В		2								$Rd8 \oplus Rs8 \to Rd8$	—	-	\updownarrow	\$	0	-	2	2
	XOR.W #xx:16, Rd	W	4									$Rd16 \oplus #xx:16 \rightarrow Rd16$	—	—	\$	\$	0	—	4	4
	XOR.W Rs, Rd	W		2								$Rd16 \oplus Rs16 \rightarrow Rd16$	—	—	\$	\$	0	—	2	2
	XOR.L #xx:32, ERd	L	6									$ERd32 \oplus \#xx:32 \to ERd32$	—	-	\uparrow	\uparrow	0	—	6	ô
	XOR.L ERs, ERd	L		4								$ERd32{\oplus}ERs32 \to ERd32$	_	-	\updownarrow	↕	0	-	4	4
NOT	NOT.B Rd	В		2								\neg Rd8 \rightarrow Rd8	—	—	↕	↕	0	-	2	2
	NOT.W Rd	W		2								\neg Rd16 \rightarrow Rd16	-	-	↕	↕	0	-	2	2
	NOT.L ERd	L		2								\neg Rd32 \rightarrow Rd32	-		\updownarrow	\updownarrow	0	-	2	2

4. Shift instructions

								Moc ngth		nd /tes)								No. Stat	
	Mnemonic	Operand Size	×	-	@ERn	@(d, ERn)	@-ERn/@ERn+	@aa	@(d, PC)	@aa		Operation		Con	ditio	n Co	de		Normal	Advanced
		ō	XX#	Rn	0	0	0	0	0	0			Т	н	N	z	۷	С	ž	Ă
SHAL	SHAL.B Rd	В		2								- C - − 0	_	_	\$	↕	↕	\$	2	2
	SHAL.W Rd	W		2									-	-	€	€	\updownarrow	\uparrow	2	2
	SHAL.L ERd	L		2								MSB LSB	-	-	€	€	\updownarrow	\uparrow	2	-
SHAR	SHAR.B Rd	В		2								r. ►	_	-	\$	€	0	\$	2	2
	SHAR.W Rd	W		2									_	_	€	↕	0	\$	2	2
	SHAR.L ERd	L		2								MSB LSB	_	_	€	€	0	\uparrow	2	2
SHLL	SHLL.B Rd	В		2									_	-	€	€	0	\uparrow	2	2
	SHLL.W Rd	W		2									_	-	€	€	0	\uparrow	2	2
	SHLL.L ERd	L		2								MSB LSB	-	<u> </u>	\$	€	0	\uparrow	2	2
SHLR	SHLR.B Rd	В		2								0-+C	-	-	\$	€	0	\uparrow	2	2
	SHLR.W Rd	W		2									-	-	\$	€	0	\uparrow	2	
	SHLR.L ERd	L		2								MSB LSB	_	_	€	↕	0	\$	2	2
ROTXL	ROTXL.B Rd	В		2									_	-	€	↕	0	\uparrow	2	2
	ROTXL.W Rd	W		2									_	-	€	€	0	\uparrow	2	2
	ROTXL.L ERd	L		2								MSB - LSB	-	_	\$	€	0	\$	2	2
ROTXR	ROTXR.B Rd	В		2								┍╼───────────	-	<u> </u>	\$	€	0	\updownarrow	2	2
	ROTXR.W Rd	W		2									-	-	\$	€	0	\updownarrow	2	2
	ROTXR.L ERd	L		2								MSB → LSB	-	-	\$	€	0	\updownarrow	2	2
ROTL	ROTL.B Rd	В		2									—	-	\$	↕	0	\updownarrow	2	2
	ROTL.W Rd	W		2									_	_	\$	↕	0	\uparrow	2	2
	ROTL.L ERd	L		2								MSB - LSB	_	_	\$	€	0	\uparrow	2	2
ROTR	ROTR.B Rd	В		2									—	_	€	€	0	\updownarrow	2	2
	ROTR.W Rd	W		2									—	_	€	€	0	\updownarrow	2	2
	ROTR.L ERd	L		2								MSB ──► LSB	_	-	\$	€	0	\updownarrow	2	2



5. Bit manipulation instructions

						essi tion				nd /tes)								No. Stat	
	Mnemonic	Operand Size	XX#	Rn	@ERn	@(d, ERn)	@-ERn/@ERn+	@aa	@(d, PC)	@ @aa	I	Operation	1	Con	ditic N	n Co	v	с	Normal	Advanced
BSET	BSET #xx:3, Rd	в		2								(#xx:3 of Rd8) ← 1	-	-	—	—	—	-	2	2
	BSET #xx:3, @ERd	В			4							(#xx:3 of @ERd) ← 1	-	—	—	—	—	-	8	3
	BSET #xx:3, @aa:8	В						4				(#xx:3 of @aa:8) ← 1	-	—	—	—	—	-	8	3
	BSET Rn, Rd	В		2								(Rn8 of Rd8) ← 1	-	—	—	—	—	-	2	2
	BSET Rn, @ERd	В			4							(Rn8 of @ERd) ← 1	-	—	—	—	—	—	6	3
	BSET Rn, @aa:8	В						4				(Rn8 of @aa:8) ← 1	—	—	—	—	—	—	8	3
BCLR	BCLR #xx:3, Rd	В		2								(#xx:3 of Rd8) ← 0	—	—	—	—	—	—	2	2
	BCLR #xx:3, @ERd	В			4							(#xx:3 of @ERd) ← 0	-	—	_	—	—	—	8	3
	BCLR #xx:3, @aa:8	В						4				(#xx:3 of @aa:8) ← 0	-	_	—	—	—	-	8	3
	BCLR Rn, Rd	В		2								(Rn8 of Rd8) ← 0	-	_	_	—	-	-	2	2
	BCLR Rn, @ERd	В			4							(Rn8 of @ERd) ← 0	-	_	_	—	_	_	8	3
	BCLR Rn, @aa:8	В						4				(Rn8 of @aa:8) ← 0	-	_	_	—	_	—	8	3
BNOT	BNOT #xx:3, Rd	В		2								(#xx:3 of Rd8) ← ¬ (#xx:3 of Rd8)	-	-	-	-	-	-	2	2
	BNOT #xx:3, @ERd	В			4							(#xx:3 of @ERd) ← ¬ (#xx:3 of @ERd)	-	-	—	-	-	-	8	3
	BNOT #xx:3, @aa:8	В						4				(#xx:3 of @aa:8) ← ¬ (#xx:3 of @aa:8)	-	-	—	-	-	-	8	3
	BNOT Rn, Rd	В		2								(Rn8 of Rd8) ← ¬ (Rn8 of Rd8)	-	-	—	-	-	-	2	2
	BNOT Rn, @ERd	В			4							(Rn8 of @ERd) ← ¬ (Rn8 of @ERd)	-	-	—	—	-	-	8	3
	BNOT Rn, @aa:8	В						4				(Rn8 of @aa:8) ← ¬ (Rn8 of @aa:8)	-	-	-	—	_	-	8	3
BTST	BTST #xx:3, Rd	В		2								¬ (#xx:3 of Rd8) → Z	-	-	—	\$	-	-	2	2
	BTST #xx:3, @ERd	В			4							¬ (#xx:3 of @ERd) → Z	-	-	—	\$	-	-	6	3
	BTST #xx:3, @aa:8	В						4				¬ (#xx:3 of @aa:8) → Z	-	-	—	\$	_	-	6	3
	BTST Rn, Rd	В		2								¬ (Rn8 of @Rd8) → Z	-	-	_	\$	_	-	2	2
	BTST Rn, @ERd	в			4							¬ (Rn8 of @ERd) → Z	-	-	_	\$	_	-	e	3
	BTST Rn, @aa:8	в						4				¬ (Rn8 of @aa:8) → Z	-	-	_	\$	_	-	6	3
BLD	BLD #xx:3, Rd	В		2								(#xx:3 of Rd8) \rightarrow C	-	_	_	_	_	\$	2	2

						essi tion)								No Stat	. of es ^{*1}
	Mnemonic	Operand Size	×		ERn	@(d, ERn)	@-ERn/@ERn+	@aa	@(d, PC)	@aa		Operation		Con	ditio	n Co	ode		Normal	Advanced
		ŏ	XX#	Rn	0	0	<u>.</u>	8	0	0	Ι		I	н	N	z	v	с	ž	Ad
BLD	BLD #xx:3, @ERd	В			4							(#xx:3 of @ERd) \rightarrow C	-	-	—	—	-	\$	6	6
	BLD #xx:3, @aa:8	В						4				(#xx:3 of @aa:8) \rightarrow C	-	—	—	—	—	\$	6	6
BILD	BILD #xx:3, Rd	В		2								\neg (#xx:3 of Rd8) \rightarrow C	-	-	—	—	—	\$	2	2
	BILD #xx:3, @ERd	В			4							$\neg \text{ (#xx:3 of @ERd)} \rightarrow \text{C}$	-	-	—	—	—	\$	6	6
	BILD #xx:3, @aa:8	В						4				\neg (#xx:3 of @aa:8) \rightarrow C	-	-	—	—	—	\$	6	6
BST	BST #xx:3, Rd	В		2								$C \rightarrow (\#xx:3 \text{ of } Rd8)$	-	-	—	—	-	-	2	2
	BST #xx:3, @ERd	В			4							$C \rightarrow (\#xx:3 \text{ of } @ERd24)$	-	-	—	—	-	-	8	3
BIST	BST #xx:3, @aa:8	В						4				$C \rightarrow (\#xx:3 \text{ of } @aa:8)$	-	-	—	—	-	-	8	3
	BIST #xx:3, Rd	В		2								$\neg C \rightarrow (\#xx:3 \text{ of Rd8})$	-	—	—	—	—	—	2	2
	BIST #xx:3, @ERd	В			4							$\neg C \rightarrow (\#xx:3 \text{ of } @ERd24)$	-	—	—	—	—	—	8	3
	BIST #xx:3, @aa:8	В						4				$\neg C \rightarrow (\#xx:3 \text{ of } @aa:8)$	-	-	—	—	—	—	8	3
BAND	BAND #xx:3, Rd	В		2								$C \land (\#xx:3 \text{ of } Rd8) \rightarrow C$	-	—	—	—	—	\$	2	2
	BAND #xx:3, @ERd	В			4							$C \land (\#xx:3 \text{ of } @ERd24) \rightarrow C$	-	-	—	—	—	\$	6	6
BIAND	BAND #xx:3, @aa:8	В						4				$C \land (\#xx:3 \text{ of } @aa:8) \rightarrow C$	-	-	—	—	—	\$	6	6
	BIAND #xx:3, Rd	в		2								$C \land \neg$ (#xx:3 of Rd8) $\rightarrow C$	-	-	—	—	—	\$	2	2
	BIAND #xx:3, @ERd	в			4							$C \land \neg$ (#xx:3 of @ERd24) $\rightarrow C$	-	—	—	—	—	\$	6	6
	BIAND #xx:3, @aa:8	в						4				$C \land \neg$ (#xx:3 of @aa:8) $\rightarrow C$	-	—	—	—	—	\$	6	6
BOR	BOR #xx:3, Rd	в		2								C/(#xx:3 of Rd8) \rightarrow C	-	-	—	—	—	\$	2	2
	BOR #xx:3, @ERd	в			4							C/(#xx:3 of @ERd24) \rightarrow C	-	-	—	_	—	\$	6	6
	BOR #xx:3, @aa:8	в						4				C/(#xx:3 of @aa:8) \rightarrow C	-	-	—	_	—	\$	6	6
BIOR	BIOR #xx:3, Rd	в		2								C⁄ ¬ (#xx:3 of Rd8) → C	-	-	—	_	—	\$	2	2
	BIOR #xx:3, @ERd	в			4							C⁄¬ (#xx:3 of @ERd24) → C	-	-	—	_	—	\$	6	6
	BIOR #xx:3, @aa:8	в						4				C⁄ ¬ (#xx:3 of @aa:8) → C	-	—	—	_	—	\$	6	6
BXOR	BXOR #xx:3, Rd	В		2								C⊕(#xx:3 of Rd8) \rightarrow C	-	-	-	_	-	\$	2	2
	BXOR #xx:3, @ERd	В			4							C⊕(#xx:3 of @ERd24) → C	-	-	-	_	-	\$	6	6
	BXOR #xx:3, @aa:8	В						4				C⊕(#xx:3 of @aa:8) → C	-	-	-	_	-	\$	6	6
BIXOR	BIXOR #xx:3, Rd	В		2								C⊕ ¬ (#xx:3 of Rd8) \rightarrow C	-	-	-	_	-	\$	2	2
	BIXOR #xx:3, @ERd	В			4							C⊕ ¬ (#xx:3 of @ERd24) → C	-	-	-	_	-	\$	6	6
	BIXOR #xx:3, @aa:8	в						4				C⊕ ¬ (#xx:3 of @aa:8) → C	-	-	—	_	-	\$	6	6



6. Branching instructions

									le ai i (by)									No Stat	. of tes ^{*1}
	Mnemonic	Operand Size			Rn	l, ERn)	@-ERn/@ERn+	6	@(d, PC)	@ aa		Oper	ation	_	Con	ditio	on Co	ode		Normal	Advanced
		Ope	XX#	R	@ERn	@(d, I	8	@ aa	00	0	1		Branch Condition	I	н	N	z	v	с	Nor	Adv
Bcc	BRA d:8 (BT d:8)	—							2			If condition	Always	—	-	-	-	-	—	4	4
	BRA d:16 (BT d:16)	—							4			is true then		—	-	-	-	-	-	6	6
	BRN d:8 (BF d:8)	—							2			PC ← PC+d	Never	-	-	-	-	-	-	4	4
	BRN d:16 (BF d:16)	—							4			else next;		—	-	—	-	-	—	6	6
	BHI d:8	—							2			1	C/Z = 0	-	-	-	-	-	-	4	4
	BHI d:16	—							4]		-	-	-	-	-	-	6	6
	BLS d:8	—							2			1	C/Z = 1	-	-	-	-	-	-	4	4
	BLS d:16	_							4			1		—	-	-	-	-	—	6	6
	BCC d:8 (BHS d:8)	_							2			1	C = 0	1-	-	-	-	-	-	4	4
	BCC d:16 (BHS d:16)	_							4			1		-	-	-	-	-	-	6	6
	BCS d:8 (BLO d:8)	—							2			1	C = 1	-	—	-	-	-	—	4	4
	BCS d:16 (BLO d:16)	_							4			1		—	-	—	-	—	—	6	6
	BNE d:8	_							2			1	Z = 0	—	_	—	-	-	—	4	4
	BNE d:16	_							4			1		—	_	—	-	-	—	6	6
	BEQ d:8	_							2			1	Z = 1	—	_	—	-	-	—	4	4
	BEQ d:16	_							4			1		—	-	-	-	-	—	6	6
	BVC d:8	_							2			1	V = 0	—	-	_	-	-	—	4	4
	BVC d:16	_							4					—	-	—	-	-	—	6	6
	BVS d:8	_							2			1	V = 1	—	-	—	—	—	—	4	4
	BVS d:16	_							4			1		-	_	-	-	-	—	6	6
	BPL d:8	—							2			1	N = 0	-	_	-	-	-	—	4	4
	BPL d:16	_							4			1		-	-	-	-	-	-	6	6
	BMI d:8	_							2			1	N = 1	1-	-	-	-	-	-	4	4
	BMI d:16	—							4			1		-	-	-	-	-	-	6	6
	BGE d:8	—							2			1	N⊕V = 0	-	-	-	-	-	-	4	4
	BGE d:16	_							4			1		-	_	-	-	-	-	6	6
	BLT d:8	_							2			1	N⊕V = 1	-	_	-	-	-	-	4	4
	BLT d:16	_							4			1		-	_	-	-	-	-	6	6
	BGT d:8	_							2			1	Z∕(N⊕V) = 0	-	_	-	-	-	-	4	4
	BGT d:16	_							4			1		-	-	-	-	-	-	6	6
	BLE d:8	_							2			1	Z∕(N⊕V) = 1	-	-	-	-	-	-	4	4
	BLE d:16	_							4			1		-	_	-	-	-	_	6	6

				A Inst			ng I Ler)									. of es ^{*1}
	Mnemonic	Operand Size	×		ERn	@(d, ERn)	-ERn/@ERn+	@aa	@(d, PC)	@aa		Operation		Con	ditio	n Co	ode		Normal	Advanced
		ő	XX#	Rn	0	0	0	0	0	0	Ι		I	н	N	z	۷	С	ž	¥
JMP	JMP @ERn	—			2							$PC \gets ERn$	-	-	-	—	—	—	4	4
	JMP @aa:24	—						4				PC ← aa:24	-	-	-	—	—	—	(6
	JMP @@aa:8									2		PC ← @aa:8	—	-	-	—	—	—	8	10
BSR	BSR d:8	-							2			$PC \rightarrow @-SP$ $PC \leftarrow PC+d:8$	-	-	-	—	—	—	6	8
	BSR d:16	-							4			$PC \rightarrow @-SP$ $PC \leftarrow PC+d:16$	-	-	-	-	—	—	8	10
JSR	JSR @ERn	-			2							$PC \rightarrow @-SP$ $PC \leftarrow ERn$	-	-	-	-	—	—	6	8
	JSR @aa:24	-						4				$PC \rightarrow @-SP$ $PC \leftarrow aa:24$	-	-	-	—	-	—	8	10
	JSR @@aa:8	-								2		$PC \rightarrow @-SP$ $PC \leftarrow @aa:8$	-	-	-	-	-	—	8	12
RTS	RTS	_									2	$PC \leftarrow @SP+$	-	-	-	-	-	-	8	10



7. System control instructions

					essi tion				nd /tes)								No Stat	. of es ^{*1}	
	Mnemonic	Operand Size	×	_	@ERn	@(d, ERn)	@-ERn/@ERn+	@ aa	@(d, PC)	@aa		Operation		Con	ditic	n Co	ode		Normal	Advanced
		õ	XX#	Rn	0	0	0	0	0	0			Т	н	Ν	z	v	С	ž	Ă
TRAPA	TRAPA #x:2	-									2	$\begin{array}{l} PC \rightarrow @-SP \\ CCR \rightarrow @-SP \\ <\!\!vector\!$	1	-	-	_	_	-	14	16
RTE	RTE	-										$\begin{array}{c} CCR \leftarrow @SP+\\ PC \leftarrow @SP+\\ \end{array}$ Transition to power-		\$	\$	\$	\$	\$	1	0
SLEEP	SLEEP	-										Transition to power- down state #xx:8 → CCR		—	—	_	—	-	2	2
LDC	LDC #xx:8, CCR	В	2									$#xx:8 \rightarrow CCR$	1 1 1 1 1 1 1 1 1		2	2				
	LDC Rs, CCR	В		2								$Rs8 \rightarrow CCR$	\$	\$	\$	\$	\$	\$	2	2
	LDC @ERs, CCR	W			4							$@ERs \rightarrow CCR$	\$	\updownarrow	\$	\$	\$	\$	6	6
	LDC @(d:16, ERs), CCR	W				6						@(d:16, ERs) → CCR	\updownarrow	\updownarrow	\updownarrow	\$	\$	\$	8	3
	LDC @(d:24, ERs), CCR	W				10						@(d:24, ERs) → CCR	\$	\updownarrow	\$	\$	\$	\$	1	2
	LDC @ERs+, CCR	W					4					$@ ERs \rightarrow CCR$ ERs32+2 \rightarrow ERs32	\$	\$	\$	\$	\$	\$	8	3
	LDC @aa:16, CCR	W						6				@aa:16 \rightarrow CCR	\$	\$	\$	\$	\$	\$	8	3
	LDC @aa:24, CCR	W						8				@aa:24 \rightarrow CCR	\$	\updownarrow	\$	\$	\$	\$	1	0
STC	STC CCR, Rd	В		2								$CCR \rightarrow Rd8$	—	—	—	—	—	-	2	2
	STC CCR, @ERd	W			4							$CCR \rightarrow @ERd$	—	—	—	—	—	-	6	6
	STC CCR, @(d:16, ERd)	W				6						$CCR \rightarrow @(d:16, ERd)$	—	—	—	—	—	—	8	3
	STC CCR, @(d:24, ERd)	W				10						$CCR \rightarrow @(d:24, ERd)$	-	—	—	—	—	—	1	2
	STC CCR, @-ERd	w					4					$\begin{array}{l} ERd32-2 \rightarrow ERd32 \\ CCR \rightarrow @ ERd \end{array}$	-	—	—	—	—	-	8	3
	STC CCR, @aa:16	W						6				$CCR \rightarrow @aa:16$	-	—	—	—	—	—	8	3
	STC CCR, @aa:24	W						8				$CCR \rightarrow @aa:24$	-	—	—	—	—	—	1	0
ANDC	ANDC #xx:8, CCR	В	2									$CCR_{\wedge}\#xx:8 \rightarrow CCR$	\uparrow	\$	\$	\$	\$	\$	1	2
ORC	ORC #xx:8, CCR	В	2									$CCR/#xx:8 \rightarrow CCR$	\$	\$	\$	\$	\$	\$	1	2
XORC	XORC #xx:8, CCR	В	2									$CCR \oplus \#xx:8 \rightarrow CCR$	\$	\$	\$	\$	\$	\$	1	2
NOP	NOP	-									2	$PC \leftarrow PC+2$	—	—	—	_	—	-	2	2

8. Block transfer instructions

					ddr					nd ytes)								No. Stat	
	Mnemonic	Operand Size	×		@ERn	@(d, ERn)	@-ERn/@ERn+	@aa	@(d, PC)	@aa		Operation		Con	ditio	n Co	ode		Normal	Advanced
		õ	XX#	Rn	0	0	0	0	0	0	Ι			н	N	z	v	С	ž	Ă
EEPMOV	EEPMOV. B										4	$\begin{array}{l} \text{if } R4L \neq 0 \text{ then} \\ \text{repeat} @R5 \rightarrow @R6 \\ & R5+1 \rightarrow R5 \\ & R6+1 \rightarrow R6 \\ & R4L-1 \rightarrow R4L \\ \text{until} \qquad R4L=0 \\ \text{else next} \end{array}$							8+ 4n ^{*2}	
	EEPMOV. W										4	$\begin{array}{l} \text{if } R4 \neq 0 \text{ then} \\ \text{repeat} @R5 \rightarrow @R6 \\ &R5+1 \rightarrow R5 \\ &R6+1 \rightarrow R6 \\ &R4-1 \rightarrow R4 \\ \text{until} \qquad R4=0 \\ \text{else next} \end{array}$							8+ 4n ^{*2}	

- Notes: 1. The number of states in cases where the instruction code and its operands are located in on-chip memory is shown here. For other cases see Appendix A.3, Number of Execution States.
 - 2. n is the value set in register R4L or R4.
 - (1) Set to 1 when a carry or borrow occurs at bit 11; otherwise cleared to 0.
 - (2) Set to 1 when a carry or borrow occurs at bit 27; otherwise cleared to 0.
 - (3) Retains its previous value when the result is zero; otherwise cleared to 0.
 - (4) Set to 1 when the adjustment produces a carry; otherwise retains its previous value.
 - (5) The number of states required for execution of an instruction that transfers data in synchronization with the E clock is variable.
 - (6) Set to 1 when the divisor is negative; otherwise cleared to 0.
 - (7) Set to 1 when the divisor is zero; otherwise cleared to 0.
 - (8) Set to 1 when the quotient is negative; otherwise cleared to 0.

A.2 Operation Code Map

Table A.2 Operation Code Map (1)

		4-2	2-1														
	ш.	Table A-2 (2)	Table A-2 (2)			BLE											
	ш	ADDX	SUBX			BGT	JSR		Table A-2 (3)								
	۵	>	۵.			BLT			Table (3								
8H is 0 8H is 1	U	MOV	CMP			BGE	BSR	>									
bit of H bit of H	۵	Table A-2 (2)	Table A-2 (2)			BMI		MOV	EEPMOV								
nificant nificant	۲	Table A-2 Table A-2 (2) (2)	Table A-2 Table A-2 (2) (2)			BPL	JMP		Table A-2 E								
lost sigi lost sigi	0					BVS			Table A-2 Table A-2 EEPMOV (2) (2)								
 Instruction when most significant bit of BH is 0. Instruction when most significant bit of BH is 1. 	8	ADD	SUB			BVC	Table A-2 (2)		MOV								
uction	2	LDC	Table A-2 (2)		MOV.B	BEQ	TRAPA T	BST BIST	BLD	ADD	ADDX	CMP	SUBX	OR	XOR	AND	MOV
 Instruction when most significant bit of BH is 0. Instruction when most significant bit of BH is 1. 	9	ANDC	AND.B			BNE	RTE	AND	BAND BIAND								
	2	XORC	XOR.B			BCS	BSR	XOR	BXOR I BIXOR								
Lfe	4	ORC	OR.B			BCC	RTS	OR	BOR I								
2nd byte BH BL	e	LDC	Table A-2 (2)			BLS	DIVXU		BISI								
1st byte AH AL	N	STC	Table A-2 ⁻ (2)			BHI	MULXU		BCLR								
	-	Table A-2 (2)	Table A-2 . (2)			BRN	DIVXU		BNOT								
on code	0	NOP	Table A-2 Table A-2 Table A-2 Table A-2 Cable A-2 Cable A-3 Cable A-3 <thcable a-3<="" th=""> <thcable a-3<="" th=""> <thc< td=""><td></td><td></td><td>BRA</td><td>MULXU</td><td></td><td>BSET</td><td></td><td></td><td></td><td></td><td></td><td></td><td></td><td></td></thc<></thcable></thcable>			BRA	MULXU		BSET								
Instruction code:	AHAL	0		5	ю	4	2	9	7	8	6	A	В	U	D	Ш	ш



ш	Table A-2 (3)		INC						EXTS		DEC		BLE		
Е													BGT		
D	Table A-2 Table A-2 (3) (3)		INC						EXTS		DEC		BLT		
С	Table A-2 (3)	ADD		MOV						SUB		CMP	BGE		
В		AL		W	SHAL	SHAR	ROTL	ROTR	NEG	SI		Ğ	BMI		
A													BPL		
6			ADDS		SHAL	SHAR	ROTL	ROTR	NEG		SUB		BVS		
8	SLEEP		AD		Ŷ	SH	RC	RC	IN		SI		BVC		
7			INC						EXTU		DEC		BEQ		
6													BNE	AND	AND
5			INC						EXTU		DEC		BCS	XOR	XOR
4	LDC/STC												BCC	OR	OR
3					SHLL	SHLR	ROTXL	ROTXR	NOT				BLS	SUB	SUB
5													BHI	CMP	CMP
1					LL	ГВ	LXL	"XR	рт				BRN	ADD	ADD
0	MOV	INC	ADDS	DAA	SHLL	SHLR	ROTXL	ROTXR	NOT	DEC	SUBS	DAS	BRA	MOV	MOV
AH AL	01	OA	OB	OF	10	11	12	13	17	1A	1B	1F	58	62	ΤA
 			-	-	-	-	-						-	_	-

Table A.2 Operation Code Map (2)

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RENESAS

RE

3rd byte4th byteCHCLDHDHDLDHDLDHDLDHDL	L L L L L L L L L L L L L L L L L L L	LDC LDC LDC LDC LDC STC STC STC			AND AND		BAND BLD OR BIAND BILD	BST BIST			BAND BLD OR BIAND BILD	BST BIST		
3rd byte CH CL	ى س				XOR		BXOR				BXOR			
	4				Ю		BOR BIOR				BOR BIOR			
2nd byte BH BL	m			DIVXS		BTST	BTST			BTST	BTST			
	N		MULXS					BCLR	BCLR			BCLR	BCLR	ttion field. ess field.
e: 1st AH	-			DIVXS				BNOT	BNOT			BNOT	BNOT	ter designé solute addri
on code	0		MULXS					BSET	BSET			BSET	BSET	 r is the register designation field a a is the absolute address field.
Instruction code: Ist byte AH	AH ALBH BLCH	01406	01C05	01D05	01F06	7Cr06*1	7Cr07*1	7Dr06*1	7Dr07*1	7Eaa6*2	7Eaa7*2	7Faa6*2	7Faa7*2	Notes: 1. r is the register designation field. 2. aa is the absolute address field.

RENESAS

Table A.2 Operation Code Map (3)

A.3 Number of Execution States

The status of execution for each instruction of the H8/300H CPU and the method of calculating the number of states required for instruction execution are shown below. Table A.4 shows the number of cycles of each type occurring in each instruction, such as instruction fetch and data read/write. Table A.3 shows the number of states required for each cycle. The total number of states required for execution of an instruction can be calculated by the following expression:

Execution states = $I \times S_1 + J \times S_2 + K \times S_K + L \times S_L + M \times S_M + N \times S_N$

Examples: When instruction is fetched from on-chip ROM, and an on-chip RAM is accessed.

BSET #0, @FF00

From table A.4: $I=L=2, \quad J=K=M=N=0$

From table A.3: $S_1 = 2$, $S_1 = 2$

Number of states required for execution $= 2 \times 2 + 2 \times 2 = 8$

When instruction is fetched from on-chip ROM, branch address is read from on-chip ROM, and on-chip RAM is used for stack area.

JSR @@ 30

From table A.4: $I=2, \quad J=K=1, \quad L=M=N=0$

From table A.3:

$$\mathbf{S}_{\mathrm{I}} = \mathbf{S}_{\mathrm{J}} = \mathbf{S}_{\mathrm{K}} = 2$$

Number of states required for execution = $2 \times 2 + 1 \times 2 + 1 \times 2 = 8$



Table A.3	Number of Cycles in Each Instruction
-----------	--------------------------------------

	Ad	ccess Location
	On-Chip Memory	On-Chip Peripheral Module
S,	2	_
S	_	
Sκ	_	
S	_	2 or 3*
S _м	_	2 or 3*
S _N		1
	S _J S _κ S _L S _M	On-Chip Memory S ₁ 2 S ₃ 2 S _k 2 S _L 5 S _M 2

Note: * Depends on which on-chip peripheral module is accessed. See section 17.1, Register Addresses (Address Order).

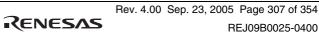
Instruction	Mnemonic	Instruction Fetch I	Branch Addr. Read J	Stack Operation K	Byte Data Access L	Word Data Access M	Internal Operation N
ADD	ADD.B #xx:8, Rd	1					
	ADD.B Rs, Rd	1					
	ADD.W #xx:16, Rd	2					
	ADD.W Rs, Rd	1					
	ADD.L #xx:32, ERd	3					
	ADD.L ERs, ERd	1					
ADDS	ADDS #1/2/4, ERd	1					
ADDX	ADDX #xx:8, Rd	1					
	ADDX Rs, Rd	1					
AND	AND.B #xx:8, Rd	1					
	AND.B Rs, Rd	1					
	AND.W #xx:16, Rd	2					
	AND.W Rs, Rd	1					
	AND.L #xx:32, ERd	3					
	AND.L ERs, ERd	2					
ANDC	ANDC #xx:8, CCR	1					
BAND	BAND #xx:3, Rd	1					
	BAND #xx:3, @ERd	2			1		
	BAND #xx:3, @aa:8	2			1		
Bcc	BRA d:8 (BT d:8)	2					
	BRN d:8 (BF d:8)	2					
	BHI d:8	2					
	BLS d:8	2					
	BCC d:8 (BHS d:8)	2					
	BCS d:8 (BLO d:8)	2					
	BNE d:8	2					
	BEQ d:8	2					
	BVC d:8	2					
	BVS d:8	2					
	BPL d:8	2					
	BMI d:8	2					
	BGE d:8	2					

Table A.4 Number of Cycles in Each Instruction



Instruction	Mnemonic	Instruction Fetch I	Branch Addr. Read J	Stack Operation K	Byte Data Access L	Word Data Access M	Internal Operation N
Bcc	BLT d:8	2					
	BGT d:8	2					
	BLE d:8	2					
	BRA d:16(BT d:16)	2					2
	BRN d:16(BF d:16)	2					2
	BHI d:16	2					2
	BLS d:16	2					2
	BCC d:16(BHS d:16)	2					2
	BCS d:16(BLO d:16)	2					2
	BNE d:16	2					2
	BEQ d:16	2					2
	BVC d:16	2					2
	BVS d:16	2					2
	BPL d:16	2					2
	BMI d:16	2					2
	BGE d:16	2					2
	BLT d:16	2					2
	BGT d:16	2					2
	BLE d:16	2					2
BCLR	BCLR #xx:3, Rd	1					
	BCLR #xx:3, @ERd	2			2		
	BCLR #xx:3, @aa:8	2			2		
	BCLR Rn, Rd	1					
	BCLR Rn, @ERd	2			2		
	BCLR Rn, @aa:8	2			2		
BIAND	BIAND #xx:3, Rd	1					
	BIAND #xx:3, @ERd	2			1		
	BIAND #xx:3, @aa:8	2			1		
BILD	BILD #xx:3, Rd	1					
	BILD #xx:3, @ERd	2			1		
	BILD #xx:3, @aa:8	2			1		

		Instruction Fetch	Addr. Read	-	Byte Data Access	Word Data Access	Operation
Instruction	Mnemonic	I	J	К	L	М	N
BIOR	BIOR #xx:8, Rd	1					
	BIOR #xx:8, @ERd	2			1		
	BIOR #xx:8, @aa:8	2			1		
BIST	BIST #xx:3, Rd	1					
	BIST #xx:3, @ERd	2			2		
	BIST #xx:3, @aa:8	2			2		
BIXOR	BIXOR #xx:3, Rd	1					
	BIXOR #xx:3, @ERd	2			1		
	BIXOR #xx:3, @aa:8	2			1		
BLD	BLD #xx:3, Rd	1					
	BLD #xx:3, @ERd	2			1		
	BLD #xx:3, @aa:8	2			1		
BNOT	BNOT #xx:3, Rd	1					
	BNOT #xx:3, @ERd	2			2		
	BNOT #xx:3, @aa:8	2			2		
	BNOT Rn, Rd	1					
	BNOT Rn, @ERd	2			2		
	BNOT Rn, @aa:8	2			2		
BOR	BOR #xx:3, Rd	1					
	BOR #xx:3, @ERd	2			1		
	BOR #xx:3, @aa:8	2			1		
BSET	BSET #xx:3, Rd	1					
	BSET #xx:3, @ERd	2			2		
	BSET #xx:3, @aa:8	2			2		
	BSET Rn, Rd	1					
	BSET Rn, @ERd	2			2		
	BSET Rn, @aa:8	2			2		
BSR	BSR d:8	2		1			
	BSR d:16	2		1			2
BST	BST #xx:3, Rd	1					
	BST #xx:3, @ERd	2			2		
	BST #xx:3, @aa:8	2			2		



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Instruction	Mnemonic	Instruction Fetch I	Branch Addr. Read J	Stack Operation K	Byte Data Access L	Word Data Access M	Internal Operation N
BTST	BTST #xx:3, Rd	1					
	BTST #xx:3, @ERd	2			1		
	BTST #xx:3, @aa:8	2			1		
	BTST Rn, Rd	1					
	BTST Rn, @ERd	2			1		
	BTST Rn, @aa:8	2			1		
BXOR	BXOR #xx:3, Rd	1					
	BXOR #xx:3, @ERd	2			1		
	BXOR #xx:3, @aa:8	2			1		
CMP	CMP.B #xx:8, Rd	1					
	CMP.B Rs, Rd	1					
	CMP.W #xx:16, Rd	2					
	CMP.W Rs, Rd	1					
	CMP.L #xx:32, ERd	3					
	CMP.L ERs, ERd	1					
DAA	DAA Rd	1					<u> </u>
DAS	DAS Rd	1					
DEC	DEC.B Rd	1					
	DEC.W #1/2, Rd	1					
	DEC.L #1/2, ERd	1					
DUVXS	DIVXS.B Rs, Rd	2					12
	DIVXS.W Rs, ERd	2					20
DIVXU	DIVXU.B Rs, Rd	1					12
	DIVXU.W Rs, ERd	1					20
EEPMOV	EEPMOV.B	2			2n+2*1		
	EEPMOV.W	2			2n+2*1		
EXTS	EXTS.W Rd	1					
	EXTS.L ERd	1					
EXTU	EXTU.W Rd	1					
	EXTU.L ERd	1					

		Instruction Fetch	Addr. Read		Byte Data Access	Word Data Access	Internal Operation
	Mnemonic	I	J	К	L	Μ	N
INC	INC.B Rd	1					
	INC.W #1/2, Rd	1					
	INC.L #1/2, ERd	1					
JMP	JMP @ERn	2					
	JMP @aa:24	2					2
	JMP @@aa:8	2	1				2
JSR	JSR @ERn	2		1			
	JSR @aa:24	2		1			2
	JSR @@aa:8	2	1	1			
LDC	LDC #xx:8, CCR	1					
	LDC Rs, CCR	1					
	LDC@ERs, CCR	2				1	
	LDC@(d:16, ERs), CCR	3				1	
	LDC@(d:24,ERs), CCR	5				1	
	LDC@ERs+, CCR	2				1	2
	LDC@aa:16, CCR	3				1	
	LDC@aa:24, CCR	4				1	
MOV	MOV.B #xx:8, Rd	1					
	MOV.B Rs, Rd	1					
	MOV.B @ERs, Rd	1			1		
	MOV.B @(d:16, ERs), Rd	2			1		
	MOV.B @(d:24, ERs), Rd	4			1		
	MOV.B @ERs+, Rd	1			1		2
	MOV.B @aa:8, Rd	1			1		
	MOV.B @aa:16, Rd	2			1		
	MOV.B @aa:24, Rd	3			1		
	MOV.B Rs, @Erd	1			1		
	MOV.B Rs, @(d:16, ERd)	2			1		
	MOV.B Rs, @(d:24, ERd)	4			1		
	MOV.B Rs, @-ERd	1			1		2
	MOV.B Rs, @aa:8	1			1		



Instruction	Mnemonic	Instruction Fetch I	Branch Addr. Read J	Stack Operation K	Byte Data Access L	Word Data Access M	Internal Operation N
MOV	MOV.B Rs, @aa:16	2			1		
	MOV.B Rs, @aa:24	3			1		
	MOV.W #xx:16, Rd	2					
	MOV.W Rs, Rd	1					
	MOV.W @ERs, Rd	1				1	
	MOV.W @(d:16,ERs), Rd	2				1	
	MOV.W @(d:24,ERs), Rd	4				1	
	MOV.W @ERs+, Rd	1				1	2
	MOV.W @aa:16, Rd	2				1	
	MOV.W @aa:24, Rd	3				1	
	MOV.W Rs, @ERd	1				1	
	MOV.W Rs, @(d:16,ERd)	2				1	
	MOV.W Rs, @(d:24,ERd)	4				1	
MOV	MOV.W Rs, @-ERd	1				1	2
	MOV.W Rs, @aa:16	2				1	
	MOV.W Rs, @aa:24	3				1	
	MOV.L #xx:32, ERd	3					
	MOV.L ERs, ERd	1					
	MOV.L @ERs, ERd	2				2	
	MOV.L @(d:16,ERs), ERd	3				2	
	MOV.L @(d:24,ERs), ERd	5				2	
	MOV.L @ERs+, ERd	2				2	2
	MOV.L @aa:16, ERd	3				2	
	MOV.L @aa:24, ERd	4				2	
	MOV.L ERs,@ERd	2				2	
	MOV.L ERs, @(d:16,ERd)	3				2	
	MOV.L ERs, @(d:24,ERd)	5				2	
	MOV.L ERs, @-ERd	2				2	2
	MOV.L ERs, @aa:16	3				2	
	MOV.L ERs, @aa:24	4				2	
MOVFPE	MOVFPE @aa:16, Rd*2	2			1		
MOVTPE	MOVTPE Rs,@aa:16*2	2			1		

		Instruction Fetch	Addr. Read		Byte Data Access	Word Data Access	Internal Operation
Instruction	Mnemonic	I	J	К	L	М	Ν
MULXS	MULXS.B Rs, Rd	2					12
	MULXS.W Rs, ERd	2					20
MULXU	MULXU.B Rs, Rd	1					12
	MULXU.W Rs, ERd	1					20
NEG	NEG.B Rd	1					
	NEG.W Rd	1					
	NEG.L ERd	1					
NOP	NOP	1					
NOT	NOT.B Rd	1					
	NOT.W Rd	1					
	NOT.L ERd	1					
OR	OR.B #xx:8, Rd	1					
	OR.B Rs, Rd	1					
	OR.W #xx:16, Rd	2					
	OR.W Rs, Rd	1					
	OR.L #xx:32, ERd	3					
	OR.L ERs, ERd	2					
ORC	ORC #xx:8, CCR	1					
POP	POP.W Rn	1				1	2
	POP.L ERn	2				2	2
PUSH	PUSH.W Rn	1				1	2
	PUSH.L ERn	2				2	2
ROTL	ROTL.B Rd	1					
	ROTL.W Rd	1					
	ROTL.L ERd	1					
ROTR	ROTR.B Rd	1					
	ROTR.W Rd	1					
	ROTR.L ERd	1					
ROTXL	ROTXL.B Rd	1					
	ROTXL.W Rd	1					
	ROTXL.L ERd	1					



Instruction	Mnemonic	Instruction Fetch I	Branch Addr. Read J	Stack Operation K	Byte Data Access L	Word Data Access M	Internal Operation N
ROTXR	ROTXR.B Rd	1					
	ROTXR.W Rd	1					
	ROTXR.L ERd	1					
RTE	RTE	2		2			2
RTS	RTS	2		1			2
SHAL	SHAL.B Rd	1					
	SHAL.W Rd	1					
	SHAL.L ERd	1					
SHAR	SHAR.B Rd	1					
	SHAR.W Rd	1					
	SHAR.L ERd	1					
SHLL	SHLL.B Rd	1					
	SHLL.W Rd	1					
	SHLL.L ERd	1					
SHLR	SHLR.B Rd	1					
	SHLR.W Rd	1					
	SHLR.L ERd	1					
SLEEP	SLEEP	1					
STC	STC CCR, Rd	1					
	STC CCR, @ERd	2				1	
	STC CCR, @(d:16,ERd)	3				1	
	STC CCR, @(d:24,ERd)	5				1	
	STC CCR,@-ERd	2				1	2
	STC CCR, @aa:16	3				1	
	STC CCR, @aa:24	4				1	
SUB	SUB.B Rs, Rd	1					
	SUB.W #xx:16, Rd	2					
	SUB.W Rs, Rd	1					
	SUB.L #xx:32, ERd	3					
	SUB.L ERs, ERd	1					
SUBS	SUBS #1/2/4, ERd	1					

Instruction	Mnemonic	Instruction Fetch I	Branch Addr. Read J	Stack Operation K	Byte Data Access L	Word Data Access M	Internal Operation N
SUBX	SUBX #xx:8, Rd	1					
	SUBX. Rs, Rd	1					
TRAPA	TRAPA #xx:2	2	1	2			4
XOR	XOR.B #xx:8, Rd	1					
	XOR.B Rs, Rd	1					
	XOR.W #xx:16, Rd	2					
	XOR.W Rs, Rd	1					
	XOR.L #xx:32, ERd	3					
	XOR.L ERs, ERd	2					
XORC	XORC #xx:8, CCR	1					

Notes: 1. n: Specified value in R4L and R4. The source and destination operands are accessed n+1 times respectively.

2. Cannot be used in this LSI.



A.4 Combinations of Instructions and Addressing Modes

Table A.5 Combinations of Instructions and Addressing Modes

		Addressing Mode												
Functions	Instructions	XX#	Rn	@ERn	@(d:16.ERn)	@(d:24.ERn)	@ERn+/@ERn	@aa:8	@aa:16	@aa:24	@(d:8.PC)	@(d:16.PC)	@ @ aa:8	
Data	MOV	BWL	BWL	BWL	BWL	BWL	BWL	В	BWL	BWL	_	—	_	—
transfer	POP, PUSH	—	—	—	_	_	_	_	—	_	_	_	_	WL
instructions	MOVFPE, MOVTPE	_	_	_	-	—	_	_	-	-	_	_		—
Arithmetic	ADD, CMP	BWL	BWL	—	—		—	—	—	—	—	—	—	—
operations	SUB	WL	BWL	—	—		—	—	—	—	—	—	—	—
	ADDX, SUBX	В	В	—	_	_	_	_	—	_	_	_	_	—
	ADDS, SUBS	—	L	—	_	_	_	_	—	_	_	_	_	—
	INC, DEC	—	BWL	—	_	_	_	_	—	_	_	_	_	—
	DAA, DAS	—	В	—	_	_	_	_	—	_	_	_	_	—
	MULXU, MULXS, DIVXU, DIVXS	_	BW		_	_			_	_	_	_		
	NEG	_	BWL	_	_		_	_	_	_	_	_	_	_
	EXTU, EXTS	—	WL	—	—	_	—	—	—	_	_	—	_	—
Logical	AND, OR, XOR	—	BWL	—	—	_	—	—	—	—	_	—	_	—
operations	NOT	—	BWL	—	—	—	—	—	—	—	—	—	_	—
Shift operation	ons	—	BWL	—	—	_	—	—	—	—	_	—	_	—
Bit manipulat	tions	—	В	В	_	_	_	В	—	_	_	_	_	—
Branching	BCC, BSR	—	—	_	_	_	_	_	—	_	_	_	_	—
instructions	JMP, JSR	—	—	0	_	_	_	_	—	_	0	0	_	—
	RTS	—	—	—	—		—	—	—	0	—	—	0	—
System	TRAPA	—	—	_	_	_	_	_	—	_	_	_	_	0
control	RTE	—	—	—	_	_	_	_	—	_	_	_	_	0
instructions	SLEEP	—	—	—	—		—	—	—	—	—	—	—	0
	LDC	В	В	W	W	W	W	—	W	W	—	—	—	0
	STC	—	В	W	W	W	W	—	W	W	—	—	—	—
	ANDC, ORC, XORC	В			_				_					
	NOP	—	—	—	—	—	_	_	_	_	_	_	_	0
Block data tr	ansfer instructions	-	-	—	-	-	—	—	-	-	_	-	_	BW



Appendix B I/O Port Block Diagrams

B.1 I/O Port Block Diagrams

 $\overline{\text{RES}}$ goes low in a reset, and $\overline{\text{SBY}}$ goes low in a reset and in standby mode.

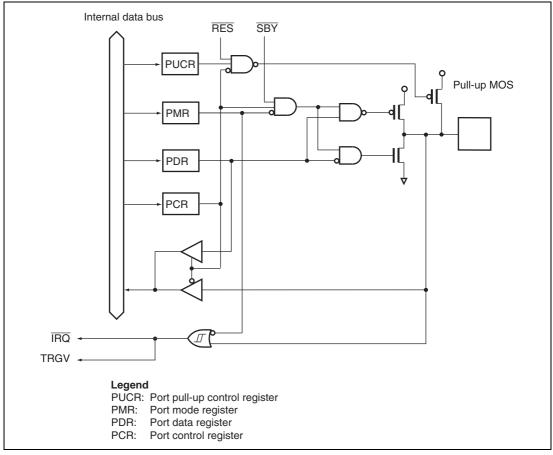


Figure B.1 Port 1 Block Diagram (P17)



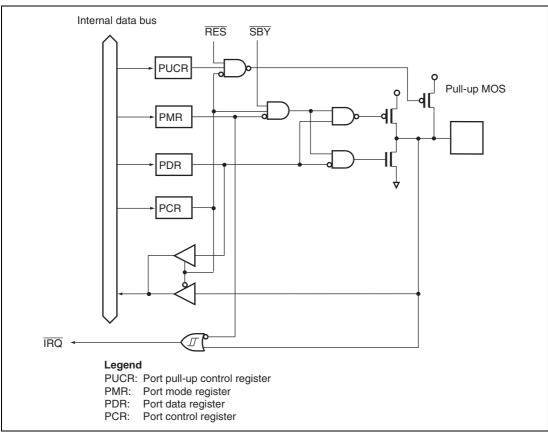


Figure B.2 Port 1 Block Diagram (P14)

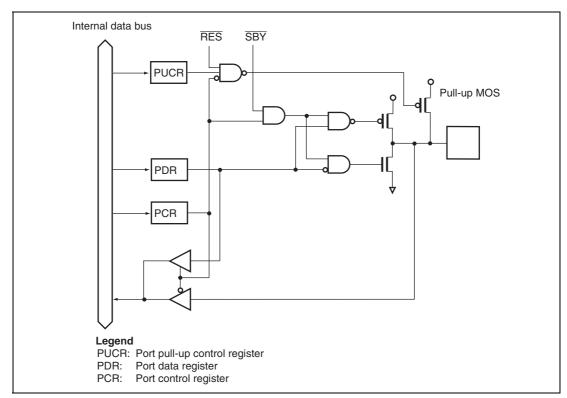


Figure B.3 Port 1 Block Diagram (P16, P15, P12*, P10)

Note: * This pin is available only in the H8/36014.



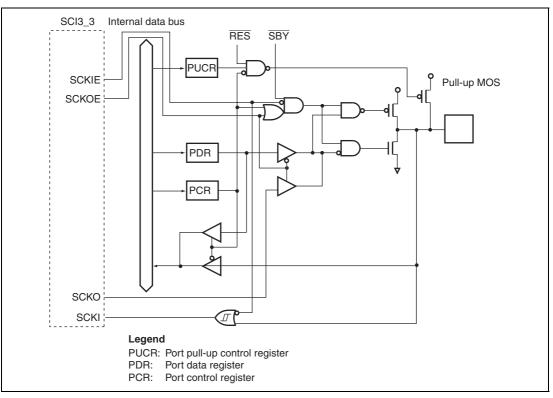


Figure B.4 Port 1 Block Diagram (P12) (H8/36024)

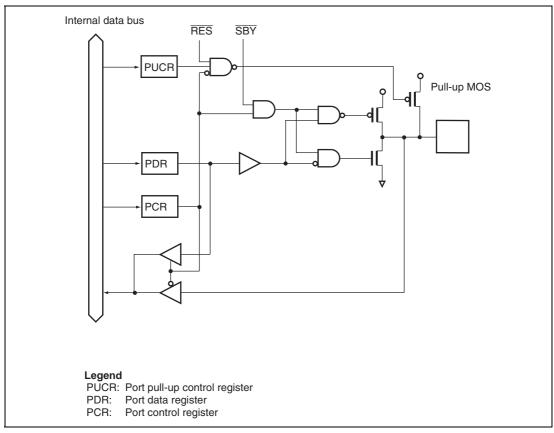


Figure B.5 Port 1 Block Diagram (P11)



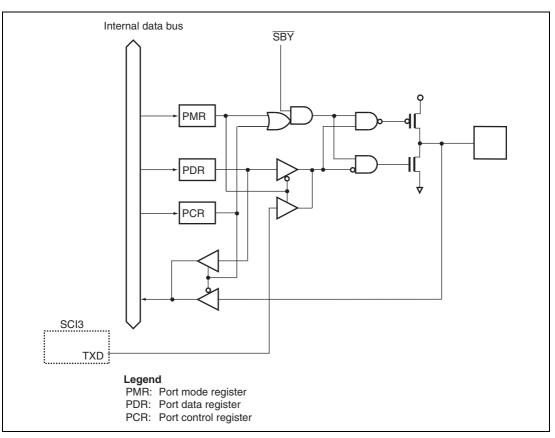


Figure B.6 Port 2 Block Diagram (P22)

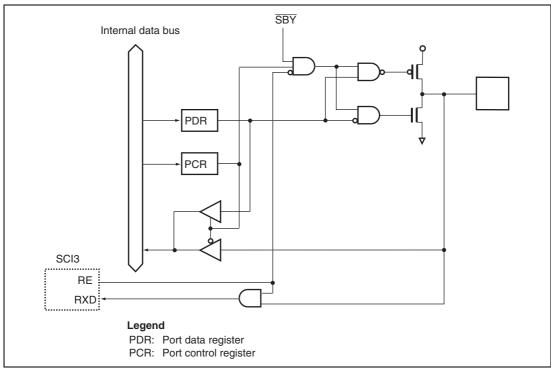


Figure B.7 Port 2 Block Diagram (P21)



Appendix

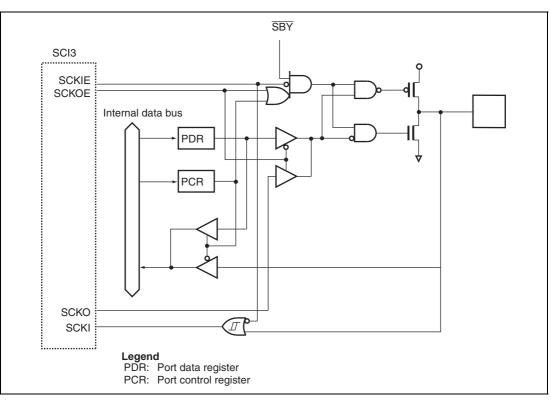


Figure B.8 Port 2 Block Diagram (P20)



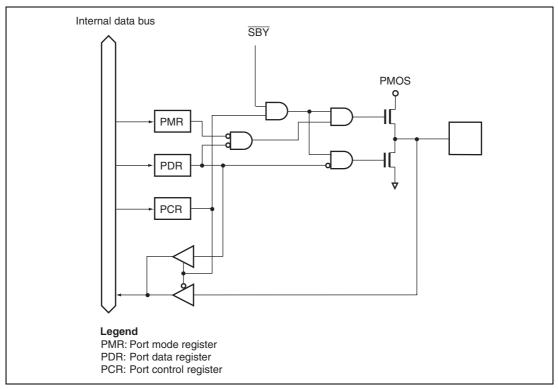


Figure B.9 Port 5 Block Diagram (P57, P56) (H8/36014)



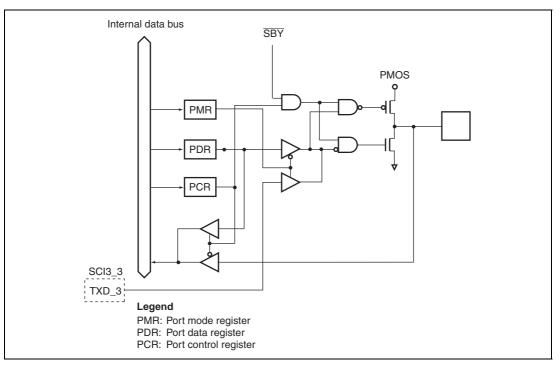


Figure B.10 Port 5 Block Diagram (P57) (H8/36024)



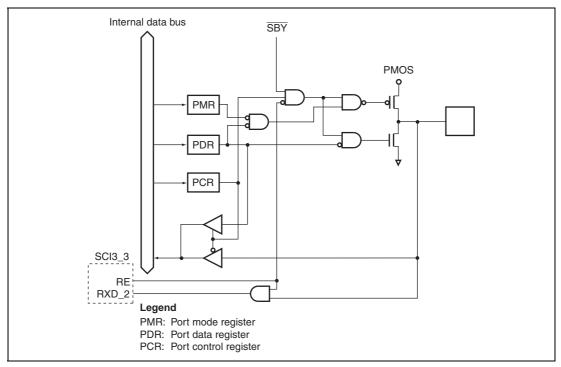


Figure B.11 Port 5 Block Diagram (P56) (H8/36024)



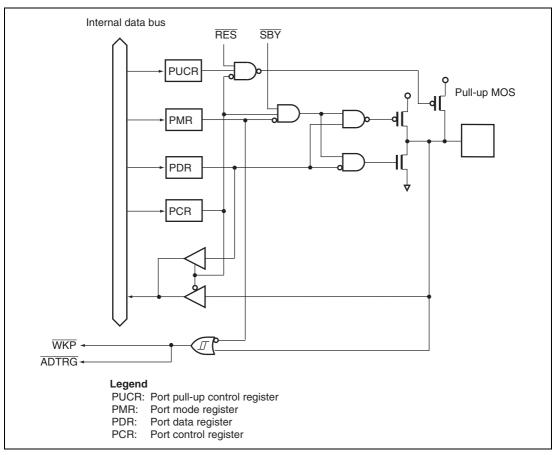


Figure B.12 Port 5 Block Diagram (P55)

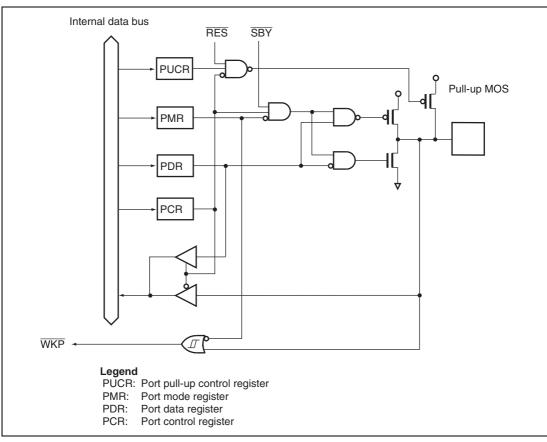


Figure B.13 Port 5 Block Diagram (P54 to P50)



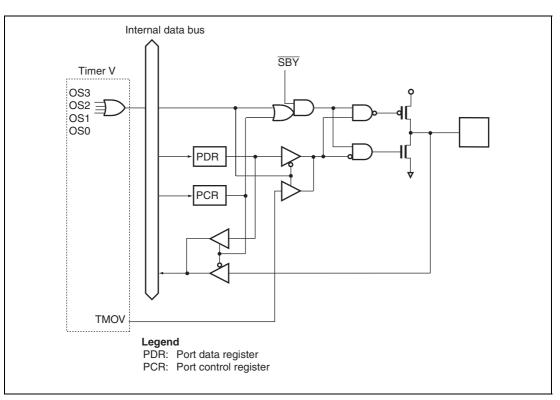


Figure B.14 Port 7 Block Diagram (P76)



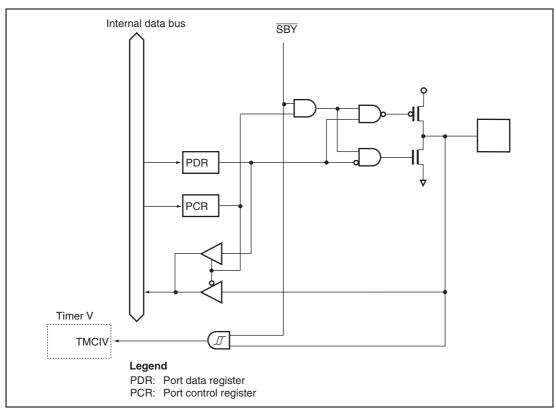


Figure B.15 Port 7 Block Diagram (P75)



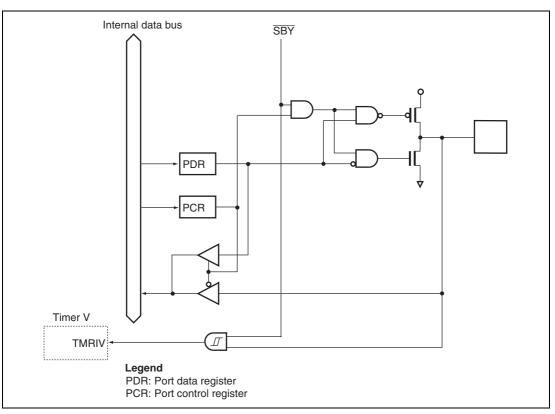


Figure B.16 Port 7 Block Diagram (P74)



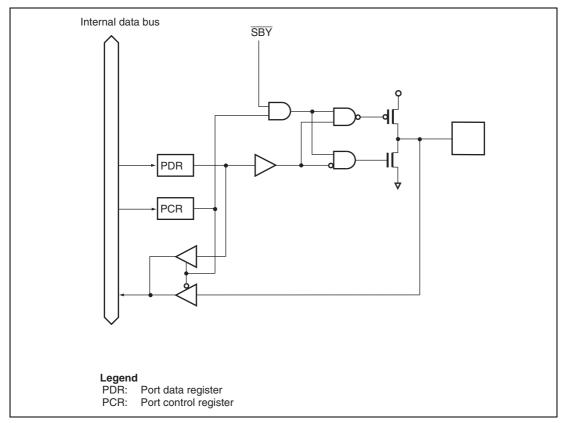


Figure B.17 Port 7 Block Diagram (P73)



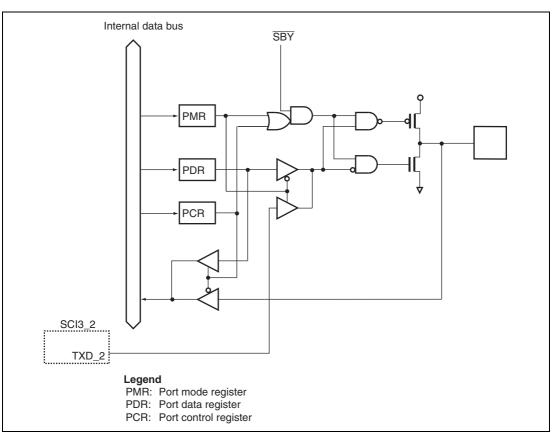


Figure B.18 Port 7 Block Diagram (P72)

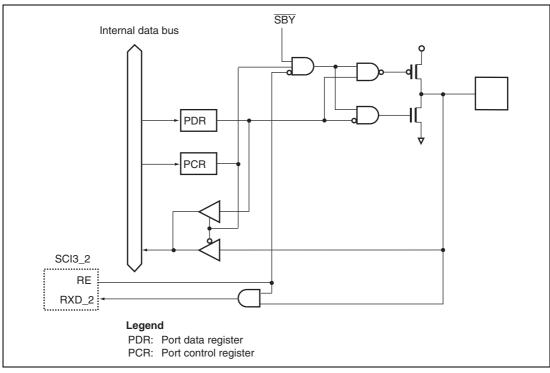


Figure B.19 Port 7 Block Diagram (P71)



Appendix

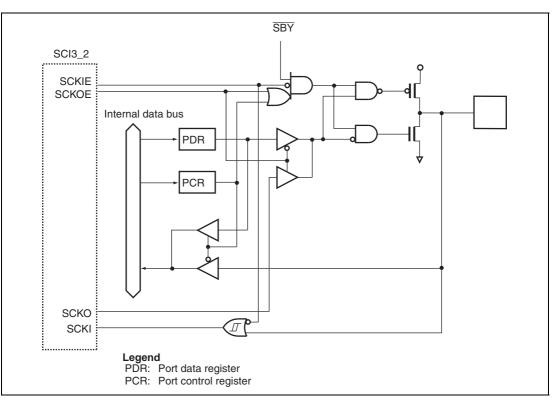


Figure B.20 Port 7 Block Diagram (P70)

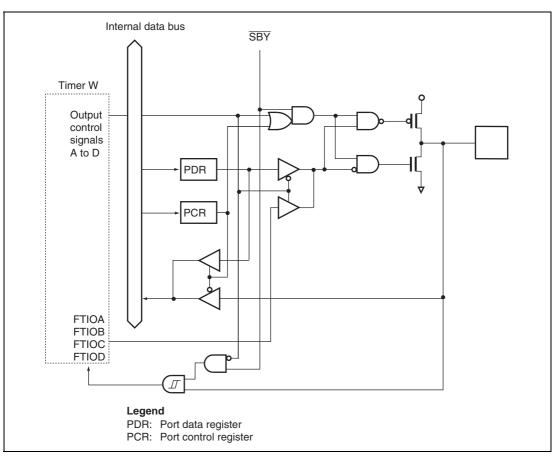


Figure B.21 Port 8 Block Diagram (P84 to P81)



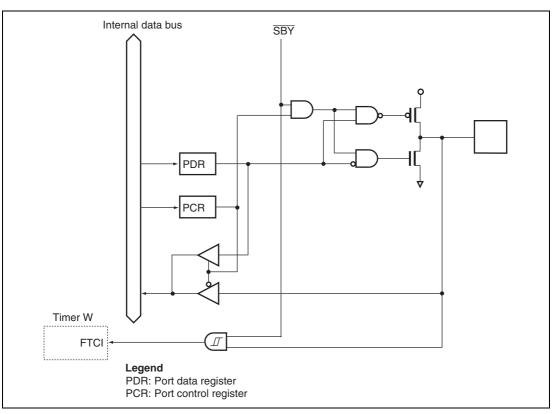


Figure B.22 Port 8 Block Diagram (P80)



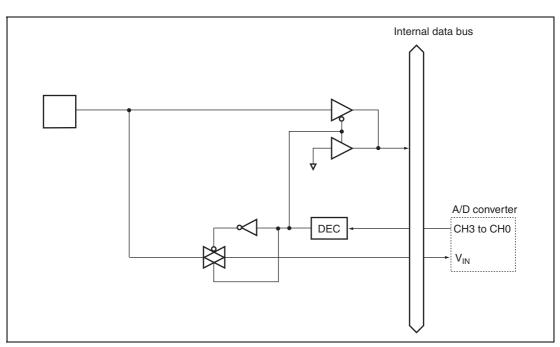


Figure B.23 Port B Block Diagram (PB3 to PB0)

B.2 Port States in Each Operating State

Port	Reset	Active	Sleep	Subsleep	Standby
P17 to P14, P12 to P10	High impedance	Functioning	Retained	Retained	High impedance*
P22 to P20	High impedance	Functioning	Retained	Retained	High impedance
P57 to P50	High impedance	Functioning	Retained	Retained	High impedance*
P76 to P70	High impedance	Functioning	Retained	Retained	High impedance
P84 to P80	High impedance	Functioning	Retained	Retained	High impedance
PB3 to PB0	High impedance	High impedance	High impedance	Retained	High impedance

Note: * High level output when the pull-up MOS is in on state.



Product Type		Product Code	Model Marking	Package Code	
H8/36024	Flash memory		HD64F36024FP	HD64F36024FP	LQFP-64 (FP-64E)
	version	product	HD64F36024FX	HD64F36024FX	LQFP-48 (FP-48F)
			HD64F36024FY	HD64F36024FY	LQFP-48 (FP-48B)
			HD64F36024FT	HD64F36024FT	QFN-48(TNP-48)
		Product	HD64F36024GFP	HD64F36024GFP	LQFP-64 (FP-64E)
		with POR & LVDC	HD64F36024GFX	HD64F36024GFX	LQFP-48 (FP-48F)
		a LVDC	HD64F36024GFY	HD64F36024GFY	LQFP-48 (FP-48B)
			HD64F36024GFT	HD64F36024GFT	QFN-48(TNP-48)
	Masked ROM		HD64336024FP	HD64336024(***)FP	LQFP-64 (FP-64E)
	version	product	HD64336024FX	HD64336024(***)FX	LQFP-48 (FP-48F)
			HD64336024FY	HD64336024(***)FY	LQFP-48 (FP-48B)
			HD64336024FT	HD64336024(***)FT	QFN-48(TNP-48)
		Product with POR & LVDC	HD64336024GFP	HD64336024G(***)FP	LQFP-64 (FP-64E)
			HD64336024GFX	HD64336024G(***)FX	LQFP-48 (FP-48F)
			HD64336024GFY	HD64336024G(***)FY	LQFP-48 (FP-48B)
			HD64336024GFT	HD64336024G(***)FT	QFN-48(TNP-48)
H8/36023	Masked ROM	Standard	HD64336023FP	HD64336023(***)FP	LQFP-64 (FP-64E)
	version	product	HD64336023FX	HD64336023(***)FX	LQFP-48 (FP-48F)
			HD64336023FY	HD64336023(***)FY	LQFP-48 (FP-48B)
			HD64336023FT	HD64336023(***)FT	QFN-48(TNP-48)
		Product	HD64336023GFP	HD64336023G(***)FP	LQFP-64 (FP-64E)
		with POR & LVDC	HD64336023GFX	HD64336023G(***)FX	LQFP-48 (FP-48F)
			HD64336023GFY	HD64336023G(***)FY	LQFP-48 (FP-48B)
			HD64336023GFT	HD64336023G(***)FT	QFN-48(TNP-48)

Appendix C Product Code Lineup

Product Ty	уре		Product Code	Model Marking	Package Code
H8/36022	Flash memory		HD64F36022FP	HD64F36022FP	LQFP-64 (FP-64E)
	version	product	HD64F36022FX	HD64F36022FX	LQFP-48 (FP-48F)
			HD64F36022FY	HD64F36022FY	LQFP-48 (FP-48B)
			HD64F36022FT	HD64F36022FT	QFN-48(TNP-48)
		Product	HD64F36022GFP	HD64F36022GFP	LQFP-64 (FP-64E)
		with POR & LVDC	HD64F36022GFX	HD64F36022GFX	LQFP-48 (FP-48F)
		a LVDC	HD64F36022GFY	HD64F36022GFY	LQFP-48 (FP-48B)
			HD64F36022GFT	HD64F36022GFT	QFN-48(TNP-48)
	Masked ROM	Standard	HD64336022FP	HD64336022(***)FP	LQFP-64 (FP-64E)
	version	product	HD64336022FX	HD64336022(***)FX	LQFP-48 (FP-48F)
			HD64336022FY	HD64336022(***)FY	LQFP-48 (FP-48B)
			HD64336022FT	HD64336022(***)FT	QFN-48(TNP-48)
		Product with POR & LVDC	HD64336022GFP	HD64336022G(***)FP	LQFP-64 (FP-64E)
			HD64336022GFX	HD64336022G(***)FX	LQFP-48 (FP-48F)
			HD64336022GFY	HD64336022G(***)FY	LQFP-48 (FP-48B)
			HD64336022GFT	HD64336022G(***)FT	QFN-48(TNP-48)
H8/36014 F	Flash memory	Standard product	HD64F36014FP	HD64F36014FP	LQFP-64 (FP-64E)
N	version		HD64F36014FX	HD64F36014FX	LQFP-48 (FP-48F)
			HD64F36014FY	HD64F36014FY	LQFP-48 (FP-48B)
			HD64F36014FT	HD64F36014FT	QFN-48(TNP-48)
		Product with POR & LVDC	HD64F36014GFP	HD64F36014GFP	LQFP-64 (FP-64E)
			HD64F36014GFX	HD64F36014GFX	LQFP-48 (FP-48F)
			HD64F36014GFY	HD64F36014GFY	LQFP-48 (FP-48B)
			HD64F36014GFT	HD64F36014GFT	QFN-48(TNP-48)
	Masked ROM	Standard	HD64336014FP	HD64336014(***)FP	LQFP-64 (FP-64E)
	version	product	HD64336014FX	HD64336014(***)FX	LQFP-48 (FP-48F)
			HD64336014FY	HD64336014(***)FY	LQFP-48 (FP-48B)
			HD64336014FT	HD64336014(***)FT	QFN-48(TNP-48)
		Product	HD64336014GFP	HD64336014G(***)FP	LQFP-64 (FP-64E)
		with POR	HD64336014GFX	HD64336014G(***)FX	LQFP-48 (FP-48F)
		& LVDC	HD64336014GFY	HD64336014G(***)FY	LQFP-48 (FP-48B)
			HD64336014GFT	HD64336014G(***)FT	QFN-48(TNP-48)



Product Type		Product Code	Model Marking	Package Code	
H8/36013	Masked ROM	Standard	HD64336013FP	HD64336013(***)FP	LQFP-64 (FP-64E)
	version	product	HD64336013FX	HD64336013(***)FX	LQFP-48 (FP-48F)
			HD64336013FY	HD64336013(***)FY	LQFP-48 (FP-48B)
			HD64336013FT	HD64336013(***)FT	QFN-48(TNP-48)
		Product	HD64336013GFP	HD64336013G(***)FP	LQFP-64 (FP-64E)
		with POR & LVDC	HD64336013GFX	HD64336013G(***)FX	LQFP-48 (FP-48F)
		a LVDC	HD64336013GFY	HD64336013G(***)FY	LQFP-48 (FP-48B)
			HD64336013GFT	HD64336013G(***)FT	QFN-48(TNP-48)
H8/36012	Flash memory	Standard	HD64F36012FP	HD64F36012FP	LQFP-64 (FP-64E)
	version	product	HD64F36012FX	HD64F36012FX	LQFP-48 (FP-48F)
			HD64F36012FY	HD64F36012FY	LQFP-48 (FP-48B)
			HD64F36012FT	HD64F36012FT	QFN-48(TNP-48)
		Product with POR & LVDC	HD64F36012GFP	HD64F36012GFP	LQFP-64 (FP-64E)
			HD64F36012GFX	HD64F36012GFX	LQFP-48 (FP-48F)
			HD64F36012GFY	HD64F36012GFY	LQFP-48 (FP-48B)
			HD64F36012GFT	HD64F36012GFT	QFN-48(TNP-48)
	Masked ROM	M Standard product Product with POR & LVDC	HD64336012FP	HD64336012(***)FP	LQFP-64 (FP-64E)
	version		HD64336012FX	HD64336012(***)FX	LQFP-48 (FP-48F)
			HD64336012FY	HD64336012(***)FY	LQFP-48 (FP-48B)
			HD64336012FT	HD64336012(***)FT	QFN-48(TNP-48)
			HD64336012GFP	HD64336012G(***)FP	LQFP-64 (FP-64E)
			HD64336012GFX	HD64336012G(***)FX	LQFP-48 (FP-48F)
			HD64336012GFY	HD64336012G(***)FY	LQFP-48 (FP-48B)
			HD64336012GFT	HD64336012G(***)FT	QFN-48(TNP-48)
H8/36011	Masked ROM	Standard	HD64336011FP	HD64336011(***)FP	LQFP-64 (FP-64E)
	version	product	HD64336011FX	HD64336011(***)FX	LQFP-48 (FP-48F)
			HD64336011FY	HD64336011(***)FY	LQFP-48 (FP-48B)
			HD64336011FT	HD64336011(***)FT	QFN-48(TNP-48)
		Product	HD64336011GFP	HD64336011G(***)FP	LQFP-64 (FP-64E)
		with POR & LVDC	HD64336011GFX	HD64336011G(***)FX	LQFP-48 (FP-48F)
			HD64336011GFY	HD64336011G(***)FY	LQFP-48 (FP-48B)
			HD64336011GFT	HD64336011G(***)FT	QFN-48(TNP-48)

Product Type		Product Code	Model Marking	Package Code	
version		Standard product	HD64336010FP	HD64336010(***)FP	LQFP-64 (FP-64E)
	version		HD64336010FX	HD64336010(***)FX	LQFP-48 (FP-48F)
		HD64336010FY	HD64336010(***)FY	LQFP-48 (FP-48B)	
		HD64336010FT	HD64336010(***)FT	QFN-48(TNP-48)	
		Product with POR & LVDC	HD64336010GFP	HD64336010G(***)FP	LQFP-64 (FP-64E)
			HD64336010GFX	HD64336010G(***)FX	LQFP-48 (FP-48F)
			HD64336010GFY	HD64336010G(***)FY	LQFP-48 (FP-48B)
			HD64336010GFT	HD64336010G(***)FT	QFN-48(TNP-48)

Legend

POR & LVDC: Power-on reset and low-voltage detection circuits

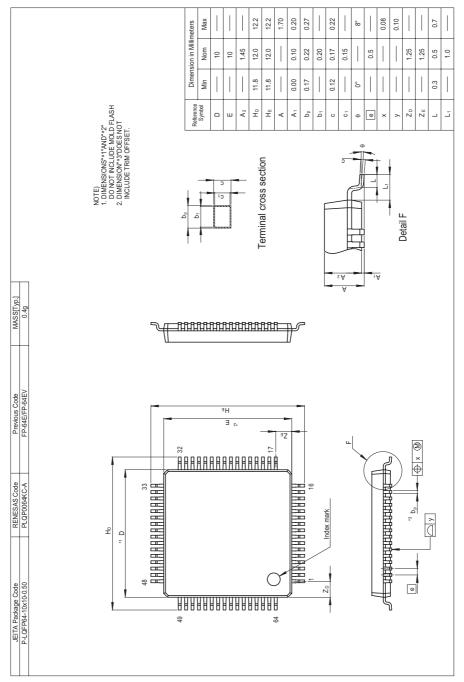
(***): ROM code



Appendix D Package Dimensions

The package dimensions that are shows in the Renesas Semiconductor Packages Data Book have priority.









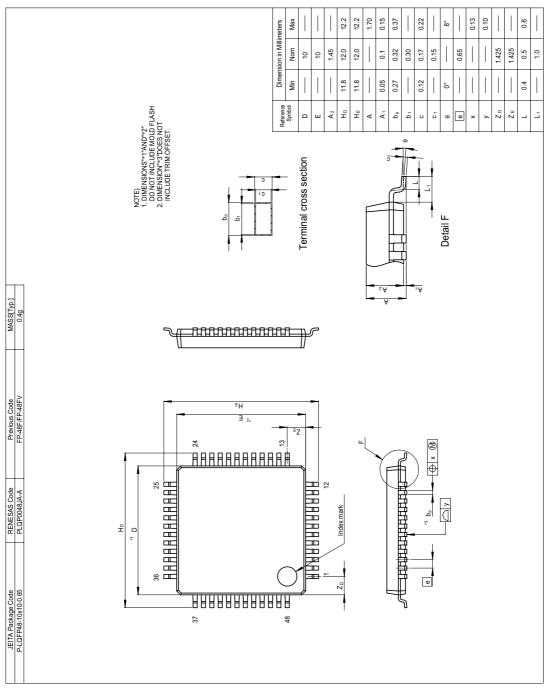
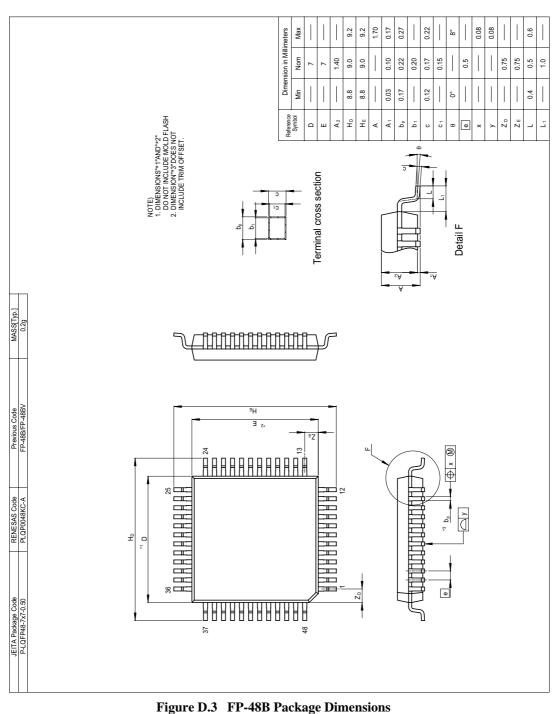


Figure D.2 FP-48F Package Dimensions

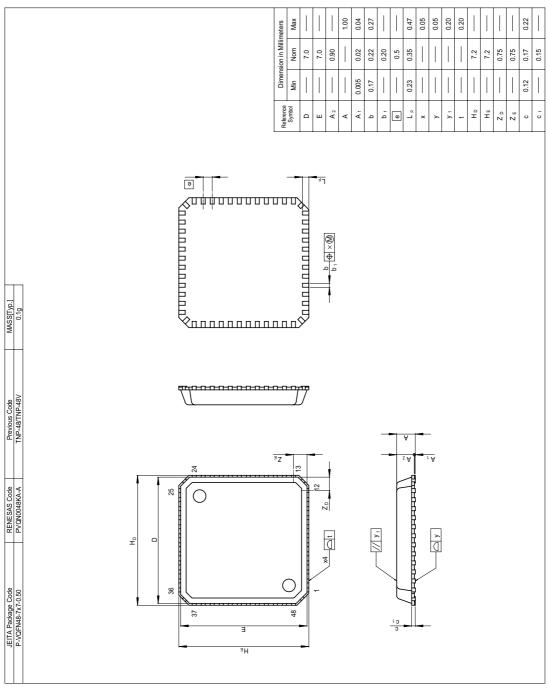
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Appendix







Main Revisions and Additions in this Edition

Item	Page	Revision (See Manual for Details)
Preface	vi, vii	When using the on-chip emulator (E7, E8) for H8/36014 program development and debugging, the following restrictions must be noted.
		 The NMI pin is reserved for the E7 or E8, and cannot be used.
		2. Area H'7000 to H'7FFF is used by the E7 or E8, and is not available to the user.
		4. When the E7 or E8 is used, address breaks can be set as either available to the user or for use by the E7 or E8. If address breaks are set as being used by the E7 or E8, the address break control registers must not be accessed.
		 When the E7 or E8 is used, NMI is an input/output pin (open-drain in output mode).
		6. Use channel 1 of the SCI3 (P21/RXD, P22/TXD) in on-
		board programming mode by boot mode.
		Note has been deleted.
Section 1 Overview 1.2 Internal Block Diagram Figure 1.1 Internal Block Diagram	3	3 Can also be used for the E7 or E8 emulator.
Figure 1.2 Pin Arrangement (FP-64E)	4	2 Can also be used for the E7 or E8 emulator.
Figure 1.3 Pin Arrangement (FP-48F, FP- 48B, TNP-48)	5	2 Can also be used for the E7 or E8 emulator.
Table 1.1 Pin Functions	7	
		TypeFunctionsE10TInterface pin for the E10T, E8, or E7 emulator
Section 7 ROM	77	The features of the 32-kbyte (4 kbytes of them are the control program area for E7 or E8) flash memory built into the HD64F36024 and HD64F36014 are summarized below.
Section 8 RAM	93	Note: When the E7 or E8 is used, area H'F780 to H'FB7F must not be accessed.

Item	Page	Revision	(See Ma	anual for Detai	ls)	
Section 12 Watchdog Timer	168	Bit Bi	it Name	Descriptio	n	
12.2.1 Timer Control/Status Register WD (TCSRWD)		4 T(CSRWE		rol/Status Registe	r WD
Section 14 A/D Converter	220				should be done by	
14.3.1 A/D Data Registers A to D (ADDRA to ADDRD)				t then the lowe initialized to H	r one. Word acces '0000.	ss is also
Section 18 Electrical Characteristics	254					Values
Table 18.2 DC Characteristics (1)		Item	Symbol	Applicable Pins	Test Condition	Min
		Input high	$V_{\rm IH}$	PB3 to PB0	V_{cc} = 4.0 V to 5.5 V	$V_{cc} \times 0.7$
		voltage				$V_{cc} \times 0.8$
		Input low voltage	V _{IL}	RXD, RXD_2, RXD_3* ¹ , P12 to P10, P17 to P14,	$\rm V_{cc}$ = 4.0 V to 5.5 V	-0.3
				: PB3 to PB0		
Table 18.2 DC	257					
Characteristics (1)	-	Mode		RES Pin	Internal State	
		Active mo	ode 1	V _{cc}	Operates	
		Active mo	ode 2		Operates (¢OSC/64)	
		Sleep mo	de 1	V _{cc}	Only timers oper	ate
		Sleep mo	ode 2		Only timers oper (¢OSC/64)	ate
				~ • • • • • • • • • • • • • • • • •		

Item	Page	Revision	(See Ma	anual for Detai	ls)	
Table 18.10 DC Characteristics (1)	270					Values
		Item	Symbol	Applicable Pins	Test Condition	Min
		Input high	$V_{\rm IH}$	PB3 to PB0	V_{cc} = 4.0 V to 5.5 V	V _{cc} ×0.7
		voltage				$V_{cc} \times 0.8$
		Input low voltage	V _{IL}	RXD, RXD_2, RXD_3* ¹ , P12 to P10, P17 to P14,	V_{cc} = 4.0 V to 5.5 V	-0.3
				:		
				PB3 to PB0		
T 10 10 DO	070					
Table 18.10 DC Characteristics (1)	273	Mode		RES Pin	Internal State	
		Active mo	ode 1	V _{cc}	Operates	
		Active mo	ode 2		Operates (¢OSC/64)	
		Sleep mo	de 1	V _{cc}	Only timers oper	ate
		Sleep mo	ode 2		Only timers oper (¢OSC/64)	ate
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